

PUBLIC
EXHIBIT 2
(Part 22 of 23)

8300541



THE UNITED STATES OF AMERICA

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**UNITED STATES DEPARTMENT OF COMMERCE
United States Patent and Trademark Office**

October 4, 2022

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April 15, 2022

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Trudie Wallace
Certifying Officer



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| PATENT ASSIGNMENT COVER SHEET |
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Electronic Version v1.1
 Stylesheet Version v1.2

EPAS ID: PAT7282440

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|------------------------------|-------------------|
| SUBMISSION TYPE: | NEW ASSIGNMENT |
| NATURE OF CONVEYANCE: | SECURITY INTEREST |

CONVEYING PARTY DATA

| Name | Execution Date |
|--------------------------------------|----------------|
| CORTLAND CAPITAL MARKET SERVICES LLC | 04/01/2022 |

RECEIVING PARTY DATA

| | |
|--------------------------|----------------------------------|
| Name: | HILCO PATENT ACQUISITION 56, LLC |
| Street Address: | 401 N. MICHIGAN AVE. |
| Internal Address: | SUITE 1630 |
| City: | CHICAGO |
| State/Country: | ILLINOIS |
| Postal Code: | 60611 |
| Name: | BELL SEMICONDUCTOR, LLC |
| Street Address: | 401 N. MICHIGAN AVE. |
| Internal Address: | SUITE 1630 |
| City: | CHICAGO |
| State/Country: | ILLINOIS |
| Postal Code: | 60611 |
| Name: | BELL NORTHERN RESEARCH, LLC |
| Street Address: | 401 N. MICHIGAN AVE. |
| Internal Address: | SUITE 1630 |
| City: | CHICAGO |
| State/Country: | ILLINOIS |
| Postal Code: | 60611 |

PROPERTY NUMBERS Total: 1204

| Property Type | Number |
|----------------|---------|
| Patent Number: | 5888120 |
| Patent Number: | 5973767 |
| Patent Number: | 6130428 |
| Patent Number: | 6407559 |
| Patent Number: | 5897381 |
| Patent Number: | 5893952 |
| Patent Number: | 5756369 |

| Property Type | Number |
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| Patent Number: | 5926720 |
| Patent Number: | 6239499 |
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| Patent Number: | 6239491 |
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| Patent Number: | 5646073 |
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| Patent Number: | 6841308 |

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| Patent Number: | 6998716 |
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PATENT
REEL: 060885 FRAME: 0003

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| Patent Number: | 6707114 |
| Patent Number: | 6211555 |
| Patent Number: | 6514824 |
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PATENT
REEL: 060885 FRAME: 0005

| Property Type | Number |
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| Patent Number: | 6620729 |
| Patent Number: | 6168502 |
| Patent Number: | 5868608 |
| Patent Number: | 6426131 |
| Patent Number: | 6596579 |
| Patent Number: | 7176082 |
| Patent Number: | 6822282 |
| Patent Number: | 5892272 |
| Patent Number: | 5482897 |
| Patent Number: | 5898228 |
| Patent Number: | 6221681 |
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| Patent Number: | 5874329 |
| Patent Number: | 6030460 |
| Patent Number: | 5710079 |
| Patent Number: | 7763414 |
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| Patent Number: | 6939800 |
| Patent Number: | 7427563 |
| Patent Number: | 7396760 |
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| Patent Number: | 7670645 |
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PATENT
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| Patent Number: | 5770492 |
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| Patent Number: | 5717238 |
| Patent Number: | 5598021 |
| Patent Number: | 5663083 |
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| Patent Number: | 5654210 |
| Patent Number: | 7955919 |
| Patent Number: | 6081004 |
| Patent Number: | 8021955 |
| Patent Number: | 7619294 |
| Patent Number: | 7001823 |
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| Patent Number: | 8106480 |
| Patent Number: | 7666750 |
| Patent Number: | 7582566 |
| Patent Number: | 7361965 |
| Patent Number: | 6872612 |
| Patent Number: | 7081379 |
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| Patent Number: | 7678639 |
| Patent Number: | 7635888 |
| Patent Number: | 7022581 |
| Patent Number: | 8039923 |
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| Patent Number: | 8227319 |
| Patent Number: | 7714361 |
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| Patent Number: | 6458016 |
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| Patent Number: | 5723897 |
| Patent Number: | 6690037 |
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PATENT
REEL: 060885 FRAME: 0009

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| Patent Number: | 6355184 |
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| Patent Number: | 5576763 |
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| Patent Number: | 6191495 |
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| Patent Number: | 6163234 |
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| Patent Number: | 6540974 |
| Patent Number: | 6762459 |
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| Patent Number: | 7220362 |
| Patent Number: | 7029591 |
| Patent Number: | 6439972 |
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PATENT
REEL: 060885 FRAME: 0010

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| Patent Number: | 6614507 |
| Patent Number: | 6787180 |
| Patent Number: | 6579371 |
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| Patent Number: | 7358594 |
| Patent Number: | 6885436 |
| Patent Number: | 7298458 |
| Patent Number: | 7098996 |
| Patent Number: | 6090656 |
| Patent Number: | 6545305 |
| Patent Number: | 7160805 |
| Patent Number: | 6642597 |
| Patent Number: | 6807655 |
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| Patent Number: | 6613637 |
| Patent Number: | 6737342 |
| Patent Number: | 6713394 |
| Patent Number: | 6489242 |
| Patent Number: | 7056392 |
| Patent Number: | 7201176 |
| Patent Number: | 6375791 |
| Patent Number: | 6716364 |
| Patent Number: | 6699766 |
| Patent Number: | 7148146 |
| Patent Number: | 6614093 |
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| Patent Number: | 6774057 |
| Patent Number: | 6472314 |
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| Patent Number: | 7345364 |
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| Patent Number: | 7078280 |
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| Patent Number: | 7056783 |
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| Patent Number: | 5858873 |
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| Patent Number: | 6033202 |
| Patent Number: | 6322736 |
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PATENT
REEL: 060885 FRAME: 0012

| Property Type | Number |
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| Patent Number: | 6627963 |
| Patent Number: | 6762457 |
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| Patent Number: | 6373087 |
| Patent Number: | 6730601 |
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| Patent Number: | 5851870 |
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| Patent Number: | 7169714 |
| Patent Number: | 6541394 |
| Patent Number: | 6432812 |
| Patent Number: | 7045835 |
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| Patent Number: | 6670242 |
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| Patent Number: | 6504202 |
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| Patent Number: | 6335295 |
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| Patent Number: | 6147409 |
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| Patent Number: | 7372547 |
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| Patent Number: | 5656399 |
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| Patent Number: | 6647348 |
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|----------------|---------|
| Patent Number: | 6074517 |
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| Patent Number: | 6066266 |
| Patent Number: | 6743725 |
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| Patent Number: | 5936876 |
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| Patent Number: | 6020242 |
| Patent Number: | 5985679 |
| Patent Number: | 5893756 |
| Patent Number: | 5973398 |
| Patent Number: | 5869395 |
| Patent Number: | 5985746 |
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| Application Number: | 12680017 |

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|--------------------|--|
| NAME OF SUBMITTER: | JOSHUA GAMMON |
| SIGNATURE: | //Joshua Gammon// |
| DATE SIGNED: | 04/15/2022 |
| | This document serves as an Oath/Declaration (37 CFR 1.63). |

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RELEASE OF PATENT SECURITY INTEREST

This RELEASE OF PATENT SECURITY INTEREST ("**Release**") is made and effective as of April 1, 2022 and granted by CORTLAND CAPITAL MARKET SERVICES LLC (the "**Collateral Agent**"), as collateral agent (in such capacity, together with its successors and permitted assigns) for the secured parties under the Loan Agreement referred to below (the "**Secured Parties**"), in favor of HILCO PATENT ACQUISITION 56, LLC, a Delaware limited liability company, BELL SEMICONDUCTOR, LLC, a Delaware limited liability company and BELL NORTHER RESEARCH, LLC, a Delaware limited liability company (each a "**Grantor**" and collectively the "**Grantors**") and their successors, assigns and legal representatives.

Background

Pursuant to the Term Loan Agreement dated as of January 24, 2018 as amended on November 17, 2020 (the "**Loan Agreement**") among Hilco Patent Acquisition 56, LLC, as borrower, Bell Semiconductor, LLC and Bell Northern Research, LLC, as guarantors, the Collateral Agent and the lenders party thereto, the Grantors executed and delivered to the Collateral Agent (i) that certain Security Agreement by and among the Grantors and the Collateral Agent dated as of January 24, 2018 (the "**Master Security Agreement**") and (ii) that certain Patent Security Agreement by and among the Grantors and the Collateral Agent dated as of January 24, 2018 (the "**Patent Security Agreement**" and, together with the Master Security Agreement, the "**Security Agreements**");

Pursuant to the Security Agreements, each Grantor pledged and granted to the Collateral Agent for the ratable benefit of the Secured Parties a security interest in and to all of the right, title and interest of such Grantor in, to and under the Patent Collateral (as defined below);

The Patent Security Agreement was recorded with the United States Patent and Trademark Office at Reel 045216, Frame 0020 on February 1, 2018; and

The Grantors have requested that the Collateral Agent enter into this Release in order to effectuate, evidence and record the release and reassignment to the Grantors of any and all right, title and interest the Collateral Agent and the Secured Parties may have in the Patent Collateral pursuant to the Security Agreements.

Collateral Agent therefore agrees as follows:

1. Release of Security Interest. Collateral Agent, on behalf of itself and the Secured Parties, their successors, legal representatives and assigns, hereby terminates the Patent Security Agreement and terminates, releases and discharges any and all security interests that it has pursuant to the Security Agreements in any and all right, title and interest of the Grantors, and reassigns to the Grantors any and all right, title and interest that it may have, in, to and under the following (collectively, the "**Patent Collateral**");

(a) any and all patents, patent applications and other patent rights and any other governmental authority-issued indicia of invention ownership, including the patents and patent applications listed in Schedule I hereto, and all reissues, divisions, continuations, continuations-in-part, renewals, extensions and reexaminations thereof and amendments thereto (the "**Patents**");

(b) all rights of any kind whatsoever of such Grantor accruing under any of the foregoing provided by applicable law of any jurisdiction, by international treaties and conventions and otherwise throughout the world;

(c) any and all license and other agreements in which such Grantor has granted or is granted a license or other right under any Patent;

(d) any and all royalties, fees, income, payments and other proceeds now or hereafter due or payable with respect to any and all of the foregoing; and

(e) any and all claims and causes of action, with respect to any of the foregoing, whether occurring before, on or after the date hereof, including all rights to and claims for damages, restitution and injunctive and other legal and equitable relief for past, present and future infringement, misappropriation, violation, misuse, breach or default, with the right but no obligation to sue for such legal and equitable relief and to collect, or otherwise recover, any such damages.

2. Further Assurances. Collateral Agent agrees to take all further actions, and provide to the Grantors and their successors, assigns and legal representatives all such cooperation and assistance, including, without limitation, the execution and delivery of any and all further documents or other instruments, as the Grantors and their successors, assigns and legal representatives may reasonably request in order to confirm, effectuate or record this Release.

3. Governing Law. This Release and any claim, controversy, dispute or cause of action (whether in contract or tort or otherwise) based upon, arising out of or relating to this Release and the transactions contemplated hereby shall be governed by, and construed in accordance with, the laws of the United States and the State of New York, without giving effect to any choice or conflict of law provision or rule (whether of the State of New York or any other jurisdiction).

[SIGNATURE PAGE FOLLOWS]

Collateral Agent has caused this Release to be duly executed and delivered by its officer duly authorized as of the date stated in the first paragraph above.

CORTLAND CAPITAL MARKET SERVICES
LLC,

as Collateral Agent

By: 

Name: Emily Ergang Pappas

Title: Head of Legal, North America

ACKNOWLEDGED AND
AGREED as of the date stated in
the first paragraph above:

HILCO PATENT ACQUISITION
56, LLC, as Grantor

By: 

Name: Michael Friedman

Title: CEO

BELL SEMICONDUCTOR, LLC,
as Grantor

By: 

Name: John Veschi

Title: CEO

BELL NORTHERN RESEARCH,
LLC, as Grantor

By: 

Name: Afzal Dean

Title: CEO

**SCHEDULE 1
TO
RELEASE OF PATENT SECURITY INTEREST
[SEE ATTACHED.]**

**PATENT
REEL: 060885 FRAME: 0042**

Schedule B(1)(a) - Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------|----------|------------|------------|-----------|--------------------------|---|
| 0839689 | 5888120 | 1997-09-29 | 1999-03-30 | Expired | United States of America | Method and apparatus for chemical mechanical polishing |
| 09216395 | | 1998-12-18 | | Abandoned | United States of America | Method and Apparatus for Chemical Mechanical Polishing |
| 08700650 | | 1996-08-14 | | Abandoned | United States of America | Off-Axis Illuminator Lens Mask For Photolithographic Projection System |
| 09105546 | 5973767 | 1998-06-26 | 1999-10-26 | Expired | United States of America | Off-axis illuminator lens mask for photolithographic projection system |
| 09089461 | 6130428 | 1998-06-02 | 2000-10-10 | Granted | United States of America | Laser Fault correction of semiconductor devices |
| 09604865 | 6407559 | 2000-06-28 | 2002-06-18 | Granted | United States of America | Laser fault correction of semiconductor devices |
| 08955384 | 5897381 | 1997-10-21 | 1999-04-27 | Expired | United States of America | Method of forming a layer and semiconductor substrate |
| 08954791 | 5893952 | 1997-10-21 | 1999-04-13 | Expired | United States of America | Apparatus for rapid thermal processing of a wafer |
| 08678718 | 5756369 | 1996-07-11 | 1998-05-26 | Expired | United States of America | Rapid thermal processing using a narrowband infrared source and feedback |
| 08924902 | 5926720 | 1997-09-08 | 1999-07-20 | Expired | United States of America | Consistent alignment mark profiles on semiconductor wafers using PVD shadowing |
| 09198208 | 6239499 | 1998-11-23 | 2001-05-29 | Expired | United States of America | Consistent alignment mark profiles on semiconductor wafers using PVD shadowing |
| 09363084 | | 1999-07-28 | | Abandoned | United States of America | Nitrogen Implanted Polysilicon Gate For Mosfet Gate Oxide Hardening |
| 08957692 | 6017808 | 1997-10-24 | 2000-01-25 | Expired | United States of America | Nitrogen implanted polysilicon gate for MOSFET gate oxide hardening |
| 09022588 | 6117795 | 1998-02-12 | 2000-09-12 | Granted | United States of America | Use of corrosion inhibiting compounds in post-etch cleaning processes of an integrated circuit |
| 09583297 | | 2000-05-30 | | Abandoned | United States of America | Use Of Corrosion Inhibiting Compounds In Post-Etch Cleaning Processes Of An Integrated Circuit |
| 09081403 | 6239491 | 1998-05-18 | 2001-05-29 | Granted | United States of America | Integrated circuit structure with thin dielectric between at least local interconnect level and first metal interconnect level, and process for making same |
| 09790821 | 6486056 | 2001-02-22 | 2002-11-26 | Granted | United States of America | Process for making integrated circuit structure with thin dielectric between at least local interconnect level and first metal interconnect level |
| 08374193 | 5646073 | 1995-01-18 | 1997-07-08 | Expired | United States of America | Process for selective deposition of polysilicon over single crystal silicon substrate and resulting product |
| 08823829 | 5818100 | 1997-03-25 | 1998-10-06 | Expired | United States of America | Product resulting from selective deposition of polysilicon over single crystal silicon substrate |
| 08566161 | | 1995-11-30 | | Abandoned | United States of America | Product Resulting From Selective Deposition Of Polysilicon Over Single Crystal Silicon Substrate |
| 08879100 | 6121159 | 1997-06-19 | 2000-09-19 | Expired | United States of America | Polymeric dielectric layers having low dielectric constants and improved adhesion to metal lines |

Schedule B(1)(a) - Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------|----------|------------|------------|-----------|--------------------------|--|
| 09618211 | 6455934 | 2000-07-10 | 2002-09-24 | Expired | United States of America | Polymeric dielectric layers having low dielectric constants and improved adhesion to metal lines |
| 09362648 | 6273798 | 1999-07-27 | 2001-08-14 | Expired | United States of America | Pre-conditioning polishing pads for chemical-mechanical polishing |
| 08841947 | 5990010 | 1997-04-08 | 1999-11-23 | Expired | United States of America | Pre-conditioning polishing pads for chemical-mechanical polishing |
| 08791244 | 6117736 | 1997-01-30 | 2000-09-12 | Expired | United States of America | Method of fabricating insulated-gate field-effect transistors having different gate capacitances |
| 09594478 | 6300663 | 2000-06-15 | 2001-10-09 | Expired | United States of America | Insulated-gate field-effect transistors having different gate capacitances |
| 08701476 | 5905381 | 1996-08-22 | 1999-05-18 | Expired | United States of America | Functional OBC analysis |
| 09244327 | 6154039 | 1999-02-03 | 2000-11-28 | Expired | United States of America | Functional OBC analysis |
| 09109331 | 6071818 | 1998-06-30 | 2000-06-06 | Granted | United States of America | Endpoint detection method and apparatus which utilize an endpoint polishing layer of catalyst material |
| 09534652 | 6258205 | 2000-03-24 | 2001-07-10 | Granted | United States of America | Endpoint detection method and apparatus which utilize an endpoint polishing layer of catalyst material |
| 08684022 | 5728612 | 1996-07-19 | 1998-03-17 | Expired | United States of America | Method for forming minimum area structures for sub-micron CMOS ESD protection in integrated circuit structures without extra implant and mask steps, and articles formed thereby |
| 08748372 | 5843813 | 1996-11-13 | 1998-12-01 | Expired | United States of America | I/O driver design for simultaneous switching noise minimization and ESD performance enhancement |
| 08936829 | 5970321 | 1997-09-25 | 1999-10-19 | Expired | United States of America | Method of fabricating a microelectronic package having polymer ESD protection |
| 08595021 | 5869869 | 1996-01-31 | 1999-02-09 | Expired | United States of America | Microelectronic device with thin film electrostatic discharge protection structure |
| 08723140 | 5955762 | 1996-10-01 | 1999-09-21 | Expired | United States of America | Microelectronic package with polymer ESD protection |
| 09188929 | | 1998-11-09 | | Abandoned | United States of America | Formation Of Gradient Doped Profile Region Between Channel Region And Heavily Doped Source/Drain Contact Region Of MOS Device In Integrated Circuit Structure Using A Re-Entrant Gate Electrode And A Higher Dose Drain Implantation |
| 08690592 | 5877530 | 1996-07-31 | 1999-03-02 | Expired | United States of America | Formation of gradient doped profile region between channel region and heavily doped source/drain contact region of MOS device in integrated circuit structure using a re-entrant gate electrode and a higher dose drain implantation |
| 08552461 | 5670425 | 1995-11-09 | 1997-09-23 | Expired | United States of America | Process for making integrated circuit structure comprising local area interconnects formed over semiconductor substrate by selective deposition on seed layer in patterned trench |
| 08873809 | 5895261 | 1997-06-12 | 1999-04-20 | Expired | United States of America | Process for making integrated circuit structure comprising local area interconnects formed over semiconductor substrate by selective deposition on seed layer in patterned trench |

Schedule B(1)(a) – Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------|----------|------------|------------|-----------|--------------------------|--|
| 08718852 | 5827777 | 1996-09-24 | 1998-10-27 | Expired | United States of America | Method of making a barrier metal technology for tungsten plug interconnection |
| 08378027 | 5600182 | 1995-01-24 | 1997-02-04 | Expired | United States of America | Barrier metal technology for tungsten plug interconnection |
| 08902507 | | 1997-07-29 | | Abandoned | United States of America | Use Of Reticle Stitching To Provide Design Flexibility |
| 08357728 | 5652163 | 1994-12-13 | 1997-07-29 | Expired | United States of America | Use of reticle stitching to provide design flexibility |
| 08233607 | 5593918 | 1994-04-22 | 1997-01-14 | Expired | United States of America | Techniques for forming superconductive lines |
| 08454542 | 5644143 | 1995-05-30 | 1997-07-01 | Expired | United States of America | Method for protecting a semiconductor device with a superconductive line |
| 11286558 | 7847285 | 2005-11-23 | 2010-12-07 | Granted | United States of America | CONFIGURABLE POWER SEGMENTATION USING A NANOTUBE STRUCTURE |
| 12912791 | 8017512 | 2010-10-27 | 2011-09-13 | Granted | United States of America | EFFICIENT POWER MANAGEMENT METHOD IN INTEGRATED CIRCUIT THROUGH A NANOTUBE STRUCTURE |
| 10418375 | 6982229 | 2003-04-18 | 2006-01-03 | Lapsed | United States of America | Ion recoil implantation and enhanced carrier mobility in CMOS device |
| 11098290 | 7129516 | 2005-04-04 | 2006-10-31 | Lapsed | United States of America | Ion recoil implantation and enhanced carrier mobility in CMOS device |
| 11063384 | 7201633 | 2005-02-22 | 2007-04-10 | Granted | United States of America | Systems and methods for wafer polishing |
| 11158450 | | 2005-06-21 | | Abandoned | United States of America | Systems and Methods For Wafer Polishing |
| 11381409 | | 2006-05-03 | | Abandoned | United States of America | Adjustable Transmission Phase Shift Mask |
| 10972898 | 7067223 | 2004-10-25 | 2006-06-27 | Lapsed | United States of America | Adjustable transmission phase shift mask |
| 10039508 | 6841308 | 2001-11-09 | 2005-01-11 | Lapsed | United States of America | Adjustable transmission phase shift mask |
| 11016468 | 6998716 | 2004-12-16 | 2006-02-14 | Granted | United States of America | Diamond metal-filled patterns achieving low parasitic coupling capacitance |
| 10327283 | 6867127 | 2002-12-19 | 2005-03-15 | Granted | United States of America | Diamond metal-filled patterns achieving low parasitic coupling capacitance |
| 60578890 | | 2004-06-10 | | Abandoned | United States of America | Vortex Phase Shift Mask Applied to Optical Direct Write |
| 13722648 | 9188848 | 2012-12-20 | 2015-11-17 | Lapsed | United States of America | Maskless Vortex Phase Shift Optical Direct Write Lithography |
| 13253554 | 8377633 | 2011-10-05 | 2013-02-19 | Lapsed | United States of America | Maskless Vortex Phase Shift Optical Direct Write Lithography |
| 11011896 | 8057963 | 2004-12-14 | 2011-11-15 | Lapsed | United States of America | Maskless Vortex Phase Shift Optical Direct Write Lithography |
| 11000772 | 7095483 | 2004-12-01 | 2006-08-22 | Lapsed | United States of America | Process independent alignment marks |
| 09887131 | 6856029 | 2001-06-22 | 2005-02-15 | Granted | United States of America | Process independent alignment marks |
| 10750348 | 6969683 | 2003-12-31 | 2005-11-29 | Granted | United States of America | Method of preventing resist poisoning in dual damascene structures |
| 10025304 | 6713386 | 2001-12-19 | 2004-03-30 | Granted | United States of America | Method of preventing resist poisoning in dual damascene structures |
| 10195775 | 6673200 | 2002-07-12 | 2004-01-06 | Granted | United States of America | Method of reducing process plasma damage using optical spectroscopy |
| 60384499 | | 1900-01-01 | | Abandoned | United States of America | Impact of F Species on Plasma Charge Damage in a RF Ather |

Schedule B(1)(a) - Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------|----------|------------|------------|-----------|--------------------------|---|
| 10680503 | 6972840 | 2003-10-06 | 2005-12-06 | Lapsed | United States of America | Method of reducing process plasma damage using optical spectroscopy |
| 10762788 | 7151059 | 2004-01-22 | 2006-12-19 | Granted | United States of America | MOS Transistor And Method Of Manufacture |
| 09597012 | 6740912 | 2000-06-20 | 2004-05-25 | Granted | United States of America | Semiconductor Device Free Of LDD Regions |
| 10291356 | | 2002-11-08 | | Abandoned | United States of America | High-K Dielectric Gate Material Uniquely Formed |
| 10643687 | 6919263 | 2003-08-19 | 2005-07-19 | Lapsed | United States of America | High-K dielectric gate material uniquely formed |
| 09408299 | 6323044 | 1999-09-29 | 2001-11-27 | Granted | United States of America | Integrated Circuit Capacitor And Associated Fabrication Methods |
| 09951178 | 6525358 | 2001-09-13 | 2003-02-25 | Granted | United States of America | Capacitor Having The Lower Electrode For Preventing Undesired Defects At The Surface Of The Metal Plug |
| 10459072 | 6806162 | 2003-06-11 | 2004-10-19 | Lapsed | United States of America | Method for composing a dielectric layer within an interconnect structure of a multilayer semiconductor device |
| 09164069 | 6614097 | 1998-09-30 | 2003-09-02 | Lapsed | United States of America | Method for composing a dielectric layer within an interconnect structure of a multilayer semiconductor device |
| 12256677 | | 2008-10-23 | | Abandoned | United States of America | Method To Reduce Boron Penetration In SiGe Bipolar Device |
| 11694021 | 7456061 | 2007-03-30 | 2008-11-25 | Granted | United States of America | Method To Reduce Boron Penetration In SiGe Bipolar Device |
| 09886780 | 6649422 | 2001-06-21 | 2003-11-18 | Granted | United States of America | Integrated Circuit Having A Micromagnetic Device And Method Of Manufacture Therefor |
| 09338143 | 6255714 | 1999-06-22 | 2001-07-03 | Granted | United States of America | An Integrated Circuit Having A Micromagnetic Device And Method Of Manufacture Therefor |
| 10234354 | 7126198 | 2002-09-03 | 2006-10-24 | Lapsed | United States of America | Protruding Spacers For Self-Aligned Contacts |
| 11542864 | 7332775 | 2006-10-04 | 2008-02-19 | Granted | United States of America | Protruding Spacers For Self-Aligned Contacts |
| 09156719 | 6495407 | 1998-09-18 | 2002-12-17 | Granted | United States of America | Method Of Making An Article Comprising An Oxide Layer On A GaAs-Based Semiconductor Body |
| 09093557 | 5962883 | 1998-06-08 | 1999-10-05 | Expired | United States of America | Article Comprising An Oxide Layer On A GaAs-Based Semiconductor Body, And Method Of Making The Article |
| 11811519 | 7384801 | 2007-06-11 | 2008-06-10 | Granted | United States of America | Integrated circuit with inductor having horizontal magnetic flux lines |
| 10614307 | 7253497 | 2003-07-02 | 2007-08-07 | Granted | United States of America | Integrated circuit with inductor having horizontal magnetic flux lines |
| 09085913 | 5949112 | 1998-05-28 | 1999-09-07 | Granted | United States of America | Integrated Circuits with Tub-Ties |
| 09339306 | 6054342 | 1999-06-23 | 2000-04-25 | Granted | United States of America | Method Of Making Integrated Circuits With Tub-Ties |
| 08562235 | 5773338 | 1995-11-21 | 1998-06-30 | Expired | United States of America | Bipolar Transistor With MOS-Controlled Protection For Reverse-Biased Emitter-Base Junction |
| 09050711 | 5949128 | 1998-03-30 | 1999-09-07 | Expired | United States of America | Bipolar Transistor With MOS-Controlled Protection For Reverse-Biased Emitter-Base Junction |
| 08347527 | 6445043 | 1994-11-30 | 2002-09-03 | Granted | United States of America | Process for Forming Isolation Regions in An Integrated Circuit and Structure Formed Thereby |
| 08620964 | 5763314 | 1996-03-22 | 1998-06-09 | Expired | United States of America | Process For Forming Isolation Regions In An Integrated Circuit |

Schedule B(1)(a) – Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------|----------|------------|------------|---------|--------------------------|--|
| 08777008 | 5830619 | 1997-01-07 | 1998-11-03 | Expired | United States of America | Resist Materials |
| 08079310 | 6159665 | 1993-06-17 | 2000-12-12 | Granted | United States of America | Processes Using Photosensitive Materials Including A Nitro Benzyl Ester Photoacid Generator |
| 10442533 | 6864152 | 2003-05-20 | 2005-03-08 | Granted | United States of America | Fabrication of trenches with multiple depths on the same substrate |
| 10931605 | 7189628 | 2004-08-31 | 2007-03-13 | Granted | United States of America | Fabrication of trenches with multiple depths on the same substrate |
| 09943403 | 6521520 | 2001-08-30 | 2003-02-18 | Granted | United States of America | Semiconductor wafer arrangement and method of processing a semiconductor wafer |
| 10321250 | 6707114 | 2002-12-16 | 2004-03-16 | Granted | United States of America | Semiconductor wafer arrangement of a semiconductor wafer |
| 09162407 | 6211555 | 1998-09-29 | 2001-04-03 | Granted | United States of America | Semiconductor device with a pair of transistors having dual work function gate electrodes |
| 09591108 | 6514824 | 2000-06-09 | 2003-02-04 | Granted | United States of America | Semiconductor device with a pair of transistors having dual work function gate electrodes |
| 09654689 | 6613651 | 2000-09-05 | 2003-09-02 | Lapsed | United States of America | Integrated circuit isolation system |
| 10383031 | 6831348 | 2003-03-06 | 2004-12-14 | Lapsed | United States of America | Integrated circuit isolation system |
| 10942444 | 7381502 | 2004-09-16 | 2008-06-03 | Lapsed | United States of America | Apparatus and method to improve the resolution of photolithography systems by improving the temperature stability of the reticle |
| 10255856 | 6866970 | 2002-10-07 | 2005-03-15 | Lapsed | United States of America | Apparatus and method to improve the resolution of photolithography systems by improving the temperature stability of the reticle |
| 10702165 | 6830943 | 2003-11-04 | 2004-12-14 | Lapsed | United States of America | Thin film CMOS calibration standard having protective cover layer |
| 10194578 | 6674092 | 2002-07-12 | 2004-01-06 | Lapsed | United States of America | Thin film CMOS calibration standard having protective cover layer |
| 10164909 | 6555475 | 2002-06-07 | 2003-04-29 | Granted | United States of America | Arrangement and method for polishing a surface of a semiconductor wafer |
| 09750639 | 6439981 | 2000-12-28 | 2002-08-27 | Granted | United States of America | Arrangement and method for polishing a surface of a semiconductor wafer |
| 10607353 | 6831022 | 2003-06-26 | 2004-12-14 | Lapsed | United States of America | Method and apparatus for removing water vapor as a byproduct of chemical reaction in a wafer processing chamber |
| 10140536 | 6630411 | 2002-05-07 | 2003-10-07 | Granted | United States of America | Method and apparatus for removing water vapor as a byproduct of chemical reaction in a wafer processing chamber |
| 09960765 | 6504219 | 2001-09-21 | 2003-01-07 | Granted | United States of America | Indium field implant for punchthrough protection in semiconductor devices |
| 09469579 | 6342429 | 1999-12-22 | 2002-01-29 | Granted | United States of America | Method of fabricating an indium field implant for punchthrough protection in semiconductor devices |
| 10819253 | 7242056 | 2004-04-05 | 2007-07-10 | Granted | United States of America | Structure And Fabrication Method For Capacitors Integratable With Vertical Replacement Gate Transistors |
| 11809686 | 7633118 | 2007-05-31 | 2009-12-15 | Lapsed | United States of America | Structure And Fabrication Method For Capacitors Integratable With Vertical Replacement Gate Transistors |

PATENT
REEL: 060885 FRAME: 0047

Schedule B(1)(a) – Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------|----------|------------|------------|-----------|--------------------------|--|
| 12319603 | 7700432 | 2009-01-09 | 2010-04-20 | Lapsed | United States of America | Method of Fabricating a Vertical Transistor and Capacitor |
| 11809873 | 7491610 | 2007-06-01 | 2009-02-17 | Granted | United States of America | Fabrication Method |
| 09956381 | | 2001-09-18 | | Abandoned | United States of America | An Integrable Vertical Replacement Gate (VRG)-Type Poly-Nitride-Poly (PNP) Or Metal-Nitride-poly (MNP) Capacitor |
| 12610733 | 7911006 | 2009-11-02 | 2011-03-22 | Granted | United States of America | Structure And Fabrication Method For Capacitors Integratable With Vertical Replacement Gate Transistors |
| 09723557 | 6455418 | 2000-11-28 | 2002-09-24 | Granted | United States of America | Barrier For Copper Metallization |
| 09218649 | 6288449 | 1998-12-22 | 2001-09-11 | Granted | United States of America | Barrier For Copper Metallization |
| 09244857 | 6068130 | 1999-02-05 | 2000-05-30 | Granted | United States of America | Device And Method For Protecting Electronic Component |
| 09580522 | 6554137 | 2000-05-30 | 2003-04-29 | Granted | United States of America | Device And Method For Protecting Electronic Component |
| 10649140 | 6821851 | 2003-08-27 | 2004-11-23 | Granted | United States of America | Method Of Making Ultra Thin Body Vertical Replacement Gate Mosfet |
| 10164202 | 6635924 | 2002-06-06 | 2003-10-21 | Granted | United States of America | Ultra Thin Body Vertical Replacement Gate Mosfet |
| 10028594 | 6624498 | 2001-12-20 | 2003-09-23 | Granted | United States of America | Micromagnetic Device Having Alloy Of Cobalt, Phosphorus and Iron |
| 09552627 | 6495019 | 2000-04-19 | 2002-12-17 | Granted | United States of America | Device Comprising Micromagnetic Components For Power Applications |
| 09934283 | 6926841 | 2001-08-21 | 2005-08-09 | Lapsed | United States of America | And Process For Forming Device |
| 09312386 | 6500521 | 1999-05-14 | 2002-12-31 | Granted | United States of America | Stepped Etalon |
| 10306565 | | 2002-11-27 | | Abandoned | United States of America | A Process For Fabricating A Semiconductor Device Having A GATE Dielectric Layer With A High Dielectric Constant |
| 10876183 | 7223677 | 2004-06-24 | 2007-05-29 | Granted | United States of America | Process For Fabricating A Semiconductor Device Having An Insulating Layer Formed Over A Semiconductor Substrate |
| 10814682 | | 2004-03-31 | | Abandoned | United States of America | Semiconductor Device Having A Doped Lattice Matching Layer And A Method Of Manufacture Therefor |
| 10003873 | 6737339 | 2001-10-24 | 2004-05-18 | Granted | United States of America | Semiconductor Device Having A Doped Lattice Matching Layer And A Method Of Manufacture Therefor |
| 10814680 | 6855991 | 2004-03-31 | 2005-02-15 | Granted | United States of America | Semiconductor Device Having A Doped Lattice Matching Layer And A Method Of Manufacture Therefor |
| 09605931 | | 2000-06-28 | | Abandoned | United States of America | A Novel Gate Dielectric Structure For Reducing Boron Penetration And Current Leakage |
| 10847789 | 7081419 | 2004-05-18 | 2006-07-25 | Lapsed | United States of America | Gate Dielectric Structure For Reducing Boron Penetration And Current Leakage |
| 09146418 | 6246095 | 1998-09-03 | 2001-06-12 | Expired | United States of America | System And Method For Forming A Thin Gate Oxide Layer |
| 08814670 | 5940736 | 1997-03-11 | 1999-08-17 | Expired | United States of America | Method For Forming A High Quality Ultrathin Gate Oxide Layer |
| 09086252 | 6060406 | 1998-05-28 | 2000-05-09 | Granted | United States of America | MOS Transistors With Improved Gate Dielectrics |
| 09519909 | 6590241 | 2000-03-07 | 2003-07-08 | Lapsed | United States of America | MOS Transistors With Improved Gate Dielectrics |
| 11821396 | 7800226 | 2007-06-22 | 2010-09-21 | Lapsed | United States of America | Integrated Circuit With Metal Silicide Regions |

Schedule B(1)(a) - Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------|----------|------------|------------|---------|--------------------------|---|
| 10245447 | 7250356 | 2002-09-17 | 2007-07-31 | Granted | United States of America | Method For Forming Metal Silicide Regions In An Integrated Circuit |
| 11827807 | 7632690 | 2007-07-13 | 2009-12-15 | Lapsed | United States of America | Real-Time Gate Etch Critical Dimension Control By Oxygen Monitoring |
| 10675572 | 7261745 | 2003-09-30 | 2007-08-28 | Granted | United States of America | Real-Time Gate Etch Critical Dimension Control By Oxygen Monitoring |
| 10978716 | 7642188 | 2004-11-01 | 2010-01-05 | Lapsed | United States of America | Mixed Signal Integrated Circuit With Improved Isolation |
| 09911035 | 6909150 | 2001-07-23 | 2005-06-21 | Granted | United States of America | Mixed Signal Integrated Circuit With Improved Isolation |
| 08150261 | 5467883 | 1993-11-27 | 1995-11-21 | Expired | United States of America | Active Neural Network Control Of Wafer Attributes In A Plasma Etch Process |
| 08468167 | 5737496 | 1995-06-06 | 1998-04-07 | Expired | United States of America | Active Neural Network Control Of Wafer Attributes In A Plasma Etch Process |
| 08446122 | 5653894 | 1995-05-19 | 1997-08-05 | Expired | United States of America | Active Neural Network Determination Of Endpoint In A Plasma Etch Process |
| 08848141 | 6054722 | 1997-04-28 | 2000-04-25 | Expired | United States of America | Current Drive of TFTs in High\Imispeed SRAMs |
| 08572196 | 5625200 | 1995-12-14 | 1997-04-29 | Expired | United States of America | Complementary Devices Using Thin Film Transistors With Improved Current Drive |
| 11385156 | 7282461 | 2006-03-21 | 2007-10-16 | Granted | United States of America | Phase-Shifting Mask And Semiconductor Device |
| 10655050 | 7053405 | 2003-09-04 | 2006-05-30 | Lapsed | United States of America | Phase-Shifting Mask And Semiconductor Device |
| 09488662 | 6638663 | 2000-01-20 | 2003-10-28 | Granted | United States of America | Phase-Shifting Mask And Semiconductor Device |
| 09335707 | 6197641 | 1999-06-18 | 2001-03-06 | Granted | United States of America | Process For Fabricating Vertical Transistors |
| 09143274 | 6027975 | 1998-08-28 | 2000-02-22 | Granted | United States of America | Process For Fabricating Vertical Transistors |
| 10226930 | 6869815 | 2002-08-22 | 2005-03-22 | Granted | United States of America | Electro-Mechanical Device Having A Charge Dissipation Layer And Method Of Manufacture Therefor |
| 10967900 | 7015056 | 2004-10-18 | 2006-03-21 | Lapsed | United States of America | Electro-Mechanical Device Having A Charge Dissipation Layer And A Method Of Manufacture Therefor |
| 08753859 | 5976623 | 1996-12-03 | 1999-11-02 | Expired | United States of America | Process For Making Composite Films |
| 09197833 | 6110543 | 1998-11-23 | 2000-08-29 | Expired | United States of America | Process For Making Compound Films |
| 09568265 | 6380083 | 2000-05-10 | 2002-04-30 | Granted | United States of America | Process For Semiconductor Device Fabrication Having Copper Interconnects |
| 09143037 | 6297154 | 1998-08-28 | 2001-10-02 | Granted | United States of America | Process For Semiconductor Device Fabrication Having Copper Interconnects |
| 09083168 | 5998099 | 1998-05-22 | 1999-12-07 | Expired | United States of America | Energy-Sensitive Resist Material And A Process For Device Fabrication Using An Energy-Sensitive Resist Material |
| 08813732 | 5879857 | 1997-03-07 | 1999-03-09 | Expired | United States of America | Energy-Sensitive Resist Material And A Process For Device Fabrication Using An Energy-Sensitive Resist Material |
| 08803703 | 5843624 | 1997-02-21 | 1998-12-01 | Expired | United States of America | Energy-Sensitive Resist Material And A Process For Device Fabrication Using An Energy-Sensitive Resist Material |

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REEL: 060885 FRAME: 0049

Schedule B(1)(a) - Semic Processing A

| AppNo | PatentNo | FileDate | GrantDate | Status | Country | Title |
|----------|----------|------------|------------|-----------|--------------------------|--|
| 09045062 | 6103615 | 1998-03-19 | 2000-08-15 | Granted | United States of America | Corrosion sensitivity structures for vias and contact holes in integrated circuits |
| 09464225 | 6278129 | 1999-12-15 | 2001-08-21 | Granted | United States of America | Corrosion sensitivity structures for vias and contact holes in integrated circuits |
| 09370501 | 6525377 | 1999-08-09 | 2003-02-25 | Granted | United States of America | Low threshold voltage MOS transistor and method of manufacture |
| 09107767 | 5985705 | 1998-06-30 | 1999-11-16 | Granted | United States of America | Low threshold voltage MOS transistor and method of manufacture |
| 09027307 | 6004880 | 1998-02-20 | 1999-12-21 | Granted | United States of America | Method of single step damascene process for deposition and global planarization |
| 09365440 | 6090239 | 1999-08-02 | 2000-07-18 | Granted | United States of America | Method of single step damascene process for deposition and global planarization |
| 09052851 | 6057571 | 1998-03-31 | 2000-05-02 | Granted | United States of America | High aspect ratio, metal-to-metal, linear capacitor for an integrated circuit |
| 09221023 | 6251740 | 1998-12-23 | 2001-06-26 | Granted | United States of America | Method of forming and electrically connecting a vertical interdigitated metal-insulator-metal capacitor extending between interconnect layers in an integrated circuit |
| 09219655 | 6417535 | 1998-12-23 | 2002-07-09 | Granted | United States of America | Vertical interdigitated metal-insulator-metal capacitor for an integrated circuit |
| 09052793 | 6358837 | 1998-03-31 | 2002-03-19 | Granted | United States of America | Method of electrically connecting and isolating components with vertical elements extending between interconnect layers in an integrated circuit |
| 09525489 | 6441419 | 2000-03-15 | 2002-08-27 | Granted | United States of America | Encapsulated-metal vertical-interdigitated capacitor and damascene method of manufacturing same |
| 09517150 | 6479857 | 2000-03-02 | 2002-11-12 | Lapsed | United States of America | Capacitor having a tantalum lower electrode and method of forming the same |
| 10228859 | 6861310 | 2002-08-27 | 2005-03-01 | Lapsed | United States of America | Capacitor having a tantalum lower electrode and method of forming the same |
| 09952343 | 6620729 | 2001-09-14 | 2003-09-16 | Lapsed | United States of America | Ion beam dual damascene process |
| 10400281 | | 2003-03-27 | | Abandoned | United States of America | Ion Beam Double Damascene Process |
| 09211024 | 6168502 | 1998-12-14 | 2001-01-02 | Expired | United States of America | Subsonic to supersonic and ultrasonic conditioning of a polishing pad in a chemical mechanical polishing apparatus |
| 08696445 | 5868608 | 1996-08-13 | 1999-02-09 | Expired | United States of America | Subsonic to supersonic and ultrasonic conditioning of a polishing pad in a chemical mechanical polishing apparatus |
| 60097750 | | 1998-08-24 | | Expired | United States of America | Off-Axis Pupil Aperture And Method For Making The Same |
| 09358606 | 6426131 | 1999-07-21 | 2002-07-30 | Granted | United States of America | Off-axis pupil aperture and method for making the same |
| 09844531 | 6596579 | 2001-04-27 | 2003-07-22 | Granted | United States of America | Method of forming analog capacitor dual damascene process |
| 10959868 | 7176082 | 2004-10-06 | 2007-02-13 | Granted | United States of America | Analog capacitor in dual damascene process |
| 10409499 | 6822282 | 2003-04-08 | 2004-11-23 | Granted | United States of America | Analog capacitor in dual damascene process |
| 08578741 | | 1995-12-26 | | Abandoned | United States of America | Integrated Circuit With On-Chip Ground Plane |

PATENT
REEL: 060885 FRAME: 0050

Schedule B(1)(a) – Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------|----------|------------|------------|-----------|--------------------------|--|
| 08867286 | 5892272 | 1997-06-02 | 1999-04-06 | Expired | United States of America | Integrated circuit with on-chip ground base |
| 08277344 | 5482897 | 1994-07-19 | 1996-01-09 | Expired | United States of America | Integrated circuit with on-chip ground plane |
| 08943371 | 5898228 | 1997-10-03 | 1999-04-27 | Expired | United States of America | On-chip misalignment indication |
| 09150076 | 6221681 | 1998-09-09 | 2001-04-24 | Expired | United States of America | On-chip misalignment indication |
| 08811818 | 5789028 | 1997-03-04 | 1998-08-04 | Expired | United States of America | Method for eliminating peeling at end of semiconductor substrate in metal organic chemical vapor deposition of titanium nitride |
| 09084027 | | 1998-05-22 | | Abandoned | United States of America | Method And Apparatus For Eliminating Peeling At End Edge Of Semiconductor Substrate In Metal Organic Chemical Vapor Deposition Of Titanium Nitride |
| 09158408 | | 1998-09-22 | | Abandoned | United States of America | Deep Sub-Micron CMOS Device Exhibiting Artificially-Induced Reverse Short-Channel Effects |
| 08761761 | 5874329 | 1996-12-05 | 1999-02-23 | Expired | United States of America | Method for artificially-inducing reverse short-channel effects in deep sub-micron CMOS devices |
| 08926220 | 6030460 | 1997-09-09 | 2000-02-29 | Expired | United States of America | Method and apparatus for forming dielectric films |
| 08653264 | 5710079 | 1996-05-24 | 1998-01-20 | Expired | United States of America | Method and apparatus for forming dielectric films |
| 10944995 | | 2004-09-20 | | Abandoned | United States of America | Pseudo Low Volume Reticle (PLVR) Design for ASIC Manufacturing |
| 12204290 | 7763414 | 2008-09-04 | 2010-07-27 | Lapsed | United States of America | Pseudo Low Volume Reticle (PLVR) Design for ASIC Manufacturing |
| 12191171 | 7646077 | 2008-08-13 | 2010-01-12 | Granted | United States of America | Dielectric Barrier Films For Use As Copper Barrier Layers In Semiconductor Trench And Via Structures |
| 10321938 | 6939800 | 2002-12-16 | 2005-09-06 | Lapsed | United States of America | Dielectric barrier films for use as copper barrier layers in semiconductor trench and via structures |
| 11131003 | 7427563 | 2005-05-16 | 2008-09-23 | Granted | United States of America | Dielectric barrier films for use as copper barrier layers in semiconductor trench and via structures |
| 10991107 | 7396760 | 2004-11-17 | 2008-07-08 | Granted | United States of America | Method and system for reducing inter-layer capacitance in integrated circuits |
| 12156281 | 8015540 | 2008-05-30 | 2011-09-06 | Granted | United States of America | Method and System for Reducing Inter-Layer Capacitance in Integrated Circuits |
| 10697506 | 7323228 | 2003-10-29 | 2008-01-29 | Granted | United States of America | Method of vaporizing and ionizing metals for use in semiconductor processing |
| 11939482 | 7670645 | 2007-11-13 | 2010-03-02 | Lapsed | United States of America | Method of Treating Metal and Metal Salts to Enable Thin Layer Deposition in Semiconductor Processing |
| 08502566 | 5543643 | 1995-07-13 | 1996-08-06 | Expired | United States of America | Combined JFET and MOS transistor device, circuit |
| 08612337 | 5631176 | 1996-03-06 | 1997-05-20 | Expired | United States of America | Method of making combined JFET & MOS transistor device |
| 11286546 | 7494842 | 2005-11-23 | 2009-02-24 | Granted | United States of America | PROGRAMMABLE NANOTUBE INTERCONNECT |
| 12354768 | 8415714 | 2009-01-15 | 2013-04-09 | Granted | United States of America | PROGRAMMABLE NANOTUBE INTERCONNECT |
| 11389643 | 7312127 | 2006-03-23 | 2007-12-25 | Granted | United States of America | Incorporating dopants to enhance the dielectric properties of metal silicates |

Schedule B(1)(a) – Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------|----------|------------|------------|-----------|--------------------------|--|
| 10738761 | 7064062 | 2003-12-16 | 2006-06-20 | Lapsed | United States of America | Incorporating dopants to enhance the dielectric properties of metal silicates |
| 11768725 | 7492049 | 2007-06-26 | 2009-02-17 | Lapsed | United States of America | Multi-layer Registration and Dimensional Test Mark for Scatterometrical Measurement |
| 11046150 | 7258953 | 2005-01-28 | 2007-08-21 | Lapsed | United States of America | Multi-layer registration and dimensional test mark for scatterometrical measurement |
| 10035704 | 6727177 | 2001-10-18 | 2004-04-27 | Granted | United States of America | Multi-step process for forming a barrier film for use in copper layer formation |
| 11733673 | 7413984 | 2007-04-10 | 2008-08-19 | Granted | United States of America | Multi-step process for forming a barrier film for use in copper layer formation |
| 10772133 | 7229923 | 2004-02-03 | 2007-06-12 | Granted | United States of America | Multi-step process for forming a barrier film for use in copper layer formation |
| 08604867 | 5688709 | 1996-02-14 | 1997-11-18 | Expired | United States of America | Method for forming composite trench-fin capacitors for DRAMS |
| 08879341 | 6081008 | 1997-06-20 | 2000-06-27 | Expired | United States of America | Composite trench-fin capacitors for DRAM |
| 08438614 | | 1995-05-10 | | Abandoned | United States of America | Microelectronic Integrated Circuit Including Triangular Semiconductor |
| 08561107 | 5650653 | 1995-11-21 | 1997-07-22 | Expired | United States of America | Microelectronic integrated circuit including triangular CMOS nand gate device |
| 08704472 | 5763302 | 1996-08-20 | 1998-06-09 | Expired | United States of America | Self-aligned twin well process |
| 08768845 | 5770492 | 1996-12-18 | 1998-06-23 | Expired | United States of America | Self-aligned twin well process |
| 08488075 | 5583062 | 1995-06-07 | 1996-12-10 | Expired | United States of America | Self-aligned twin well process having a SiO ₂ -polysilicon-SiO ₂ barrier mask |
| 08521795 | 5585286 | 1995-08-31 | 1996-12-17 | Expired | United States of America | Implantation of a semiconductor substrate with controlled amount of noble gas ions to reduce channeling and/or diffusion of a boron dopant subsequently implanted into the substrate to form P-LDD region of a PMOS device |
| 08677078 | 5717238 | 1996-07-09 | 1998-02-10 | Expired | United States of America | Substrate with controlled amount of noble gas ions to reduce channeling and/or diffusion of a boron dopant forming P-LDD region of a PMOS device |
| 08374195 | 5598021 | 1995-01-18 | 1997-01-28 | Expired | United States of America | MOS structure with hot carrier reduction |
| 08695569 | 5663083 | 1996-08-12 | 1997-09-02 | Expired | United States of America | Process for making improved MOS structure with hot carrier reduction |
| 08939350 | 5858864 | 1997-09-29 | 1999-01-12 | Expired | United States of America | Process for making group IV semiconductor substrate treated with one or more group IV elements to form barrier region capable of inhibiting migration of dopant materials in substrate |

Schedule B(1)(a) – Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------|----------|------------|------------|-----------|--------------------------|---|
| 08306179 | | 1994-09-13 | | Abandoned | United States of America | Group IV Semiconductor Substrate Treated With One Or More Group IV Elements To Form Barrier Region Capable Of Inhibiting Migration Of Dopant Materials In Substrate And Process For Making Same |
| 08434673 | 5654210 | 1995-05-04 | 1997-08-05 | Expired | United States of America | Process for making group IV semiconductor substrate treated with one or more group IV elements to form one or more barrier regions capable of inhibiting migration of dopant materials in substrate |
| 10791337 | | 2004-03-01 | | Abandoned | United States of America | Spacer-Less Transistor Integration Scheme For High-K Gate Dielectrics And Small Gate-To-Gate Spaces Applicable To Si, SiGe And Strained Silicon Schemes |
| 11960554 | 7955919 | 2007-12-19 | 2011-06-07 | Granted | United States of America | Spacer-Less Transistor Integration Scheme For High-K Gate Dielectrics And Small Gate-To-Gate Spaces Applicable To Si, SiGe And Strained Silicon Schemes |
| 07754201 | | 1991-08-19 | | Abandoned | United States of America | Bicmos Compacted Logic Array |
| 08410375 | 6081004 | 1995-03-27 | 2000-06-27 | Expired | United States of America | BICMOS compacted logic array |
| 07523445 | | 1990-05-14 | | Abandoned | United States of America | Bicmos Compacted Logic Array |
| 08014084 | | 1993-02-04 | | Abandoned | United States of America | Bicmos Compacted Logic Array |
| 12574426 | 8021955 | 2009-10-06 | 2011-09-20 | Granted | United States of America | Method Characterizing Materials For A Trench Isolation Structure Having Low Trench Parasitic Capacitance |
| 11262173 | 7619294 | 2005-10-28 | 2009-11-17 | Lapsed | United States of America | Shallow Trench Isolation Structure With Low Trench Parasitic Capacitance |
| 09991202 | 7001823 | 2001-11-14 | 2006-02-21 | Lapsed | United States of America | Method of manufacturing a shallow trench isolation structure with low trench parasitic capacitance |
| 60314148 | | 1900-01-01 | | Abandoned | United States of America | Process Enhancement to Prevent LI or Borderless Contact To Well Leakage |
| 10360746 | 6893937 | 2003-02-05 | 2005-05-17 | Granted | United States of America | Method for preventing borderless contact to well leakage |
| 11104050 | 7098515 | 2005-04-11 | 2006-08-29 | Lapsed | United States of America | Semiconductor chip with borderless contact that avoids well leakage |
| 10006540 | 6551901 | 2001-11-30 | 2003-04-22 | Granted | United States of America | Method for preventing borderless contact to well leakage |
| 11090107 | 7312532 | 2005-03-24 | 2007-12-25 | Granted | United States of America | Dual damascene interconnect structure with improved electro migration lifetimes |
| 10328333 | 7033929 | 2002-12-23 | 2006-04-25 | Lapsed | United States of America | Dual damascene interconnect structure with improved electro migration lifetimes |
| 07982093 | | 1992-11-24 | | Abandoned | United States of America | Improved Metal Oxide Semiconductors Devices And Method For Making Same |
| 08259575 | 6432759 | 1994-06-14 | 2002-08-13 | Granted | United States of America | Method of forming source and drain regions for CMOS devices |
| 11258253 | 7582938 | 2005-10-25 | 2009-09-01 | Lapsed | United States of America | I/O and Power ESD Protection Circuits by Enhancing Substrate-Bias In Deep-Submicron CMOS Process |

Schedule B(1)(a) – Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------|----------|------------|------------|-----------|--------------------------|--|
| 12506746 | 7948036 | 2009-07-21 | 2011-05-24 | Granted | United States of America | I/O and Power ESD Protection Circuits by Enhancing Substrate-Bias In Deep-Submicron CMOS Process |
| 13110581 | 8269280 | 2011-05-18 | 2012-09-18 | Granted | United States of America | I/O and Power ESD Protection Circuits by Enhancing Substrate-Bias In Deep-Submicron CMOS Process |
| 10676602 | 6979869 | 2003-10-01 | 2005-12-27 | Granted | United States of America | Substrate-biased I/O and power ESD protection circuits in deep-submicron twin-well process |
| 11838546 | 8134188 | 2007-08-14 | 2012-03-13 | Granted | United States of America | Circuits And Methods For Improved FET Matching |
| 13368985 | 8440512 | 2012-02-08 | 2013-05-14 | Granted | United States of America | Circuits and Methods for Improved FET Matching |
| 07591646 | 5123375 | 1990-10-02 | 1992-06-23 | Expired | United States of America | Structure for filtering CVD chamber process gases |
| 08979733 | 6113699 | 1997-11-26 | 2000-09-05 | Expired | United States of America | Purging gas control structure for CVD chamber |
| 08390329 | 5681613 | 1995-02-17 | 1997-10-28 | Expired | United States of America | Filtering technique for CVD chamber process gases |
| 07591587 | | 1990-10-02 | | Abandoned | United States of America | Method For Performing In-Situ Etch Of A Cvd Chamber |
| 07794780 | 5203956 | 1991-11-18 | 1993-04-20 | Expired | United States of America | Method for performing in-situ etch of a CVD chamber |
| 07591655 | | 1990-10-02 | | Abandoned | United States of America | Apparatus For Performing In-Situ Etch Of A Cvd Chamber |
| 07809104 | 5211796 | 1991-12-12 | 1993-05-18 | Expired | United States of America | Apparatus for performing in-situ etch of CVD chamber |
| 08979734 | | 1997-11-26 | | Abandoned | United States of America | In-Situ Etch Of Cvd Chamber |
| 07797773 | 5391394 | 1991-07-29 | 1995-02-21 | Expired | United States of America | Tungsten deposition process for low contact resistivity to silicon |
| 08851846 | 5853804 | 1997-05-06 | 1998-12-29 | Expired | United States of America | Gas control technique for limiting surging of gas into a CVD chamber |
| 07461959 | | 1990-01-08 | | Abandoned | United States of America | Tungsten Deposition Process For Low Contact Resistivity To Silicon |
| 07592014 | 5180432 | 1990-10-02 | 1993-01-19 | Expired | United States of America | Apparatus for conducting a refractory metal deposition process |
| 11937199 | 7560292 | 2007-11-08 | 2009-07-14 | Lapsed | United States of America | Voltage Contrast Monitor for Integrated Circuit Defects |
| 10652369 | 6936920 | 2003-08-29 | 2005-08-30 | Lapsed | United States of America | Voltage contrast monitor for integrated circuit defects |
| 11131705 | 7323768 | 2005-05-18 | 2008-01-29 | Lapsed | United States of America | Voltage contrast monitor for integrated circuit defects |
| 12890336 | 8527912 | 2010-09-24 | 2013-09-03 | Lapsed | United States of America | Digitally Obtaining Contours of Fabricated Polygons |
| 11182615 | 7827509 | 2005-07-15 | 2010-11-02 | Granted | United States of America | Digitally Obtaining Contours of Fabricated Polygons |
| 12652560 | 8106480 | 2010-01-05 | 2012-01-31 | Granted | United States of America | Bipolar Device Having Improved Capacitance |
| 11531477 | 7666750 | 2006-09-13 | 2010-02-23 | Lapsed | United States of America | Bipolar Device Having Improved Capacitance |
| 12018849 | 7582566 | 2008-01-24 | 2009-09-01 | Lapsed | United States of America | Method and Apparatus For Redirecting Void Diffusion Away From Vias In An Integrated Circuit Design |
| 11323400 | 7361965 | 2005-12-29 | 2008-04-22 | Granted | United States of America | Method and apparatus for redirecting void diffusion away from vias in an integrated circuit design |
| 10383149 | 6872612 | 2003-03-06 | 2005-03-29 | Lapsed | United States of America | Local Interconnect for integrated circuit |
| 11058498 | 7081379 | 2005-02-15 | 2006-07-25 | Lapsed | United States of America | Local Interconnect for integrated circuit |
| 10801310 | 7395522 | 2004-03-16 | 2008-07-01 | Granted | United States of America | Yield profile manipulator |
| 12117379 | 7930655 | 2008-05-08 | 2011-04-19 | Granted | United States of America | Yield Profile Manipulator |
| 11414902 | 7541238 | 2006-05-01 | 2009-06-02 | Granted | United States of America | Inductor Formed In An Integrated Circuit |
| 10953475 | 7068139 | 2004-09-29 | 2006-06-27 | Granted | United States of America | Inductor Formed In An Integrated Circuit |

Schedule B(1)(a) – Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------|----------|------------|------------|-----------|--------------------------|---|
| 12340813 | 7678639 | 2008-12-22 | 2010-03-16 | Granted | United States of America | Inductor Formed In An Integrated Circuit |
| 11265062 | 7635888 | 2005-11-02 | 2009-12-22 | Granted | United States of America | Interdigitated Capacitors |
| 10886763 | 7022581 | 2004-07-08 | 2006-04-04 | Granted | United States of America | Interdigitated Capacitors |
| 12616050 | 8039923 | 2009-11-10 | 2011-10-18 | Granted | United States of America | Interdigitated Capacitors |
| 10454027 | 6880140 | 2003-06-04 | 2005-04-12 | Lapsed | United States of America | Method to selectively identify reliability risk die based on characteristics of local regions on the wafer |
| 11031564 | 7390680 | 2005-01-06 | 2008-06-24 | Granted | United States of America | Method to selectively identify reliability risk die based on characteristics of local regions on the wafer |
| 12728412 | 8227319 | 2010-03-22 | 2012-07-24 | Granted | United States of America | A Bipolar Junction Transistor Having A High Germanium Concentration In A Silicon Germanium Layer and a Method for Forming the Bipolar Junction Transistor |
| 10598213 | 7714361 | 2006-08-21 | 2010-05-11 | Lapsed | United States of America | A Bipolar Junction Transistor Having A High Germanium Concentration In A Silicon-Germanium Layer And A Method For Forming The Bipolar Junction Transistor |
| 13348415 | | 2012-01-11 | | Abandoned | United States of America | A Bipolar Junction Transistor Having A High Germanium Concentration In A Silicon-Germanium Layer and a Method for Forming the Bipolar Junction Transistor |
| 10669398 | 6784044 | 2003-09-24 | 2004-08-31 | Granted | United States of America | High Dopant Concentration Diffused Resistor And Method Of Manufacture Thereof |
| 10256466 | 6690082 | 2002-09-27 | 2004-02-10 | Granted | United States of America | A High Dopant Concentration Diffused Resistor And Method Of Manufacture Thereof |
| 12208929 | 7776678 | 2008-09-11 | 2010-08-17 | Lapsed | United States of America | A Thermally Stable BiCMOS Fabrication Method And Bipolar Junction Transistors Formed According To The Method |
| 11361430 | 7439119 | 2006-02-24 | 2008-10-21 | Lapsed | United States of America | A Thermally Stable BiCMOS Fabrication Method And Bipolar Junction Transistors Formed According To The Method |
| 12832110 | 8084313 | 2010-07-08 | 2011-12-27 | Granted | United States of America | A Thermally Stable BiCMOS Fabrication Method And Bipolar Junction Transistor Formed According To The Method |
| 10828993 | | 2004-04-21 | | Abandoned | United States of America | Method For Making A Radio Frequency Component And Component Produced Thereby |
| 09715651 | 6743731 | 2000-11-17 | 2004-06-01 | Granted | United States of America | Method For Making A Radio Frequency Component And Component Produced Thereby |
| 09528071 | 6530074 | 2000-03-17 | 2003-03-04 | Granted | United States of America | Apparatus For Verification Of IC Mask Sets |
| 10317147 | 7103869 | 2002-12-11 | 2006-09-05 | Lapsed | United States of America | Method Of Verifying IC Mask Sets |
| 10718536 | 7456064 | 2003-11-24 | 2008-11-25 | Lapsed | United States of America | High K Dielectric Material And Method Of Making A High K Dielectric Material |
| 10155173 | 6680130 | 2002-05-28 | 2004-01-20 | Lapsed | United States of America | High K Dielectric Material And Method Of Making A High K Dielectric Material |

Schedule B(1)(a) – Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------|----------|------------|------------|-----------|--------------------------|---|
| 12506090 | 7981305 | 2009-07-20 | 2011-07-19 | Granted | United States of America | High Density Field Emission Elements And A Method For Forming Said Emission Elements |
| 11057690 | 7564178 | 2005-02-14 | 2009-07-21 | Lapsed | United States of America | High Density Field Emission Elements and a Method for Forming Said Emission Elements |
| 09901073 | | 2001-07-09 | | Abandoned | United States of America | Lateral High-Q Inductor For Semiconductor Devices |
| 09416348 | 6292086 | 1999-10-12 | 2001-09-18 | Granted | United States of America | Lateral High-Q Inductor For Semiconductor Devices |
| 09894116 | 6458016 | 2001-06-28 | 2002-10-01 | Granted | United States of America | Polishing Fluid, Polishing Method, Semiconductor Device And Semiconductor Device Fabrication Method |
| 09483576 | 6375541 | 2000-01-14 | 2002-04-23 | Granted | United States of America | Polishing Fluid, Polishing Method, Semiconductor Device and Semiconductor Device Fabrication Method |
| 10637385 | 7067048 | 2003-08-08 | 2006-06-27 | Lapsed | United States of America | Method to improve the control of electro-polishing by use of a plating electrode an electrolyte bath |
| 11409377 | | 2006-04-21 | | Abandoned | United States of America | Method To Improve The Control Of Electro-Polishing By Use Of A Plating Electrode In An Electrolyte Bath |
| 10152879 | | 2002-05-21 | | Abandoned | United States of America | Microstructure Control Of Copper Interconnects |
| 09419986 | 6440849 | 1999-10-18 | 2002-08-27 | Granted | United States of America | Microstructure Control Of Copper Interconnects |
| 08814051 | 5936831 | 1997-03-06 | 1999-08-10 | Expired | United States of America | Thin Film Tantalum Oxide Capacitors And Resulting Product |
| 08918174 | 6075691 | 1997-08-25 | 2000-06-13 | Expired | United States of America | THIN FILM CAPACITORS AND PROCESS FOR MAKING THEM |
| 08678971 | 5821148 | 1996-07-12 | 1998-10-13 | Expired | United States of America | Method of fabricating a segmented emitter low noise transistor |
| 08484675 | 5723897 | 1995-06-07 | 1998-03-03 | Expired | United States of America | Segmented Emitter Low Noise Transistor |
| 09653616 | 6690037 | 2000-08-31 | 2004-02-10 | Granted | United States of America | Field Plated Schottky Diode |
| 10696136 | 6790753 | 2003-10-29 | 2004-09-14 | Granted | United States of America | Field Plated Schottky Diode And Method Of Fabrication Thereof |
| 09878657 | 6482694 | 2001-06-11 | 2002-11-19 | Granted | United States of America | Semiconductor Device Structure Including A Tantalum Pentoxide Layer Sandwiched Between Silicon Nitride Layers |
| 09259001 | 6294807 | 1999-02-26 | 2001-09-25 | Granted | United States of America | Semiconductor Device Structure Including A Tantalum Pentoxide Layer Sandwiched Between Silicon Nitride Layers |
| 11649197 | 7670203 | 2007-01-03 | 2010-03-02 | Lapsed | United States of America | Process For Making An On-Chip Vacuum Tube Device |
| 09651696 | 7259510 | 2000-08-30 | 2007-08-21 | Granted | United States of America | On-Chip Vacuum Tube Device And Process For Making Device |
| 09643784 | 6383923 | 2000-08-22 | 2002-05-07 | Granted | United States of America | Article Comprising Vertically Nano-InterConnected Circuit Devices And Method For Making The Same |
| 09426457 | 6340822 | 1999-10-05 | 2002-01-22 | Granted | United States of America | Article Comprising Vertically Nano-InterConnected Circuit Devices And Method For Making The Same |
| 11748569 | 7407824 | 2007-05-15 | 2008-08-05 | Granted | United States of America | Guard Ring For Improved Matching |
| 10941665 | 7253012 | 2004-09-14 | 2007-08-07 | Granted | United States of America | Guard Ring For Improved Matching |
| 10916322 | 7405116 | 2004-08-11 | 2008-07-29 | Granted | United States of America | Application of gate edge liner to maintain gate length CD in a replacement gate transistor flow |
| 12140773 | 8384165 | 2008-06-17 | 2013-02-26 | Granted | United States of America | Application of Gate Edge Liner To Maintain Gate Length CD In A Replacement Gate Transistor Flow |

Schedule B(1)(a) - Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------|----------|------------|------------|-----------|--------------------------|---|
| 09410686 | 6410435 | 1999-10-01 | 2002-06-25 | Granted | United States of America | Process For Fabricating Copper Interconnect For ULSI Integrated Circuits |
| 10120707 | | 2002-04-11 | | Abandoned | United States of America | Process For Fabricating Copper Interconnect For ULSI Integrated Circuits |
| 12356600 | 8022481 | 2009-01-21 | 2011-09-20 | Granted | United States of America | Robust Shallow Trench Isolation Structures And A Method For Forming Shallow Trench Isolation Structures |
| 11321206 | 7514336 | 2005-12-29 | 2009-04-07 | Lapsed | United States of America | Robust Shallow Trench Isolation Structures And A Method For Forming Shallow Trench Isolation Structures |
| 09280103 | 6252245 | 1999-03-29 | 2001-06-26 | Granted | United States of America | Device Comprising N-Channel Semiconductor Material |
| 09476511 | 6387727 | 2000-01-03 | 2002-05-14 | Granted | United States of America | Device Comprising N-Channel Semiconductor Material |
| 11927950 | 7579245 | 2007-10-30 | 2009-08-25 | Lapsed | United States of America | Dual-Gate Metal-Oxide Semiconductor Device |
| 10999705 | 7329922 | 2004-11-30 | 2008-02-12 | Granted | United States of America | Dual\Imigate Metal\Imioxide Semiconductor Device |
| 09884736 | 6930056 | 2001-06-19 | 2005-08-16 | Lapsed | United States of America | Plasma treatment of low dielectric constant dielectric material to form structures useful in formation of metal interconnects and/or filled vias for integrated circuit structure |
| 10422270 | 6790784 | 2003-04-24 | 2004-09-14 | Lapsed | United States of America | Plasma treatment of low dielectric constant dielectric material to form structures useful in formation of metal interconnects and/or filled vias for integrated circuit structure |
| 11530550 | 7271485 | 2006-09-11 | 2007-09-18 | Granted | United States of America | Systems And Methods For Distributing \SIO In A Semiconductor Device |
| 11684674 | 7709861 | 2007-03-12 | 2010-05-04 | Granted | United States of America | Systems And Methods For Supporting a Subset of Multiple Interface Types In A Semiconductor Device |
| 09456224 | 6576529 | 1999-12-07 | 2003-06-10 | Granted | United States of America | A Method Of Forming An Alignment Feature In Or On A Multi-Layered Semiconductor Structure |
| 10704449 | 6977128 | 2003-11-07 | 2005-12-20 | Lapsed | United States of America | Multi-Layered Semiconductor Structure |
| 09867202 | 6706609 | 2001-05-29 | 2004-03-16 | Granted | United States of America | Method Of Forming An Alignment Feature In Or On A Multi-Layered Semiconductor Structure |
| 09804783 | 6586326 | 2001-03-13 | 2003-07-01 | Lapsed | United States of America | Metal planarization system |
| 10400278 | 6951808 | 2003-03-27 | 2005-10-04 | Lapsed | United States of America | Metal planarization system |
| 09617550 | 6569751 | 2000-07-17 | 2003-05-27 | Granted | United States of America | Low via resistance system |
| 10400252 | 6893962 | 2003-03-27 | 2005-05-17 | Granted | United States of America | Low via resistance system |
| 08718113 | 5804975 | 1996-09-18 | 1998-09-08 | Expired | United States of America | Detecting Breakdown In Dielectric Layers |
| 09002497 | 6043662 | 1998-01-02 | 2000-03-28 | Expired | United States of America | Detecting Defects In Integrated Circuits |
| 08702073 | 5969376 | 1996-08-23 | 1999-10-19 | Expired | United States of America | An Organic Thin Film Transistor Having A Phthalocyanine Semiconductor Layer |
| 09204002 | 6150191 | 1998-12-01 | 2000-11-21 | Expired | United States of America | Method of Making an Organic Thin Film Transistor and Article Made by the Method |
| 09135260 | 6015333 | 1998-08-17 | 2000-01-18 | Expired | United States of America | Method Of Forming Planarized Layers In An Integrated Circuit |

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REEL: 060885 FRAME: 0057

Schedule B(1)(a) - Semic Processing A

| AppNo. | PatentNo. | FiledDate | GrantDate | Status | Country | Title |
|----------|-----------|------------|------------|---------|--------------------------|--|
| 08769717 | 5836805 | 1996-12-18 | 1998-11-17 | Expired | United States of America | Method of Forming Planarized Layers In An Integrated Circuit |
| 09083072 | 6024829 | 1998-05-21 | 2000-02-15 | Granted | United States of America | Method Of Eliminating Agglomerate Particles In A Polishing Slurry |
| 09427306 | 6355184 | 1999-10-26 | 2002-03-12 | Granted | United States of America | A Method Of Eliminating Agglomerate Particles In A Polishing Slurry |
| 09992135 | 6750145 | 2001-11-14 | 2004-06-15 | Granted | United States of America | A Method Of Eliminating Agglomerate Particles In A Polishing Slurry |
| 08344785 | 5576763 | 1994-11-22 | 1996-11-19 | Expired | United States of America | Single-Polysilicon CMOS Active Pixel |
| 08675026 | 5835141 | 1996-07-03 | 1998-11-10 | Expired | United States of America | Single-Polysilicon CMOS Active Pixel Image Sensor |
| 08872250 | 6118351 | 1997-06-10 | 2000-09-12 | Expired | United States of America | A Micromagnetic Device For Power Processing Applications And Method Of Manufacture Therefor |
| 09292860 | 6191495 | 1999-04-16 | 2001-02-20 | Expired | United States of America | Micromagnetic Device Having An Anisotropic Ferromagnetic Core and Method of Manufacture Therefor |
| 09511343 | 6440750 | 2000-02-23 | 2002-08-27 | Expired | United States of America | Method Of Making Integrated Circuit Having A Micromagnetic Device |
| 10387846 | 7021518 | 2003-03-13 | 2006-04-04 | Lapsed | United States of America | Micromagnetic Device For Power Processing Applications And Method Of Manufacture Therefor |
| 09978871 | 6696744 | 2001-10-15 | 2004-02-24 | Expired | United States of America | Integrated Circuit Having A Micromagnetic Device And Method Of Manufacture Therefor |
| 09109963 | 6163234 | 1998-07-02 | 2000-12-19 | Expired | United States of America | A Micromagnetic Device For Data Transmission Applications And Method Of Manufacture Therefor |
| 09490655 | 6160721 | 2000-01-24 | 2000-12-12 | Expired | United States of America | A Micromagnetic Device For Power Processing Applications And Method Of Manufacture Therefor |
| 10400279 | 6927494 | 2003-03-27 | 2005-08-09 | Lapsed | United States of America | Local Interconnect |
| 09966464 | 6576544 | 2001-09-28 | 2003-06-10 | Granted | United States of America | Local Interconnect |
| 08381375 | 5616368 | 1995-01-31 | 1997-04-01 | Expired | United States of America | Field Emission Devices Employing Activated Diamond Particle Emitters And Methods For Making Same |
| 08361616 | 5709577 | 1994-12-22 | 1998-01-20 | Expired | United States of America | Method Of Making Field Emission Devices Employing Ultra-Fine Diamond Particle Emitters |
| 09006347 | 5977697 | 1998-01-13 | 1999-11-02 | Expired | United States of America | Field Emission Devices Employing Diamond Particle Emitters |
| 10368760 | 6747358 | 2003-02-18 | 2004-06-08 | Granted | United States of America | Self-aligned alloy capping layers for copper interconnect structures |
| 10004461 | 6566262 | 2001-11-01 | 2003-05-20 | Granted | United States of America | Method for creating self-aligned alloy capping layers for copper interconnect structures |
| 09533428 | 6312565 | 2000-03-23 | 2001-11-06 | Granted | United States of America | Thin Film Deposition Of Mixed Metal Oxides |
| 09917365 | 6540974 | 2001-07-27 | 2003-04-01 | Granted | United States of America | Process For Making Mixed Metal Oxides |
| 10038734 | 6762459 | 2001-12-31 | 2004-07-13 | Granted | United States of America | Method For Fabricating MOS Device With Halo Implanted Region |
| 09523782 | 6362054 | 2000-03-13 | 2002-03-26 | Granted | United States of America | Method For Fabricating MOS Device With Halo Implanted Region |
| 10368811 | 6977400 | 2003-02-18 | 2005-12-20 | Lapsed | United States of America | Silicon germanium CMOS channel |
| 09724444 | 6544854 | 2000-11-28 | 2003-04-08 | Granted | United States of America | Silicon germanium CMOS channel |

Schedule B(1)(a) – Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------|----------|------------|------------|-----------|--------------------------|---|
| 10641768 | 6987059 | 2003-08-14 | 2006-01-17 | Granted | United States of America | Method and structure for creating ultra low resistance damascene copper wiring |
| 11259965 | 7196420 | 2005-10-26 | 2007-03-27 | Granted | United States of America | Method and structure for creating ultra low resistance damascene copper wiring |
| 10802522 | | 2004-03-17 | | Abandoned | United States of America | Interconnect Integration |
| 10448082 | 6777807 | 2003-05-29 | 2004-08-17 | Granted | United States of America | Interconnect integration |
| 11314649 | | 2005-12-21 | | Abandoned | United States of America | Variable Mask Field Exposure |
| 12167381 | 7638245 | 2008-07-03 | 2009-12-29 | Lapsed | United States of America | Variable Mask Field Exposure |
| 10429376 | 7018753 | 2003-05-05 | 2006-03-28 | Lapsed | United States of America | Variable mask field exposure |
| 10951646 | | 2004-09-28 | | Abandoned | United States of America | Plasma Removal Of High K Metal Oxide |
| 10413051 | 7413996 | 2003-04-14 | 2008-08-19 | Granted | United States of America | High k gate insulator removal |
| 11337460 | 7220362 | 2006-01-23 | 2007-05-22 | Granted | United States of America | Planarization with reduced dishing |
| 10421068 | 7029591 | 2003-04-23 | 2006-04-18 | Lapsed | United States of America | Planarization with reduced dishing |
| 11695169 | | 2007-04-02 | | Abandoned | United States of America | Planarization with Reduced Dishing |
| 09894117 | 6439972 | 2001-06-28 | 2002-08-27 | Granted | United States of America | Polishing Fluid, Polishing Method, Semiconductor Device And Semiconductor Device Fabrication Method |
| 09483785 | 6328633 | 2000-01-14 | 2001-12-11 | Granted | United States of America | Polishing Fluid, Polishing Method, Semiconductor Device And Semiconductor Device Fabrication Method |
| 10964032 | | 2004-10-12 | | Abandoned | United States of America | Via and Metal Line Interface Capable of Reducing the Incidence of Electro-Migration Induced Voids |
| 10400297 | 6875693 | 2003-03-26 | 2005-04-05 | Granted | United States of America | Via and metal line interface capable of reducing the incidence of electro-migration induced voids |
| 11189625 | | 2005-07-25 | | Abandoned | United States of America | Memory Device Having an Electron Trapping Layer in a High-K Dielectric Gate Stack |
| 10123263 | 7132336 | 2002-04-15 | 2006-11-07 | Granted | United States of America | Method and apparatus for forming a memory structure having an electron affinity region |
| 10698169 | 6989565 | 2003-10-31 | 2006-01-24 | Lapsed | United States of America | Memory device having an electron trapping layer in a high-K dielectric gate stack |
| 09879642 | 6495312 | 2001-06-12 | 2002-12-17 | Granted | United States of America | Method and apparatus for removing photoresist edge beads from thin film substrates |
| 10263593 | 6614507 | 2002-10-03 | 2003-09-02 | Granted | United States of America | Apparatus for removing photoresist edge beads from thin film substrates |
| 09775223 | | 2001-02-01 | | Abandoned | United States of America | Method and Apparatus for Removing Photoresist Edge Beads From Thin Film Substrates |
| 10196787 | 6787180 | 2002-07-17 | 2004-09-07 | Granted | United States of America | Exhaust flow control system |
| 09666507 | 6579371 | 2000-09-20 | 2003-06-17 | Granted | United States of America | Exhaust flow control system |
| 10328614 | 6972217 | 2002-12-23 | 2005-12-06 | Lapsed | United States of America | Low k polymer E-beam printable mechanical support |

Schedule B(1)(a) - Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------|----------|------------|------------|-----------|--------------------------|--|
| 11225310 | 7358594 | 2005-09-12 | 2008-04-15 | Granted | United States of America | Method of forming a low k polymer E-beam printable mechanical support |
| 10243562 | 6885436 | 2002-09-13 | 2005-04-26 | Lapsed | United States of America | Optical error minimization in a semiconductor manufacturing apparatus |
| 11473627 | 7298458 | 2006-06-22 | 2007-11-20 | Granted | United States of America | Optical error minimization in a semiconductor manufacturing apparatus |
| 11075195 | 7098996 | 2005-03-07 | 2006-08-29 | Lapsed | United States of America | Optical error minimization in a semiconductor manufacturing apparatus |
| 09074837 | 6090656 | 1998-05-08 | 2000-07-18 | Granted | United States of America | Linear capacitor and process for making same |
| 09550381 | 6545305 | 2000-04-14 | 2003-04-08 | Granted | United States of America | Linear capacitor and process for making same |
| 10623082 | 7160805 | 2003-07-17 | 2007-01-09 | Granted | United States of America | Inter-layer interconnection structure for large electrical connections |
| 10272767 | 6642597 | 2002-10-16 | 2003-11-04 | Granted | United States of America | Inter-layer interconnection structure for large electrical connections |
| 10197956 | 6807655 | 2002-07-16 | 2004-10-19 | Lapsed | United States of America | Adaptive off tester screening method based on intrinsic die parametric measurements |
| 60381746 | | 2002-05-17 | | Expired | United States of America | Process and Apparatus for Wafer Edge Profile Control Using Gas Flow Control Ring |
| 10821708 | | 2004-04-09 | | Abandoned | United States of America | Process and Apparatus for Wafer Edge Profile Control Using Gas Flow Control Ring |
| 10200469 | 6753255 | 2002-07-18 | 2004-06-22 | Granted | United States of America | Process for wafer edge profile control using gas flow control ring |
| 10160812 | 6613637 | 2002-05-31 | 2003-09-02 | Granted | United States of America | Composite spacer scheme with low overlapped parasitic capacitance |
| 10458141 | 6737342 | 2003-06-09 | 2004-05-18 | Granted | United States of America | Composite spacer scheme with low overlapped parasitic capacitance |
| 10253158 | 6713394 | 2002-09-24 | 2004-03-30 | Granted | United States of America | Process for planarization of integrated circuit structure which inhibits cracking of low dielectric constant dielectric material adjacent underlying raised structures |
| 09661465 | 6489242 | 2000-09-13 | 2002-12-03 | Granted | United States of America | Process for planarization of integrated circuit structure which inhibits cracking of low dielectric constant dielectric material adjacent underlying raised structures |
| 10417708 | 7056392 | 2003-04-16 | 2006-06-06 | Lapsed | United States of America | Wafer chucking apparatus and method for spin processor |
| 11403137 | 7201176 | 2006-04-11 | 2007-04-10 | Granted | United States of America | Wafer chucking apparatus for spin processor |
| 09467622 | 6375791 | 1999-12-20 | 2002-04-23 | Granted | United States of America | Method and apparatus for detecting presence of residual polishing slurry subsequent to polishing of a semiconductor wafer |
| 10012847 | 6716364 | 2001-12-10 | 2004-04-06 | Granted | United States of America | Method and apparatus for detecting presence of residual polishing slurry subsequent to polishing of a semiconductor wafer |
| 10185537 | 6699766 | 2002-07-01 | 2004-03-02 | Granted | United States of America | Method of fabricating an integral capacitor and gate transistor having nitride and oxide polish stop layers using chemical mechanical polishing elimination |

PATENT
REEL: 060885 FRAME: 0060

Schedule B(1)(a) - Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------|----------|------------|------------|-----------|--------------------------|---|
| 10733034 | 7148146 | 2003-12-11 | 2006-12-12 | Granted | United States of America | Method of fabricating an integral capacitor and gate transistor having nitride and oxide polish stop layers using chemical mechanical polishing elimination |
| 10013572 | 6614093 | 2001-12-11 | 2003-09-02 | Granted | United States of America | Integrated Inductor in Semiconductor manufacturing |
| 10463158 | | 2003-06-16 | | Abandoned | United States of America | Integrated Inductor in Semiconductor Manufacturing |
| 60292832 | | 2001-05-21 | | Expired | United States of America | Web-Bases Interface With Defect Database To View And Update Failure Events |
| 10128534 | 6775630 | 2002-04-23 | 2004-08-10 | Granted | United States of America | Web-based interface with defect database to view and update failure events |
| 10845716 | | 2004-05-14 | | Abandoned | United States of America | Method And Structure For Forming Dielectric Layers Having Reduced Dielectric Constants |
| 10180661 | 6774057 | 2002-06-25 | 2004-08-10 | Granted | United States of America | Method and structure for forming dielectric layers having reduced dielectric constants |
| 09968944 | 6472314 | 2001-10-02 | 2002-10-29 | Granted | United States of America | Diamond barrier layer |
| 10238073 | 6734560 | 2002-09-09 | 2004-05-11 | Granted | United States of America | Diamond barrier layer |
| 10035501 | 6743474 | 2001-10-25 | 2004-06-01 | Granted | United States of America | Method for growing thin films |
| 10804980 | 7081296 | 2004-03-16 | 2006-07-25 | Lapsed | United States of America | Method for growing thin films |
| 11906196 | 8631547 | 2007-10-01 | 2014-01-21 | Granted | United States of America | Method Of Isolation For Acoustic Resonator Devices |
| 09497993 | 7296329 | 2000-02-04 | 2007-11-20 | Granted | United States of America | Method Of Isolation For Acoustic Resonator Devices |
| 12243137 | 7713811 | 2008-10-01 | 2010-05-11 | Lapsed | United States of America | Multiple Doping Level Bipolar Junctions Transistors And Method For Forming |
| 12272304 | 7910425 | 2010-03-19 | 2011-03-22 | Granted | United States of America | Multiple Doping Level Bipolar Junctions Transistors And Method For Forming |
| 10953894 | 7095094 | 2004-09-29 | 2006-08-22 | Lapsed | United States of America | Multiple Doping Level Bipolar Junctions Transistors And Method For Forming |
| 13026528 | 8143120 | 2011-02-14 | 2012-03-27 | Granted | United States of America | Multiple Doping Level Bipolar Junctions Transistors And Method For Forming |
| 11458270 | 7449388 | 2006-07-18 | 2008-11-11 | Lapsed | United States of America | Method For Forming Multiple Doping Level Bipolar Junctions Transistors |
| 10955238 | 7345364 | 2004-09-30 | 2008-03-18 | Granted | United States of America | Structure And Method For Improved Heat Conduction For Semiconductor Devices |
| 11968693 | 7498204 | 2008-01-03 | 2009-03-03 | Granted | United States of America | Structure And Method For Improved Heat Conduction For Semiconductor Devices |
| 10773900 | 7078280 | 2004-02-06 | 2006-07-18 | Lapsed | United States of America | Vertical Replacement-Gate Silicon-On-Insulator Transistor |
| 11419356 | 7259048 | 2006-05-19 | 2007-08-21 | Granted | United States of America | Vertical Replacement-Gate Silicon-On-Insulator Transistor |
| 09968234 | 6709904 | 2001-09-28 | 2004-03-23 | Granted | United States of America | Vertical Replacement-Gate (VRG) Silicon-On-Insulator (SOI) CMOS Transistor |
| 09968388 | | 2001-09-28 | | Abandoned | United States of America | Lithographically Defined CMOS Threshold Voltage |

Schedule B(1)(a) – Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------|----------|------------|------------|---------|--------------------------|---|
| 10619058 | 7049199 | 2003-07-14 | 2006-05-23 | Granted | United States of America | Method Of Ion Implantation For Achieving Desired Dopant Concentration |
| 09961477 | 6686604 | 2001-09-21 | 2004-02-03 | Granted | United States of America | Multiple Operating Voltage Vertical Replacement-Gate (VRG) Transistor |
| 10684713 | 7056783 | 2003-10-14 | 2006-06-06 | Lapsed | United States of America | Multiple Operating Voltage Vertical Replacement-Gate (VRG) Transistor |
| 10409423 | 6821831 | 2003-04-08 | 2004-11-23 | Lapsed | United States of America | Electrostatic Discharge Protection In Double Diffused MOS Transistors |
| 09896669 | 6576506 | 2001-06-29 | 2003-06-10 | Granted | United States of America | Electrostatic Discharge Protection In Double Diffused MOS Transistors |
| 10777250 | 6873171 | 2004-02-12 | 2005-03-29 | Granted | United States of America | Integrated Circuit Early Life Failure Detection By Monitoring Changes In Current Signatures |
| 09558130 | 6714032 | 2000-04-25 | 2004-03-30 | Granted | United States of America | Integrated Circuit Early Life Failure Detection By Monitoring Changes In Current Signatures |
| 10147384 | 6683382 | 2002-05-16 | 2004-01-27 | Granted | United States of America | Semiconductor Device Having An Interconnect Layer With A Plurality Of Layout Regions Having Substantially Uniform Densities Of Active Interconnects And Dummy Fills |
| 09484310 | 6436807 | 2000-01-18 | 2002-08-20 | Granted | United States of America | Method For Making An Interconnect Layer And A Semiconductor Device Including The Same |
| 08820063 | 5913146 | 1997-03-18 | 1999-06-15 | Expired | United States of America | Semiconductor Device Having Aluminum Contacts Or Vias And Method Of Manufacture Therefor |
| 09166832 | 6157082 | 1998-10-05 | 2000-12-05 | Expired | United States of America | Semiconductor Device Having Aluminum Contacts Or Vias And Method Of Manufacture Therefor |
| 09073556 | 6028359 | 1998-05-06 | 2000-02-22 | Expired | United States of America | Integrated Circuit Having Amorphous Silicide Layer In Contacts And Vias And Method Of Manufacture Therefor |
| 08816185 | 5858873 | 1997-03-12 | 1999-01-12 | Expired | United States of America | Integrated Circuit Having Amorphous Silicide Layer In Contacts And Vias And Method Of Manufacture Therefor |
| 09523210 | 6139995 | 2000-03-10 | 2000-10-31 | Granted | United States of America | Method Of Manufacturing Schottky Gate Transistor Utilizing Alignment Techniques With Multiple Photoresist Layers |
| 09111534 | 6042975 | 1998-07-08 | 2000-03-28 | Granted | United States of America | Alignment Techniques For Photolithography |
| 09049531 | 6033202 | 1998-03-27 | 2000-03-07 | Granted | United States of America | Mold For Non-Photolithographic Fabrication Of Microstructures |
| 09393032 | 6322736 | 1999-09-09 | 2001-11-27 | Granted | United States of America | Mold For Non-Photolithographic Fabrication Of Microstructures |
| 11999168 | 8153484 | 2007-12-04 | 2012-04-10 | Granted | United States of America | Metal-Oxide-Semiconductor Device Having Trenched Diffusion Region And Method Of Forming Same |
| 13428540 | 8648445 | 2012-03-23 | 2014-02-11 | Lapsed | United States of America | Metal-Oxide-Semiconductor Device Having Trenched Diffusion Region And Method Of Forming Same |
| 10953477 | 7338569 | 2004-09-29 | 2008-03-04 | Granted | United States of America | Method And System Of Using Offset Gag For CMP Polishing Pad Alignment And Adjustment |

PATENT
REEL: 060885 FRAME: 0062

Schedule B(1)(a) – Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------|----------|------------|------------|-----------|--------------------------|--|
| 11968930 | 7527544 | 2008-01-03 | 2009-05-05 | Lapsed | United States of America | System Of Using Offset Gage For CMP Polishing Pad Alignment And Adjustment |
| 09150529 | 6215158 | 1998-09-10 | 2001-04-10 | Granted | United States of America | Device And Method For Forming Semiconductor Interconnections In An Integrated Circuit Substrate |
| 09631546 | 6503787 | 2000-08-03 | 2003-01-07 | Granted | United States of America | Device And Method For Forming Semiconductor Interconnections In An Integrated Circuit Substrate |
| 11641507 | 7537984 | 2006-12-19 | 2009-05-26 | Lapsed | United States of America | III-V Power Field Effect Transistors |
| 10948897 | 7180103 | 2004-09-24 | 2007-02-20 | Granted | United States of America | III-V Power Field Effect Transistors |
| 10926631 | 7109589 | 2004-08-26 | 2006-09-19 | Granted | United States of America | Integrated Circuit With Substantially Perpendicular Wire Bonds |
| 11494221 | 7465655 | 2006-07-27 | 2008-12-16 | Granted | United States of America | Integrated Circuit With Substantially Perpendicular Wire Bonds |
| 08752235 | 5811916 | 1996-11-19 | 1998-09-22 | Expired | United States of America | Field Emission Devices Employing Enhanced Diamond Field Emitters |
| 08752234 | 5744195 | 1996-11-19 | 1998-04-28 | Expired | United States of America | Field Emission Devices Employing Enhanced Diamond Field Emitters |
| 08331458 | 5637950 | 1994-10-31 | 1997-06-10 | Expired | United States of America | Field Emission Devices Employing Enhanced Diamond Field Emitters |
| 10850812 | 7235489 | 2004-05-21 | 2007-06-26 | Granted | United States of America | Device And Method To Eliminate Shorting Induced By Via To Metal Misalignment |
| 11738050 | 7675179 | 2007-04-20 | 2010-03-09 | Lapsed | United States of America | Device And Method To Eliminate Shorting Induced By Via To Metal Misalignment |
| 09246402 | 6214675 | 1999-02-08 | 2001-04-10 | Granted | United States of America | A Method For Fabricating A Merged Integrated Circuit Device |
| 09789254 | 6627963 | 2001-02-20 | 2003-09-30 | Granted | United States of America | Method For Fabricating A Merged Integrated Circuit Device |
| 10300254 | 6762457 | 2002-11-20 | 2004-07-13 | Granted | United States of America | LDMOS Device Having A Tapered Oxide |
| 09641086 | 6506641 | 2000-08-17 | 2003-01-14 | Granted | United States of America | The Use Of Selective Oxidation To Improve LDMOS Power Transistors |
| 11419252 | 7381607 | 2006-05-19 | 2008-06-03 | Granted | United States of America | A Method Of Forming A Spiral Inductor In A Semiconductor Substrate |
| 10646997 | 7075167 | 2003-08-22 | 2006-07-11 | Lapsed | United States of America | A Spiral Inductor Formed In A Semiconductor Substrate And A Method For Forming The Inductor |
| 09335646 | | 1999-06-18 | | Abandoned | United States of America | A CMOS Integrated Circuit Having Vertical Transistors And A Process For Fabricating Same |
| 10211674 | 6653181 | 2002-08-02 | 2003-11-25 | Granted | United States of America | A CMOS Integrated Circuit Having Vertical Transistors And A Process For Fabricating Same |
| 10918981 | 7345354 | 2004-08-16 | 2008-03-18 | Granted | United States of America | Increased Quality Factor Of A Varactor In An Integrated Circuit Via A High Conductive Region In A Well |
| 10454133 | 6825089 | 2003-06-04 | 2004-11-30 | Granted | United States of America | Increased Quality Factor Of A Varactor In An Integrated Circuit Via A High Conductive Region In A Well |
| 09652479 | 6373087 | 2000-08-31 | 2002-04-16 | Granted | United States of America | Methods of Fabricating A Metal-Oxide-Metal Capacitor And Associated Apparatus |
| 10080186 | 6730601 | 2002-02-21 | 2004-05-04 | Granted | United States of America | Methods of Fabricating A Metal-Oxide-Metal Capacitor |

PATENT
REEL: 060885 FRAME: 0063

Schedule B(1)(a) - Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------|----------|------------|------------|-----------|--------------------------|---|
| 11116903 | 7297606 | 2005-04-28 | 2007-11-20 | Granted | United States of America | Metal\miOxide\miSemiconductor Device Including A Buried Lightly\miDoped Drain Region |
| 10675633 | 6927453 | 2003-09-30 | 2005-08-09 | Lapsed | United States of America | Metal-Oxide-Semiconductor Device Including A Buried Lightly-Doped Drain Region |
| 09540473 | 6373266 | 2000-03-31 | 2002-04-16 | Granted | United States of America | Apparatus And Method For Determining Process Width Variations In Integrated Circuits |
| 10053097 | 6728940 | 2002-01-18 | 2004-04-27 | Granted | United States of America | Apparatus And Method For Determining Process Width Variations In Integrated Circuits |
| 08353015 | 5576240 | 1994-12-09 | 1996-11-19 | Expired | United States of America | Method For Making A Metal To metal Capacitor |
| 08644086 | 5851870 | 1996-05-09 | 1998-12-22 | Expired | United States of America | Method For Making A Capacitor |
| 08472033 | 5654581 | 1995-06-06 | 1997-08-05 | Expired | United States of America | Integrated Circuit Capacitor |
| 08909563 | 6040616 | 1997-08-12 | 2000-03-21 | Expired | United States of America | A Device and Method of Forming A Metal To Metal Capacitor Within an Integrated Circuit |
| 08863713 | 5825073 | 1997-05-27 | 1998-10-20 | Expired | United States of America | An Electronic Component For An Integrated Circuit |
| 10179057 | | 2002-06-25 | | Abandoned | United States of America | A Graded Growth Gate Oxide (G3) For A Vertical Replacement Gate (VRG) MOSFET. |
| 10986984 | 7169714 | 2004-11-12 | 2007-01-30 | Granted | United States of America | Method And Structure For Graded Gate Oxides On Vertical And Non-Planar Surfaces |
| 09481992 | 6541394 | 2000-01-11 | 2003-04-01 | Granted | United States of America | Method Of Making A Graded Growth, High Quality Oxide Layer For A Semiconductor Device |
| 10171701 | | 2002-06-14 | | Abandoned | United States of America | Coupling Capacitance Reduction |
| 09906331 | 6432812 | 2001-07-16 | 2002-08-13 | Granted | United States of America | Method of coupling capacitance reduction |
| 11392375 | | 2006-03-29 | | Abandoned | United States of America | High\miDensity Inter\miDie Interconnect Structure |
| 10638248 | 7045835 | 2003-08-08 | 2006-05-16 | Granted | United States of America | High\miDensity Inter\miDie Interconnect Structure |
| 11540056 | 7239160 | 2006-09-29 | 2007-07-03 | Granted | United States of America | Method Of Electrical Testing Of An Integrated Circuit With An Electrical Probe |
| 11138152 | 7132840 | 2005-05-26 | 2006-11-07 | Granted | United States of America | Method Of Electrical Testing |
| 08979297 | 5849639 | 1997-11-26 | 1998-12-15 | Granted | United States of America | Method For Removing Etching Residues And Contaminants |
| 09164283 | 6046115 | 1998-10-01 | 2000-04-04 | Granted | United States of America | Method for Removing Etching Residues and Contaminants |
| 09434424 | 6284663 | 1999-11-04 | 2001-09-04 | Granted | United States of America | Method For Making Field Effect Devices And Capacitors With Thin Film Dielectrics And Resulting Devices |
| 09060420 | 6001741 | 1998-04-15 | 1999-12-14 | Granted | United States of America | Method For Making Field Effect Devices And Capacitors With Improved Thin Film Dielectrics And Resulting Devices |
| 09651447 | 6670242 | 2000-08-30 | 2003-12-30 | Granted | United States of America | Method For Making An Integrated Circuit Device Including A Graded, Growth, High Quality Gate Oxide Layer And A Nitride Layer |
| 09651593 | | 2000-08-30 | | Abandoned | United States of America | Method For Making An Integrated Circuit Device Including A Graded, Growth, High Quality Gate Oxide Layer And A Gate Electrode Layer With Improved Dopant Activation |

PATENT
REEL: 060885 FRAME: 0064

Schedule B(1)(a) – Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------|----------|------------|------------|-----------|--------------------------|---|
| 09651857 | | 2000-08-30 | | Abandoned | United States of America | Integrated Circuit Device Including a Graded, Grown, High Quality Gate Oxide Layer |
| 09651592 | | 2000-08-30 | | Abandoned | United States of America | Flash Device w\slg3 (High Temperature) Oxide Grown In RTP or RTP Furnace |
| 09651458 | | 2000-08-30 | | Abandoned | United States of America | Integrated Circuit Device Including a Graded, Grown, High Quality Gate Oxide Layer And a Nitride Layer |
| 09651450 | | 2000-08-30 | | Abandoned | United States of America | Method For Making A High Quality, Graded, Grown Gate Oxide Layer Including Native Oxide Removal |
| 09651451 | | 2000-08-30 | | Abandoned | United States of America | Method For Making An Integrated Circuit Device Including A Graded, Grown, High Quality Gate Oxide Layer |
| 09015981 | 6153920 | 1998-01-30 | 2000-11-28 | Expired | United States of America | A Semiconductor Device Configured to Control Dopant Diffusion In the Semiconductor Device Substrate |
| 08862226 | 5731626 | 1997-05-23 | 1998-03-24 | Expired | United States of America | Process For Controlling Dopant Diffusion In A Semiconductor Layer And Semiconductor Layer Formed Thereby |
| 09650164 | 6635116 | 2000-08-29 | 2003-10-21 | Granted | United States of America | Residual oxygen reduction system |
| 10640530 | | 2003-08-13 | | Abandoned | United States of America | Residual Oxygen Reduction System |
| 09006918 | 6133077 | 1998-01-13 | 2000-10-17 | Granted | United States of America | Formation of high-voltage and low-voltage devices on a semiconductor substrate |
| 09495512 | 6194766 | 2000-02-01 | 2001-02-27 | Granted | United States of America | Integrated circuit having low voltage and high voltage devices on a common semiconductor substrate |
| 09724225 | 6521549 | 2000-11-28 | 2003-02-18 | Granted | United States of America | Method of reducing silicon oxynitride gate insulator thickness in some transistors of a hybrid integrated circuit to obtain increased differential in gate insulator thickness with other transistors of the hybrid circuit |
| 10304631 | 6656805 | 2002-11-26 | 2003-12-02 | Lapsed | United States of America | Method of reducing silicon oxynitride gate insulator thickness in some transistors of a hybrid integrated circuit to obtain increased differential in gate insulator thickness with other transistors of the hybrid circuit |
| 10260824 | 7118985 | 2002-09-27 | 2006-10-10 | Lapsed | United States of America | Method of forming a metal-insulator-metal capacitor in an interconnect cavity |
| 09496971 | 6504202 | 2000-02-02 | 2003-01-07 | Granted | United States of America | Interconnect-embedded metal-insulator-metal capacitor |
| 09442078 | 6179956 | 1999-11-16 | 2001-01-30 | Granted | United States of America | Method and apparatus for using across wafer back pressure differentials to influence the performance of chemical mechanical polishing |
| 09005364 | | 1998-01-09 | | Abandoned | United States of America | Method And Apparatus For Using Across Wafer Back Pressure Differentials To Influence The Performance Of Chemical Mechanical Polishing |

Schedule B(1)(a) - Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------|----------|------------|------------|-----------|--------------------------|---|
| 09427572 | 6174798 | 1999-10-26 | 2001-01-16 | Granted | United States of America | Process for forming metal interconnect stack for integrated circuit structure |
| 09261270 | 6087726 | 1999-03-01 | 2000-07-11 | Granted | United States of America | Metal interconnect stack for integrated circuit structure |
| 09454257 | 6297558 | 1999-12-02 | 2001-10-02 | Expired | United States of America | Slurry filling a recess formed during semiconductor fabrication |
| 08899111 | 6069085 | 1997-07-23 | 2000-05-30 | Expired | United States of America | Slurry filling a recess formed during semiconductor fabrication |
| 10706120 | 6855586 | 2003-11-12 | 2005-02-15 | Granted | United States of America | Low voltage breakdown element for ESD trigger device |
| 10055082 | 6710990 | 2002-01-22 | 2004-03-23 | Granted | United States of America | Low voltage breakdown element for ESD trigger device |
| 10153011 | 6794756 | 2002-05-21 | 2004-09-21 | Granted | United States of America | Integrated circuit structure having low dielectric constant material and having silicon oxynitride caps over closely spaced apart metal lines |
| 09425552 | 6423628 | 1999-10-22 | 2002-07-23 | Granted | United States of America | Method of forming integrated circuit structure having low dielectric constant material and having silicon oxynitride caps over closely spaced apart metal lines |
| 09583434 | 6383332 | 2000-05-31 | 2002-05-07 | Granted | United States of America | Endpoint detection method and apparatus which utilize a chelating agent to detect a polishing endpoint |
| 09212503 | 6117779 | 1998-12-15 | 2000-09-12 | Granted | United States of America | Endpoint detection method and apparatus which utilize a chelating agent to detect a polishing endpoint |
| 08768905 | 5821572 | 1996-12-17 | 1998-10-13 | Expired | United States of America | Simple BiCMOS process for creation of low trigger voltage SCR and zener diode pad protection |
| 09081475 | 6130117 | 1998-05-19 | 2000-10-10 | Expired | United States of America | Simple BiCMOS process for creation of low trigger voltage SCR and zener diode pad protection |
| 08469293 | | 1995-06-06 | | Abandoned | United States of America | Polymorphic Rectilinear Thieving Pad |
| 08781992 | 5736680 | 1997-01-06 | 1998-04-07 | Expired | United States of America | Polymorphic rectilinear thieving pad |
| 09395507 | 6328802 | 1999-09-14 | 2001-12-11 | Granted | United States of America | Method and apparatus for determining temperature of a semiconductor wafer during fabrication thereof |
| 09952540 | 6794310 | 2001-09-14 | 2004-09-21 | Granted | United States of America | Method and apparatus for determining temperature of a semiconductor wafer during fabrication thereof |
| 09070188 | 5920110 | 1998-04-30 | 1999-07-06 | Expired | United States of America | Antifuse device for use on a field programmable interconnect chip |
| 08534008 | 5844297 | 1995-09-26 | 1998-12-01 | Expired | United States of America | Antifuse device for use on a field programmable interconnect chip |
| 09245193 | 6063672 | 1999-02-05 | 2000-05-16 | Granted | United States of America | NMOS electrostatic discharge protection device and method for CMOS integrated circuit |
| 09476295 | | 1999-12-30 | | Abandoned | United States of America | NMOS Electrostatic Discharge Protection Device and Method for CMOS Integrated Circuit |
| 09072705 | 6066560 | 1998-05-05 | 2000-05-23 | Granted | United States of America | Non-linear circuit elements on integrated circuits |
| 09467340 | 6228767 | 1999-12-20 | 2001-05-08 | Granted | United States of America | Non-linear circuit elements on integrated circuits |
| 09228906 | 6261406 | 1999-01-11 | 2001-07-17 | Lapsed | United States of America | Confinement device for use in dry etching of substrate surface and method of dry etching a wafer surface |

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REEL: 060885 FRAME: 0066

Schedule B(1)(a) - Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|---------------|------------------|------------|------------|-----------|--------------------------|--|
| 09884805 | 6852243 | 2001-06-18 | 2005-02-08 | Lapsed | United States of America | Confinement device for use in dry etching of substrate surface and method of dry etching a wafer surface |
| 10893659 | 7071094 | 2004-07-16 | 2006-07-04 | Granted | United States of America | Dual layer barrier film techniques to prevent resist poisoning |
| 11418873 | 7393780 | 2006-05-04 | 2008-07-01 | Granted | United States of America | Dual layer barrier film techniques to prevent resist poisoning |
| 09896363 | 6812134 | 2001-06-28 | 2004-11-02 | Granted | United States of America | Dual layer barrier film techniques to prevent resist poisoning |
| 12947948 | 8289051 | 2010-11-17 | 2012-10-16 | Lapsed | United States of America | Input/Output Core Design and Method of Manufacture Therefor |
| 13443691 | | 2012-04-10 | | Abandoned | United States of America | Input/Output Core Design and Method of Manufacture Therefor |
| 2008801316818 | ZL200880131681.8 | 2008-09-19 | 2013-06-19 | Lapsed | China | Allotropic Or Morphologic Change In Silicon Induced By Electromagnetic Radiation For Resistance Tuning Of Integrated Circuits |
| 14073526 | | 2013-11-06 | | Abandoned | United States of America | Allotropic Or Morphologic Change In Silicon Induced By Electromagnetic Radiation For Resistance Tuning Of Integrated Circuits |
| 098130968 | I413235 | 2009-09-14 | 2013-10-21 | Lapsed | Taiwan | Allotropic Or Morphologic Change In Silicon Induced By Electromagnetic Radiation For Resistance Tuning Of Integrated Circuits |
| 13119005 | 8610215 | 2011-03-15 | 2013-12-17 | Granted | United States of America | Allotropic Or Morphologic Change In Silicon Induced By Electromagnetic Radiation For Resistance Tuning Of Integrated Circuits |
| 1020117008762 | 10-1306685 | 2008-09-19 | 2013-09-04 | Lapsed | Korea, Republic of (KR) | Allotropic Or Morphologic Change In Silicon Induced By Electromagnetic Radiation For Resistance Tuning Of Integrated Circuits |
| 08430084 | 5891784 | 1995-04-27 | 1999-04-06 | Expired | United States of America | Transistor Fabrication Method |
| 08587061 | 6498080 | 1996-01-16 | 2002-12-24 | Expired | United States of America | Transistor Fabrication Method |
| 12114589 | | 2008-05-02 | | Abandoned | United States of America | Transistor Fabrication Method |
| 10224220 | | 2002-08-20 | | Abandoned | United States of America | Transistor Fabrication Method |
| 12689749 | 8030199 | 2010-01-19 | 2011-10-04 | Granted | United States of America | Transistor Fabrication Method |
| 08832245 | 5780329 | 1997-04-03 | 1998-07-14 | Expired | United States of America | Process for fabricating a moderate-depth diffused emitter bipolar transistor in a BICMOS device without using an additional mask |
| 08823305 | 6211096 | 1997-03-21 | 2001-04-03 | Expired | United States of America | Tunable dielectric constant oxide and method of manufacture |
| 2000008156 | 4777494 | 2000-01-17 | 2011-07-08 | Granted | Japan | Pyrogenic Devoid Wet Oxidation |
| 09231265 | 6335295 | 1999-01-15 | 2002-01-01 | Granted | United States of America | Flame-free wet oxidation |
| 10094520 | 6654226 | 2002-03-08 | 2003-11-25 | Lapsed | United States of America | Thermal low k dielectrics |
| 09064802 | 6418353 | 1998-04-22 | 2002-07-09 | Granted | United States of America | Automating photolithography in the fabrication of integrated circuits |
| 1998287829 | 4555410 | 1998-10-09 | 2010-07-23 | Lapsed | Japan | Apparatus And A Method For Forming An Oxide Film On A Semiconductor |

Schedule B(1)(a) - Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|------------|----------|------------|------------|-----------|--------------------------|---|
| 09474666 | 6323106 | 1999-12-29 | 2001-11-27 | Granted | United States of America | Dual nitrogen implantation techniques for oxynitride formation in semiconductor devices |
| 1998096236 | 4565674 | 1998-04-08 | 2010-08-13 | Lapsed | Japan | Pre-Conditioning Polishing Pads For Chemical-Mechanical Polishing |
| 87102678 | 115428 | 1998-02-25 | 2000-05-11 | Lapsed | Taiwan | Method For Artificially-Inducing Reverse Short-Channel Effects In Deep Sub-Micron Cmos Devices |
| 09098019 | 6147409 | 1998-06-15 | 2000-11-14 | Granted | United States of America | Modified multilayered metal line structure for use with tungsten-filled vias in integrated circuit structures |
| 09920890 | 6601008 | 2001-08-02 | 2003-07-29 | Granted | United States of America | Parametric device signature |
| 09098032 | 6037262 | 1998-06-15 | 2000-03-14 | Granted | United States of America | Process for forming vias, and trenches for metal lines, in multiple dielectric layers of integrated circuit structure |
| 87103103 | 135215 | 1998-03-04 | 2001-06-07 | Lapsed | Taiwan | Insulated-Gate Field-Effect Transistors Having Different Gate Capacitances |
| 09896958 | 6358806 | 2001-06-29 | 2002-03-19 | Granted | United States of America | Silicon carbide CMOS channel |
| 10014449 | 4381491 | 1998-01-27 | 2009-10-02 | Lapsed | Japan | Insulated-Gate Field-Effect Transistors Having Different Gate Capacitances |
| 1998094757 | 4996781 | 1998-04-07 | 2012-05-18 | Lapsed | Japan | Process For Forming Improved Cobalt Silicide Layer On Integrated Circuit Structure Using Two Capping Layers. |
| 1998051650 | 4881497 | 1998-03-04 | 2011-12-09 | Lapsed | Japan | Method And Apparatus For Eliminating Peeling At End Edge Of Semiconductor Substrate In Metal Organic Chemical Vapor Deposition Of Titanium Nitride |
| 09081337 | 6073361 | 1998-05-19 | 2000-06-13 | Granted | United States of America | Apparatus for externally monitoring RPM of spin rinse dryer |
| 09069027 | 6037233 | 1998-04-27 | 2000-03-14 | Granted | United States of America | Metal-encapsulated polysilicon gate and interconnect |
| 09063801 | 6061814 | 1998-04-21 | 2000-05-09 | Granted | United States of America | Test circuitry for determining the defect density of a semiconductor process as a function of individual metal layers |
| 09079413 | 6166422 | 1998-05-13 | 2000-12-26 | Granted | United States of America | Inductor with cobalt/nickel core for integrated circuit structure with high inductance and high Q-factor |
| 9762865 | 0271949 | 1997-11-25 | 2000-08-21 | Lapsed | Korea, Republic of (KR) | Method For Artificially-Inducing Reverse Short-Channel Effects In Deep Sub-Micron Cmos Devices |
| 09046113 | 6013952 | 1998-03-20 | 2000-01-11 | Granted | United States of America | Structure and method for measuring interface resistance in multiple interface contacts and via structures in semiconductor devices |
| 09076399 | 6331468 | 1998-05-11 | 2001-12-18 | Granted | United States of America | Formation of integrated circuit structure using one or more silicon layers for implantation and out-diffusion in formation of defect-free source/drain regions and also for subsequent formation of silicon nitride spacers |
| 08979733 | | 1997-11-26 | | Abandoned | United States of America | Purging Gas Control Structure For Cvd Chamber |

Schedule B(1)(a) – Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------|----------|------------|------------|-----------|--------------------------|---|
| 09081403 | | 1998-05-18 | | Abandoned | United States of America | Integrated Circuit Structure With Thin Dielectric Between At Least Local Interconnect Level And First Metal Interconnect Level, And Process For Making Same |
| 09882124 | 6503828 | 2001-06-14 | 2003-01-07 | Granted | United States of America | Process for selective polishing of metal-filled trenches of integrated circuit structures |
| 09076502 | 6127286 | 1998-05-11 | 2000-10-03 | Granted | United States of America | Apparatus and process for deposition of thin film on semiconductor substrate while inhibiting particle formation and deposition |
| 09150220 | 6248180 | 1998-09-09 | 2001-06-19 | Granted | United States of America | Method for removing particles from a semiconductor wafer |
| 09037588 | 6087229 | 1998-03-09 | 2000-07-11 | Granted | United States of America | Composite semiconductor gate dielectrics |
| 09210184 | 6288773 | 1998-12-11 | 2001-09-11 | Granted | United States of America | Method and apparatus for removing residual material from an alignment mark of a semiconductor wafer |
| 08990315 | 6059637 | 1997-12-15 | 2000-05-09 | Granted | United States of America | Process for abrasive removal of copper from the back surface of a silicon substrate |
| 08915000 | 5865666 | 1997-08-20 | 1999-02-02 | Expired | United States of America | Apparatus and method for polish removing a precise amount of material from a wafer |
| 08887910 | 5902704 | 1997-07-02 | 1999-05-11 | Expired | United States of America | Process for forming photoresist mask over integrated circuit structures with critical dimension control |
| 08991397 | 6162714 | 1997-12-16 | 2000-12-19 | Granted | United States of America | Method of forming thin polygates for sub quarter micron CMOS process |
| 08919394 | 5851890 | 1997-08-28 | 1998-12-22 | Expired | United States of America | Process for forming integrated circuit structure with metal silicide contacts using notched sidewall spacer on gate electrode |
| 08914854 | 5882251 | 1997-08-19 | 1999-03-16 | Expired | United States of America | Chemical mechanical polishing pad slurry distribution grooves |
| 08879659 | 5933757 | 1997-06-23 | 1999-08-03 | Expired | United States of America | Etch process selective to cobalt silicide for formation of integrated circuit structures |
| 08351516 | 5627099 | 1994-12-07 | 1997-05-06 | Expired | United States of America | Method of manufacturing semiconductor device |
| 08942991 | 5944585 | 1997-10-02 | 1999-08-31 | Expired | United States of America | Use of abrasive tape conveying assemblies for conditioning polishing pads |
| 08918846 | 5931719 | 1997-08-25 | 1999-08-03 | Expired | United States of America | Method and apparatus for using pressure differentials through a polishing pad to improve performance in chemical mechanical polishing |
| 08772310 | 5769692 | 1996-12-23 | 1998-06-23 | Expired | United States of America | On the use of non-spherical carriers for substrate chemi-mechanical polishing |
| 08760466 | 5770520 | 1996-12-05 | 1998-06-23 | Expired | United States of America | Method of making a barrier layer for via or contact opening of integrated circuit structure |
| 08833597 | 5902129 | 1997-04-07 | 1999-05-11 | Expired | United States of America | Process for forming improved cobalt silicide layer on integrated circuit structure using two capping layers |

Schedule B(1)(a) - Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|------------|------------|------------|------------|-----------|-------------------------------|---|
| 08730809 | 5717490 | 1996-10-17 | 1998-02-10 | Expired | United States of America | Method for identifying order skipping in spectroreflective film measurement equipment |
| 08592870 | 5953631 | 1996-01-24 | 1999-09-14 | Expired | United States of America | Low stress, highly conformal CVD metal thin film |
| 08586587 | 6303995 | 1996-01-11 | 2001-10-16 | Expired | United States of America | Sidewall structure for metal interconnect and method of making same |
| 08475028 | 5661069 | 1995-06-06 | 1997-08-26 | Expired | United States of America | Method of forming an MOS-type integrated circuit structure with a diode formed in the substrate under a polysilicon gate electrode to conserve space |
| 2000322452 | 3527700 | 2000-10-23 | 2004-02-27 | Lapsed | Japan | Low Dielectric Constant Silicon Oxide-Based Dielectric Layer for Integrated Circuit Structures Having Improved Compatibility with Via Filler Materials, and Method of Making Same |
| 11524107 | 7408227 | 2006-09-20 | 2008-08-05 | Granted | United States of America | Apparatus and method of manufacture for integrated circuit and CMOS device including epitaxially grown dielectric on silicon carbide |
| 09777996 | 6724404 | 2001-02-06 | 2004-04-20 | Granted | United States of America | Cluster tool reporting system |
| 989197264 | 69831734.3 | 1998-04-02 | 2005-09-28 | Granted | Germany (Federal Republic of) | Process for fabricating a Moderate-Depth Diffused Emitter Bipolar Transistor in a BiCMOS Device Without Using an Additional Mask |
| 013093220 | 60145418.9 | 2001-04-09 | 2011-10-05 | Lapsed | Germany (Federal Republic of) | Copper ICs Interconnect |
| 2012122801 | 5744790 | 2012-05-30 | 2015-05-15 | Granted | Japan | Damascene Capacitors For Integrated Circuits |
| 200864008 | | 2000-05-10 | | Abandoned | Japan | Damascene Capacitors For Integrated Circuits |
| 09405805 | 6225215 | 1999-09-24 | 2001-05-01 | Granted | United States of America | Method for enhancing anti-reflective coatings used in photolithography of electronic devices |
| 10973851 | 7204920 | 2004-10-25 | 2007-04-17 | Granted | United States of America | Contact ring design for reducing bubble and electrolyte effects during electrochemical plating in manufacturing |
| 10945777 | 7300869 | 2004-09-20 | 2007-11-27 | Granted | United States of America | Integrated barrier and seed layer for copper interconnect technology |
| 10953322 | 7550236 | 2004-09-29 | 2009-06-23 | Lapsed | United States of America | MULTI WAVELENGTH MULTI LAYER PRINTING |
| 11012003 | 7372547 | 2004-12-14 | 2008-05-13 | Granted | United States of America | Process and apparatus for achieving single exposure pattern transfer using maskless optical direct write lithography |
| 10984286 | 7148556 | 2004-11-09 | 2006-12-12 | Granted | United States of America | High performance diode-implanted voltage-controlled poly resistors for mixed-signal and RF applications |
| 09426061 | 6756674 | 1999-10-22 | 2004-06-29 | Granted | United States of America | Low dielectric constant silicon oxide-based dielectric layer for integrated circuit structures having improved compatibility with via filler materials, and method of making same |
| 10949760 | 7315360 | 2004-09-24 | 2008-01-01 | Granted | United States of America | Surface coordinate system |

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Schedule B(1)(a) – Semic Processing A

| AppNo. | PatentNo. | FiledDate | GrantDate | Status | Country | Title |
|---------------|-----------|------------|------------|---------|--------------------------|--|
| 10820494 | 7119432 | 2004-04-07 | 2006-10-10 | Lapsed | United States of America | Method and apparatus for establishing improved thermal communication between a die and a heatspreader in a semiconductor package |
| 60144277 | | 1999-07-15 | | Expired | United States of America | Field Emitting Device Comprising Field-Concentrating Nanosconductor Assembly And Method For Making The Same |
| 60141657 | | 1999-06-30 | | Expired | United States of America | Solvent Absorption By CMP Pads And Its Relationship To Pad Chemistry |
| 60130378 | | 1999-04-21 | | Expired | United States of America | Dark Spin Rinse/Dry |
| 60115525 | | 1999-01-12 | | Expired | United States of America | Multi-Layered WSi/WSiN/Poly (Optional) Resistor for Si C's |
| 60110711 | | 1998-12-03 | | Expired | United States of America | Semiconductor Device With Increased Gate Insulator Lifetime |
| 60117186 | | 1999-01-26 | | Expired | United States of America | Planarization Technique For HDPCVD FSG Layer |
| 60168036 | | 1999-11-30 | | Expired | United States of America | MOS Transistor And Method Of Manufacture |
| 60378476 | | 2002-05-07 | | Expired | United States of America | A Thin Film Toroidal Inductor |
| 60167132 | | 1999-11-23 | | Expired | United States of America | Electrically Measured IC Wafer Masks Version Control Indicator |
| 09698375 | 6306780 | 2000-10-26 | 2001-10-23 | Granted | United States of America | Method For Making A Photoresist Layer Having Increased Resistance To Blistering, Peeling, Lifting, Or Reticulation |
| 09745236 | 6606371 | 2000-12-19 | 2003-08-12 | Granted | United States of America | X-Ray System |
| 10159268 | 6847433 | 2002-06-03 | 2005-01-25 | Lapsed | United States of America | Holder, System, And Process For Improving Overlay In Lithography |
| 08558997 | 5814562 | 1995-11-16 | 1998-09-29 | Expired | United States of America | Process For Semiconductor Device Fabrication |
| 09469090 | 6375912 | 1999-12-21 | 2002-04-23 | Granted | United States of America | Electrochemical Abatement Of Perfluorinated Compounds |
| 09519193 | 6331484 | 2000-03-06 | 2001-12-18 | Granted | United States of America | Titanium-Tantalum Barrier Layer Film And Method For Forming The Same |
| 1020047013135 | 10-979658 | 2003-02-24 | 2010-08-27 | Lapsed | Korea, Republic of (KR) | Monitoring And Control Of A Fabrication Process |
| 09967074 | 6727165 | 2001-09-28 | 2004-04-27 | Granted | United States of America | Fabrication of metal contacts for deep-submicron technologies |
| 10883137 | 7015096 | 2004-07-01 | 2006-03-21 | Lapsed | United States of America | Bimetallic oxide compositions for gate dielectrics |
| 09652571 | 6556409 | 2000-08-31 | 2003-04-29 | Granted | United States of America | An Integrated Circuit Including ESD Circuits For A Multi-Chip Module And A Method Therefor |
| 09956382 | 6759730 | 2001-09-18 | 2004-07-06 | Granted | United States of America | Bipolar Junction Transistor Compatible With Vertical Replacement Gate Transistors |
| 10693110 | 6927177 | 2003-10-24 | 2005-08-09 | Lapsed | United States of America | Chemical mechanical electropolishing system |
| 10929706 | 8685633 | 2004-08-30 | 2014-04-01 | Lapsed | United States of America | Method for Optimizing Wafer Edge Patterning |
| 10158775 | 6985229 | 2002-05-30 | 2006-01-10 | Lapsed | United States of America | Overlay Metrology Using Scatterometry Profiling |
| 10875029 | 7494888 | 2004-06-23 | 2009-02-24 | Lapsed | United States of America | Device And Method Using Isotopically Enriched Silicon |
| 10439863 | 6710416 | 2003-05-16 | 2004-03-23 | Granted | United States of America | Split-Gate Metal-Oxide-Semiconductor Device |
| 10659134 | 7138292 | 2003-09-10 | 2006-11-21 | Granted | United States of America | Apparatus and method of manufacture for integrated circuit and CMOS device including epitaxially grown dielectric on silicon carbide |
| 09310388 | 6750495 | 1999-05-12 | 2004-06-15 | Granted | United States of America | Damascene Capacitors For Integrated Circuits |

Schedule B(1)(a) - Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------|----------|------------|------------|---------|--------------------------|--|
| 10700791 | 7023230 | 2003-11-03 | 2006-04-04 | Lapsed | United States of America | Method for testing IDD at multiple voltages |
| 09298068 | 6191017 | 1999-04-22 | 2001-02-20 | Granted | United States of America | A Method Of Forming A Multi-Layered Dual-Polysilicon Structure |
| 09439048 | 6459946 | 1999-11-12 | 2002-10-01 | Granted | United States of America | Method And System For Determining Operating Staffing |
| 09437930 | 6424160 | 1999-11-10 | 2002-07-23 | Granted | United States of America | Testing Insulation Between Conductors |
| 09286869 | 6048256 | 1999-04-06 | 2000-04-11 | Granted | United States of America | Apparatus And Method For Continuous Delivery And Conditioning Of A Polishing Slurry |
| 09095468 | 6388290 | 1998-06-10 | 2002-05-14 | Granted | United States of America | Single Crystal Silicon On Polycrystalline Silicon Integrated Circuits |
| 08907834 | 6133618 | 1997-08-14 | 2000-10-17 | Expired | United States of America | A Semiconductor Device Having An Anti-Reflective Layer And A Method Of Manufacture Thereof |
| 08924730 | 6074933 | 1997-09-05 | 2000-06-13 | Expired | United States of America | Integrated Circuit Fabrication |
| 08941556 | 5972179 | 1997-09-30 | 1999-10-26 | Expired | United States of America | Silicon IC Contacts Using Composite TiN Barrier Layer |
| 11016014 | 7075179 | 2004-12-17 | 2006-07-11 | Granted | United States of America | System for implementing a configurable integrated circuit |
| 10607116 | 6979251 | 2003-06-26 | 2005-12-27 | Lapsed | United States of America | Method and apparatus to add slurry to a polishing system |
| 09016475 | 5994221 | 1998-01-30 | 1999-11-30 | Granted | United States of America | Device And Method Of Fabricating Vias For ULSI Metallization And Interconnect |
| 09243377 | 6194750 | 1999-02-01 | 2001-02-27 | Granted | United States of America | Integrated Circuit Comprising Means For High Frequency Signal Transmission |
| 08853582 | 5767561 | 1997-05-09 | 1998-06-16 | Expired | United States of America | Integrated Circuit Devices With Isolated Circuit Elements |
| 10658168 | 7079966 | 2003-09-08 | 2006-07-18 | Granted | United States of America | Method of qualifying a process tool with wafer defect maps |
| 08971422 | 5993947 | 1997-11-17 | 1999-11-30 | Granted | United States of America | Low Temperature Coefficient Dielectric Material Comprising Binary Calcium Niobate And Calcium Tantalate Oxides |
| 08346806 | 5549512 | 1994-11-30 | 1996-08-27 | Expired | United States of America | Mini environment for Hazardous Process Tools |
| 08326444 | 5510230 | 1994-10-20 | 1996-04-23 | Expired | United States of America | Device Fabrication Using DUV/EUV Pattern Delineation |
| 08589229 | 5656399 | 1996-01-22 | 1997-08-12 | Expired | United States of America | Process for Making An X-Ray Mask |
| 08346810 | 5441614 | 1994-11-30 | 1995-08-15 | Expired | United States of America | Method and Apparatus for Planar Magnetron Sputtering |
| 08664227 | 5670062 | 1996-06-07 | 1997-09-23 | Expired | United States of America | Method For Producing Tapered Lines |
| 08683291 | 5656515 | 1996-07-18 | 1997-08-12 | Expired | United States of America | Method Of Making High-Speed Double-Heterostructure Bipolar Transistor Devices |
| 10452360 | 7332062 | 2003-06-02 | 2008-02-19 | Granted | United States of America | Electroplating tool for semiconductor manufacture having electric field control |
| 08413527 | 5663677 | 1995-03-30 | 1997-09-02 | Expired | United States of America | Integrated Circuit Multi-Level Interconnection Technique |
| 08439040 | 5538819 | 1995-04-10 | 1996-07-23 | Expired | United States of America | Self-Aligned Alignment Marks For Phase-Shifting Masks |
| 08351977 | 5599730 | 1994-12-08 | 1997-02-04 | Expired | United States of America | Poly-Buffered LOCCOS |
| 08353032 | 5574291 | 1994-12-09 | 1996-11-12 | Expired | United States of America | Article Comprising A Thin Film Transistor With Low Conductivity Organic Layer |
| 08918781 | 5958654 | 1997-08-25 | 1999-09-28 | Expired | United States of America | Lithographic Process And Energy-Sensitive Material For Use Therein |
| 08324842 | 6524645 | 1994-10-18 | 2003-02-25 | Granted | United States of America | A Process For The Electroless Deposition of Metal On A Substrate |

Schedule B(1)(a) - Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|---------------|------------|------------|------------|---------|-------------------------------|--|
| 08163967 | 5959342 | 1993-12-08 | 1999-09-28 | Expired | United States of America | Semiconductor Device Having A High Voltage Termination Improvement |
| 10410925 | 6739953 | 2003-04-09 | 2004-05-25 | Granted | United States of America | Mechanical stress free processing method |
| 07707365 | 5879997 | 1991-05-30 | 1999-03-09 | Expired | United States of America | Method For Forming Self Aligned Polysilicon Contact |
| 10423096 | 6722948 | 2003-04-25 | 2004-04-20 | Granted | United States of America | Pad conditioning monitor |
| 09547132 | 6461225 | 2000-04-11 | 2002-10-08 | Granted | United States of America | Local Area Alloying For Preventing Dishing Of Copper During Chemical Mechanical Polishing (CMP) |
| 10412867 | 7079963 | 2003-04-14 | 2006-07-18 | Granted | United States of America | Modified binary search for optimizing efficiency of data collection time |
| 979319175 | 69709934.2 | 1997-07-15 | 2002-01-09 | Expired | Germany (Federal Republic of) | Subsonic to Supersonic and Ultrasonic Conditioning of Polishing Pad in a Chemical Mechanical Polishing Apparatus |
| 891232228 | NI-165325 | 2000-11-21 | 2002-10-21 | Lapsed | Taiwan | Method For Making Field Effect Devices And Capacitors With Thin Film Dielectrics And Resulting Devices |
| 91119024 | NI-198062 | 2002-08-22 | 2004-07-07 | Lapsed | Taiwan | Multiple Operating Voltage Vertical Replacement-Gate (VRG) Transistor Interconnections To Copper IC's |
| 90108450 | 1223427 | 2001-04-09 | 2004-11-01 | Lapsed | Taiwan | A Method For Reducing Dishing Related Issues During The Formation Of Shallow Trench Isolation Structures |
| 090113472 | NI-157181 | 2001-06-04 | 2002-05-11 | Lapsed | Taiwan | Damascene Capacitors For Integrated Circuits |
| 89104065 | NI-144505 | 2000-03-07 | 2001-11-11 | Granted | Taiwan | Integrated Circuit Capacitor And Associated Fabrication Methods |
| 89100158 | NI-134826 | 2000-01-06 | 2001-10-17 | Lapsed | Taiwan | Capacitor Comprising Improved Taox-Based Dielectric |
| 87105577 | NI-132141 | 1998-04-13 | 2001-05-16 | Lapsed | Taiwan | Silicon-On-Insulator (SOI) Semiconductor Structure With Trench Including A Conductive Layer |
| 90116133 | 1282168 | 2001-07-02 | 2007-06-01 | Lapsed | Taiwan | Metal-Oxide-Semiconductor Device Including A Buried Lightly-Doped Drain Region |
| 093110409 | 1325175 | 2004-04-14 | 2010-05-21 | Lapsed | Taiwan | Method For Making Field Effect Devices And Capacitors With Thin Film Dielectrics And Resulting Devices |
| 20000064498 | 675988 | 2000-11-01 | 2007-01-23 | Lapsed | Korea, Republic of (KR) | Process For Fabricating A Semiconductor Device Having A Metal Oxide Or A Metal Silicate Gatedielectric Layer |
| 1020010049568 | 809305 | 2001-08-17 | 2008-02-26 | Lapsed | Korea, Republic of (KR) | Method For Making An Integrated Circuit Including Alignment Marks |
| 1020000001128 | 699186 | 2000-01-11 | 2007-03-19 | Lapsed | Korea, Republic of (KR) | Capacitor Comprising Improved Taox-Based Dielectric |
| 1019980018520 | 505305 | 1998-05-22 | 2005-07-25 | Lapsed | Korea, Republic of (KR) | Method Of Manufacturing An Integrated Circuit Using Chemical Mechanical Polishing |
| 1019980050349 | 495717 | 1998-11-24 | 2005-06-08 | Lapsed | Korea, Republic of (KR) | System And Method Of Manufacturing Semicustom Reticles Using Reticle Primitives |
| 19990024635 | 0303937 | 1999-06-28 | 2001-07-16 | Lapsed | Korea, Republic of (KR) | A Device and Method of Forming A Metal To Metal Capacitor Within an Integrated Circuit |
| 9832710 | 280565 | 1998-08-12 | 2000-11-10 | Granted | Korea, Republic of (KR) | |

Schedule B(1)(a) – Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------------|------------|------------|------------|---------|--------------------------|--|
| 9723238 | 455640 | 1997-06-05 | 2004-10-26 | Expired | Korea, Republic of (KR) | Method For Producing Tapered Lines |
| 10335470 | 7014957 | 2002-12-31 | 2006-03-21 | Granted | United States of America | Interconnect routing using parallel lines and method of manufacture |
| 1020000016832 | 367185 | 2000-03-31 | 2002-12-23 | Lapsed | Korea, Republic of (KR) | Lithographic Process For Device Fabrication Using Dark-Field Illumination |
| 1020000035027 | 617894 | 2000-06-24 | 2006-08-23 | Granted | Korea, Republic of (KR) | Semiconductor Device Free Of LDD Regions |
| 1020010019270 | 707705 | 2001-04-11 | 2007-04-09 | Lapsed | Korea, Republic of (KR) | Local Area Alloying For Preventing Dishing Of Copper During Chemical Mechanical Polishing (CMP) |
| 1020000074125 | 753777 | 2000-12-07 | 2007-08-24 | Lapsed | Korea, Republic of (KR) | Article Comprising A Dielectric Material Of Zr-Ge-Ti-O Or Hf-Ge-Ti-O And Method Of Making The Same |
| 1020060012904 | 10-1184202 | 2006-02-10 | 2012-09-13 | Lapsed | Korea, Republic of (KR) | High-Density Field Emission Elements and a Method for Forming Said Emission Elements |
| 1020050085840 | 10-1215425 | 2005-09-14 | 2012-12-18 | Granted | Korea, Republic of (KR) | Guard Ring for Improved Matching |
| 10200200566476 | 10-918779 | 2002-09-17 | 2009-09-17 | Lapsed | Korea, Republic of (KR) | Bipolar Junction Transistor Compatible With Vertical Replacement Gate Transistors |
| 1020030034713 | 10-948495 | 2003-05-30 | 2010-03-12 | Lapsed | Korea, Republic of (KR) | Overlay Metrology Using Scatterometry Profiling |
| 1020020057533 | 10-908991 | 2002-09-23 | 2009-07-16 | Lapsed | Korea, Republic of (KR) | Multiple Operating Voltage Vertical Replacement-Gate (VRG) Transistor |
| 2001196104 | 4931291 | 2001-06-28 | 2012-02-24 | Lapsed | Japan | Silicon-On-Insulator (SOI) Semiconductor Structure With Trench Including A Conductive Layer |
| 2000135071 | 3492978 | 2000-05-08 | 2003-11-14 | Granted | Japan | Improved Wehnelt Gun For Electron Lithography |
| 11015686 | 3521119 | 1999-01-25 | 2004-02-13 | Lapsed | Japan | Device And Method Of Fabricating Vias For ULSI Metallization And Interconnect |
| 10227743 | 3321101 | 1998-08-12 | 2002-06-21 | Granted | Japan | A Device and Method of Forming A Metal To Metal Capacitor Within an Integrated Circuit |
| 2000233853 | 3782293 | 2000-08-02 | 2006-03-17 | Lapsed | Japan | Methods And Apparatus For Testing Integrated Circuits |
| 10313333 | 6897102 | 2002-12-06 | 2005-05-24 | Granted | United States of America | Process to minimize polysilicon gate depletion and dopant penetration and to increase conductivity |
| 2003180575 | 4386680 | 2003-06-25 | 2009-10-09 | Lapsed | Japan | Capacitor For A Semiconductor Device And Method For Fabrication Therefor |
| 2006035891 | 5153075 | 2006-02-14 | 2012-12-14 | Lapsed | Japan | High-Density Field Emission Elements and a Method for Forming Said Emission Elements |
| 2001168642 | 5239107 | 2001-06-04 | 2013-04-12 | Lapsed | Japan | A Method For Reducing Dishing Related Issues During The Formation Of Shallow Trench Isolation Structures |
| 2000372277 | 4358430 | 2000-12-07 | 2009-08-14 | Lapsed | Japan | A Process for Fabricating Integrated Circuit Devices Having Thin Film Transistors |
| 10245219 | 6855624 | 2002-09-17 | 2005-02-15 | Lapsed | United States of America | Low-loss on-chip transmission line for integrated circuit structures and method of manufacture |

Schedule B(1)(a) - Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|-----------|------------|------------|------------|---------|-------------------------------|---|
| 09704200 | 6537923 | 2000-10-31 | 2003-03-25 | Granted | United States of America | Process for forming integrated circuit structure with low dielectric constant material between closely spaced apart metal lines |
| 983065624 | 69835260.2 | 1998-08-18 | 2006-07-19 | Lapsed | Germany (Federal Republic of) | Embedded Thin Film Passive Components |
| 003071784 | 60000174.1 | 2000-08-21 | 2002-05-22 | Lapsed | Germany (Federal Republic of) | Semiconductor Device Having Regions Of Insulating Material Formed In A Semiconductor Substrate And Process Of Making The Device |
| 993071026 | 69902133.2 | 1999-09-07 | 2002-07-17 | Lapsed | Germany (Federal Republic of) | Method Of Making An Article Comprising An Oxide Layer On A Gas-Based Semiconductor Body |
| 993064708 | 69901142.6 | 1999-08-17 | 2002-04-03 | Granted | Germany (Federal Republic of) | Process For Semiconductor Device Fabrication Having Copper Interconnects |
| 973090285 | 69724972.7 | 1997-11-11 | 2003-09-17 | Granted | Germany (Federal Republic of) | Electronic Apparatus |
| 10172849 | 6917430 | 2002-06-17 | 2005-07-12 | Lapsed | United States of America | Method to improve the control of source chemicals delivery by a carrier gas |
| 003032737 | 60032051.0 | 2000-04-18 | 2006-11-29 | Lapsed | Germany (Federal Republic of) | A Method Of Forming A Multi-Layered Dual-Polysilicon Structure |
| 10078233 | 6830984 | 2002-02-15 | 2004-12-14 | Granted | United States of America | Thick traces from multiple damascene layers |
| 10033090 | 6817941 | 2001-10-25 | 2004-11-16 | Lapsed | United States of America | Uniform airflow diffuser |
| 10008170 | 6706583 | 2001-10-19 | 2004-03-16 | Granted | United States of America | High speed low noise transistor |
| 10053537 | 6673498 | 2001-11-02 | 2004-01-06 | Lapsed | United States of America | Method for reticle formation utilizing metal vaporization |
| 09970392 | 6647348 | 2001-10-03 | 2003-11-11 | Granted | United States of America | Latent defect classification system |
| 11368780 | 7476951 | 2006-03-06 | 2009-01-13 | Granted | United States of America | Selective Isotropic Etch For Titanium Based Materials |
| 08935521 | 5895960 | 1997-09-23 | 1999-04-20 | Expired | United States of America | Thin Oxide Mask Level Resistor |
| 09999872 | 6582568 | 2001-10-19 | 2003-06-24 | Granted | United States of America | First stage salsiclation of cobalt during cobalt deposition or subsequent Ti or Tin cap deposition using energy from a directional plasma |
| 983079187 | 69832352.1 | 1998-09-29 | 2005-11-16 | Granted | Germany (Federal Republic of) | Energy-Sensitive Resist Material And A Process For Device Fabrication Using An Energy-Sensitive Resist Material |
| 09758603 | 6741122 | 2001-01-12 | 2004-05-25 | Granted | United States of America | Routing technique to adjust clock skew using frames and prongs |
| 08924277 | 6102962 | 1997-09-05 | 2000-08-15 | Expired | United States of America | Method for estimating quiescent current in integrated circuits |
| 09574771 | 6506678 | 2000-05-19 | 2003-01-14 | Granted | United States of America | Integrated circuit structures having low k porous aluminum oxide dielectric material separating aluminum lines, and method of making same |
| 09817642 | 6476497 | 2001-03-26 | 2002-11-05 | Granted | United States of America | Concentric metal density power routing |
| 10271860 | 4094743 | 1998-09-25 | 2008-03-14 | Lapsed | Japan | A Method and Apparatus for Chemical Mechanical Polishing |
| 09292079 | 6211051 | 1999-04-14 | 2001-04-03 | Granted | United States of America | Reduction of plasma damage at contact etch in MOS integrated circuits |

Schedule B(1)(a) – Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|---------------|----------|------------|------------|-----------|--------------------------|---|
| 09213847 | 6177305 | 1998-12-17 | 2001-01-23 | Granted | United States of America | Fabrication of metal-insulator-metal capacitive structures |
| 87103907 | 133913 | 1998-03-17 | 2001-10-08 | Lapsed | Taiwan | Tunable Dielectric Constant Oxide and Method of Manufacture |
| 09112222 | 6074517 | 1998-07-08 | 2000-06-13 | Granted | United States of America | Method and apparatus for detecting an endpoint polishing layer by transmitting infrared light signals through a semiconductor wafer |
| 09909175 | 6970622 | 2001-07-19 | 2005-11-29 | Lapsed | United States of America | Arrangement and method for controlling the transmission of a light signal based on intensity of a received light signal |
| 08923676 | 5915414 | 1997-09-04 | 1999-06-29 | Expired | United States of America | Standardized gas isolation box (GIB) installation |
| 08651018 | 5966599 | 1996-05-21 | 1999-10-12 | Expired | United States of America | Method for fabricating a low trigger voltage silicon controlled rectifier and thick field device |
| 08623470 | 5861652 | 1996-03-28 | 1999-01-19 | Expired | United States of America | Method and apparatus for protecting functions imbedded within an integrated circuit from reverse engineering |
| 1019980033782 | 499194 | 1998-08-20 | 2005-06-24 | Lapsed | Korea, Republic of (KR) | Process For Forming Integrated Circuit Structure With Improved Metal Silicide Contacts Using Notched Sidewall Spacer On Gate Electrode, And Resulting Structure |
| 09703616 | 6391768 | 2000-10-30 | 2002-05-21 | Granted | United States of America | Process for CMP removal of excess trench or via filler metal which inhibits formation of concave regions on oxide surface of integrated circuit structure |
| 09948808 | 6727107 | 2001-09-07 | 2004-04-27 | Granted | United States of America | Method of testing the processing of a semiconductor wafer on a CMP apparatus |
| 10304974 | 6667488 | 2002-11-26 | 2005-03-15 | Lapsed | United States of America | Thick metal top layer |
| 09111271 | 6114215 | 1998-07-06 | 2000-09-05 | Granted | United States of America | Generating non-planar topology on the surface of planar and near-planar substrates |
| 09112403 | 6066266 | 1998-07-08 | 2000-05-23 | Granted | United States of America | In-situ chemical-mechanical polishing slurry formulation for compensation of polish pad degradation |
| 09928570 | 6743725 | 2001-08-13 | 2004-06-01 | Granted | United States of America | High selectivity SiC etch in integrated circuit fabrication |
| 08979734 | 5914001 | 1997-11-26 | 1999-06-22 | Expired | United States of America | In-situ etch of CVD chamber |
| 08979733 | | 1997-11-26 | | Abandoned | United States of America | Gas Control Structure For Cvd Chamber |
| 09072915 | 5992242 | 1998-05-04 | 1999-11-30 | Granted | United States of America | Silicon wafer or die strength test fixture using high pressure fluid Method and system for alignment of openings in semiconductor fabrication |
| 09054279 | 5998226 | 1998-04-02 | 1999-12-07 | Granted | United States of America | Apparatus and method for electrical determination of delamination at one or more interfaces within a semiconductor wafer |
| 08995260 | 6066561 | 1997-12-19 | 2000-05-23 | Granted | United States of America | Shimming substrate holder assemblies to produce more uniformly polished substrate surfaces |
| 08960925 | 5961375 | 1997-10-30 | 1999-10-05 | Expired | United States of America | Semiconductor integrated circuit core probing for failure analysis |
| 08984003 | 5936876 | 1997-12-03 | 1999-08-10 | Granted | United States of America | Plasma-enhanced oxide process optimization and material and apparatus therefor |
| 08966637 | 6028014 | 1997-11-10 | 2000-02-22 | Granted | United States of America | Dual purpose retaining ring and polishing pad conditioner |
| 08895960 | 6004193 | 1997-07-17 | 1999-12-21 | Expired | United States of America | |

Schedule B(1)(a) – Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|------------|----------|------------|------------|-----------|--------------------------|--|
| 08926590 | 6020242 | 1997-09-04 | 2000-02-01 | Expired | United States of America | Effective silicide blocking |
| 08874055 | 5985679 | 1997-06-12 | 1999-11-16 | Expired | United States of America | Automated endpoint detection system during chemical-mechanical polishing |
| 08918483 | 5893756 | 1997-08-26 | 1999-04-13 | Expired | United States of America | Use of ethylene glycol as a corrosion inhibitor during cleaning after metal chemical mechanical polishing |
| 08963813 | 5973398 | 1997-11-04 | 1999-10-26 | Granted | United States of America | Semiconductor device and fabrication method employing a palladium-plated heat spreader substrate |
| 08786695 | 5869395 | 1997-01-22 | 1999-02-09 | Expired | United States of America | Simplified hole interconnect process |
| 08754696 | 5985746 | 1996-11-21 | 1999-11-16 | Expired | United States of America | Process for forming self-aligned conductive plugs in multiple insulation levels in integrated circuit structures and resulting product |
| 08596894 | 5760428 | 1996-01-25 | 1998-06-02 | Expired | United States of America | Variable width low profile gate array input/output architecture |
| 08520030 | 5614249 | 1995-08-28 | 1997-03-25 | Expired | United States of America | Leak detection system for a gas manifold of a chemical vapor deposition apparatus |
| 08486803 | 5698468 | 1995-06-07 | 1997-12-16 | Expired | United States of America | Silicidation process with etch stop |
| 08396560 | 5539246 | 1995-03-01 | 1996-07-23 | Expired | United States of America | Microelectronic integrated circuit including hexagonal semiconductor gate device |
| 08792479 | 5773855 | 1997-01-31 | 1998-06-30 | Expired | United States of America | Microelectronic circuit including silicided field-effect transistor elements that bifunction as interconnects |
| 10015255 | 6562735 | 2001-12-11 | 2003-05-13 | Granted | United States of America | Control of reaction rate in formation of low k carbon-containing silicon oxide dielectric material using organosilane, unsubstituted silane, and hydrogen peroxide reactants |
| 09848758 | 6503840 | 2001-05-02 | 2003-01-07 | Granted | United States of America | Process for forming metal-filled openings in low dielectric constant dielectric material while inhibiting via poisoning |
| 08627622 | 5654895 | 1996-04-04 | 1997-08-05 | Expired | United States of America | Process monitor usig impedance controlled I/O controller |
| 08512678 | 5663076 | 1995-08-08 | 1997-09-02 | Expired | United States of America | Automating photolithography in the fabrication of integrated circuits |
| 09808441 | 6492736 | 2001-03-14 | 2002-12-10 | Granted | United States of America | Power mesh bridge |
| 2013174500 | 5710714 | 2005-03-10 | 2015-03-13 | Lapsed | Japan | A Bipolar Junction Transistor Having A High Germanium Concentration In A Silicon-Germanium Layer And A Method For Forming The Bipolar Junction Transistor |
| 08283296 | 5474648 | 1994-07-29 | 1995-12-12 | Expired | United States of America | Uniform and repeatable plasma processing |
| 201184505 | | 2011-04-06 | | Abandoned | Japan | Method And Structure For DC And RF Shielding Of Integrated Circuits |
| 11534340 | 7535330 | 2006-09-22 | 2009-05-19 | Granted | United States of America | LOW MUTUAL INDUCTANCE MATCHED INDUCTORS |
| 2012105770 | | 2012-05-07 | | Abandoned | Japan | Multiple Operating Voltage Vertical Replacement-Gate (VRG) Transistor |

Schedule B(1)(a) – Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|---------------|------------|------------|------------|-----------|-------------------------------|---|
| 1020127015010 | 10-1216580 | 2012-06-11 | 2012-12-21 | Granted | Korea, Republic of (KR) | A Bipolar Junction Transistor Having A High Germanium Concentration In A Silicon-Germanium Layer And A Method For Forming The Bipolar Junction Transistor |
| 09730704 | 6413151 | 2000-12-06 | 2002-07-02 | Granted | United States of America | CMP slurry recycling apparatus and method for recycling CMP slurry |
| 2012100569 | | 2012-04-26 | | Abandoned | Japan | An Integrated Circuit Including ESD Circuits For A Multi-Chip Module And A Method Therefor |
| 08475586 | 5637887 | 1995-06-07 | 1997-06-10 | Expired | United States of America | Silicon controller rectifier (SCR) with capacitive trigger |
| 08650476 | 5780347 | 1996-05-20 | 1998-07-14 | Expired | United States of America | Method of forming polysilicon local interconnects |
| 057254047 | | 2005-03-10 | | Abandoned | European Patent | A Bipolar Junction Transistor Having A High Germanium Concentration In A Silicon-Germanium Layer And A Method For Forming The Bipolar Junction Transistor |
| 011016839 | 60133155.9 | 2001-01-30 | 2008-03-12 | Granted | Germany (Federal Republic of) | Interconnect-Embedded Metal-Insulator-Metal Capacitor and Method of Fabricating Same |
| 08685772 | 5689134 | 1996-07-24 | 1997-11-18 | Expired | United States of America | Integrated circuit structure having reduced cross-talk and method of making same |
| 131550428 | | 2005-03-10 | | Abandoned | European Patent | A Bipolar Junction Transistor Having A High Germanium Concentration In A Silicon-Germanium Layer And A Method For Forming The Bipolar Junction Transistor |
| 2009246032 | 5404308 | 2009-10-27 | 2013-11-08 | Granted | Japan | Semiconductor Device Free Of LDD Regions |
| 001226885 | | 2000-10-18 | | Lapsed | European Patent | Low Dielectric Constant Silicon Oxide-Based Dielectric Layer for Integrated Circuit Structures Having Improved Compatibility with Via Filler Materials, and Method of Making Same |
| 09892250 | 6559033 | 2001-06-27 | 2003-05-06 | Granted | United States of America | Processing for forming integrated circuit structure with low dielectric constant material between closely spaced apart metal lines |
| 2009143777 | 4505036 | 2009-06-17 | 2010-04-30 | Lapsed | Japan | A Process for Fabricating Integrated Circuit Devices Having Thin Film Transistors |
| 09148028 | 6340434 | 1998-09-03 | 2002-01-22 | Granted | United States of America | Method and apparatus for chemical-mechanical polishing |
| 11140142 | 7106073 | 2005-05-27 | 2006-09-12 | Lapsed | United States of America | Method and system for area efficient charge-based capacitance measurement |
| 111323405 | 7429733 | 2005-12-29 | 2008-09-30 | Granted | United States of America | Method and sample for radiation microscopy including a particle beam channel formed in the sample source |
| 09881151 | 6914786 | 2001-06-14 | 2005-07-05 | Lapsed | United States of America | Converter device |
| 10035346 | 6825546 | 2001-12-28 | 2004-11-30 | Lapsed | United States of America | CMOS varactor with constant dc/dv characteristic |
| 10966074 | 7179736 | 2004-10-14 | 2007-02-20 | Granted | United States of America | Method for fabricating planar semiconductor wafers |
| 11005765 | 7242074 | 2004-12-06 | 2007-07-10 | Granted | United States of America | Reduced capacitance resistors |
| 11247517 | 7284213 | 2005-10-11 | 2007-10-16 | Granted | United States of America | Defect analysis using a yield vehicle |

Schedule B(1)(a) – Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|-----------|----------|------------|------------|---------|--------------------------|--|
| 11397252 | 8053824 | 2006-04-03 | 2011-11-08 | Granted | United States of America | Interdigitated Mesh To Provide Distributed, High Quality Factor Capacitive Coupling |
| 10927802 | 7137098 | 2004-08-27 | 2006-11-14 | Granted | United States of America | Pattern component analysis and manipulation |
| 60002275 | | 1995-08-14 | | Expired | United States of America | A Process For Semiconductor Device Fabrication |
| 60426842 | | 2002-11-15 | | Expired | United States of America | In-Situ Removal Of Surface Impurities Prior To As Doped Poly Dep |
| 60552308 | | 2004-03-10 | | Expired | United States of America | Creation of A High Ge Concentration SiGe Layer In BiCMOS Processing Through Thermal Oxidation of the SiGe Base Layer |
| 60541878 | | 2004-02-04 | | Expired | United States of America | Structure For Improved Heat Conduction For Semiconductor Devices |
| 60115717 | | 1999-01-12 | | Expired | United States of America | Method Of Making A Graded Grown, High Quality Oxide Layer For A Semiconductor |
| 60117242 | | 1999-01-26 | | Expired | United States of America | Device |
| 10971961 | 7259083 | 2004-10-22 | 2007-08-21 | Granted | United States of America | Device Comprising Thermally Stable, Low Dielectric Constant Material |
| 60115532 | | 1999-01-12 | | Expired | United States of America | Local Interconnect manufacturing process |
| 10117487 | 6878406 | 2002-04-05 | 2005-04-12 | Lapsed | United States of America | Novel Methods To Fabricate MOM Capacitors |
| 062546304 | | 2006-09-06 | | Lapsed | European Patent | Dynamic use of process temperature |
| 60180809 | | 2000-02-07 | | Expired | United States of America | Robust Shallow Trench Isolation Structures And A Method For Forming Shallow Trench Isolation Structures |
| 60174566 | | 2000-01-05 | | Expired | United States of America | Improvement Of Thick Photoresist (PR) Integrity For High-Current High-Dose High-Energy Ion Implantation Using A Novel Thermal And UV-Irradiation Treatment |
| 10867014 | 7013192 | 2004-06-14 | 2006-03-14 | Lapsed | United States of America | An Integrated Circuit And A Method Of Making An Integrated Circuit |
| 11269275 | 8076779 | 2005-11-08 | 2011-12-13 | Granted | United States of America | Substrate contact analysis |
| 09464297 | 6759337 | 1999-12-15 | 2004-07-06 | Granted | United States of America | Reduction of macro level stresses in copper/Low-K wafers |
| 09972481 | 6667536 | 2001-10-05 | 2003-12-23 | Lapsed | United States of America | Process for etching a controllable thickness of oxide on an integrated circuit structure on a semiconductor substrate using nitrogen plasma and plasma and an rf bias applied to the substrate |
| 60140666 | | 1999-06-24 | | Expired | United States of America | Thin Film Multi-Layer High Q Transformer Formed In A Semiconductor Substrate |
| 60096581 | | 1998-08-14 | | Expired | United States of America | Method Of Making A Graded, High Quality Oxide Layer For A Semiconductor Device |
| 09271084 | 6531751 | 1999-03-17 | 2003-03-11 | Granted | United States of America | Process For Fabricating Device Comprising Lead Zirconate Titanate Semiconductor Device |
| 60141656 | | 1999-06-30 | | Expired | United States of America | Semiconductor Device With Increased Gate Insulator Lifetime |
| | | | | | | Impact Of Post Window Etch Cleans Process On Reliability Of 0.25 (* mm Vintage Windows |

Schedule B(1)(a) - Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|------------|----------|------------|------------|---------|--------------------------|---|
| 09345039 | 6368972 | 1999-06-30 | 2002-04-09 | Granted | United States of America | Method For Making An Integrated Circuit Including Alignment Marks |
| 09376233 | 6274933 | 1999-08-17 | 2001-08-14 | Granted | United States of America | An Integrated Circuit Device Having A Planar Interlevel Dielectric Layer |
| 60507335 | | 2003-09-30 | | Expired | United States of America | A Spiral Inductor Formed In A Semiconductor Substrate |
| 60005141 | | 1995-10-12 | | Expired | United States of America | A Process For Device Fabrication In Which The Plasma Etch Is Controlled By Monitoring Optical Emission |
| 09345556 | 6265260 | 1999-06-30 | 2001-07-24 | Granted | United States of America | Method For Making An Integrated Circuit Capacitor Including Tantalum Pentoxide |
| 09235735 | 6248394 | 1999-01-22 | 2001-06-19 | Granted | United States of America | Process For Fabricating Device Comprising Lead Zirconate Titanate |
| 08714909 | 5835221 | 1996-09-17 | 1998-11-10 | Expired | United States of America | Process For Fabricating A Device Using Polarized Light To Determine Film Thickness |
| 09113594 | 6372520 | 1998-07-10 | 2002-04-16 | Granted | United States of America | Sonic assisted strengthening of gate oxides |
| 60115527 | | 1999-01-12 | | Expired | United States of America | Technique To Fabricate Gate Mask Photo Alignment Marks For STI |
| 10701328 | 6939727 | 2003-11-03 | 2005-09-06 | Lapsed | United States of America | Method for performing statistical post processing in semiconductor manufacturing using ID cells |
| 60326050 | | 2001-09-28 | | Expired | United States of America | A Resistor Located On A Semiconductor Substrate And A Method of Manufacture Therefor |
| 10928292 | 7062415 | 2004-08-27 | 2006-06-13 | Lapsed | United States of America | Parametric outlier detection |
| 10020084 | 6686272 | 2001-12-13 | 2004-02-03 | Granted | United States of America | Anti-reflective coatings for use at 248 nm and 193 nm |
| 10799851 | 7299158 | 2004-03-12 | 2007-11-20 | Granted | United States of America | Process control data collection |
| 60145127 | | 1999-07-22 | | Expired | United States of America | Article Comprising Aligned Carbon Nanotubes With Reduced Diameter And Method For Making The Same |
| 2007503058 | 5393027 | 2005-03-10 | 2013-10-25 | Granted | Japan | A Bipolar Junction Transistor Having A High Germanium Concentration In A Silicon-Germanium Layer And A Method For Forming The Bipolar Junction Transistor |
| 60149036 | | 1999-08-16 | | Expired | United States of America | Electrochemical Abatement Of Perfluorinated Compounds |
| 60013093 | | 1996-03-08 | | Expired | United States of America | An Energy-Sensitive Resist Material And A Process For Device Fabrication Using An Energy-Sensitive Resist Material |
| 09369802 | 6538367 | 1999-08-06 | 2003-03-25 | Granted | United States of America | Field Emitting Device Comprising Field-Concentrating Nanosconductor Assembly And Method For Making The Same |
| 60135565 | | 1999-05-24 | | Expired | United States of America | Use Of Titanium-Tantalum Alloy As A Diffusion Barrier Material For Copper/interconnects |
| 60115881 | | 1999-01-14 | | Expired | United States of America | A 3-Step Passivation-Depassivation-Passivation D 2 Annealing Process For Hot Carrier Immunity And Transistor Matching |
| 60007002 | | 1995-10-16 | | Expired | United States of America | A Process For Fabricating A Device Using Polarized Light To Determine Film Thickness |
| 09131860 | 6136672 | 1998-08-10 | 2000-10-24 | Granted | United States of America | Process For Device Fabrication Using A High-Energy Boron Implant |

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REEL: 060885 FRAME: 0080

Schedule B(1)(a) – Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|---------------|------------|------------|------------|---------|--------------------------|---|
| 10779966 | 6971944 | 2004-02-17 | 2005-12-06 | Lapsed | United States of America | Method and control system for improving CMP process by detecting and reacting to harmonic oscillation |
| 60060869 | | 1997-10-02 | | Expired | United States of America | An Energy-Sensitive Resist Material And A Process For Device Fabrication Using An Energy-Sensitive Resist Material |
| 10668875 | 7071811 | 2003-09-23 | 2006-07-04 | Lapsed | United States of America | High performance voltage control diffusion resistor |
| 09480224 | 6359339 | 2000-01-10 | 2002-03-19 | Granted | United States of America | Multi-Layered Metal Silicide Resistor For Si IC's |
| 10505197 | 7972440 | 2005-06-10 | 2011-07-05 | Granted | United States of America | Monitoring And Control Of A Fabrication Process |
| 60172654 | | 1999-12-20 | | Expired | United States of America | X-Ray System |
| 60082076 | | 1998-04-17 | | Expired | United States of America | Process For Device Fabrication Using A High-Energy Boron Implant |
| 60294566 | | 2001-06-01 | | Expired | United States of America | Process For Controlling Alignment In A Lithographic Process And Apparatus Therefor |
| 10713951 | 7166492 | 2003-11-14 | 2007-01-23 | Granted | United States of America | Integrated circuit carrier apparatus method and system |
| 10513121 | 7132297 | 2004-10-27 | 2006-11-07 | Granted | United States of America | Multi-Layer Inductor Formed In A Semiconductor Substrate And Having A Core Of Ferromagnetic Material |
| 1020067018437 | 10-1173526 | 2005-03-10 | 2012-08-07 | Granted | Korea, Republic of (KR) | A Bipolar Junction Transistor Having A High Germanium Concentration In A Silicon-Germanium Layer And A Method For Forming The Bipolar Junction Transistor |
| 09594189 | 6365503 | 2000-06-14 | 2002-04-02 | Granted | United States of America | A Method Of Improving Electromigration In Semiconductor Device Manufacturing Processes |
| 09879783 | 6765806 | 2001-06-12 | 2004-07-20 | Granted | United States of America | Composition with EMC shielding characteristics |
| 09296001 | 6469390 | 1999-04-21 | 2002-10-22 | Granted | United States of America | Device Comprising Thermally Stable, Low Dielectric Constant Material |
| 10690861 | 6909591 | 2003-10-22 | 2005-06-21 | Lapsed | United States of America | Complimentary metal oxide semiconductor capacitor and method for making same |
| 10721971 | 6998343 | 2003-11-24 | 2006-02-14 | Lapsed | United States of America | Method for creating barrier layers for copper diffusion |
| 09611844 | 6503841 | 2000-07-07 | 2003-01-07 | Granted | United States of America | Oxide Etch |
| 08703756 | 5877032 | 1996-08-27 | 1999-03-02 | Expired | United States of America | A Process For Device Fabrication In Which The Plasma Etch Is Controlled By Monitoring Optical Emission |
| 09472332 | 6290822 | 1999-12-23 | 2001-09-18 | Granted | United States of America | Sputtering Method For Forming Dielectric Films |
| 09641160 | 6479404 | 2000-08-17 | 2002-11-12 | Granted | United States of America | Process For Fabricating A Semiconductor Device Having A Metal Oxide Or A Metal Silicate Gate Dielectric Layer |
| 10156242 | 6708574 | 2002-05-24 | 2004-03-23 | Granted | United States of America | Abnormal Photoresist Line\Space Profile Detection Through Signal Processing Of Metrology Waveform |
| 09510015 | 6361614 | 2000-02-22 | 2002-03-26 | Granted | United States of America | Method And Apparatus For Dark Spin Rinse/Dry Semiconductor Processing |
| 09514832 | 6439968 | 2000-02-28 | 2002-08-27 | Granted | United States of America | A Polishing Pad Having A Water-Repellant Film Thereon And A Method Of Manufacture Therefor |
| 09650604 | 7439146 | 2000-08-30 | 2008-10-21 | Granted | United States of America | Field Plated Resistor With Enhanced Routing Area Thereover |

Schedule B(1)(a) - Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|------------|----------|------------|------------|---------|--------------------------|---|
| 09483297 | 6465132 | 2000-01-14 | 2002-10-15 | Granted | United States of America | Article Comprising Small Diameter Nanowires And Method For Making The Same |
| 09378856 | 6187665 | 1999-08-23 | 2001-02-13 | Granted | United States of America | A process For Deuterium Passivation And Hot Carrier Immunity |
| 10675575 | 7556048 | 2003-09-30 | 2009-07-07 | Lapsed | United States of America | In-Situ Removal Of Surface Impurities Prior To Arsenic-Doped Polysilicon In The Fabrication Of Heterojunction Biloplar Transistor |
| 09426453 | 6297063 | 1999-10-25 | 2001-10-02 | Granted | United States of America | In-Situ Nano-Interconnected Circuit Devices And Method For Making The Same |
| 09364367 | 6153901 | 1999-07-30 | 2000-11-28 | Granted | United States of America | Integrated Circuit Capacitor Including Anchored Plug |
| 09366388 | 6560735 | 1999-08-03 | 2003-05-06 | Granted | United States of America | Methods And Apparatus For Testing Integrated Circuits |
| 10650395 | 7067882 | 2003-08-28 | 2006-06-27 | Lapsed | United States of America | High quality factor spiral inductor that utilizes active negative capacitance |
| 09521768 | 6319095 | 2000-03-09 | 2001-11-20 | Granted | United States of America | Colloidal Suspension Of Abrasive Particles Containing Magnesium As CMP Slurry |
| 09451053 | 6576980 | 1999-11-30 | 2003-06-10 | Granted | United States of America | Surface Treatment Anneal Of Hydrogenated Silicon-Oxy-Carbide Dielectric Layer |
| 09334977 | 6417570 | 1999-06-17 | 2002-07-09 | Granted | United States of America | Layered Dielectric Film Structure Suitable For Gate Dielectric Application In Sub\(\mu\m0.25 ìm Technologies |
| 09140275 | 6080625 | 1998-08-26 | 2000-06-27 | Granted | United States of America | Method For Making Dual-Polysilicon Structures In Integrated Circuits |
| 10723701 | 7183787 | 2003-11-26 | 2007-02-27 | Granted | United States of America | Contact resistance device for improved process control |
| 2003572051 | 4737933 | 2003-02-24 | 2011-05-13 | Lapsed | Japan | Monitoring And Control Of A Fabrication Process |
| 09653297 | 6548892 | 2000-08-31 | 2003-04-15 | Granted | United States of America | Low K Dielectric Insulator and Method of Forming Semiconductor Circuit Structures |
| 10026407 | 6730588 | 2001-12-20 | 2004-05-04 | Granted | United States of America | Method of forming SiGe gate electrode |
| 09759120 | 6509242 | 2001-01-12 | 2003-01-21 | Granted | United States of America | Heterojunction Bipolar Transistor |
| 10736386 | 7653523 | 2003-12-15 | 2010-01-26 | Lapsed | United States of America | Method For Calculating High-Resolution Wafer Parameter Profiles |
| 09121284 | 6013958 | 1998-07-23 | 2000-01-11 | Granted | United States of America | Apparatus and Method for Integrated Circuit With Variable Capacitor |
| 10730554 | 6984869 | 2003-12-08 | 2006-01-10 | Lapsed | United States of America | High performance diode implanted voltage controlled p-type diffusion resistor |
| 09232418 | 6111750 | 1999-01-15 | 2000-08-29 | Granted | United States of America | Electronic Apparatus |
| 09236933 | 6283812 | 1999-01-25 | 2001-09-04 | Granted | United States of America | Article Comprising Aligned, Truncated Carbon Nanotubes And Process For Fabricating Article |
| 09277778 | 6218255 | 1999-03-29 | 2001-04-17 | Granted | United States of America | Method Of Making A Capacitor |
| 09911364 | 6844236 | 2001-07-23 | 2005-01-18 | Granted | United States of America | Method And Structure For DC And RF Shielding Of Integrated Circuits |
| 10644116 | 7245758 | 2003-08-20 | 2007-07-17 | Granted | United States of America | Whole-wafer photoemission analysis |
| 09311631 | 6358865 | 1999-05-14 | 2002-03-19 | Granted | United States of America | Oxidation Of Silicon Using Fluorine Implant |

PATENT
REEL: 060885 FRAME: 0082

Schedule B(1)(a) -- Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------|----------|------------|------------|---------|--------------------------|---|
| 09363758 | 6153268 | 1999-07-29 | 2000-11-28 | Granted | United States of America | Method For Producing Oriented Piezoelectric Films |
| 09388297 | 6350659 | 1999-09-01 | 2002-02-26 | Granted | United States of America | Semiconductor Device Having Regions Of Insulating Material Formed In A Semiconductor Substrate And Process Of Making The Device |
| 09140270 | 6348393 | 1998-08-26 | 2002-02-19 | Granted | United States of America | A Capacitor In An Integrated Circuit And A Method Of Manufacturing An Integrated Circuit |
| 09153522 | 6103607 | 1998-09-15 | 2000-08-15 | Granted | United States of America | Manufacture Of Mosfet Devices |
| 10261463 | 6940151 | 2002-09-30 | 2005-09-06 | Granted | United States of America | Silicon-Rich Low Thermal Budget Silicon Nitride For Integrated Circuits |
| 10260693 | 6784478 | 2002-09-30 | 2004-08-31 | Granted | United States of America | Plate Capacitor Structure And Fabrication Method Therefor In A Dual Damascene Process |
| 09236966 | 6250984 | 1999-01-25 | 2001-06-26 | Granted | United States of America | Article Comprising Enhanced Nanotube Emitter Structure And Process For Fabricating Article |
| 09108848 | 6284413 | 1998-07-01 | 2001-09-04 | Granted | United States of America | System and Method of Manufacturing Semicustom Reticles Using Reticle Primitives |
| 10153231 | 6686662 | 2002-05-21 | 2004-02-03 | Granted | United States of America | A Semiconductor Device Barrier Layer |
| 09283528 | 6379868 | 1999-04-01 | 2002-04-30 | Granted | United States of America | Lithographic Process For Device Fabrication Using Dark-Field Illumination |
| 10953750 | 7067890 | 2004-09-29 | 2006-06-27 | Lapsed | United States of America | Thick Oxide Region In A Semiconductor Device |
| 09082924 | 6192290 | 1998-05-21 | 2001-02-20 | Granted | United States of America | System And Method Of Manufacturing Semicustom Integrated Circuits Using Reticle Primitives From A Library And Interconnect Reticles |
| 09456210 | 6197663 | 1999-12-07 | 2001-03-06 | Granted | United States of America | A Process For Fabricating Integrated Circuit Devices Having Thin Film Transistors |
| 09226730 | 6107684 | 1999-01-07 | 2000-08-22 | Granted | United States of America | Semiconductor Device Having a Signal Pin with Multiple Connections |
| 08847704 | 6023093 | 1997-04-28 | 2000-02-08 | Expired | United States of America | Deuterated Dielectric And Polysilicon Film-Based Semiconductor Devices And Method Of Manufacture Thereof |
| 09080430 | 6002113 | 1998-05-18 | 1999-12-14 | Granted | United States of America | Apparatus For Processing Silicon Device With Improved Temperature Control |
| 10658017 | 6665435 | 2003-09-08 | 2005-03-08 | Lapsed | United States of America | Method of translating a net description of an integrated circuit die |
| 09152189 | 6101371 | 1998-09-12 | 2000-08-08 | Granted | United States of America | Article Comprising An Inductor |
| 08566040 | 5589416 | 1995-12-06 | 1996-12-31 | Expired | United States of America | Process For Forming Integrated Capacitors |
| 08555594 | 5648699 | 1995-11-09 | 1997-07-15 | Expired | United States of America | Field Emission Devices Employing Improved Emitters On Metal Foil And Methods For Making Such Devices |
| 09999848 | 6734081 | 2001-10-24 | 2004-05-11 | Granted | United States of America | Shallow trench isolation structure for laser thermal processing |
| 10668021 | 7081037 | 2003-09-22 | 2006-07-25 | Lapsed | United States of America | Pad conditioner setup |
| 10719195 | 6890804 | 2003-11-21 | 2005-05-10 | Granted | United States of America | Metal-Oxide-Semiconductor Device Formed in Silicon-On-Insulator |

PATENT
REEL: 060885 FRAME: 0083

Schedule B(1)(a) – Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------|----------|------------|------------|---------|--------------------------|--|
| 08957122 | 6556703 | 1997-10-24 | 2003-04-29 | Expired | United States of America | Scanning Electron Microscope System And Method Of Manufacturing An Integrated Circuit |
| 08538317 | 5552355 | 1995-10-03 | 1996-09-03 | Expired | United States of America | Compensation Of The Temperature Coefficient Of The Dielectric Constant Of Barium Strontium Titanate |
| 09280387 | 6323537 | 1999-03-29 | 2001-11-27 | Granted | United States of America | A Capacitor For An Integrated Circuit |
| 10675569 | 7137400 | 2003-09-30 | 2006-11-21 | Granted | United States of America | Bypass Loop Gas Flow Calibration |
| 10151887 | 6797525 | 2002-05-22 | 2004-09-28 | Granted | United States of America | Fabrication Process For A Semiconductor Device Having A Metal Oxide Dielectric Material With A High Dielectric Constant, Annealed With A Buffered Anneal Process |
| 09742855 | 6625250 | 2000-12-19 | 2003-09-23 | Granted | United States of America | Optical Structures And Methods For X-Ray Applications |
| 08534356 | 5642014 | 1995-09-27 | 1997-06-24 | Expired | United States of America | Self-Powered Devices |
| 09310701 | 6492647 | 1999-05-07 | 2002-12-10 | Granted | United States of America | Improved Wehnelt Gun For Electron Lithography |
| 08509930 | 5739562 | 1995-08-01 | 1998-04-14 | Expired | United States of America | Combined Photogate And Photodiode Active Pixel Image Sensor |
| 10180910 | 6847077 | 2002-06-25 | 2005-01-25 | Granted | United States of America | Capacitor For A Semiconductor Device And Method For Fabrication Therefor |
| 10767205 | 7037820 | 2004-01-30 | 2006-05-02 | Granted | United States of America | Cross-Fill Pattern For Metal Fill Levels, Power-Supply Filtering, And Analog Circuit Shielding |
| 09409115 | 6322934 | 1999-09-30 | 2001-11-27 | Granted | United States of America | Method For Making Integrated Circuits Including Features With A Relatively Small Critical Dimension |
| 10629496 | 6818516 | 2003-07-29 | 2004-11-16 | Lapsed | United States of America | Selective high k dielectrics removal |
| 09364366 | 6204186 | 1999-07-30 | 2001-03-20 | Granted | United States of America | Method Of Making Integrated Circuit Capacitor Including Tapered Plug |
| 08380774 | 5598056 | 1995-01-31 | 1997-01-28 | Expired | United States of America | Multilayer Pillar Structure For Improved Field Emission Devices |
| 08903974 | 6566224 | 1997-07-31 | 2003-05-20 | Expired | United States of America | Process For Device Fabrication |
| 08355787 | 5670376 | 1994-12-14 | 1997-09-23 | Expired | United States of America | Methodology For Monitoring Solvent Quality |
| 09178720 | 6218077 | 1998-10-26 | 2001-04-17 | Granted | United States of America | Method Of Manufacturing An Integrated Circuit Using A Scanning System And A Scanning System |
| 09209787 | 6339246 | 1998-12-11 | 2002-01-15 | Granted | United States of America | Tungsten Silicide Nitride As An Electrode For Tantalum Pentoxide Devices |
| 08431355 | 5620573 | 1995-04-28 | 1997-04-15 | Expired | United States of America | Reduced Stress Tungsten Deposition |
| 08581665 | 5681763 | 1995-12-29 | 1997-10-28 | Expired | United States of America | Method For Making Bipolar Transistors Having Indium Doped Base |
| 09430147 | 6294465 | 1999-10-29 | 2001-09-25 | Granted | United States of America | Method For Making Integrated Circuits Having Features With Reduced Critical Dimensions |
| 08350439 | 5545916 | 1994-12-06 | 1996-08-13 | Expired | United States of America | High Q _c Integrated Inductors |
| 09388166 | 6436187 | 1999-09-01 | 2002-08-20 | Granted | United States of America | Process For Fabricating Article Having Substantial Three-Dimensional Order |
| 08751472 | 5736749 | 1996-11-19 | 1998-04-07 | Expired | United States of America | Integrated Circuit Device With Inductor Incorporated Therein |
| 09878820 | 6875702 | 2001-06-11 | 2005-04-05 | Lapsed | United States of America | Plasma treatment system |

Schedule B(1)(a) - Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------|----------|------------|------------|---------|--------------------------|--|
| 08948874 | 5912498 | 1997-10-10 | 1999-06-15 | Expired | United States of America | Article Comprising An Oxide Layer On Gan |
| 09094920 | 6200734 | 1998-06-15 | 2001-03-13 | Granted | United States of America | METHOD FOR FABRICATING SEMICONDUCTOR DEVICES |
| 08344318 | 5656510 | 1994-11-22 | 1997-08-12 | Expired | United States of America | Method For Manufacturing Gate Oxide Capacitors Including Wafer Backside Dielectric And Implantation Electron Flood |
| 08775490 | 6017787 | 1996-12-31 | 2000-01-25 | Expired | United States of America | Integrated Circuit With Twin Tub |
| 08935121 | 5981319 | 1997-09-22 | 1999-11-09 | Expired | United States of America | Method Of Forming A T-Shaped Gate |
| 08393494 | 5659181 | 1995-03-02 | 1997-08-19 | Expired | United States of America | Article Comprising alpha-Hexathienyl |
| 09151077 | 6150271 | 1998-09-10 | 2000-11-21 | Granted | United States of America | Differential Temperature Control In Chemical Mechanical Polishing Processes |
| 08373732 | 5631462 | 1995-01-17 | 1997-05-20 | Expired | United States of America | Laser-Assisted Particle Analysis |
| 09420157 | 6741019 | 1999-10-18 | 2004-05-25 | Granted | United States of America | Article Comprising Aligned |
| 08879926 | 6141050 | 1997-06-20 | 2000-10-31 | Expired | United States of America | MOS Image Sensor |
| 08366952 | 5589303 | 1994-12-30 | 1996-12-31 | Expired | United States of America | Self-Aligned Opaque Regions For Attenuating Phase-Shifting Masks |
| 08366529 | 5489552 | 1994-12-30 | 1996-02-06 | Expired | United States of America | Multiple Layer Tungsten Deposition Process |
| 08286606 | 5472562 | 1994-08-05 | 1995-12-05 | Expired | United States of America | Method Of Etching Silicon Nitride |
| 08982109 | 5967885 | 1997-12-01 | 1999-10-19 | Granted | United States of America | Method Of Manufacturing An Integrated Circuit Using Chemical Mechanical Polishing |
| 08862907 | 5977582 | 1997-05-23 | 1999-11-02 | Expired | United States of America | Capacitor Comprising Improved Taox-Based Dielectric |
| 08332179 | 5623180 | 1994-10-31 | 1997-04-22 | Expired | United States of America | Electron field emitters comprising particles cooled with low voltage emitting material |
| 10455489 | 7429749 | 2003-06-04 | 2008-09-30 | Granted | United States of America | Strained-silicon for CMOS device using amorphous silicon deposition or silicon epitaxial growth |
| 08366515 | 5532510 | 1994-12-30 | 1996-07-02 | Expired | United States of America | Reverse Side Etching for Producing Layers with Strain Variation |
| 08570429 | 5821147 | 1995-12-11 | 1998-10-13 | Expired | United States of America | Integrated Circuit Fabrication |
| 08587426 | 5625199 | 1996-01-16 | 1997-04-29 | Expired | United States of America | Article Comprising Complementary Circuit with Inorganic N-Channel and Organic P-Channel |
| 08749719 | 6491732 | 1996-11-15 | 2002-12-10 | Expired | United States of America | Wafer Handling Apparatus and Method |
| 08381262 | 5561340 | 1995-01-31 | 1996-10-01 | Expired | United States of America | Field Emission Display Having Corrugated Support Pillars and Method for Manufacturing |
| 08932005 | 5903493 | 1997-09-17 | 1999-05-11 | Expired | United States of America | Metal To Metal Capacitor Apparatus And Method For Making |
| 10421421 | 7442113 | 2003-04-23 | 2008-10-28 | Lapsed | United States of America | Visual wear confirmation polishing pad |
| 09586384 | 6500729 | 2000-06-02 | 2002-12-31 | Granted | United States of America | A Method For Reducing Dishing Related Issues During The Formation Of Shallow Trench Isolation Structures |
| 09611907 | 6538283 | 2000-07-07 | 2003-03-25 | Granted | United States of America | Silicon-On-Insulator (SOI) Semiconductor Structure With Trench Including A Conductive Layer |
| 09546037 | 6620720 | 2000-04-10 | 2003-09-16 | Granted | United States of America | Interconnections To Copper IC's |
| 09499411 | 6404027 | 2000-02-07 | 2002-06-11 | Granted | United States of America | High Dielectric Constant Gate Oxides For Silicon-Based Devices |

PATENT
REEL: 060885 FRAME: 0085

Schedule B(1)(a) - Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|-----------|-----------|------------|------------|---------|--------------------------|---|
| 10631528 | 6794304 | 2003-07-31 | 2004-09-21 | Granted | United States of America | Method and apparatus for reducing microtrenching for borderless vias created in a dual damascene process |
| 09416336 | 6187647 | 1999-10-12 | 2001-02-13 | Granted | United States of America | Method Of Manufacturing Lateral High-Q Inductor For Semiconductor Devices |
| 09456807 | 6437392 | 1999-12-08 | 2002-08-20 | Granted | United States of America | Article Comprising A Dielectric Material Of Zr-Ge-Ti-O Or Hf-Ge-Ti-O And Method Of Making The Same |
| 09454909 | 6329281 | 1999-12-03 | 2001-12-11 | Granted | United States of America | Methods For Fabricating A Multilevel Interconnection For An Integrated Circuit Device Utilizing A Selective Overlayer |
| 10693078 | 6894524 | 2003-10-23 | 2005-05-17 | Granted | United States of America | Daisy chain gang testing |
| 89125762 | NI-151729 | 2000-12-04 | 2002-03-11 | Lapsed | Taiwan | A Process For Fabricating Integrated Circuit Devices Having Thin Film Transistors |
| 92114785 | 1279888 | 2003-05-30 | 2007-04-21 | Lapsed | Taiwan | Capactor For A Semiconductor Device And Method For Fabrication Therefor |
| 89108684 | NI-159798 | 2000-07-15 | 2002-08-01 | Lapsed | Taiwan | Improved Wehnelt Gun For Electron Lithography |
| 91118815 | NI-190012 | 2002-08-20 | 2004-03-04 | Granted | Taiwan | A Semiconductor Device Barrier Layer |
| 10698167 | 6930362 | 2003-10-30 | 2005-08-16 | Lapsed | United States of America | Calcium doped polysilicon gate electrodes |
| 89112388 | NI-204341 | 2000-06-29 | 2004-06-21 | Granted | Taiwan | Semiconductor Device Free Of LDD Regions |
| 89106001 | NI-145942 | 2000-03-31 | 2001-12-11 | Granted | Taiwan | Apparatus And Method For Continuous Delivery And Conditioning Of A Polishing Slurry |
| 90108664 | NI-166224 | 2001-04-11 | 2003-03-18 | Lapsed | Taiwan | Local Area Alloying For Preventing Dishing Of Copper During Chemical Mechanical Polishing (CMP) |
| 090121356 | NI-189135 | 2001-08-29 | 2003-11-01 | Lapsed | Taiwan | Field Plated Resistor With Enhanced Routing Area Thereover |
| 90121457 | NI-180535 | 2001-08-30 | 2003-07-01 | Lapsed | Taiwan | Low K Dielectric Insulator and Method of Forming Semiconductor Circuit Structures |
| 091100151 | NI-193273 | 2002-01-08 | 2004-01-01 | Granted | Taiwan | Heterojunction Bipolar Transistor |
| 92108572 | 1300584 | 2003-04-14 | 2008-09-01 | Lapsed | Taiwan | Overlay Metrology Using Scatterometry Profiling |
| 89100425 | NI-138500 | 2000-02-16 | 2001-12-05 | Lapsed | Taiwan | Method For Making An Integrated Circuit Including Alignment Marks |
| 10368520 | 6959258 | 2003-02-18 | 2005-10-25 | Lapsed | United States of America | Methods and structure for IC temperature self-monitoring |
| 093116604 | 1319598 | 2004-06-09 | 2010-01-11 | Lapsed | Taiwan | Metal-Oxide-Semiconductor Device Formed in Silicon-On-Insulator |
| 92126350 | 1315909 | 2003-09-24 | 2009-10-11 | Granted | Taiwan | Silicon-Rich Low Thermal Budget Silicon Nitride For Integrated Circuits |
| 92125649 | 1273702 | 2003-09-17 | 2007-02-11 | Lapsed | Taiwan | Plate Capacitor Structure And Fabrication Method Therefor In A Dual Damascene Process |
| 88104885 | NI-138873 | 1999-03-29 | 2001-08-21 | Granted | Taiwan | Method Of Eliminating Agglomerate Particles In A Polishing Slurry |
| 88105177 | NI-122696 | 1999-04-01 | 2000-11-01 | Lapsed | Taiwan | Apparatus For Processing Silicon Device With Improved Temperature Control |
| 89115497 | NI-152144 | 2000-11-13 | 2002-03-21 | Lapsed | Taiwan | Methods And Apparatus For Testing Integrated Circuits |

PATENT
REEL: 060885 FRAME: 0086

Schedule B(1)(a) - Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|---------------|------------|------------|------------|---------|--------------------------|---|
| 89107369 | NI-148715 | 2000-04-19 | 2002-01-11 | Lapsed | Taiwan | A Method Of Forming A Multi-Layered Dual-Polysilicon Structure |
| 093113007 | 1325158 | 2004-05-07 | 2010-05-21 | Lapsed | Taiwan | Splice-Gate Metal-Oxide-Semiconductor Device |
| 1020010053350 | 10-861665 | 2001-08-31 | 2008-09-29 | Lapsed | Korea, Republic of (KR) | An Integrated Circuit Including ESD Circuits For A Multi-Chip Module And A Method Therefor |
| 1020010052999 | 10-870256 | 2001-08-30 | 2008-11-19 | Granted | Korea, Republic of (KR) | Field Plated Resistor With Enhanced Routing Area Thereover |
| 93129464 | 1362098 | 2004-09-29 | 2012-04-11 | Lapsed | Taiwan | Inductor Formed In An Integrated Circuit |
| 1020010053414 | 853360 | 2001-08-31 | 2008-08-14 | Lapsed | Korea, Republic of (KR) | Low K Dielectric Insulator and Method of Forming Semiconductor Circuit Structures |
| 1020000024335 | 850034 | 2000-05-08 | 2008-07-29 | Lapsed | Korea, Republic of (KR) | Improved Wehnelt Gun For Electron Lithography |
| 1019990035378 | 711526 | 1999-08-25 | 2007-04-19 | Lapsed | Korea, Republic of (KR) | Process For Semiconductor Device Fabrication Having Copper Interconnects |
| 1020000025275 | 695028 | 2000-05-12 | 2007-03-08 | Lapsed | Korea, Republic of (KR) | Damascene Capacitors For Integrated Circuits |
| 19990017990 | 335703 | 1999-05-19 | 2002-04-24 | Lapsed | Korea, Republic of (KR) | Method Of Eliminating Agglomerate Particles In A Polishing Slurry |
| 1020000033163 | 392278 | 2000-06-16 | 2003-07-09 | Lapsed | Korea, Republic of (KR) | Process For Fabricating Vertical Transistors |
| 1019990003869 | 0324072 | 1999-02-05 | 2002-01-29 | Granted | Korea, Republic of (KR) | Electronic Apparatus |
| 9842256 | 516252 | 1998-10-09 | 2005-09-06 | Lapsed | Korea, Republic of (KR) | Article Comprising An Oxide Layer On Gan |
| 20000073674 | 0437743 | 2000-12-06 | 2004-06-17 | Lapsed | Korea, Republic of (KR) | A Method Of Forming An Alignment Feature In Or On A Multi-Layered Semiconductor Structure |
| 10358968 | 6986972 | 2003-02-04 | 2006-01-17 | Lapsed | United States of America | Alternating aperture phase-shift mask fabrication method |
| 20000051024 | 456705 | 2000-08-31 | 2004-11-02 | Granted | Korea, Republic of (KR) | Semiconductor Device Having Regions Of Insulating Material Formed In A Semiconductor Substrate And Process Of Making The Device |
| 1019990046565 | 598471 | 1999-10-26 | 2006-07-03 | Lapsed | Korea, Republic of (KR) | Method Of Manufacturing An Integrated Circuit Using A Scanning System And A Scanning System |
| 1020000046601 | 421757 | 2000-08-11 | 2004-02-25 | Lapsed | Korea, Republic of (KR) | Electrochemical Abatement Of Perfluorinated Compounds |
| 1019990035568 | 705308 | 1999-08-26 | 2007-04-03 | Lapsed | Korea, Republic of (KR) | Method For Making Dual-Polysilicon Structures In Integrated Circuits |
| 1019990058177 | 716436 | 1999-12-16 | 2007-05-03 | Granted | Korea, Republic of (KR) | Deep Sub-Micron Metal Etch With In-Situ Hard Mask Etch |
| 1019990002654 | 307421 | 1999-01-28 | 2001-08-21 | Lapsed | Korea, Republic of (KR) | Device And Method Of Fabricating Vias For ULSI Metallization And Interconnect |
| 9840192 | 298970 | 1998-09-28 | 2001-06-05 | Lapsed | Korea, Republic of (KR) | Silicon IC Contacts Using Composite TiN Barrier Layer |
| 9781732 | 554648 | 1997-12-31 | 2006-02-16 | Lapsed | Korea, Republic of (KR) | Integrated Circuit With Twin Tub |
| 20000044542 | 687979 | 2000-08-01 | 2007-02-21 | Lapsed | Korea, Republic of (KR) | Methods And Apparatus For Testing Integrated Circuits |
| 1020040078024 | 10-1045195 | 2004-09-30 | 2011-06-23 | Granted | Korea, Republic of (KR) | Inductor Formed In An Integrated Circuit |
| 20050090978 | 10-1206628 | 2005-09-29 | 2012-11-23 | Granted | Korea, Republic of (KR) | Thick Oxide Region In A Semiconductor Device |
| 2001112078 | 4548759 | 2001-04-11 | 2010-07-16 | Lapsed | Japan | Local Area Alloying For Preventing Dishing Of Copper During Chemical Mechanical Polishing (CMP) |

PATENT
REEL: 060885 FRAME: 0087

Schedule B(1)(a) - Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|---------------|------------|------------|------------|---------|--------------------------|--|
| 2000373648 | 5208335 | 2000-12-08 | 2013-03-01 | Lapsed | Japan | Article Comprising A Dielectric Material Of Zr-Ge-Ti-O Or Hf-Ge-Ti-O And Method Of Making The Same |
| 10392206 | 6897673 | 2003-03-19 | 2005-05-24 | Granted | United States of America | Method and integrated circuit for capacitor measurement with digital readout |
| 11353614 | 4347479 | 1999-12-13 | 2009-07-24 | Lapsed | Japan | Tungsten Silicide Nitride As An Electrode For Tantalum Pentoxide Devices |
| 1020030033218 | 10-1003958 | 2003-05-24 | 2010-12-20 | Granted | Korea, Republic of (KR) | Abnormal Photoresist Line/Space Profile Detection Through Signal Processing of Metrology Waveform |
| 11263647 | 3725742 | 1999-09-17 | 2005-09-30 | Lapsed | Japan | Method Of Making An Article Comprising An Oxide Layer On A GaAs-Based Semiconductor Body |
| 2000152242 | 3445557 | 2000-05-24 | 2003-06-27 | Granted | Japan | Titanium-Tantalum Barrier Layer Film And Method For Forming The Same |
| 2000003096 | 3581285 | 2000-01-12 | 2004-07-30 | Lapsed | Japan | Method For Making An Integrated Circuit Including Alignment Marks |
| 90120871 | NI-179943 | 2001-08-24 | 2003-06-21 | Lapsed | Taiwan | An Integrated Circuit Including ESD Circuits For A Multi-Chip Module And A Method Therefor |
| 89125642 | NI-165332 | 2000-12-01 | 2002-10-01 | Lapsed | Taiwan | A Method Of Forming An Alignment Feature In Or On A Multi-Layered Semiconductor Structure |
| 92108571 | 1279872 | 2003-04-14 | 2007-04-21 | Lapsed | Taiwan | Abnormal Photoresist Line/Space Profile Detection Through Signal Processing of Metrology Waveform |
| 89100157 | NI-144336 | 2000-01-06 | 2002-03-06 | Lapsed | Taiwan | Method For Making An Integrated Circuit Capacitor Including Tantalum Pentoxide |
| 10287056 | 3023090 | 1998-10-08 | 2000-01-14 | Lapsed | Japan | Article Comprising An Oxide Layer On GaN |
| 11135599 | 3550315 | 1999-05-17 | 2004-04-30 | Lapsed | Japan | Apparatus For Processing Silicon Device With Improved Temperature Control |
| 88118471 | NI-129146 | 1999-10-26 | 2001-04-01 | Lapsed | Taiwan | Method Of Manufacturing An Integrated Circuit Using A Scanning System And A Scanning System |
| 88114626 | NI-151235 | 1999-08-26 | 2002-03-01 | Lapsed | Taiwan | Method For Making Dual-Polysilicon Structures In Integrated Circuits |
| 87113667 | NI-143565 | 1998-08-19 | 2001-10-21 | Lapsed | Taiwan | Article Comprising An Oxide Layer On GaN |
| 10303471 | 3720201 | 1998-10-26 | 2005-09-16 | Lapsed | Japan | Scanning Electron Microscope System And Method Of Manufacturing An Integrated Circuit |
| 11005911 | 3062485 | 1999-01-13 | 2000-04-28 | Lapsed | Japan | Semiconductor Device |
| 09714000 | 6607967 | 2000-11-15 | 2003-08-19 | Granted | United States of America | Process for forming planarized isolation trench in integrated circuit structure on semiconductor substrate |
| 10106377 | 3737277 | 1998-04-16 | 2005-11-04 | Granted | Japan | Deuterated Dielectric And Polysilicon Film-Based Semiconductor Devices And Method Of Manufacture Thereof |

PATENT
REEL: 060885 FRAME: 0088

Schedule B(1)(a) - Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|---------------|------------|------------|------------|---------|--------------------------|--|
| 08262805 | 3530319 | 1996-10-03 | 2004-03-05 | Expired | Japan | Compensation Of The Temperature Coefficient Of The Dielectric Constant Of Barium Strontium Titanate |
| 11141016 | 3550316 | 1999-05-21 | 2004-04-30 | Lapsed | Japan | Method Of Eliminating Agglomerate Particles In A Polishing Slurry |
| 10171971 | 3878744 | 1998-06-19 | 2006-11-10 | Granted | Japan | MOS Image Sensor |
| 11160696 | 3655497 | 1999-06-08 | 2005-03-11 | Lapsed | Japan | Single Crystal Silicon On Polycrystalline Silicon Integrated Circuits |
| 11207606 | 3699301 | 1999-07-22 | 2005-07-15 | Lapsed | Japan | Apparatus and Method for Integrated Circuit With Variable Capacitor |
| 09283277 | 3153163 | 1997-10-16 | 2001-01-26 | Lapsed | Japan | Integrated Circuit Device With Inductor Incorporated Therein |
| 09360176 | 3253908 | 1997-12-26 | 2001-11-22 | Granted | Japan | Integrated Circuit With Twin Tub |
| 94128975 | 1368258 | 2005-08-24 | 2012-07-11 | Lapsed | Taiwan | Guard Ring for Improved Matching |
| 20030041375 | 803489 | 2003-06-25 | 2008-02-04 | Lapsed | Korea, Republic of (KR) | Capacitor For A Semiconductor Device And Method For Fabrication Therefor |
| 1020010018579 | 857727 | 2001-04-09 | 2008-09-03 | Lapsed | Korea, Republic of (KR) | Interconnections To Copper/Cs |
| 1019990056953 | 671722 | 1999-12-11 | 2007-01-15 | Lapsed | Korea, Republic of (KR) | Tungsten Silicide Nitride As An Electrode For Tantalum Pentoxide Devices |
| 19990039502 | 632613 | 1999-09-15 | 2006-09-28 | Lapsed | Korea, Republic of (KR) | Manufacture Of Mosfet Devices |
| 1019990017300 | 304031 | 1999-05-14 | 2001-07-18 | Lapsed | Korea, Republic of (KR) | Apparatus For Processing Silicon Device With Improved Temperature Control |
| 9834393 | 373819 | 1998-08-25 | 2003-02-13 | Lapsed | Korea, Republic of (KR) | THIN FILM CAPACITORS AND PROCESS FOR MAKING THEM |
| 9815164 | 0307339 | 1998-04-28 | 2001-08-20 | Lapsed | Korea, Republic of (KR) | Deuterated Dielectric And Polysilicon Film-Based Semiconductor Devices And Method Of Manufacture Thereof |
| 1019970060838 | 516245 | 1997-11-18 | 2005-09-06 | Lapsed | Korea, Republic of (KR) | Integrated Circuit Device With Inductor Incorporated Therein |
| 1020000021415 | 697963 | 2000-04-22 | 2007-03-15 | Lapsed | Korea, Republic of (KR) | A Method Of Forming A Multi-Layered Dual-Polysilicon Structure |
| 1020010040533 | 753788 | 2001-07-06 | 2007-08-24 | Lapsed | Korea, Republic of (KR) | Silicon-On-Insulator (SOI) Semiconductor Structure With Trench Including A Conductive Layer |
| 10676934 | 6838379 | 2003-09-30 | 2005-01-04 | Granted | United States of America | Process for reducing impurity levels, stress, and resistivity, and increasing grain size of copper filler in trenches and vias of integrated circuit structures to enhance electrical performance of copper filler |
| 20030031929 | 10-0977947 | 2003-05-20 | 2010-08-18 | Granted | Korea, Republic of (KR) | A Semiconductor Device Barrier Layer |
| 1020030067833 | 10-988446 | 2003-09-30 | 2010-10-12 | Lapsed | Korea, Republic of (KR) | Plate Capacitor Structure And Fabrication Method Therefor In A Dual Damascene Process |
| 20040076311 | 10-1099907 | 2004-09-23 | 2011-12-21 | Lapsed | Korea, Republic of (KR) | Metal-Oxide-Semiconductor Device Including A Buried Lightly-Doped Drain Region |
| 2003334485 | 5039267 | 2003-09-26 | 2012-07-13 | Lapsed | Japan | Plate Capacitor Structure And Fabrication Method Therefor In A Dual Damascene Process |
| 09580939 | 6527867 | 2000-05-30 | 2003-03-04 | Granted | United States of America | Method for enhancing anti-reflective coatings used in photolithography of electronic devices |

Schedule B(1)(a) – Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|---------------|------------------|------------|------------|-----------|--------------------------|---|
| 2000265144 | 3958506 | 2000-09-01 | 2007-05-18 | Lapsed | Japan | Semiconductor Device Having Regions Of Insulating Material Formed In A Semiconductor Substrate And Process Of Making The Device |
| 11024534 | 3084015 | 1999-02-02 | 2000-06-30 | Lapsed | Japan | Electronic Apparatus |
| 10275117 | 3386385 | 1998-09-29 | 2003-01-10 | Lapsed | Japan | Silicon IC Contacts Using Composite TiN Barrier Layer |
| 10140989 | 3464607 | 1998-05-22 | 2003-08-22 | Granted | Japan | Capacitor Comprising Improved Taox-Based Dielectric |
| 2000372411 | 4749537 | 2000-12-07 | 2011-05-27 | Lapsed | Japan | A Method Of Forming An Alignment Feature In Or On A Multi-Layered Semiconductor Structure |
| 11260600 | 3774088 | 1999-09-14 | 2006-02-24 | Lapsed | Japan | Manufacture Of Mosfet Devices |
| 09146787 | 3550272 | 1997-06-04 | 2004-04-30 | Lapsed | Japan | Method For Producing Tapered Lines |
| 10453118 | 6864141 | 2003-06-03 | 2005-03-08 | Granted | United States of America | Method of incorporating nitrogen into metal silicate based dielectrics by energized nitrogen ion beams |
| 10406847 | 7005217 | 2003-04-04 | 2006-02-28 | Lapsed | United States of America | Chromeless phase shift mask |
| 2004283352 | 4948756 | 2004-09-29 | 2012-03-16 | Lapsed | Japan | Inductor Formed In An Integrated Circuit |
| 10290437 | 6837967 | 2002-11-06 | 2005-01-04 | Granted | United States of America | Method and apparatus for cleaning deposited films from the edge of a water |
| 2003145567 | 4964400 | 2003-05-23 | 2012-04-06 | Lapsed | Japan | Abnormal Photoresist Line/Space Profile Detection Through Signal Processing of Metrology Waferform |
| 2004144248 | 4791706 | 2004-05-14 | 2011-07-29 | Lapsed | Japan | Split-Gate Metal-Oxide-Semiconductor Device |
| 2005277005 | | 2005-09-26 | | Abandoned | Japan | Thick Oxide Region In A Semiconductor Device |
| 2004333824 | 5378635 | 2004-11-18 | 2013-10-04 | Lapsed | Japan | Metal-Oxide-Semiconductor Device Formed In Silicon-On-Insulator |
| 09735084 | 6586814 | 2000-12-11 | 2003-07-01 | Lapsed | United States of America | Etch resistant shallow trench isolation in a semiconductor water |
| 2000120437 | 4038530 | 2000-04-21 | 2007-11-16 | Granted | Japan | A Method Of Forming A Multi-Layered Dual-Polysilicon Structure |
| 2000093711 | 3387888 | 2000-03-30 | 2003-01-10 | Lapsed | Japan | Lithographic Process For Device Fabrication Using Dark-Field Illumination |
| 2005266157 | 4944414 | 2005-09-14 | 2012-03-09 | Lapsed | Japan | Guard Ring for Improved Matching |
| 2005101096430 | ZL200510109643.0 | 2005-09-14 | 2012-05-30 | Lapsed | China | Guard Ring for Improved Matching |
| 200510078169X | ZL200510078169.X | 2005-06-17 | 2009-09-30 | Lapsed | China | Thick Oxide Region In A Semiconductor Device |
| 10153011 | | 2002-05-21 | | Abandoned | United States of America | Integrated Circuit Structure Having Low Dielectric Constant Material and Having Silicon Oxytrifide Caps Over Closely Spaced Apart Metal Lines |
| 09088801 | 6211517 | 1998-06-02 | 2001-04-03 | Granted | United States of America | Electron beam fault detection of semiconductor devices |
| 2004278820 | 5547361 | 2004-09-27 | 2014-05-23 | Lapsed | Japan | Metal-Oxide-Semiconductor Device Including A Buried Lightly-Doped Drain Region |
| 2001247517 | 5177924 | 2001-08-17 | 2013-01-18 | Lapsed | Japan | Process For Fabricating A Semiconductor Device Having A Metal Oxide Or A Metal Silicate GateDielectric Layer |
| 2002274695 | 5179693 | 2002-09-20 | 2013-01-18 | Lapsed | Japan | Multiple Operating Voltage Vertical Replacement-Gate (VRG) Transistor |

PATENT
REEL: 060885 FRAME: 0090

Schedule B(1)(a) – Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|------------|------------|------------|------------|---------|-------------------------------|---|
| 2001261004 | 5176050 | 2001-08-30 | 2013-01-18 | Lapsed | Japan | Field Plated Resistor With Enhanced Routing Area Thereover |
| 2006345124 | 5579358 | 2006-12-22 | 2014-07-18 | Lapsed | Japan | Robust Shallow Trench Isolation Structures And A Method For Forming Shallow Trench Isolation Structures |
| 2002270858 | 4797185 | 2002-09-18 | 2011-08-12 | Lapsed | Japan | Bipolar Junction Transistor Compatible With Vertical Replacement Gate Transistors |
| 09108092 | 6175124 | 1998-06-30 | 2001-01-16 | Granted | United States of America | Method and apparatus for a wafer level system |
| 10207607 | 6764749 | 2002-07-29 | 2004-07-20 | Granted | United States of America | Method to improve the resolution of a photolithography system by use of a coupling layer between the photo resist and the ARC |
| 10251082 | 7149340 | 2002-09-20 | 2006-12-12 | Granted | United States of America | Mask defect analysis for both horizontal and vertical processing effects |
| 10267810 | 6784102 | 2002-10-09 | 2004-08-31 | Granted | United States of America | Laterally Interconnecting structures |
| 09675109 | 6472715 | 2000-09-28 | 2002-10-29 | Granted | United States of America | Reduced soft error rate (SER) construction for integrated circuit structures |
| 10216425 | 6569739 | 2002-08-08 | 2003-05-27 | Granted | United States of America | Method of reducing the effect of implantation damage to shallow trench isolation regions during the formation of variable thickness gate layers |
| 10288410 | 6707132 | 2002-11-05 | 2004-03-16 | Granted | United States of America | High performance Si-Ge device module with CMOS technology |
| 003000536 | 60023573.4 | 2000-01-06 | 2005-11-02 | Granted | Germany (Federal Republic of) | Method For Making An Integrated Circuit Capacitor Including Tantalum Pentoxide |
| 973035785 | 69729913.9 | 1997-05-27 | 2004-07-21 | Expired | Germany (Federal Republic of) | Method For Producing Tapered Lines |
| 963069646 | 69607715.9 | 1996-09-25 | 2000-04-12 | Expired | Germany (Federal Republic of) | Compensation Of The Temperature Coefficient Of The Dielectric Constant Of Barium Strontium Titanate |
| 10135383 | 7174281 | 2002-05-01 | 2007-02-06 | Granted | United States of America | Method for analyzing manufacturing data |
| 10106128 | 6733829 | 2002-03-19 | 2004-05-11 | Granted | United States of America | Anti-binding deposition ring |
| 983095977 | 69842401.8 | 1998-11-24 | 2011-09-07 | Granted | Germany (Federal Republic of) | Method Of Manufacturing An Integrated Circuit Using Chemical Mechanical Polishing |
| 993036359 | 69944270.2 | 1999-05-10 | 2012-06-20 | Granted | Germany (Federal Republic of) | Apparatus For Processing Silicon Device With Improved Temperature Control |
| 013070594 | 60127777.5 | 2001-08-20 | 2007-04-11 | Lapsed | Germany (Federal Republic of) | Field Plated Resistor With Enhanced Routing Area Thereover |
| 993040732 | 69942327.9 | 1999-05-26 | 2010-05-05 | Granted | Germany (Federal Republic of) | Single Crystal Silicon On Polycrystalline Silicon Integrated Circuits |
| 003067238 | 60006751.3 | 2000-08-07 | 2003-11-26 | Lapsed | Germany (Federal Republic of) | Electrochemical Abatement Of Perfluorinated Compounds |
| 003095783 | 60030386.1 | 2000-10-30 | 2006-08-30 | Lapsed | Germany (Federal Republic of) | Method For Making Field Effect Devices And Capacitors With Thin Film Dielectrics And Resulting Devices |

Schedule B(1)(a) - Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|-----------|------------|------------|------------|---------|-------------------------------|---|
| 003049921 | 60020011.6 | 2000-06-13 | 2005-05-11 | Granted | Germany (Federal Republic of) | An Integrated Circuit Having A Micromagnetic Device And Method Of Manufacture Therefor |
| 003047974 | 60001600.5 | 2000-06-06 | 2003-03-12 | Granted | Germany (Federal Republic of) | Process For Fabricating Vertical Transistors |
| 993069186 | 69937217.8 | 1999-08-31 | 2007-10-03 | Lapsed | Germany (Federal Republic of) | Article Having Passive Self-Assembly Inductor |
| 983002049 | 69839597.2 | 1998-01-13 | 2008-06-11 | Granted | Germany (Federal Republic of) | Semiconductor Device |
| 983045238 | 69804380.4 | 1998-06-09 | 2002-03-27 | Granted | Germany (Federal Republic of) | MOS Image Sensor |
| 993055078 | 69900624.4 | 1999-07-12 | 2001-12-19 | Granted | Germany (Federal Republic of) | Apparatus and Method for Integrated Circuit With Variable Capacitor |
| 983079286 | 69823450.2 | 1998-09-29 | 2004-04-28 | Lapsed | Germany (Federal Republic of) | Article Comprising An Oxide Layer On Gan |
| 10242165 | 6842042 | 2002-09-11 | 2005-01-11 | Lapsed | United States of America | Global chip interconnect |
| 09792321 | 6458508 | 2001-02-23 | 2002-10-01 | Granted | United States of America | Method of protecting acid-catalyzed photoresist from chip-generated basic contaminants |
| 003105228 | 60039220.1 | 2000-11-27 | 2008-06-18 | Granted | Germany (Federal Republic of) | Article Comprising A Dielectric Material Of Zr-Ge-Ti-O Or Hf-Ge-Ti-O And Method Of Making The Same |
| 10036621 | 6935933 | 2001-12-21 | 2005-08-30 | Lapsed | United States of America | Viscous electropolishing system |
| 003023272 | 60030024.2 | 2000-03-22 | 2006-08-16 | Lapsed | Germany (Federal Republic of) | Lithographic Process For Device Fabrication Using Dark-Field Illumination |
| 003037868 | 60042468.5 | 2000-05-05 | 2009-07-01 | Granted | Germany (Federal Republic of) | Improved Wehnelt Gun For Electron Lithography |
| 10060002 | 6710851 | 2002-01-29 | 2004-03-23 | Granted | United States of America | Multi pattern reticle |
| 10067299 | 6621134 | 2002-02-07 | 2003-09-16 | Granted | United States of America | Vacuum sealed RF/microwave microresonator |
| 09213948 | 6528389 | 1998-12-17 | 2003-03-04 | Granted | United States of America | Substrate planarization with a chemical mechanical polishing stop layer |
| 09964157 | 6621146 | 2001-09-26 | 2003-09-16 | Granted | United States of America | Method and apparatus for the use of embedded resistance to linearize and improve the matching properties of transistors |
| 09209855 | 6303899 | 1998-12-11 | 2001-10-16 | Granted | United States of America | Method and apparatus for scribing a code in an inactive outer clear out area of a semiconductor wafer |
| 09974251 | 6513376 | 2001-10-10 | 2003-02-04 | Lapsed | United States of America | Liquid level height measurement system |
| 09994083 | 6549062 | 2001-11-21 | 2003-04-15 | Granted | United States of America | Method and apparatus for improving the tolerance of integrated resistors |
| 09974008 | 6658361 | 2001-10-10 | 2003-12-02 | Lapsed | United States of America | Heaviest only fail potential |
| 10615558 | 6989331 | 2003-07-08 | 2006-01-24 | Granted | United States of America | Hard mask removal |

PATENT
REEL: 060885 FRAME: 0092

Schedule B(1)(a) - Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|------------|----------|------------|------------|---------|--------------------------|---|
| 10002981 | 6613665 | 2001-10-26 | 2003-09-02 | Granted | United States of America | Process for forming integrated circuit structure comprising layer of low k dielectric material having antireflective properties in an upper surface |
| 10002831 | 6528423 | 2001-10-26 | 2003-03-04 | Granted | United States of America | Process for forming composite of barrier layers of dielectric material to inhibit migration of copper from copper metal interconnect of integrated circuit structure into adjacent layer of low k dielectric material |
| 10061519 | 6752916 | 2002-02-01 | 2004-06-22 | Granted | United States of America | Electrochemical planarization end point detection |
| 08563688 | 6043139 | 1995-11-28 | 2000-03-28 | Expired | United States of America | Process For Controlling Dopant Diffusion in a Semiconductor Layer and Semiconductor Layer |
| 09950008 | 6664633 | 2001-09-10 | 2003-12-16 | Lapsed | United States of America | Alkaline copper plating |
| 10603041 | 7160799 | 2003-06-24 | 2007-01-09 | Granted | United States of America | Define Via In Dual Damascene Process |
| 2007206087 | 5121348 | 2007-08-08 | 2012-11-02 | Granted | Japan | Local Area Alloying For Preventing Dishing Of Copper During Chemical Mechanical Polishing (CMP) |
| 2007034850 | 5236884 | 2007-02-15 | 2013-04-05 | Lapsed | Japan | Low K Dielectric Insulator and Method of Forming Semiconductor Circuit Structures |
| 2007060148 | 4880501 | 1999-09-09 | 2011-12-09 | Lapsed | Japan | Article Having Passive Self-Assembly Inductor |
| 10435561 | 6852648 | 2003-05-09 | 2005-02-08 | Lapsed | United States of America | Semiconductor Device Having A Low Dielectric Constant Dielectric Material And Process For Its Manufacture |
| 09370963 | 6228748 | 1999-08-10 | 2001-05-08 | Expired | United States of America | Use Of A Getter Layer To Improve Metal-To-Metal Contact Resistance At Low Radio Frequency Power |
| 09291781 | 6317948 | 1999-04-14 | 2001-11-20 | Expired | United States of America | Embedded Thin Film Passive Components |
| 09333626 | 6264749 | 1999-06-15 | 2001-07-24 | Expired | United States of America | Process For Making Composite Films |
| 08566445 | 5688634 | 1995-12-01 | 1997-11-18 | Expired | United States of America | Energy Sensitive Resist Material And Process For Device Fabrication Using The Resist Material |
| 08716829 | 5693977 | 1996-09-05 | 1997-12-02 | Expired | United States of America | N-Channel Field-Effect (sic) Transistor Including A Thin-Film Fullerene |
| 09398977 | 6143658 | 1999-09-17 | 2000-11-07 | Granted | United States of America | Multilevel Wiring Structure and Method of Fabricating a Multilevel Wiring Structure |
| 08478133 | 5710055 | 1995-06-07 | 1998-01-20 | Expired | United States of America | Method Of Making PMOSFETs Having Indium Or Gallium Doped Buried Channels And N(p)Polysilicon Gates And CMOS Devices Fabricated Therefrom |
| 2001111006 | 5010782 | 2000-12-07 | 2012-06-08 | Lapsed | Japan | A Method Of Forming An Alignment Feature In Or On A Multi-Layered Semiconductor Structure |
| 2007108964 | 5247059 | 2000-01-12 | 2013-04-19 | Lapsed | Japan | Method For Making An Integrated Circuit Capacitor Including Tantalum Pentoxide |
| 08767153 | 5923524 | 1996-12-16 | 1999-07-13 | Expired | United States of America | Dielectric Material Comprising Ta sub 2 O sub 5 Doped With TiO sub 2 And Devices Employing Same |

Schedule B(1)(a) - Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|---------------|------------|------------|------------|-----------|-------------------------------|---|
| 200756483 | | 2007-03-07 | | Abandoned | Japan | An Integrated Circuit Including ESD Circuits For A Multi-Chip Module And A Method Therefor |
| 08746184 | 5976637 | 1996-11-06 | 1999-11-02 | Expired | United States of America | Method For Coating Heterogeneous Substrates With Homogeneous Layers |
| 2005060155 | 4276194 | 1998-06-19 | 2009-03-13 | Lapsed | Japan | MOS Image Sensor |
| 08931066 | 5804460 | 1997-09-15 | 1998-09-08 | Expired | United States of America | Linewidth Metrology Of Integrated Circuit And Structures |
| 08853210 | 5918116 | 1997-05-09 | 1999-06-29 | Expired | United States of America | Process For Forming Different Gate Oxides Possessing Different Thicknesses On A Semiconductor Substrate |
| 07866942 | 5679589 | 1992-04-03 | 1997-10-21 | Expired | United States of America | FET With Gate Spacer |
| 08156953 | 5982034 | 1993-11-19 | 1999-11-09 | Expired | United States of America | Conductive Oxide Films |
| 07719699 | 5744403 | 1991-06-25 | 1998-04-28 | Expired | United States of America | Dielectric Film Deposition Method And Apparatus |
| 09404702 | 6239035 | 1999-09-23 | 2001-05-29 | Expired | United States of America | Semiconductor Wafer Fabrication |
| 08697402 | 5728421 | 1996-08-23 | 1998-03-17 | Expired | United States of America | Article Comprising Spinel-Structure Material On A Substrate, And Method Of Making The Article |
| 08857079 | 5798300 | 1997-05-15 | 1998-08-25 | Expired | United States of America | Method For Forming Conductors In Integrated Circuits |
| 08610646 | 5620907 | 1996-03-04 | 1997-04-15 | Expired | United States of America | Method For Making A Heterojunction Bipolar Transistor |
| 1019980041563 | 364338 | 1998-10-02 | 2002-11-28 | Granted | Korea, Republic of (KR) | Energy-Sensitive Resist Material And A Process For Device Fabrication Using An Energy-Sensitive Resist Material |
| 983015629 | 69800033.1 | 1998-03-03 | 1999-10-27 | Lapsed | Germany (Federal Republic of) | Energy-Sensitive Resist Material And A Process For Device Fabrication Using An Energy-Sensitive Resist Material |
| 08961383 | 6106371 | 1997-10-30 | 2000-08-22 | Expired | United States of America | Effective pad conditioning |
| 08610026 | 5834800 | 1996-03-04 | 1998-11-10 | Expired | United States of America | A Heterojunction Bipolar Transistor Having Monocrystalline SiGe Intrinsic Base And Polycrystalline SiGe and Si Extrinsic Base Regions |
| 09543412 | 6346490 | 2000-04-05 | 2002-02-12 | Granted | United States of America | Process for treating damaged surfaces of low k carbon doped silicon oxide dielectric material after plasma etching and plasma cleaning steps |
| 09395062 | 6288453 | 1999-09-13 | 2001-09-11 | Granted | United States of America | Alignment of openings in semiconductor fabrication |
| 09553140 | 7751609 | 2000-04-20 | 2010-07-06 | Lapsed | United States of America | A Method of Performing Oxide End-Point During CMP |
| 1019980007413 | 588369 | 1998-03-06 | 2006-06-02 | Lapsed | Korea, Republic of (KR) | Energy-Sensitive Resist Material And A Process For Device Fabrication Using An Energy-Sensitive Resist Material |
| 10280394 | 3481469 | 1998-10-02 | 2003-10-10 | Granted | Japan | Energy-Sensitive Resist Material And A Process For Device Fabrication Using An Energy-Sensitive Resist Material |
| 09521312 | 6413881 | 2000-03-09 | 2002-07-02 | Granted | United States of America | Process for forming thin gate oxide with enhanced reliability by nitridation of upper surface of gate of oxide to form barrier of nitrogen atoms in upper surface region of gate oxide, and resulting product |
| 09706286 | 6544807 | 2000-11-03 | 2003-04-08 | Granted | United States of America | Process monitor with statistically selected ring oscillator |
| 10158641 | 6864563 | 2002-05-30 | 2005-03-08 | Lapsed | United States of America | Grounding mechanism for semiconductor devices |

PATENT
REEL: 060885 FRAME: 0094

Schedule B(1)(a) – Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|------------|------------|------------|------------|---------|-------------------------------|---|
| 09574804 | 6426286 | 2000-05-19 | 2002-07-30 | Granted | United States of America | Interconnection system with lateral barrier layer |
| 09639440 | 6782500 | 2000-08-15 | 2004-08-24 | Granted | United States of America | Statistical decision system |
| 08770046 | 6180470 | 1996-12-19 | 2001-01-30 | Expired | United States of America | FETs having lightly doped drain regions that are shaped with counter and noncounter dorant elements |
| 09438642 | 6147012 | 1999-11-12 | 2000-11-14 | Granted | United States of America | Process for forming low k silicon oxide dielectric material while suppressing pressure spiking and inhibiting increase in dielectric constant |
| 08787992 | 6010952 | 1997-01-23 | 2000-01-04 | Expired | United States of America | Process for forming metal silicide contacts using amorphization of exposed silicon while minimizing device degradation |
| 09005364 | 6531397 | 1998-01-09 | 2003-03-11 | Granted | United States of America | Method and apparatus for using across wafer back pressure differentials to influence the performance of chemical mechanical polishing |
| 09487984 | 6448084 | 2000-01-20 | 2002-09-10 | Granted | United States of America | Multiple metal etchant system for integrated circuits |
| 1998542006 | 4386468 | 1998-04-02 | 2009-10-09 | Granted | Japan | Process for Fabricating a Moderate-Depth Diffused Emitter Bipolar Transistor In a BICMOS Device Without Using an Additional Mask |
| 09607177 | 6464566 | 2000-06-29 | 2002-10-15 | Granted | United States of America | Apparatus and method for linearly planarizing a surface of a semiconductor wafer |
| 10033164 | 6511925 | 2001-10-19 | 2003-01-28 | Granted | United States of America | Process for forming high dielectric constant gate dielectric for integrated circuit structure |
| 1999351216 | 4657412 | 1999-12-10 | 2011-01-07 | Lapsed | Japan | Slurry Collecting Device for CMP Slurry Circulation |
| 199207577 | 19920757.7 | 1999-05-05 | 2008-05-15 | Granted | Germany (Federal Republic of) | Non-linear Circuit Elements on Integrated Circuits |
| 09347487 | 6281092 | 1999-07-02 | 2001-08-28 | Granted | United States of America | Method for manufacturing a metal-to-metal capacitor utilizing only one masking step |
| 87114682 | 142684 | 1998-09-04 | 2002-02-08 | Lapsed | Taiwan | Standardized Gas Isolation Box (GIB) Installation |
| 09216394 | 6235590 | 1998-12-18 | 2001-05-22 | Granted | United States of America | Fabrication of differential gate oxide thicknesses on a single integrated circuit chip |
| 09211922 | 6090724 | 1998-12-15 | 2000-07-18 | Granted | United States of America | Method for composing a thermally conductive thin film having a low dielectric property |
| 87115810 | 120367 | 1998-09-23 | 2001-02-01 | Lapsed | Taiwan | A Method and Apparatus for Chemical Mechanical Polishing |
| 09108091 | 6268224 | 1998-06-30 | 2001-07-31 | Granted | United States of America | Method and apparatus for detecting an ion-implanted polishing endpoint layer within a semiconductor wafer |
| 86119036 | 120428 | 1997-12-17 | 2001-02-05 | Lapsed | Taiwan | Simple BICMOS Process for Creation of Low Trigger Voltage SCR and Zener Diode Pad Protection |
| 86118838 | 112608 | 1997-12-13 | 2000-07-04 | Lapsed | Taiwan | Variable Step Height Control of Lithographic Patterning Through Transmitted Light Intensity Variation |
| 979156007 | 69706043.8 | 1997-03-26 | 2001-08-08 | Expired | Germany (Federal Republic of) | Method and Apparatus for Protecting Functions Imbedded Within an Integrated Circuit from Reverse Engineering |

Schedule B(1)(a) – Semic Processing A

| AppNo | PatentNo | FileDate | GrantDate | Status | Country | Title |
|----------|-----------|------------|------------|---------|--------------------------|--|
| 09204767 | 6174407 | 1998-12-03 | 2001-01-16 | Granted | United States of America | Apparatus and method for detecting an endpoint of an etching process by transmitting infrared light signals through a semiconductor wafer |
| 09111529 | 6285035 | 1998-07-08 | 2001-09-04 | Granted | United States of America | Apparatus for detecting an endpoint polishing layer of a semiconductor wafer having a wafer carrier with independent concentric sub-carriers and associated method |
| 09082810 | 6206573 | 1998-05-21 | 2001-03-27 | Granted | United States of America | High reliability bearing structure |
| 86105907 | NI-094528 | 1997-05-03 | 1998-09-10 | Lapsed | Taiwan | Method and Apparatus for Protecting Functions Imbedded Within an Integrated Circuit from Reverse Engineering |
| 87104961 | 118316 | 1998-04-02 | 2000-12-05 | Lapsed | Taiwan | Process for Fabricating a Moderate-Depth Diffused Emitter Bipolar Transistor In a BICMOS Device Without Using an Additional Mask |
| 09212931 | 6277707 | 1998-12-16 | 2001-08-21 | Granted | United States of America | Method of manufacturing semiconductor device having a recessed gate structure |
| 09942220 | 6898064 | 2001-08-29 | 2005-05-24 | Lapsed | United States of America | System and method for optimizing the electrostatic removal of a workpiece from a chuck |
| 09107342 | 6241847 | 1998-06-30 | 2001-06-05 | Granted | United States of America | Method and apparatus for detecting a polishing endpoint based upon infrared signals |
| 09131921 | 6080670 | 1998-08-10 | 2000-06-27 | Granted | United States of America | Method of detecting a polishing endpoint layer of a semiconductor wafer which includes a non-reactive reporting specie |
| 08580674 | 5645736 | 1995-12-29 | 1997-07-08 | Expired | United States of America | Method for polishing a wafer |
| 08767698 | 5976309 | 1996-12-17 | 1999-11-02 | Expired | United States of America | Electrode assembly for plasma reactor |
| 09046242 | 6071817 | 1998-03-23 | 2000-06-06 | Granted | United States of America | Isolation method utilizing a high pressure oxidation |
| 08763373 | 5821013 | 1996-12-13 | 1998-10-13 | Expired | United States of America | Variable step height control of lithographic patterning through transmitted light intensity variation |
| 08773471 | 5963828 | 1996-12-23 | 1999-10-05 | Expired | United States of America | Method for tungsten nucleation from Wf6 using titanium as a reducing agent |
| 09075029 | 6093585 | 1998-05-08 | 2000-07-25 | Granted | United States of America | High voltage tolerant thin film transistor |
| 12344016 | 7898277 | 2008-12-24 | 2011-03-01 | Granted | United States of America | Hot-Electron Injection Testing Of Transistors On A Wafer |
| 11469032 | 7479438 | 2006-08-31 | 2009-01-20 | Granted | United States of America | Method to Improve Performance Of A Bipolar Device Using An Amorphizing Implant |
| 10953480 | 7197723 | 2004-09-29 | 2007-03-27 | Granted | United States of America | Semiconductor Device Manufacturing |
| 10878857 | 7148540 | 2004-06-28 | 2006-12-12 | Granted | United States of America | Graded Conductive Structure For Use In A Metal\\(miOxide\\(miSemiconductor Device |
| 10300365 | 6825538 | 2002-11-20 | 2004-11-30 | Granted | United States of America | Semiconductor Device Using An Insulating Layer Having A Seed Layer |
| 10007417 | 6683465 | 2001-10-31 | 2004-01-27 | Granted | United States of America | Integrated Circuit Having Stress Migration Test Structure And Method Therefor |
| 10007904 | 6747445 | 2001-10-31 | 2004-06-08 | Granted | United States of America | Stress Migration Test Structure And Method Therefor |

Schedule B(1)(a) – Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------|----------|------------|------------|---------|--------------------------|--|
| 09865124 | 6541819 | 2001-05-24 | 2003-04-01 | Granted | United States of America | Semiconductor Device Having Non\miPower Enhanced And Power Enhanced Metal Oxide Semiconductor And Method Of Manufacture Therefor |
| 09935241 | 6548906 | 2001-08-22 | 2003-04-15 | Granted | United States of America | Method For Reducing A Metal Seam In An Interconnect Structure And A Device Manufactured Thereby |
| 09964041 | 6737311 | 2001-09-26 | 2004-05-18 | Granted | United States of America | Semiconductor Device Having A Buried Layer For Reducing Latchup And A Method Of Manufacture Therefor |
| 09731402 | 6896583 | 2001-02-06 | 2005-05-24 | Lapsed | United States of America | Method And Apparatus For Conditioning A Polishing Pad |
| 0963531 | 6630699 | 2000-08-31 | 2003-10-07 | Granted | United States of America | Transistor Device Having An Isolation Structure Located Under A Source Region, Drain Region And Channel Region And A Method Of Manufacture Thereof |
| 09653364 | 6569690 | 2000-08-31 | 2003-05-27 | Granted | United States of America | Monitoring System For Determining Progress In A Fabrication Activity |
| 09648015 | 6367329 | 2000-08-25 | 2002-04-09 | Granted | United States of America | Acoustic Time Of Flight And Acoustic Resonance Methods For Detecting Endpoint In Plasma Processes |
| 09640329 | 6362094 | 2000-08-16 | 2002-03-26 | Granted | United States of America | Hydrogenated Silicon Carbide As A Liner For Self-Aligning Contact Vias |
| 09737717 | 6551410 | 2000-12-15 | 2003-04-22 | Granted | United States of America | Method Of Cleaning A Semiconductor Wafer With A Cleaning Brush Assembly Having A Contractible An Expandable Arbor |
| 09611581 | 6435946 | 2000-07-07 | 2002-08-20 | Granted | United States of America | Technique For Reducing Silvers On Optical Components Resulting From Friction Processes |
| 09397716 | 6251546 | 1999-09-16 | 2001-06-26 | Granted | United States of America | An Improved Method Of Fabricating Devices Using An Attenuated Phase-Shifting Mask And An Attenuated Phase-Shifting Mask |
| 09520670 | 6611729 | 2000-03-07 | 2003-08-26 | Granted | United States of America | System And Method For Introducing Multiple Component-Type Factors Into An Integrated Circuit Yield Prediction |
| 09603340 | 6372605 | 2000-06-26 | 2002-04-16 | Granted | United States of America | Additional Etching To Decrease Polishing Time for Shallow-Trench Isolation In Semiconductor Processing |
| 09459708 | 6537135 | 1999-12-13 | 2003-03-25 | Granted | United States of America | Curvilinear Chemical Mechanical Planarization Device And Method |
| 09482390 | 6401929 | 2000-01-12 | 2002-06-11 | Granted | United States of America | Insert For Use In Transporting A Wafer Carrier |
| 09430635 | 6136615 | 1999-10-29 | 2000-10-24 | Granted | United States of America | Migration From Control Wafer To Product Wafer Particle Checks |
| 09376696 | 6206770 | 1999-08-18 | 2001-03-27 | Granted | United States of America | Wafer Carrier Head For Prevention Of Unintentional Semiconductor Wafer Rotation |
| 09399621 | 6281129 | 1999-09-20 | 2001-08-28 | Granted | United States of America | Corrosion-Resistant Polishing Pad Conditioner |
| 09338520 | 6815876 | 1999-06-23 | 2004-11-09 | Lapsed | United States of America | Cathode With Improved Work Function And Method Of Making Same |
| 10963156 | 7179148 | 2004-10-12 | 2007-02-20 | Granted | United States of America | Cathode With Improved Work Function And Method For Making The Same |

Schedule B(1)(a) - Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|-------------|------------|------------|------------|-----------|-------------------------------|--|
| 2000188555 | 3901915 | 2000-06-23 | 2007-01-12 | Lapsed | Japan | Cathode With Improved Work Function And Method Of Making Same |
| 89111997 | NI-141143 | 2000-05-19 | 2001-09-11 | Lapsed | Taiwan | Cathode With Improved Work Function And Method Of Making Same |
| 003050150 | 60044167.9 | 2000-06-13 | 2010-04-14 | Granted | Germany (Federal Republic of) | Cathode With Improved Work Function And Method Of Making Same |
| 20000034530 | 744896 | 2000-06-22 | 2007-07-25 | Lapsed | Korea, Republic of (KR) | Cathode With Improved Work Function And Method Of Making Same |
| 003050150 | 1063669 | 2000-06-13 | 2010-04-14 | Lapsed | France | Cathode With Improved Work Function And Method Of Making Same |
| 003050150 | 1063669 | 2000-06-13 | 2010-04-14 | Lapsed | United Kingdom | Cathode With Improved Work Function And Method Of Making Same |
| 09477310 | 6559499 | 2000-01-04 | 2003-05-06 | Granted | United States of America | Process For Fabricating An Integrated Circuit Device Having Capacitors With A Multilevel Metallization |
| 09347313 | 6258610 | 1999-07-02 | 2001-07-10 | Granted | United States of America | Method Analyzing A Semiconductor Surface Using Line Width Metrology With Auto-Correlation Operation |
| 09346754 | | 1999-07-02 | | Abandoned | United States of America | Method For Manufacturing Semiconductor Integrated Circuits With Etch Process Modification |
| 09232120 | 6162733 | 1999-01-15 | 2000-12-19 | Granted | United States of America | Method For Removing Contaminants From Integrated Circuits |
| 09222587 | 6359317 | 1998-12-28 | 2002-03-19 | Granted | United States of America | Vertical PNP Bipolar Transistor And Its Method Of Fabrication |
| 09024601 | 6384446 | 1998-02-17 | 2002-05-07 | Expired | United States of America | Integrated Circuit Fabrication |
| | | | | | | Dielectric Materials Of Amorphous Compositions of Ti\mi 02 Doped With Rare Earth |
| 09090295 | 6093944 | 1998-06-04 | 2000-07-25 | Granted | United States of America | Elements And Devices Employing Same |
| 09058826 | 6091279 | 1998-04-13 | 2000-07-18 | Granted | United States of America | Temperature Compensation of LDMOS Devices |
| 09017103 | 6222863 | 1998-01-31 | 2001-04-24 | Granted | United States of America | Article Comprising A Stable, Low-Resistance Ohmic Contact |
| 09105712 | 6075909 | 1998-06-26 | 2000-06-13 | Granted | United States of America | Optical Monitoring System For III\mIV Wafer Processing |
| 08924728 | 6013556 | 1997-09-05 | 2000-01-11 | Expired | United States of America | Method Of Integrated Circuit Fabrication |
| 08727726 | 5779929 | 1996-10-07 | 1998-07-14 | Expired | United States of America | Thin Film Metallization For Barium Nanotitanate Substrates |
| 08674956 | 5683917 | 1996-07-03 | 1997-11-04 | Expired | United States of America | Method Of Making A Low Noise Semiconductor Device Comprising A Screening Measurement |
| 08572599 | 585280 | 1995-12-14 | 1999-01-05 | Expired | United States of America | Cassette Light |
| 08509678 | 5620253 | 1995-07-31 | 1997-04-15 | Expired | United States of America | Method Of Determining The Thermal Conductivity Of Electrically Insulating Crystalline Materials |
| 08561473 | 5670396 | 1995-11-21 | 1997-09-23 | Expired | United States of America | Method Of Forming A DMOS-Controlled Lateral Bipolar Transistor |
| 08412678 | 5588969 | 1995-03-29 | 1996-12-31 | Expired | United States of America | Method for Supplying Phosphorous Vapor |
| 08497470 | 5712176 | 1995-06-30 | 1998-01-27 | Expired | United States of America | Doping Of Silicon Layers |

Schedule B(1)(a) - Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|---------------|------------------|------------|------------|-------------|--------------------------|---|
| 08278688 | 6197375 | 1994-07-21 | 2001-03-06 | Granted | United States of America | Method Comprising Removal Of Material From A Diamond Film |
| 08774036 | 5976943 | 1996-12-27 | 1999-11-02 | Expired | United States of America | Method for Bi-Layer Programmable Resistor |
| 08883403 | 5854510 | 1997-06-26 | 1998-12-29 | Expired | United States of America | Low Power Programmable Fuse Structures |
| 09055018 | 5882998 | 1998-04-03 | 1999-03-16 | Expired | United States of America | Low power programmable fuse structures and methods for making the same |
| 97342851 | 3973744 | 1997-12-12 | 2007-06-22 | Lapsed | Japan | Two-Layer Type Programmable Resistor |
| 099113363 | 1424152 | 2010-04-27 | 2014-01-21 | Granted | Taiwan | An Electronic Pressure-Sensing Device |
| 2010109863 | 5885909 | 2010-05-12 | 2016-02-19 | Granted | Japan | An Electronic Pressure-Sensing Device |
| 12465309 | 8037771 | 2009-05-13 | 2011-10-18 | Granted | United States of America | Electronic Pressure-Sensing Device |
| 1020100042858 | 101512527 | 2010-05-07 | 2015-04-09 | Lapsed | Korea, Republic of (KR) | An Electronic Pressure-Sensing Device |
| 101627768 | | 2010-05-13 | | Application | European Patent | An Electronic Pressure-Sensing Device |
| 2010101787444 | ZL201010178744.4 | 2010-05-12 | 2014-07-02 | Lapsed | China | An Electronic Pressure-Sensing Device |
| 12290054 | 7972873 | 2008-10-27 | 2011-07-05 | Granted | United States of America | Material Removing Processes In Device Formation And The Devices Formed Thereby |
| 12112076 | 7977721 | 2008-04-30 | 2011-07-12 | Granted | United States of America | High Voltage Tolerant Metal-Oxide-Semiconductor Device |
| 13149122 | 8105912 | 2011-05-31 | 2012-01-31 | Granted | United States of America | High Voltage Tolerant Metal-Oxide-Semiconductor Device |
| 09741667 | 6518619 | 2000-12-19 | 2003-02-11 | Granted | United States of America | Virtual-Ground, Split Gate Flash Memory Cell Arrangements and Method For Producing Same |
| 11609509 | 7607112 | 2006-12-12 | 2009-10-20 | Granted | United States of America | Method And Apparatus For Performing Metallization In An Integrated Circuit Process |
| 100121509 | 1402965 | 2011-06-20 | 2013-07-21 | Lapsed | Taiwan | Defectivity-Immune Technique of Implementing MIM-based Decoupling Capacitors |
| 2011101979218 | ZL2011101979218 | 2011-07-15 | 2015-04-08 | Lapsed | China | Defectivity-Immune Technique of Implementing MIM-based Decoupling Capacitors |
| 2011157508 | 5566346 | 2011-07-19 | 2014-06-27 | Lapsed | Japan | Defectivity-Immune Technique of Implementing MIM-based Decoupling Capacitors |
| 12839148 | 8411399 | 2010-07-19 | 2013-04-02 | Granted | United States of America | Defectivity-Immune Technique of Implementing MIM-based Decoupling Capacitors |
| 1020110069793 | 10-1395584 | 2011-07-14 | 2014-05-09 | Lapsed | Korea, Republic of (KR) | Defectivity-Immune Technique of Implementing MIM-based Decoupling Capacitors |
| 111745519 | | 2011-07-19 | | Abandoned | European Patent | Defectivity-Immune Technique of Implementing MIM-based Decoupling Capacitors |
| 12546855 | 8318606 | 2009-08-25 | 2012-11-27 | Lapsed | United States of America | Dielectric Etching |
| 11332103 | 7712066 | 2005-12-29 | 2010-05-04 | Lapsed | United States of America | Area-Efficient Power Switching Cell |
| 2006255124 | 5275558 | 2006-09-21 | 2013-05-24 | Granted | Japan | Controlling Overspray Coating In Semiconductor Devices |
| 1020060091668 | 10-1356667 | 2006-09-21 | 2014-01-22 | Granted | Korea, Republic of (KR) | Controlling Overspray Coating In Semiconductor Devices |
| 11832711 | 7772085 | 2007-08-02 | 2010-08-10 | Lapsed | United States of America | Controlling Overspray Coating In Semiconductor Devices |
| 06175889 | 2431042 | 2006-09-07 | 2011-07-27 | Lapsed | United Kingdom | Controlling Overspray Coating In Semiconductor Devices |

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Schedule B(1)(a) - Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|-----------|----------|------------|------------|-----------|--------------------------|--|
| 095134838 | 1437785 | 2006-09-20 | 2014-05-11 | Granted | Taiwan | Controlling Overspray Coating In Semiconductor Devices |
| 11232074 | 7269197 | 2005-09-21 | 2007-09-11 | Granted | United States of America | Controlling Overspray Coating In Semiconductor Devices |
| 12680017 | | 2010-03-25 | 2013-02-05 | Abandoned | United States of America | Method To Reduce Trench Capacitor Leakage For Random Access Memory Device |
| 11094975 | 7329605 | 2005-03-31 | 2008-02-12 | Granted | United States of America | Semiconductor Structure Formed Using A Sacrificial Structure |
| 11927978 | 7741702 | 2007-10-30 | 2010-05-22 | Granted | United States of America | Semiconductor Structure Formed Using A Sacrificial Structure |
| 11068237 | 7247556 | 2005-02-28 | 2007-07-24 | Granted | United States of America | Control Of Wafer Warpage During Backend Processing |
| 11124307 | 7399648 | 2005-05-06 | 2008-07-15 | Granted | United States of America | Methods And Apparatus For Determining Location-Based On-Chip Variation Factor |
| 11673645 | 7557010 | 2007-02-12 | 2009-07-07 | Granted | United States of America | Method To Improve Writer Leakage In A Stige Bipolar Device |
| 12476994 | 7898038 | 2009-06-02 | 2011-03-01 | Granted | United States of America | Method To Improve Writer Leakage In Stige Bipolar Device |
| 10902332 | 7115157 | 2004-07-29 | 2006-09-26 | Lapsed | United States of America | Apparatus And Method For In-Situ Measuring Of Vibrational Energy In A Process Bath Of A Vibrational Cleaning System |
| 10773614 | 7214568 | 2004-02-06 | 2007-05-08 | Granted | United States of America | Semiconductor Device Configured For Reducing Post-Fabrication Damage |
| 10778454 | 7005724 | 2004-02-13 | 2006-02-28 | Lapsed | United States of America | A Semiconductor Device And A Method Of Manufacture Therefor |
| 11167772 | 7811944 | 2005-06-27 | 2010-10-12 | Lapsed | United States of America | A Semiconductor Device And A Method Of Manufacture Therefor |
| 10675581 | 6906538 | 2003-09-30 | 2005-06-14 | Granted | United States of America | Alternating Pulse Dual\Imibeam Apparatus, Methods And Systems For Voltage Contrast Behavior Assessment Of Microcircuits |
| 10919591 | 7339274 | 2004-08-17 | 2008-03-04 | Granted | United States of America | Metallization Performance In Electronic Devices |
| 10695193 | 6975040 | 2003-10-28 | 2005-12-13 | Lapsed | United States of America | Fabricating Semiconductor Chips |
| 10999704 | 7262476 | 2004-11-30 | 2007-08-28 | Granted | United States of America | Semiconductor Device Having Improved Power Density |
| 10981175 | 7573097 | 2004-11-03 | 2009-08-11 | Lapsed | United States of America | Lateral Double Diffused MOS Transistors |
| 10200233 | 6838213 | 2002-07-23 | 2005-01-04 | Granted | United States of America | Process For Fabricating A Mask |
| 09882624 | 6958518 | 2001-06-15 | 2005-10-25 | Lapsed | United States of America | A Semiconductor Device Having At Least One Source\Is Drain Region Formed On An Isolation Region And A Method Of Manufacture Therefor |
| 09943630 | 6648734 | 2001-08-30 | 2003-11-18 | Granted | United States of America | Polishing Head For Pressurized Delivery Of Slurry |
| 10008015 | 6703712 | 2001-11-13 | 2004-03-09 | Granted | United States of America | Microelectronic Device Layer Deposited With Multiple Electrolytes |
| 09839316 | 6433628 | 2001-05-17 | 2002-08-13 | Granted | United States of America | Wafer Testable Integrated Circuit |
| 09882623 | 6569744 | 2001-06-15 | 2003-05-27 | Granted | United States of America | Method Of Converting A Metal Oxide Semiconductor Transistor Into A Bipolar Transistor |
| 09927752 | 6503793 | 2001-08-10 | 2003-01-07 | Granted | United States of America | Method For Concurrently Forming An ESD Protection Device And A Shallow Trench Isolation Region |
| 10180221 | 6825467 | 2002-06-25 | 2004-11-30 | Granted | United States of America | Apparatus For Scanning A Crystalline Sample And Associated Methods |
| 10274765 | 6723581 | 2002-10-21 | 2004-04-20 | Granted | United States of America | Semiconductor Device Having A High-K Gate Dielectric And Method Of Manufacture Thereof |

Schedule B(1)(a) - Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|-----------|-----------|------------|------------|---------|--------------------------|--|
| 10120767 | 6783426 | 2002-04-10 | 2004-08-31 | Granted | United States of America | Method And Apparatus For Detection Of Chemical Mechanical Planarization Endpoint And Device Planarity |
| 09771621 | 6440816 | 2001-01-30 | 2002-08-27 | Granted | United States of America | Alignment Mark Fabrication Process To Limit Accumulation Of Errors In Level To Level Overlay |
| 10140616 | 6828649 | 2002-05-07 | 2004-12-07 | Lapsed | United States of America | Semiconductor Device Having An Interconnect That Electrically Connects A Conductive Material And A Doped Layer, And A Method Of Manufacture Therefor |
| 10047516 | 6576563 | 2001-10-26 | 2003-06-10 | Granted | United States of America | Method Of Manufacturing A Semiconductor Device Employing A Fluorine-Based Etch Substantially Free Of Hydrogen |
| 09713106 | 6639285 | 2000-11-15 | 2003-10-28 | Granted | United States of America | A Semiconductor Device |
| 09606833 | 6319837 | 2000-06-29 | 2001-11-20 | Granted | United States of America | Technique For Reducing Dishing In Cu-Based Interconnects |
| 09954341 | 6659846 | 2001-09-17 | 2003-12-09 | Granted | United States of America | Pad For Chemical Mechanical Polishing |
| 09882961 | 6602758 | 2001-06-15 | 2003-08-05 | Granted | United States of America | Formation Of Silicon On Insulator (SOI) Devices As An Add On Module For System On A Chip (SOC) Processing |
| 02138634 | 2381378 | 2002-06-17 | 2006-01-25 | Lapsed | United Kingdom | Formation Of Silicon On Insulator (SOI) Devices As An Add On Module For System On A Chip (SOC) Processing |
| 091113153 | NI-183665 | 2002-06-17 | 2003-08-11 | Lapsed | Taiwan | Formation Of Silicon On Insulator (SOI) Devices As An Add On Module For System On A Chip (SOC) Processing |
| 09632445 | 6436829 | 2000-08-04 | 2002-08-20 | Granted | United States of America | Two Phase Chemical\slMechanical Polishing Process For Tungsten Layers |
| 09692012 | 6559011 | 2000-10-19 | 2003-05-06 | Granted | United States of America | Dual Level Gate Process For Hot Carrier Control In Double Diffused MOS Transistors |
| 09792266 | 6706603 | 2001-02-23 | 2004-03-16 | Granted | United States of America | Method Of Forming A Semiconductor Device |
| 09559494 | 6486075 | 2000-04-27 | 2002-11-26 | Granted | United States of America | Anisotropic Wet Etching Method |
| 09966156 | 6695572 | 2001-09-28 | 2004-02-24 | Granted | United States of America | Method And Apparatus For Minimizing Semiconductor Wafer Contamination |
| 09706319 | 6358824 | 2000-11-03 | 2002-03-19 | Granted | United States of America | Integrated Circuits with Tub-Ties and Shallow Trench Isolation |
| 10122645 | 6750447 | 2002-04-12 | 2004-06-15 | Lapsed | United States of America | Calibration Standard For High Resolution Electron Microscopy |
| 09965739 | 6573183 | 2001-09-28 | 2003-06-03 | Granted | United States of America | Method And Apparatus For Controlling Contamination During The Electroplating Deposition Of Metals Onto A Semiconductor Wafer Surface |
| 09631862 | 6525394 | 2000-08-03 | 2003-02-25 | Granted | United States of America | Improved Substrate Isolation For Analog\sdigital IC Chips |
| 09542362 | 6359400 | 2000-04-04 | 2002-03-19 | Granted | United States of America | Direct Drive Spindle For Use In Chemical Vapor Deposition |
| 09727326 | 6585830 | 2000-11-30 | 2003-07-01 | Lapsed | United States of America | Method For Cleaning Tungsten From Deposition Wall Chambers |
| 09713504 | 6559062 | 2000-11-15 | 2003-05-06 | Granted | United States of America | Method For Avoiding Notching In A Semiconductor Interconnect During A Metal Etching Step |
| 09651661 | 6555910 | 2000-08-29 | 2003-04-29 | Granted | United States of America | Use Of Small Openings In Large Topography Features To Improve Dielectric Thickness Control And A Method Of Manufacture Thereof |

Schedule B(1)(a) - Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------|----------|------------|------------|---------|--------------------------|---|
| 10055583 | 6800255 | 2002-01-23 | 2004-10-05 | Lapsed | United States of America | System And Method For The Abatement Of Toxic Constituents Of Effluent Gases |
| 09665279 | 6558238 | 2000-09-19 | 2003-05-06 | Granted | United States of America | Apparatus And Method For Reclamation Of Used Polishing Slurry |
| 09326688 | 6423149 | 2000-03-22 | 2002-07-23 | Granted | United States of America | Apparatus And Method For Improved Cleaning Of Post-CMP Semiconductor Wafers |
| 09605507 | 6403397 | 2000-06-28 | 2002-06-11 | Granted | United States of America | Process For Fabricating Organic Semiconductor Device Involving Selective Patterning |
| 09785756 | 6544107 | 2001-02-16 | 2003-04-08 | Granted | United States of America | Composite Polishing Pads For Chemical\Mechanical Polishing |
| 09490912 | 6579797 | 2000-01-25 | 2003-05-17 | Granted | United States of America | Cleaning Brush Conditioning Apparatus |
| 09567373 | 6519542 | 2000-05-09 | 2003-02-11 | Granted | United States of America | Method Of Testing An Unknown Sample With An Analytical Tool |
| 09567359 | 6519543 | 2000-05-09 | 2003-02-11 | Granted | United States of America | Calibration Method For Quantitative Elemental Analysis |
| 09659668 | 6495474 | 2000-09-11 | 2002-12-17 | Granted | United States of America | Method Of Fabricating A Dielectric Layer |
| 09718935 | 6514123 | 2000-11-21 | 2003-02-04 | Granted | United States of America | Semiconductor Polishing Pad Alignment Device For A Polishing Apparatus And Method Of Use |
| 09755826 | 7927939 | 2001-01-04 | 2011-04-19 | Granted | United States of America | Method of Manufacturing a Laterally Diffused Metal Oxide Semiconductor Device |
| 12555082 | 7927940 | 2009-09-08 | 2011-04-19 | Granted | United States of America | Method of Manufacturing a Laterally Diffused Metal Oxide Semiconductor Device |
| 10028614 | 6815302 | 2001-12-21 | 2004-11-09 | Granted | United States of America | Method For Making A Bipolar Transistor With An Oxygen Implanted Emitter Window |
| 09727325 | 6537887 | 2000-11-30 | 2003-03-25 | Granted | United States of America | Integrated Circuit Fabrication |
| 09821506 | 6615433 | 2001-03-29 | 2003-09-09 | Granted | United States of America | Apparatus For Detecting Wetness Of A Semiconductor Wafer Cleaning Brush |
| 09382611 | 6235072 | 1999-08-25 | 2001-05-22 | Granted | United States of America | Glove Box Filter System |
| 09809379 | 6870950 | 2001-03-15 | 2005-03-22 | Granted | United States of America | Method For Detecting Defects In A Material And A System For Accomplishing The Same |
| 09420234 | 6511221 | 1999-10-19 | 2003-01-28 | Granted | United States of America | Apparatus For Measuring Thermomechanical Properties Of Photo\Sensitive Materials |
| 09442688 | 6246325 | 1999-11-18 | 2001-06-12 | Granted | United States of America | A Distributed Communications System For Reducing Equipment Down-Time |
| 09407575 | 6156675 | 1999-09-28 | 2000-12-05 | Granted | United States of America | Apparatus And Method For Enhanced Dielectric Film Uniformity |
| 09397459 | 6406999 | 1999-09-16 | 2002-06-18 | Granted | United States of America | A Semiconductor Device Having Reduced Line Width Variations Between Tightly Spaced And Isolated Features |
| 09397458 | 6395639 | 1999-09-16 | 2002-05-28 | Granted | United States of America | A Process For Improving Line Width Variations Between Tightly Spaced And Isolated Features In Integrated Circuits |
| 09494705 | 6354910 | 2000-01-31 | 2002-03-12 | Granted | United States of America | Apparatus And Method For In-Situ Measurement Of Polishing Pad Thickness Loss |
| 09533429 | 6616965 | 2000-03-23 | 2003-09-09 | Lapsed | United States of America | Non\Umlthydrolytic Sol\Umlgel Process For High K Dielectric |

PATENT
REEL: 060885 FRAME: 0102

Schedule B(1)(a) – Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|---------------|-----------|------------|------------|---------|--------------------------|--|
| 09356396 | 6259764 | 1999-07-16 | 2001-07-10 | Granted | United States of America | Zone Plates For X-Rays |
| 09591037 | 6451660 | 2000-06-09 | 2002-09-17 | Granted | United States of America | Method Of Forming Bipolar Transistors Comprising A Native Oxide Layer Formed On A Substrate By Rinsing The Substrate In Ozinated Water |
| | | | | | | Method Of Determining A Trap Density Of A Semiconductor\(\sOxide Interface By A Contactless Charge Technique |
| 09562346 | 6391668 | 2000-05-01 | 2002-05-21 | Granted | United States of America | Method For Chemical\(\sMechanical Planarization Of A Semiconductor Wafer Having Dissimilar Metal Pattern Densities |
| 09415529 | 6596639 | 1999-10-08 | 2003-07-22 | Granted | United States of America | Reference Thickness Endpoint Techniques For Polishing Operations |
| 09426017 | 6254454 | 1999-10-25 | 2001-07-03 | Granted | United States of America | Diffusion Preventing Barrier Layer In Integrated Circuit Inter-Metal Layer Dielectrics |
| 89112520 | NI-139603 | 2000-06-26 | 2001-09-01 | Granted | Taiwan | Diffusion Preventing Barrier Layer In Integrated Circuit Inter-Metal Layer Dielectrics |
| 1020000048028 | 757214 | 2000-08-19 | 2007-09-04 | Granted | Korea, Republic of (KR) | Diffusion Preventing Barrier Layer In Integrated Circuit Inter-Metal Layer Dielectrics |
| 00194837 | 2359661 | 2000-08-08 | 2002-11-20 | Lapsed | United Kingdom | Diffusion Preventing Barrier Layer In Integrated Circuit Inter-Metal Layer Dielectrics |
| 09377386 | 6727588 | 1999-08-19 | 2004-04-27 | Granted | United States of America | Diffusion Preventing Barrier Layer In Integrated Circuit Inter-Metal Layer Dielectrics |
| 09491836 | 6368190 | 2000-01-26 | 2002-04-09 | Granted | United States of America | Electrochemical Mechanical Planarization Apparatus And Method |
| 09575214 | 6680542 | 2000-05-18 | 2004-01-20 | Granted | United States of America | Damascene Structure Having A Metal-Oxide-Metal Capacitor Associated Therewith |
| 09354657 | 6414383 | 1999-07-16 | 2002-07-02 | Granted | United States of America | Very Low Magnetic Field Integrated Circuit |
| 09388203 | 6362638 | 1999-09-01 | 2002-03-26 | Granted | United States of America | Stacked Via Kelvin Resistance Test Structure For Measuring Contact Anomalies In Multi-Level Metal Integrated Circuit Technologies |
| | | | | | | Method Of Polishing Semiconductor Structures Using Chemical Mechanical Planarization |
| 09444817 | 6368955 | 1999-11-22 | 2002-04-09 | Granted | United States of America | Method Of Forming A Capacitor Having A Tungsten Bottom Electrode In A Semiconductor Wafer |
| 09478725 | 6303426 | 2000-01-06 | 2001-10-16 | Granted | United States of America | Energy-Sensitive Resist Material And A Process For Device Fabrication Using An Energy-Sensitive Resist Material |
| 09266912 | 6048664 | 1999-03-12 | 2000-04-11 | Granted | United States of America | Selective Etching Of Thin Films |
| 09497982 | 6306313 | 2000-02-04 | 2001-10-23 | Granted | United States of America | High-Resolution Method For Patterning A Substrate With Micro-Printing |
| 09305722 | 6736985 | 1999-05-05 | 2004-05-18 | Granted | United States of America | |

Schedule B(1)(a) – Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|---------------|-----------|------------|------------|---------|--------------------------|---|
| 09465880 | 6746577 | 1999-12-16 | 2004-06-08 | Granted | United States of America | Method And Apparatus For Thickness Control And Reproducibility Of Dielectric Film Deposition |
| 09390181 | 6387817 | 1999-09-07 | 2002-05-14 | Granted | United States of America | Plasma Confinement Shield |
| 09273299 | 6066884 | 1999-03-19 | 2000-05-23 | Granted | United States of America | Schottky Diode Guard Ring Structures |
| 09363781 | 6175137 | 1999-07-29 | 2001-01-16 | Granted | United States of America | Monolithic Resistor Having Dynamically Controllable Impedance And Method Of Manufacturing The Same |
| 09480387 | 6309900 | 2000-01-11 | 2001-10-30 | Granted | United States of America | Test Structures For Testing Planarization Systems And Methods For Using Same |
| 1020000046955 | 718823 | 2000-08-14 | 2007-05-10 | Granted | Korea, Republic of (KR) | A Silicon-Germanium Transistor And Associated Methods |
| 00194811 | 2356739 | 2000-08-08 | 2002-04-17 | Lapsed | United Kingdom | A Silicon-Germanium Transistor And Associated Methods |
| 89116118 | NI-151814 | 2000-08-10 | 2002-03-11 | Lapsed | Taiwan | A Silicon-Germanium Transistor And Associated Methods |
| 09375150 | 6235560 | 1999-08-16 | 2001-05-22 | Granted | United States of America | A Silicon-Germanium Transistor And Associated Methods |
| 09370912 | 6287970 | 1999-08-06 | 2001-09-11 | Granted | United States of America | Method Of Making A Semiconductor With Copper Passivating Film |
| 09332216 | 6281128 | 1999-06-14 | 2001-08-28 | Granted | United States of America | Wafer Carrier Modification For Reduced Extraction Force |
| 09253445 | 6307252 | 1999-03-05 | 2001-10-23 | Granted | United States of America | On-Chip Shielding Of Signals |
| 09286430 | 6217427 | 1999-04-06 | 2001-04-17 | Granted | United States of America | Mobius Strip Belt For Linear CMP Tools |
| 09441676 | 6331460 | 1999-11-17 | 2001-12-18 | Granted | United States of America | A Method Of Fabricating A MOM Capacitor Having A Metal Silicide Barrier |
| 09441561 | 6335557 | 1999-11-17 | 2002-01-01 | Granted | United States of America | Metal Silicide As A Barrier For MOM Capacitors In CMOS Technologies |
| 09281642 | 6317643 | 1999-03-31 | 2001-11-13 | Granted | United States of America | Manufacturing And Engineering Data Base |
| 09236763 | 6278105 | 1999-01-25 | 2001-08-21 | Granted | United States of America | Transistor Utilizing Photonic Band\mGap Material And Integrated Circuit Devices Comprising Same |
| 09197351 | 6246060 | 1998-11-20 | 2001-06-12 | Granted | United States of America | Apparatus For Holding And Aligning A Scanning Electron Microscope Sample |
| 09136095 | 6080671 | 1998-08-18 | 2000-06-27 | Granted | United States of America | Process Of Chemical-Mechanical Polishing And Manufacturing An Integrated Circuit |
| 09099715 | 6121124 | 1998-06-18 | 2000-09-19 | Granted | United States of America | Process For Fabricating Integrated Circuits With Dual Gate Devices Therein |
| 09113583 | 6146975 | 1998-07-10 | 2000-11-14 | Granted | United States of America | Shallow Trench Isolation |
| 08980943 | 5951382 | 1997-12-01 | 1999-09-14 | Granted | United States of America | Chemical Mechanical Polishing Carrier Fixture and System |
| 09039213 | 6043496 | 1998-03-14 | 2000-03-28 | Granted | United States of America | Method Of Linewidth Monitoring For Nanolithography |
| 09062606 | 5897362 | 1998-04-17 | 1999-04-27 | Granted | United States of America | Bonding Silicon Waters |
| 08878579 | 6007685 | 1997-06-19 | 1999-12-28 | Expired | United States of America | Deposition Of Highly Doped Silicon Dioxide Films |
| 09089792 | 6090534 | 1998-06-03 | 2000-07-18 | Granted | United States of America | Device And Method Of Decreasing Circular Defects And Charge Buildup In Integrated Circuit Fabrication |

Schedule B(1)(a) - Semic Processing A

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------|----------|------------|------------|---------|--------------------------|--|
| 08887587 | 5811844 | 1997-07-03 | 1998-09-22 | Expired | United States of America | Low Noise, High Power Pseudomorphic HEMT |
| 08871385 | 6001701 | 1997-06-09 | 1999-12-14 | Expired | United States of America | Process For Making Bipolar Having Graded Or Modulated Collector |
| 08988420 | 6258241 | 1997-12-10 | 2001-07-10 | Granted | United States of America | Process For Electroplating Metals |
| 08807209 | 5861651 | 1997-02-28 | 1999-01-19 | Expired | United States of America | Field Effect Devices And Capacitors With Improved Thin Film Dielectrics And Method For Making Same |
| 08970298 | 5951372 | 1997-11-14 | 1999-09-14 | Granted | United States of America | Method Of Roughing A Metallic Surface Of A Semiconductor Deposition Tool |
| 08761052 | 5894154 | 1996-12-05 | 1999-04-13 | Expired | United States of America | Improved P\michannel MOS Transistor |
| 08834261 | 5902504 | 1997-04-15 | 1999-05-11 | Expired | United States of America | Systems And Method For Determining Semiconductor Wafer Temperature And Calibrating A Vapor Deposition Device |
| 08805404 | 6274198 | 1997-02-24 | 2001-08-14 | Expired | United States of America | Shadow Mask Deposition |
| 08904527 | 5930650 | 1997-08-01 | 1999-07-27 | Expired | United States of America | Method Of Etching Silicon Materials |
| 08767758 | 5735963 | 1996-12-17 | 1998-04-07 | Expired | United States of America | Method Of Polishing |
| 08775790 | 5960302 | 1996-12-31 | 1999-09-28 | Expired | United States of America | Method Of Making A Dielectric For An Integrated Circuit |
| 08577077 | 6078035 | 1995-12-22 | 2000-06-20 | Expired | United States of America | Integrated Circuit Processing Utilizing Microwave Radiation |
| 08705936 | 5966627 | 1996-08-30 | 1999-10-12 | Expired | United States of America | In-situ Doped Silicon Layers |
| 08516060 | 5654540 | 1995-08-17 | 1997-08-05 | Expired | United States of America | High Resolution Remote Position Detection Using Segmented Gratings |
| 08846769 | 5942775 | 1997-04-30 | 1999-08-24 | Expired | United States of America | Photosensing Device With Improved Spectral Response And Low Thermal Leakage |
| 08798580 | 5768335 | 1997-02-10 | 1998-06-16 | Expired | United States of America | Apparatus And Method For Measuring The Orientation Of A Single Crystal Surface |
| 08370902 | 5534465 | 1995-01-10 | 1996-07-09 | Expired | United States of America | Method For Making Multichip Circuits Using Active Semiconductor Substrates |
| 08362616 | 5538921 | 1994-12-22 | 1996-07-23 | Expired | United States of America | Integrated Circuit Fabrication |
| 08573923 | 5683758 | 1995-12-18 | 1997-11-04 | Expired | United States of America | Method Of Forming Vias |
| 08316745 | 5550583 | 1994-10-03 | 1996-08-27 | Expired | United States of America | Inspection Apparatus And Method |
| 08622797 | 5705298 | 1996-03-27 | 1998-01-06 | Expired | United States of America | Holographic Method For Generating Three-Dimensional Conformal Photographic Masks |
| 08622795 | 5764390 | 1996-03-27 | 1998-06-09 | Expired | United States of America | Holographic Method For Generating Three-Dimensional Conformal Photographic Masks |
| 08199910 | 6211539 | 1994-02-22 | 2001-04-03 | Granted | United States of America | Semi-Insulated Indium Phosphide Based Compositions |

Schedule B(1)(b) - Semic Processing B

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------|----------|------------|------------|-----------|--------------------------|---|
| 08943371 | 5898228 | 1997-10-03 | 1999-04-27 | Expired | United States of America | On-chip misalignment indication |
| 09150076 | 6221681 | 1998-09-09 | 2001-04-24 | Expired | United States of America | On-chip misalignment indication |
| 09943403 | 6521520 | 2001-08-30 | 2003-02-18 | Granted | United States of America | Semiconductor wafer arrangement and method of processing a semiconductor wafer |
| 10321250 | 6707114 | 2002-12-16 | 2004-03-16 | Granted | United States of America | Semiconductor wafer arrangement of a semiconductor wafer |
| 08796945 | 5804249 | 1997-02-07 | 1998-09-08 | Expired | United States of America | Multistep tungsten CVD process with amorphization step |
| 09067545 | 6016009 | 1998-04-27 | 2000-01-18 | Expired | United States of America | Integrated circuit with tungsten plug containing amorphization layer |
| 10619978 | 7071113 | 2003-07-14 | 2006-07-04 | Granted | United States of America | Process for removal of photoresist mask used for making vias in low K carbon-doped silicon oxide dielectric material, and for removal of etch residues from formation of vias and removal of photoresist mask |
| 09898194 | 6673721 | 2001-07-02 | 2004-01-06 | Granted | United States of America | Process for removal of photoresist mask used for making vias in low K carbon-doped silicon oxide dielectric material, and for removal of etch residues from formation of vias and removal of photoresist mask |
| 09946895 | 6372524 | 2001-09-05 | 2002-04-16 | Granted | United States of America | Method for CMP endpoint detection |
| 60273959 | | 2001-03-06 | | Expired | United States of America | Detection of CMP Endpoint With Multiple Wavelength Lasers |
| 08851607 | 5898478 | 1997-05-05 | 1999-04-27 | Expired | United States of America | Method of using a test reticle to optimize alignment of integrated circuit process layers |
| 08302598 | 5627624 | 1994-10-31 | 1997-05-06 | Expired | United States of America | Integrated circuit test reticle and alignment mark optimization method |
| 09477170 | 6495408 | 2000-01-04 | 2002-12-17 | Granted | United States of America | Local interconnection process for preventing dopant cross diffusion in shared gate electrodes |
| 09020029 | 6034401 | 1998-02-06 | 2000-03-07 | Granted | United States of America | Local interconnection process for preventing dopant cross diffusion in shared gate electrodes |
| 09076249 | | 1998-05-12 | | Abandoned | United States of America | Mosfet Device With Improved LDD Region And Method Of Making Same |
| 08791283 | 5780350 | 1997-01-30 | 1998-07-14 | Expired | United States of America | MOSFET device with improved LDD region and method of making same |
| 08962420 | | 1997-10-31 | | Abandoned | United States of America | Hybrid Surface/Buried-Channel MOSFET |
| 08719773 | 6246093 | 1996-09-25 | 2001-06-12 | Expired | United States of America | Hybrid surface/buried-channel MOSFET |
| 09300823 | 6030425 | 1999-04-27 | 2000-02-29 | Expired | United States of America | Catalytic acceleration and electrical bias control of CMP processing |
| 08652905 | 5948697 | 1996-05-23 | 1999-09-07 | Expired | United States of America | Catalytic acceleration and electrical bias control of CMP processing |
| 08788125 | | 1997-01-23 | | Abandoned | United States of America | Wafer Clamp For Chemical Vapor Deposition |
| 08520058 | 5635244 | 1995-08-28 | 1997-06-03 | Expired | United States of America | Method of forming a layer of material on a wafer |
| 08463064 | 5525837 | 1995-06-05 | 1996-06-11 | Expired | United States of America | Reliable metallization with barrier for semiconductors |

Schedule B(1)(b) - Semic Processing B

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------|----------|------------|------------|-----------|--------------------------|--|
| 08378750 | 5614437 | 1995-01-26 | 1997-03-25 | Expired | United States of America | Method for fabricating reliable metallization with Ta-Si-N barrier for semiconductors |
| 08942511 | | 1997-10-02 | | Abandoned | United States of America | Self-Aligned Remote Polysilicon Contacts |
| 08474794 | 5674774 | 1995-06-07 | 1997-10-07 | Expired | United States of America | Method of making self-aligned remote polysilicon contacts |
| 09792691 | 6649219 | 2001-02-23 | 2003-11-18 | Lapsed | United States of America | Process for forming a low dielectric constant fluorine and carbon-containing silicon oxide dielectric material characterized by improved resistance to oxidation |
| 10652007 | 7015168 | 2003-08-29 | 2006-03-21 | Lapsed | United States of America | Low dielectric constant fluorine and carbon-containing silicon oxide dielectric material characterized by improved resistance to oxidation |
| 07954958 | | 1992-09-30 | | Abandoned | United States of America | Camera |
| 08294076 | 5432333 | 1994-08-22 | 1995-07-11 | Expired | United States of America | Image-sensing display panels with LCD display panel and photosensor array |
| 08863372 | 5977535 | 1997-05-27 | 1999-11-02 | Expired | United States of America | Light sensing device having an array of photosensitive elements coincident with an array of lens formed on an optically transmissive material |
| 08017202 | | 1993-02-11 | | Abandoned | United States of America | Camera Based Devices |
| 08287128 | 5760834 | 1994-08-08 | 1998-06-02 | Expired | United States of America | Electronic camera with binary lens element array |
| 08287204 | 5519205 | 1994-08-08 | 1996-05-21 | Expired | United States of America | Color electronic camera including photosensor array having binary diffractive lens elements |
| 08578746 | 5648655 | 1995-12-26 | 1997-07-15 | Expired | United States of America | Sensing device for capturing a light image |
| 08051028 | 5340978 | 1993-04-21 | 1994-08-23 | Expired | United States of America | Image-sensing display panels with LCD display panel and photosensitive element array |
| 10942444 | 7381502 | 2004-09-16 | 2008-06-03 | Lapsed | United States of America | Apparatus and method to improve the resolution of photolithography systems by improving the temperature stability of the reticle |
| 10265856 | 6866970 | 2002-10-07 | 2005-03-15 | Lapsed | United States of America | Apparatus and method to improve the resolution of photolithography systems by improving the temperature stability of the reticle |
| 10833834 | | 2004-05-04 | | Abandoned | United States of America | Implementation of Si-Ge HBT Module with CMOS Process |
| 10191670 | 6767842 | 2002-07-09 | 2004-07-27 | Granted | United States of America | Implementation of Si-Ge HBT with CMOS process |
| 10889901 | 7365015 | 2004-07-13 | 2008-04-29 | Granted | United States of America | Damascene replacement metal gate process with controlled gate profile and length using Si _{1-x} Ge _x as sacrificial material |
| 12021728 | | 2008-01-29 | | Abandoned | United States of America | Damascene replacement metal gate process with controlled gate profile and length using Si _{1-x} Ge _x as sacrificial material |
| 09650038 | 6500740 | 2000-08-29 | 2002-12-31 | Expired | United States of America | Process For Fabricating Semiconductor Devices In Which The Distribution Of Dopants Is Controlled |
| 08902044 | 6406952 | 1997-07-29 | 2002-06-18 | Expired | United States of America | Process For Device Fabrication |

Schedule B(1)(b) - Semic Processing B

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------|----------|------------|------------|-----------|--------------------------|---|
| 10272734 | 6989552 | 2002-10-17 | 2006-01-24 | Lapsed | United States of America | Method For Making An Integrated Circuit Device With Dielectrically Isolated Tubs And Related Circuit |
| 09728448 | 6500717 | 2000-12-01 | 2002-12-31 | Granted | United States of America | Method For Making An Integrated Circuit Device With Dielectrically Isolated Tubs and Related Circuit |
| 10300254 | 6762457 | 2002-11-20 | 2004-07-13 | Granted | United States of America | LDMOS Device Having A Tapered Oxide |
| 09641086 | 6506641 | 2000-08-17 | 2003-01-14 | Granted | United States of America | The Use Of Selective Oxidation To Improve LDMOS Power Transistors |
| 11390015 | | 2006-03-27 | | Abandoned | United States of America | A Vertical Replacement-Gate Junction Field-Effect Transistor |
| 09950384 | 6690040 | 2001-09-10 | 2004-02-10 | Granted | United States of America | Vertical Replacement-Gate Junction Field-Effect Transistor |
| 10723547 | 7033877 | 2003-11-26 | 2006-04-25 | Lapsed | United States of America | A Vertical Replacement-Gate Junction Field-Effect Transistor |
| 09885497 | 6617251 | 2001-06-19 | 2003-09-09 | Granted | United States of America | Method of shallow trench isolation formation and planarization |
| 10457942 | 6949446 | 2003-06-09 | 2005-09-27 | Lapsed | United States of America | Method of shallow trench isolation formation and planarization |
| 10409423 | 6821831 | 2003-04-08 | 2004-11-23 | Lapsed | United States of America | Electrostatic Discharge Protection In Double Diffused MOS Transistors |
| 09896669 | 6576506 | 2001-06-29 | 2003-06-10 | Granted | United States of America | Electrostatic Discharge Protection In Double Diffused MOS Transistors |
| 11821396 | 7800226 | 2007-06-22 | 2010-09-21 | Lapsed | United States of America | Integrated Circuit With Metal Silicide Regions |
| 10245447 | 7250356 | 2002-09-17 | 2007-07-31 | Granted | United States of America | Method For Forming Metal Silicide Regions In An Integrated Circuit |
| 10263638 | 6770536 | 2002-10-03 | 2004-08-03 | Granted | United States of America | Process For Semiconductor Device Fabrication In Which A Insulating Layer Is Formed On A Semiconductor Substrate |
| 10870834 | | 2004-06-17 | | Abandoned | United States of America | Process For Semiconductor Device Fabrication In Which A Insulating Layer Is Formed On A Semiconductor Substrate |
| 08979297 | 5849639 | 1997-11-26 | 1998-12-15 | Granted | United States of America | Method For Removing Etching Residues And Contaminants |
| 09164283 | 6046115 | 1998-10-01 | 2000-04-04 | Granted | United States of America | Method For Removing Etching Residues and Contaminants |
| 08814051 | 5936831 | 1997-03-06 | 1999-08-10 | Expired | United States of America | Thin Film Tantalum Oxide Capacitors And Resulting Product |
| 08918174 | 6075691 | 1997-08-25 | 2000-06-13 | Expired | United States of America | THIN FILM CAPACITORS AND PROCESS FOR MAKING THEM |
| 08752235 | 5811916 | 1996-11-19 | 1998-09-22 | Expired | United States of America | Field Emission Devices Employing Enhanced Diamond Field Emitters |
| 08752234 | 5744195 | 1996-11-19 | 1998-04-28 | Expired | United States of America | Field Emission Devices Employing Enhanced Diamond Field Emitters |
| 08331458 | 5637950 | 1994-10-31 | 1997-06-10 | Expired | United States of America | Field Emission Devices Employing Enhanced Diamond Field Emitters |
| 08379052 | 5561008 | 1995-01-27 | 1996-10-01 | Expired | United States of America | A Process For Device Fabrication Using Projection Lithography And An Apparatus Therefor |
| 08673705 | 5701014 | 1996-06-25 | 1997-12-23 | Expired | United States of America | A Projection Lithography Apparatus |
| 10383149 | 6872612 | 2003-03-06 | 2005-03-29 | Lapsed | United States of America | Local Interconnect for integrated circuit |
| 11058498 | 7081379 | 2005-02-15 | 2006-07-25 | Lapsed | United States of America | Local Interconnect for integrated circuit |
| 10028594 | 6624498 | 2001-12-20 | 2003-09-23 | Granted | United States of America | Micromagnetic Device Having Alloy Of Cobalt, Phosphorus and Iron |
| 09552627 | 6495019 | 2000-04-19 | 2002-12-17 | Granted | United States of America | Device Comprising Micromagnetic Components For Power Applications And Process For Forming Device |

Schedule B(1)(b) – Semic Processing B

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------|----------|------------|------------|-----------|--------------------------|---|
| 09386132 | 6225182 | 1999-08-30 | 2001-05-01 | Granted | United States of America | Simplified High Q Inductor Substrate |
| 09800049 | 6410974 | 2001-03-05 | 2002-06-25 | Granted | United States of America | Simplified High Q Inductor Substrate |
| 10400279 | 6927494 | 2003-03-27 | 2005-08-09 | Lapsed | United States of America | Local Interconnect |
| 09966464 | 6576544 | 2001-09-28 | 2003-06-10 | Granted | United States of America | Local Interconnect |
| 09583434 | 6383332 | 2000-05-31 | 2002-05-07 | Granted | United States of America | Endpoint detection method and apparatus which utilize a chelating agent to detect a polishing endpoint |
| 09212503 | 6117779 | 1998-12-15 | 2000-09-12 | Granted | United States of America | Endpoint detection method and apparatus which utilize a chelating agent to detect a polishing endpoint |
| 12220644 | | 2008-07-25 | | Abandoned | United States of America | In-Situ Metrology System and Method for Monitoring Metalization and Other Thin Film Formation |
| 10328066 | 7414721 | 2002-12-23 | 2008-08-19 | Granted | United States of America | In-situ metrology system and method for monitoring metalization and other thin film formation |
| 10164909 | 6555475 | 2002-06-07 | 2003-04-29 | Granted | United States of America | Arrangement and method for polishing a surface of a semiconductor wafer |
| 09750639 | 6439981 | 2000-12-28 | 2002-08-27 | Granted | United States of America | Arrangement and method for polishing a surface of a semiconductor wafer |
| 10099641 | 6800940 | 2002-03-15 | 2004-10-05 | Granted | United States of America | Low k dielectric composite layer for integrated circuit structure which provides void-free low k dielectric material between metal lines while mitigating via poisoning |
| 09426056 | 6391795 | 1999-10-22 | 2002-05-21 | Granted | United States of America | Low k dielectric composite layer for integrated circuit structure which provides void-free low k dielectric material between metal lines while mitigating via poisoning |
| 10197956 | 6807655 | 2002-07-16 | 2004-10-19 | Lapsed | United States of America | Adaptive off tester screening method based on intrinsic die parametric measurements |
| 60381746 | | 2002-05-17 | | Expired | United States of America | Process and Apparatus for Wafer Edge Profile Control Using Gas Flow Control Ring |
| 10821708 | | 2004-04-09 | | Abandoned | United States of America | Process and Apparatus for Wafer Edge Profile Control Using Gas Flow Control Ring |
| 10200469 | 6753255 | 2002-07-18 | 2004-06-22 | Granted | United States of America | Process for wafer edge profile control using gas flow control ring |
| 09609527 | 6455363 | 2000-07-03 | 2002-09-24 | Granted | United States of America | System to improve SER immunity and punchthrough |
| 10191107 | | 2002-07-09 | | Abandoned | United States of America | System To Improve SER Immunity And Punchthrough |
| 10602510 | 6768130 | 2003-06-24 | 2004-07-27 | Granted | United States of America | Integration of semiconductor on implanted insulator |
| 10060867 | 6613639 | 2002-01-30 | 2003-09-02 | Granted | United States of America | Forming a semiconductor on implanted insulator |
| 09690047 | 6557566 | 2000-10-16 | 2003-05-06 | Granted | United States of America | Method and apparatus for washing drums |
| 10370812 | 6672320 | 2003-02-20 | 2004-01-06 | Lapsed | United States of America | Apparatus for washing drums |
| 10002413 | 6621404 | 2001-10-23 | 2003-09-16 | Granted | United States of America | Low temperature coefficient resistor |
| 10615039 | 6960979 | 2003-07-08 | 2005-11-01 | Lapsed | United States of America | Low temperature coefficient resistor |
| 09528071 | 6530074 | 2000-03-17 | 2003-03-04 | Granted | United States of America | Apparatus For Verification Of IC Mask Sets |

Schedule B(1)(b) - Semic Processing B

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|-----------|----------|------------|------------|-----------|--------------------------|---|
| 10317147 | 7103869 | 2002-12-11 | 2006-09-05 | Lapsed | United States of America | Method Of Verifying IC Mask Sets |
| 08678971 | 5821148 | 1996-07-12 | 1998-10-13 | Expired | United States of America | Method of Fabricating a Segmented Emitter Low Noise Transistor |
| 08484675 | 5723897 | 1995-06-07 | 1998-03-03 | Expired | United States of America | Segmented Emitter Low Noise Transistor |
| 09643784 | 6383923 | 2000-08-22 | 2002-05-07 | Granted | United States of America | Article Comprising Vertically Nano-InterConnected Circuit Devices And Method For Making The Same |
| 09426457 | 6340822 | 1999-10-05 | 2002-01-22 | Granted | United States of America | Article Comprising Vertically Nano-InterConnected Circuit Devices And Method For Making The Same |
| 09408299 | 6323044 | 1999-09-29 | 2001-11-27 | Granted | United States of America | Integrated Circuit Capacitor And Associated Fabrication Methods |
| 09951178 | 6525358 | 2001-09-13 | 2003-02-25 | Granted | United States of America | Capacitor Having The Lower Electrode For Preventing Undesired Defects At The Surface Of The Metal Plug |
| 10776752 | 6927125 | 2004-02-11 | 2005-08-09 | Granted | United States of America | Interdigitated Capacitor And Method Of Manufacturing Thereof |
| 09929188 | 6740922 | 2001-08-14 | 2004-05-25 | Granted | United States of America | Interdigitated Capacitor And Method Of Manufacturing Thereof |
| 08878242 | 6090686 | 1997-06-18 | 2000-07-18 | Expired | United States of America | LOCOS Isolation Process Using Layered PAD Nitride And Dry Field Oxidation Stack And Semiconductor Device Employing The Same |
| 09205413 | 6380606 | 1998-12-02 | 2002-04-30 | Expired | United States of America | Locos Isolation Process Using A Layered Pad Nitride And Dry Field Oxidation Stack And Semiconductor Device Employing The Same |
| 08562235 | 5773338 | 1995-11-21 | 1998-06-30 | Expired | United States of America | Bipolar Transistor With MOS-Controlled Protection For Reverse-Biased Emitter-Base Junction |
| 09050711 | 5949128 | 1998-03-30 | 1999-09-07 | Expired | United States of America | Bipolar Transistor With MOS-Controlled Protection For Reverse-Biased Emitter-Base Junction |
| 12253403 | 7960812 | 2008-10-17 | 2011-06-14 | Granted | United States of America | Electrical Devices Having Adjustable Capacitance |
| 10746824 | 7456716 | 2003-12-24 | 2008-11-25 | Granted | United States of America | Electrical Devices Having Adjustable Electrical Characteristics |
| 08848141 | 6054722 | 1997-04-28 | 2000-04-25 | Expired | United States of America | Current Drive of TFTs in High-Speed SRAMs |
| 08572196 | 5625200 | 1995-12-14 | 1997-04-29 | Expired | United States of America | Complementary Devices Using Thin Film Transistors With Improved Current Drive |
| 10234354 | 7126198 | 2002-09-03 | 2006-10-24 | Lapsed | United States of America | Protruding Spacers For Self-Aligned Contacts |
| 11542864 | 7332775 | 2006-10-04 | 2008-02-19 | Granted | United States of America | Protruding Spacers For Self-Aligned Contacts |
| 08381375 | 5616368 | 1995-01-31 | 1997-04-01 | Expired | United States of America | Field Emission Devices Employing Activated Diamond Particle Emitters And Methods For Making Same |
| 08361616 | 5709577 | 1994-12-22 | 1998-01-20 | Expired | United States of America | Method Of Making Field Emission Devices Employing Ultra-Fine Diamond Particle Emitters |
| 090006347 | 5977697 | 1998-01-13 | 1999-11-02 | Expired | United States of America | Field Emission Devices Employing Diamond Particle Emitters |
| 09573137 | 6566186 | 2000-05-17 | 2003-05-20 | Granted | United States of America | Capacitor with stoichiometrically adjusted dielectric and method of fabricating same |
| 10382709 | 6951787 | 2003-03-06 | 2005-10-04 | Lapsed | United States of America | Capacitor with stoichiometrically adjusted dielectric and method of fabricating same |
| 11122375 | | 2005-05-05 | | Abandoned | United States of America | Capacitor with Stoichiometrically Adjusted Dielectric and Method of Fabricating Same |

Schedule B(1)(b) – Semic Processing B

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------|----------|------------|------------|-----------|--------------------------|---|
| 09960765 | 6504219 | 2001-09-21 | 2003-01-07 | Granted | United States of America | Indium field implant for punchthrough protection in semiconductor devices |
| 09469579 | 6342429 | 1999-12-22 | 2002-01-29 | Granted | United States of America | Method of fabricating an indium field implant for punchthrough protection in semiconductor devices |
| 09211024 | 6168502 | 1998-12-14 | 2001-01-02 | Expired | United States of America | Subsonic to supersonic and ultrasonic conditioning of a polishing pad in a chemical mechanical polishing apparatus |
| 08696445 | 5868608 | 1996-08-13 | 1999-02-09 | Expired | United States of America | Subsonic to supersonic and ultrasonic conditioning of a polishing pad in a chemical mechanical polishing apparatus |
| 09052851 | 6057571 | 1998-03-31 | 2000-05-02 | Granted | United States of America | High aspect ratio, metal-to-metal, linear capacitor for an integrated circuit |
| 09221023 | 6251740 | 1998-12-23 | 2001-06-26 | Granted | United States of America | Method of forming and electrically connecting a vertical interdigitated metal-insulator-metal capacitor extending between interconnect layers in an integrated circuit |
| 09219655 | 6417535 | 1998-12-23 | 2002-07-09 | Granted | United States of America | Vertical interdigitated metal-insulator-metal capacitor for an integrated circuit |
| 09052793 | 6358837 | 1998-03-31 | 2002-03-19 | Granted | United States of America | Method of electrically connecting and isolating components with vertical elements extending between interconnect layers in an integrated circuit |
| 09525489 | 6441419 | 2000-03-15 | 2002-08-27 | Granted | United States of America | Encapsulated-metal vertical-interdigitated capacitor and damascene method of manufacturing same |
| 09907424 | 6489231 | 2001-07-17 | 2002-12-03 | Granted | United States of America | Method for forming barrier and seed layer |
| 10268735 | | 2002-10-10 | | Abandoned | United States of America | Barrier and Seed Layer System |
| 09027307 | 6004880 | 1998-02-20 | 1999-12-21 | Granted | United States of America | Method of single step damascene process for deposition and global planarization |
| 09365440 | 6090239 | 1999-08-02 | 2000-07-18 | Granted | United States of America | Method of single step damascene process for deposition and global planarization |
| 08604867 | 5688709 | 1996-02-14 | 1997-11-18 | Expired | United States of America | Method for forming composite trench-fin capacitors for DRAMS |
| 08879341 | 6081008 | 1997-06-20 | 2000-06-27 | Expired | United States of America | Composite trench-fin capacitors for DRAM |
| 08552461 | 5670425 | 1995-11-09 | 1997-09-23 | Expired | United States of America | Process for making integrated circuit structure comprising local area interconnects formed over semiconductor substrate by selective deposition on seed layer in patterned trench |
| 08873809 | 5895261 | 1997-06-12 | 1999-04-20 | Expired | United States of America | Process for making integrated circuit structure comprising local area interconnects formed over semiconductor substrate by selective deposition on seed layer in patterned trench |
| 09454257 | 6297558 | 1999-12-02 | 2001-10-02 | Expired | United States of America | Slurry filling a recess formed during semiconductor fabrication |
| 08899111 | 6069085 | 1997-07-23 | 2000-05-30 | Expired | United States of America | Slurry filling a recess formed during semiconductor fabrication |

Schedule B(1)(b) - Semic Processing B

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------|----------|------------|------------|-----------|--------------------------|---|
| 08752334 | | 1996-11-19 | | Abandoned | United States of America | Structure For Reduction Of Channeling During Implantation Of Source And Drain Regions In Formation Of Mos Integrated Circuit Structures |
| 08546921 | 5614428 | 1995-10-23 | 1997-03-25 | Expired | United States of America | Process and structure for reduction of channeling during implantation of source and drain regions in formation of MOS integrated circuit structures |
| 08704472 | 5763302 | 1996-08-20 | 1998-06-09 | Expired | United States of America | Self-aligned twin well process |
| 08768845 | 5770492 | 1996-12-18 | 1998-06-23 | Expired | United States of America | Self-aligned twin well process |
| 08488075 | 5583062 | 1995-06-07 | 1996-12-10 | Expired | United States of America | Self-aligned twin well process having a SiO ₂ -polysilicon-SiO ₂ barrier mask |
| 08374193 | 5646073 | 1995-01-18 | 1997-07-08 | Expired | United States of America | Process for selective deposition of polysilicon over single crystal silicon substrate and resulting product |
| 08823829 | 5818100 | 1997-03-25 | 1998-10-06 | Expired | United States of America | Product resulting from selective deposition of polysilicon over single crystal silicon substrate |
| 08566161 | | 1995-11-30 | | Abandoned | United States of America | Product Resulting From Selective Deposition Of Polysilicon Over Single Crystal Silicon Substrate |
| 08438613 | | 1995-05-10 | | Abandoned | United States of America | Microelectronic Integrated Circuit Including Triangular Semiconductor And Gate Device |
| 08567952 | 5631581 | 1995-12-06 | 1997-05-20 | Expired | United States of America | Microelectronic integrated circuit including triangular semiconductor and gate device |
| 08788403 | 5739580 | 1997-01-27 | 1998-04-14 | Expired | United States of America | Oxide formed in semiconductor substrate by implantation of substrate with a noble gas prior to oxidation |
| 08434674 | 5707888 | 1995-05-04 | 1998-01-13 | Expired | United States of America | Oxide formed in semiconductor substrate by implantation of substrate with a noble gas prior to oxidation |
| 11383171 | 7460211 | 2006-05-12 | 2008-12-02 | Lapsed | United States of America | Apparatus for wafer patterning to reduce edge exclusion zone |
| 10980945 | 7074710 | 2004-11-03 | 2006-07-11 | Lapsed | United States of America | Method of wafer patterning for reducing edge exclusion zone |
| 10893659 | 7071094 | 2004-07-16 | 2006-07-04 | Granted | United States of America | Dual layer barrier film techniques to prevent resist poisoning |
| 11418873 | 7393780 | 2006-05-04 | 2008-07-01 | Granted | United States of America | Dual layer barrier film techniques to prevent resist poisoning |
| 09896363 | 6812134 | 2001-06-28 | 2004-11-02 | Granted | United States of America | Dual layer barrier film techniques to prevent resist poisoning |
| 08485517 | 5696428 | 1995-06-07 | 1997-12-09 | Expired | United States of America | Apparatus and method using optical energy for specifying and quantitatively controlling chemically-reactive components of semiconductor processing plasma etching gas |
| 08986681 | | 1997-12-08 | | Abandoned | United States of America | Apparatus For Igniting Low-Pressure Inductively Coupled Plasma |
| 11964920 | 7565592 | 2007-12-27 | 2009-07-21 | Lapsed | United States of America | Failure Analysis and Testing of Semi-Conductor Devices Using Intelligent Software on Automated Test Equipment (ATE) |
| 11670031 | 7430700 | 2007-02-01 | 2008-09-30 | Granted | United States of America | Failure analysis and testing of semi-conductor devices using intelligent software on automated test equipment (ATE) |

Schedule B(1)(b) - Semic Processing B

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------|----------|------------|------------|-----------|--------------------------|--|
| 11028695 | 7203877 | 2005-01-04 | 2007-04-10 | Granted | United States of America | Failure analysis and testing of semi-conductor devices using intelligent software on automated test equipment (ATE) |
| 08955384 | 5897381 | 1997-10-21 | 1999-04-27 | Expired | United States of America | Method of forming a layer and semiconductor substrate |
| 08954791 | 5893952 | 1997-10-21 | 1999-04-13 | Expired | United States of America | Apparatus for rapid thermal processing of a wafer |
| 08678718 | 5756369 | 1996-07-11 | 1998-05-26 | Expired | United States of America | Rapid thermal processing using a narrowband infrared source and feedback |
| 10930590 | 8404960 | 2004-08-31 | 2013-03-26 | Granted | United States of America | Method for Heat Dissipation on Semiconductor Device |
| 13775922 | 8653357 | 2013-02-25 | 2014-02-18 | Lapsed | United States of America | Method for Heat Dissipation on Semiconductor Device |
| 10921538 | 7129101 | 2004-08-18 | 2006-10-31 | Lapsed | United States of America | Failure analysis vehicle for yield enhancement with self test at speed burnin capability for reliability testing |
| 11527108 | 7420229 | 2006-09-25 | 2008-09-02 | Granted | United States of America | Failure analysis vehicle for yield enhancement with self test at speed burnin capability for reliability testing |
| 10907018 | 6781151 | 2002-11-27 | 2004-08-24 | Granted | United States of America | Failure analysis vehicle |
| 08521795 | 5585286 | 1995-08-31 | 1996-12-17 | Expired | United States of America | Implantation of a semiconductor substrate with controlled amount of noble gas ions to reduce channeling and/or diffusion of a boron dopant subsequently implanted into the substrate to form P-LDD region of a PMOS device |
| 08677078 | 5717238 | 1996-07-09 | 1998-02-10 | Expired | United States of America | Substrate with controlled amount of noble gas ions to reduce channeling and/or diffusion of a boron dopant forming P-LDD region of a PMOS device |
| 08502566 | 5543643 | 1995-07-13 | 1996-08-06 | Expired | United States of America | Combined JFET and MOS transistor device, circuit |
| 08612337 | 5631176 | 1996-03-06 | 1997-05-20 | Expired | United States of America | Method of making combined JFET & MOS transistor device |
| 08578743 | 5686855 | 1995-12-26 | 1997-11-11 | Expired | United States of America | Process monitor for CMOS integrated circuits |
| 08287653 | 5486786 | 1994-08-09 | 1996-01-23 | Expired | United States of America | Process monitor for CMOS integrated circuits |
| 08506821 | 5631596 | 1995-07-25 | 1997-05-20 | Expired | United States of America | Process monitor for CMOS integrated circuits |
| 11425295 | 8089130 | 2006-06-20 | 2012-01-03 | Granted | United States of America | Semiconductor Device And Process For Reducing Damaging Breakdown In Gate Dielectrics |
| 13311299 | 8241986 | 2011-12-05 | 2012-08-14 | Granted | United States of America | Semiconductor Device And Process For Reducing Damaging Breakdown In Gate Dielectrics |
| 09804783 | 6586326 | 2001-03-13 | 2003-07-01 | Lapsed | United States of America | Metal planarization system |
| 10400278 | 6951808 | 2003-03-27 | 2005-10-04 | Lapsed | United States of America | Metal planarization system |
| 11337460 | 7220362 | 2006-01-23 | 2007-05-22 | Granted | United States of America | Planarization with reduced dishing |
| 10421068 | 7029591 | 2003-04-23 | 2006-04-18 | Lapsed | United States of America | Planarization with reduced dishing |
| 11695169 | | 2007-04-02 | | Abandoned | United States of America | Planarization with Reduced Dishing |
| 10801310 | 7395522 | 2004-03-16 | 2008-07-01 | Granted | United States of America | Yield profile manipulator |
| 12117379 | 7930655 | 2008-05-08 | 2011-04-19 | Granted | United States of America | Yield Profile Manipulator |
| 08473543 | 5659189 | 1995-06-07 | 1997-08-19 | Expired | United States of America | Layout configuration for an integrated circuit gate array |

Schedule B(1)(b) - Semic Processing B

| App No | Patent No | Filed Date | Grant Date | Status | Country | Title |
|----------|-----------|------------|------------|-----------|--------------------------|---|
| 08665016 | 5650348 | 1996-06-11 | 1997-07-22 | Expired | United States of America | Method of making an integrated circuit chip having an array of logic gates |
| 08892827 | 5773854 | 1997-07-15 | 1998-06-30 | Expired | United States of America | Method of fabricating a linearly continuous integrated circuit gate array |
| 09792683 | 6572925 | 2001-02-23 | 2003-06-03 | Granted | United States of America | Process for forming a low dielectric constant fluorine and carbon containing silicon oxide dielectric material |
| 10397993 | | 2003-03-25 | | Abandoned | United States of America | Low Dielectric Constant Fluorine and Carbon-Containing Silicon Oxide Dielectric Material Characterized by Improved Resistance to Oxidation |
| 10243562 | 6885436 | 2002-09-13 | 2005-04-26 | Lapsed | United States of America | Optical error minimization in a semiconductor manufacturing apparatus |
| 11473627 | 7298458 | 2006-06-22 | 2007-11-20 | Granted | United States of America | Optical error minimization in a semiconductor manufacturing apparatus |
| 11075195 | 7098996 | 2005-03-07 | 2006-08-29 | Lapsed | United States of America | Optical error minimization in a semiconductor manufacturing apparatus |
| 11419548 | 7259462 | 2006-05-22 | 2007-08-21 | Granted | United States of America | Interconnect dielectric tuning |
| 10915719 | 7081406 | 2004-08-10 | 2006-07-25 | Lapsed | United States of America | Interconnect dielectric tuning |
| 10417708 | 7056392 | 2003-04-16 | 2006-06-06 | Lapsed | United States of America | Wafer chucking apparatus and method for spin processor |
| 11403137 | 7201176 | 2006-04-11 | 2007-04-10 | Granted | United States of America | Wafer chucking apparatus for spin processor |
| 10153011 | 6794756 | 2002-05-21 | 2004-09-21 | Granted | United States of America | Integrated circuit structure having low dielectric constant material and having silicon oxynitride caps over closely spaced apart metal lines |
| 09425552 | 6423628 | 1999-10-22 | 2002-07-23 | Granted | United States of America | Method of forming integrated circuit structure having low dielectric constant material and having silicon oxynitride caps over closely spaced apart metal lines |
| 11258253 | 7582938 | 2005-10-25 | 2009-09-01 | Lapsed | United States of America | I/O and Power ESD Protection Circuits by Enhancing Substrate-Bias in Deep-Submicron CMOS Process |
| 12506746 | 7948036 | 2009-07-21 | 2011-05-24 | Granted | United States of America | I/O and Power ESD Protection Circuits by Enhancing Substrate-Bias in Deep-Submicron CMOS Process |
| 13110581 | 8269280 | 2011-05-18 | 2012-09-18 | Granted | United States of America | I/O and Power ESD Protection Circuits by Enhancing Substrate-Bias in Deep-Submicron CMOS Process |
| 10676602 | 6979869 | 2003-10-01 | 2005-12-27 | Granted | United States of America | Substrate-biased I/O and power ESD protection circuits in deep-submicron twin-well process |
| 10328614 | 6972217 | 2002-12-23 | 2005-12-06 | Lapsed | United States of America | Low k polymer E-beam printable mechanical support |
| 11225310 | 7358594 | 2005-09-12 | 2008-04-15 | Granted | United States of America | Method of forming a low k polymer E-beam printable mechanical support |
| 10706120 | 6855586 | 2003-11-12 | 2005-02-15 | Granted | United States of America | Low voltage breakdown element for ESD trigger device |
| 10055082 | 6710990 | 2002-01-22 | 2004-03-23 | Granted | United States of America | Low voltage breakdown element for ESD trigger device |

Schedule B(1)(b) - Semic Processing B

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------|----------|------------|------------|-----------|--------------------------|--|
| 11007392 | 7619272 | 2004-12-07 | 2009-11-17 | Lapsed | United States of America | Bi-Axial Texturing Of High-K Dielectric Films To Reduce Leakage Currents |
| 12574479 | 7956401 | 2009-10-06 | 2011-06-07 | Granted | United States of America | Bi-Axial Texturing Of High-K Dielectric Films To Reduce Leakage Currents |
| 11506659 | 7456076 | 2006-08-18 | 2008-11-25 | Granted | United States of America | Techniques for forming passive devices during semiconductor back-end processing |
| 10944373 | 7122436 | 2004-09-16 | 2006-10-17 | Lapsed | United States of America | Techniques for forming passive devices during semiconductor back-end processing |
| 11856196 | 7612427 | 2007-09-17 | 2009-11-03 | Granted | United States of America | Apparatus For Confining Inductively Coupled Surface Currents |
| 11248509 | 7397105 | 2005-10-12 | 2008-07-08 | Granted | United States of America | Apparatus to passivate inductively or capacitively coupled surface currents under capacitor structures |
| 11010970 | 7285840 | 2004-12-12 | 2007-10-23 | Granted | United States of America | Apparatus for confining inductively coupled surface currents |
| 60578890 | | 2004-06-10 | | Abandoned | United States of America | Vortex Phase Shift Mask Applied to Optical Direct Write |
| 13722648 | 9188848 | 2012-12-20 | 2015-11-17 | Lapsed | United States of America | Maskless Vortex Phase Shift Optical Direct Write Lithography |
| 13253554 | 8377633 | 2011-10-05 | 2013-02-19 | Lapsed | United States of America | Maskless Vortex Phase Shift Optical Direct Write Lithography |
| 11011896 | 8057963 | 2004-12-14 | 2011-11-15 | Lapsed | United States of America | Maskless Vortex Phase Shift Optical Direct Write Lithography |
| 11210986 | | 2005-08-24 | | Abandoned | United States of America | Temperature Control System |
| 09670975 | 6967177 | 2000-09-27 | 2005-11-22 | Granted | United States of America | Temperature control system |
| 10035501 | 6743474 | 2001-10-25 | 2004-06-01 | Granted | United States of America | Method for growing thin films |
| 10804980 | 7081296 | 2004-03-16 | 2006-07-25 | Lapsed | United States of America | Method for growing thin films |
| 11741195 | 7825522 | 2007-04-27 | 2010-11-02 | Lapsed | United States of America | Hybrid Bump Capacitor |
| 12885722 | 8384226 | 2010-09-20 | 2013-02-26 | Lapsed | United States of America | Hybrid Bump Capacitor |
| 10327283 | | 2002-12-19 | | Abandoned | United States of America | Diamond Metal-Filled Patterns Achieving Low Parasitic Coupling Capacitance |
| 11016468 | 6998716 | 2004-12-16 | 2006-02-14 | Granted | United States of America | Diamond metal-filled patterns achieving low parasitic coupling capacitance |
| 10035704 | 6727177 | 2001-10-18 | 2004-04-27 | Granted | United States of America | Multi-step process for forming a barrier film for use in copper layer formation |
| 11733673 | 7413984 | 2007-04-10 | 2008-08-19 | Granted | United States of America | Multi-step process for forming a barrier film for use in copper layer formation |
| 10772133 | 7229923 | 2004-02-03 | 2007-06-12 | Granted | United States of America | Multi-step process for forming a barrier film for use in copper layer formation |
| 10265867 | | 2002-10-07 | | Abandoned | United States of America | MOS Transistor Having Aluminum Nitride Gate Structure And Method Of Manufacturing Same |
| 09472331 | 6495409 | 1999-12-23 | 2002-12-17 | Granted | United States of America | MOS Transistor Having Aluminum Nitride Gate Structure And Method Of Manufacturing Same |

Schedule B(1)(b) - Semic Processing B

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|-----------|----------|------------|------------|-----------|--------------------------|---|
| 11106307 | | 2005-04-14 | | Abandoned | United States of America | Ultra Low Dielectric Constant Thin Film |
| 106991400 | 6905909 | 2003-10-22 | 2005-06-14 | Lapsed | United States of America | Ultra low dielectric constant thin film |
| 11540056 | 7239160 | 2006-09-29 | 2007-07-03 | Granted | United States of America | Method Of Electrical Testing Of An Integrated Circuit With An Electrical Probe |
| 11138152 | 7132840 | 2005-05-26 | 2006-11-07 | Granted | United States of America | Method Of Electrical Testing |
| 10825342 | 7270942 | 2004-04-14 | 2007-09-18 | Granted | United States of America | Optimized mirror design for optical direct write |
| 60513780 | | 1900-01-01 | | Abandoned | United States of America | New Optimized Mirror Design For Optical Direct Write |
| 11769486 | 7738078 | 2007-06-27 | 2010-06-15 | Lapsed | United States of America | Optimized Mirror Design For Optical Direct Write |
| 09818799 | 6400090 | 2001-03-27 | 2002-06-04 | Granted | United States of America | Electron Emitters For Lithography Tools |
| 09306287 | 6232040 | 1999-05-06 | 2001-05-15 | Granted | United States of America | Electron Emitters For Lithography Tools |
| 09332061 | 6251543 | 1999-06-14 | 2001-06-26 | Granted | United States of America | Process For Fabricating A Projection Electron Lithography Mask And A Removable, Reuseable Cover For Use Therein |
| 09854753 | 6372393 | 2001-05-15 | 2002-04-16 | Granted | United States of America | Process For Fabricating A Projection Electron Lithography Mask And A Removable, Reuseable Cover For Use Therein |
| 08879100 | 6121159 | 1997-06-19 | 2000-09-19 | Expired | United States of America | Polymeric dielectric layers having low dielectric constants and improved adhesion to metal lines |
| 09618211 | 6455934 | 2000-07-10 | 2002-09-24 | Expired | United States of America | Polymeric dielectric layers having low dielectric constants and improved adhesion to metal lines |
| 10628601 | 6943055 | 2003-07-28 | 2005-09-13 | Lapsed | United States of America | Method and apparatus for detecting backside contamination during fabrication of a semiconductor wafer |
| 10138742 | 6627466 | 2002-05-03 | 2003-09-30 | Lapsed | United States of America | Method and apparatus for detecting backside contamination during fabrication of a semiconductor wafer |
| 10368811 | 6977400 | 2003-02-18 | 2005-12-20 | Lapsed | United States of America | Silicon germanium CMOS channel |
| 09724444 | 6544854 | 2000-11-28 | 2003-04-08 | Granted | United States of America | Silicon germanium CMOS channel |
| 10454027 | 6880140 | 2003-06-04 | 2005-04-12 | Lapsed | United States of America | Method to selectively identify reliability risk die based on characteristics of local regions on the wafer |
| 11031564 | 7390680 | 2005-01-06 | 2008-06-24 | Granted | United States of America | Method to selectively identify reliability risk die based on characteristics of local regions on the wafer |
| 09652479 | 6373087 | 2000-08-31 | 2002-04-16 | Granted | United States of America | Methods of Fabricating A Metal-Oxide-Metal Capacitor And Associated Apparatus |
| 10080186 | 6730601 | 2002-02-21 | 2004-05-04 | Granted | United States of America | Methods of Fabricating A Metal-Oxide-Metal Capacitor |
| 10020304 | 6747318 | 2001-12-13 | 2004-06-08 | Granted | United States of America | Buried channel devices and a process for their fabrication simultaneously with surface channel devices to produce transistors and capacitors with multiple electrical gate oxides |
| 10786481 | | 2004-02-24 | | Abandoned | United States of America | Buried Channel Devices And A Process For Their Fabrication Simultaneously With Surface Channel Devices To Produce Transistors And Capacitors With Multiple Electrical Gate Oxides |
| 11265062 | 7635888 | 2005-11-02 | 2009-12-22 | Granted | United States of America | Interdigitated Capacitors |

Schedule B(1)(b) - Semic Processing B

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------|----------|------------|------------|-----------|--------------------------|---|
| 10886763 | 7022581 | 2004-07-08 | 2006-04-04 | Granted | United States of America | Interdigitated Capacitors |
| 12616050 | 8039923 | 2009-11-10 | 2011-10-18 | Granted | United States of America | Interdigitated Capacitors |
| 10649140 | 6821851 | 2003-08-27 | 2004-11-23 | Granted | United States of America | Method Of Making Ultra Thin Body Vertical Replacement Gate Mosfet |
| 10164202 | 6635924 | 2002-06-06 | 2003-10-21 | Granted | United States of America | Ultra Thin Body Vertical Replacement Gate Mosfet |
| 09335707 | 6197641 | 1999-06-18 | 2001-03-06 | Granted | United States of America | Process For Fabricating Vertical Transistors |
| 09143274 | 6027975 | 1998-08-28 | 2000-02-22 | Granted | United States of America | Process For Fabricating Vertical Transistors |
| 11641507 | 7537984 | 2006-12-19 | 2009-05-26 | Lapsed | United States of America | III-V Power Field Effect Transistors |
| 10948897 | 7180103 | 2004-09-24 | 2007-02-20 | Granted | United States of America | III/V Power Field Effect Transistors |
| 10404832 | 7329926 | 2003-04-01 | 2008-02-12 | Granted | United States of America | Semiconductor Device With Constricted Current Passage |
| 11872347 | 7569445 | 2007-10-15 | 2009-08-04 | Lapsed | United States of America | Semiconductor Device With Constricted Current Passage |
| 09723557 | 6455418 | 2000-11-28 | 2002-09-24 | Granted | United States of America | Barrier For Copper Metallization |
| 09218649 | 6288449 | 1998-12-22 | 2001-09-11 | Granted | United States of America | Barrier For Copper Metallization |
| 11533785 | 8049282 | 2006-09-21 | 2011-11-01 | Lapsed | United States of America | Bipolar Device Having Buried Contacts |
| 13222877 | 8372723 | 2011-08-31 | 2013-02-12 | Lapsed | United States of America | Bipolar Device Having Buried Contacts |
| 09602797 | 6288454 | 2000-06-23 | 2001-09-11 | Granted | United States of America | Semiconductor wafer having a layer-to-layer alignment mark and method for fabricating the same |
| 09311253 | 6136662 | 1999-05-13 | 2000-10-24 | Granted | United States of America | Semiconductor wafer having a layer-to-layer alignment mark and method for fabricating the same |
| 11937199 | 7560292 | 2007-11-08 | 2009-07-14 | Lapsed | United States of America | Voltage Contrast Monitor for Integrated Circuit Defects |
| 10652369 | 6936920 | 2003-08-29 | 2005-08-30 | Lapsed | United States of America | Voltage contrast monitor for integrated circuit defects |
| 11131705 | 7323768 | 2005-05-18 | 2008-01-29 | Lapsed | United States of America | Voltage contrast monitor for integrated circuit defects |
| 09246402 | 6214675 | 1999-02-08 | 2001-04-10 | Granted | United States of America | A Method For Fabricating A Merged Integrated Circuit Device |
| 09789254 | 6627963 | 2001-02-20 | 2003-09-30 | Granted | United States of America | Method For Fabricating A Merged Integrated Circuit Device |
| 11827807 | 7632690 | 2007-07-13 | 2009-12-15 | Lapsed | United States of America | Real-Time Gate Etch Critical Dimension Control By Oxygen Monitoring |
| 10675572 | 7261745 | 2003-09-30 | 2007-08-28 | Granted | United States of America | Real-Time Gate Etch Critical Dimension Control By Oxygen Monitoring |
| 10814682 | | 2004-03-31 | | Abandoned | United States of America | Semiconductor Device Having A Doped Lattice Matching Layer And A Method Of Manufacturing Therefor |
| 10003873 | 6737339 | 2001-10-24 | 2004-05-18 | Granted | United States of America | Semiconductor Device Having A Doped Lattice Matching Layer And A Method Of Manufacturing Therefor |
| 10814680 | 6855991 | 2004-03-31 | 2005-02-15 | Granted | United States of America | Semiconductor Device Having A Doped Lattice Matching Layer And A Method Of Manufacturing Therefor |
| 10773900 | 7078280 | 2004-02-06 | 2006-07-18 | Lapsed | United States of America | Vertical Replacement-Gate Silicon-On-Insulator Transistor |
| 11419356 | 7259048 | 2006-05-19 | 2007-08-21 | Granted | United States of America | Vertical Replacement-Gate Silicon-On-Insulator Transistor |
| 09968234 | 6709904 | 2001-09-28 | 2004-03-23 | Granted | United States of America | Vertical Replacement-Gate (VRG) Silicon-On-Insulator (SOI) CMOS Transistor |

Schedule B(1)(b) - Semic Processing B

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------|----------|------------|------------|---------|--------------------------|---|
| 11419252 | 7381607 | 2006-05-19 | 2008-06-03 | Granted | United States of America | A Method Of Forming A Spiral Inductor In A Semiconductor Substrate |
| 10646997 | 7075167 | 2003-08-22 | 2006-07-11 | Lapsed | United States of America | A Spiral Inductor Formed In A Semiconductor Substrate And A Method For Forming The Inductor |
| 10918981 | 7345354 | 2004-08-16 | 2008-03-18 | Granted | United States of America | Increased Quality Factor Of A Varactor In An Integrated Circuit Via A High Conductive Region In A Well |
| 10454133 | 6825089 | 2003-06-04 | 2004-11-30 | Granted | United States of America | Increased Quality Factor Of A Varactor In An Integrated Circuit Via A High Conductive Region In A Well |
| 10648602 | 6884720 | 2003-08-25 | 2005-04-26 | Granted | United States of America | Forming copper interconnects with Sn coatings |
| 11074456 | 7675177 | 2005-03-07 | 2010-03-09 | Lapsed | United States of America | Forming copper interconnects with Sn coatings |
| 09434424 | 6284663 | 1999-11-04 | 2001-09-04 | Granted | United States of America | Method For Making Field Effect Devices And Capacitors With Thin Film Dielectrics And Resulting Devices |
| 09060420 | 6001741 | 1998-04-15 | 1999-12-14 | Granted | United States of America | Method For Making Field Effect Devices And Capacitors With Improved Thin Film Dielectrics And Resulting Devices |
| 10400310 | 6753268 | 2003-03-27 | 2004-06-22 | Granted | United States of America | Reduced particulate etching |
| 09898267 | 6576981 | 2001-07-03 | 2003-06-10 | Granted | United States of America | Reduced particulate etching |
| 09071006 | 5907165 | 1998-05-01 | 1999-05-25 | Granted | United States of America | InP Heterostructure Devices |
| 09255845 | 6165859 | 1999-02-23 | 2000-12-26 | Granted | United States of America | Method Of Making InP Heterostructure Devices |
| 08965706 | 6107191 | 1997-11-07 | 2000-08-22 | Granted | United States of America | Method Of Creating An Interconnect In A Substrate And Semiconductor Device Employing The Same |
| 09428073 | 6222255 | 1999-10-27 | 2001-04-24 | Granted | United States of America | Method Of Creating An Interconnect In A Substrate And Semiconductor Device Employing The Same |
| 08848109 | 6025280 | 1997-04-28 | 2000-02-15 | Expired | United States of America | System And Method For Forming A High Quality Ultrathin Gate Oxide Layer |
| 09338939 | 6281138 | 1999-06-24 | 2001-08-28 | Expired | United States of America | System And Method For Forming A High Quality Ultrathin Gate Oxide Layer |
| 09049531 | 6033202 | 1998-03-27 | 2000-03-07 | Granted | United States of America | Mold For Non-Photolithographic Fabrication Of Microstructures |
| 09393032 | 6322736 | 1999-09-09 | 2001-11-27 | Granted | United States of America | Mold For Non-Photolithographic Fabrication Of Microstructures |
| 08820063 | 5913146 | 1997-03-18 | 1999-06-15 | Expired | United States of America | Semiconductor Device Having Aluminum Contacts Or Vias And Method Of Manufacture Therefor |
| 09166832 | 6157082 | 1998-10-05 | 2000-12-05 | Expired | United States of America | Semiconductor Device Having Aluminum Contacts Or Vias And Method Of Manufacture Therefor |
| 08346444 | 5462012 | 1994-11-29 | 1995-10-31 | Expired | United States of America | Substrates and Methods for Gas Phase Deposition of Semiconductors and Other Materials |
| 08475110 | 5589693 | 1995-06-07 | 1996-12-31 | Expired | United States of America | Substrates and methods for gas phase deposition of semiconductors and other materials |
| 09073556 | 6028359 | 1998-05-06 | 2000-02-22 | Expired | United States of America | Integrated Circuit Having Amorphous Silicide Layer In Contacts And Vias And Method Of Manufacture Therefor |

Schedule B(1)(b) - Semic Processing B

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------|----------|------------|------------|-----------|--------------------------|---|
| 08816185 | 5858873 | 1997-03-12 | 1999-01-12 | Expired | United States of America | Integrated Circuit Having Amorphous Silicide Layer In Contacts And Vias AndMethod Of Manufacture Therefor |
| 09489092 | 6498364 | 2000-01-21 | 2002-12-24 | Granted | United States of America | A Capacitor For Integration With Copper Damascene Processes |
| 10195935 | 7135733 | 2002-07-16 | 2006-11-14 | Granted | United States of America | Capacitor For Integration With Copper Damascene Processes And A Method Of Manufacture Therefor |
| 09580530 | 6333508 | 2000-05-30 | 2001-12-25 | Granted | United States of America | Illumination System For Electron Beam Lithography Tool |
| 09414004 | 7345290 | 1999-10-07 | 2008-03-18 | Granted | United States of America | Lens Array For Electron Beam Lithography Tool |
| 09642376 | 6534851 | 2000-08-21 | 2003-03-18 | Granted | United States of America | Modular Semiconductor Substrates |
| 10303280 | 6713409 | 2002-11-25 | 2004-03-30 | Granted | United States of America | Semiconductor Manufacturing Using Modular Substrates |
| 09557536 | 6387772 | 2000-04-25 | 2002-05-14 | Granted | United States of America | Method For Forming Trenches Capacitors In Soi Substrates |
| 10072500 | 6552381 | 2002-02-05 | 2003-04-22 | Granted | United States of America | Trench Capacitors In Soi Substrates |
| 09654689 | 6613651 | 2000-09-05 | 2003-09-02 | Lapsed | United States of America | Integrated circuit isolation system |
| 10383031 | 6831348 | 2003-03-06 | 2004-12-14 | Lapsed | United States of America | Integrated circuit isolation system |
| 09737504 | 6271911 | 2000-12-15 | 2001-08-07 | Granted | United States of America | Apparatus for enhancing image contrast using intensity filtration |
| 09557946 | 6549322 | 2000-04-24 | 2003-04-15 | Granted | United States of America | Method and apparatus for enhancing image contrast using intensity filtration |
| 10368812 | 7033710 | 2003-02-18 | 2006-04-25 | Lapsed | United States of America | Method and apparatus for enhancing image contrast using intensity filtration |
| 09106720 | | 1998-06-29 | | Abandoned | United States of America | Method and Apparatus for Enhancing Image Contrast Using Intensity Filtration |
| 10418560 | 6861864 | 2003-04-16 | 2005-03-01 | Lapsed | United States of America | Self-timed reliability and yield vehicle array |
| 10900642 | 7308627 | 2004-07-27 | 2007-12-11 | Granted | United States of America | Self-timed reliability and yield vehicle with gated data and clock |
| 10909821 | | 2004-08-02 | | Abandoned | United States of America | Semiconductor Wafer Chuck Assembly for a Semiconductor Processing Device |
| 10461255 | 6805338 | 2003-06-13 | 2004-10-19 | Granted | United States of America | Semiconductor wafer chuck assembly for a semiconductor processing device |
| 09540473 | 6373266 | 2000-03-31 | 2002-04-16 | Granted | United States of America | Apparatus And Method For Determining Process Width Variations In Integrated Circuits |
| 10053097 | 6728940 | 2002-01-18 | 2004-04-27 | Granted | United States of America | Apparatus And Method For Determining Process Width Variations In Integrated Circuits |
| 09466715 | 6458648 | 1999-12-17 | 2002-10-01 | Granted | United States of America | Method For In-Situ Removal Of Side Walls In MOM Capacitor Formation |
| 10215170 | 6656850 | 2002-08-08 | 2003-12-02 | Granted | United States of America | Method For In-Situ Removal Of Side Walls In MOM Capacitor Formation |
| 10147384 | 6683382 | 2002-05-16 | 2004-01-27 | Granted | United States of America | Semiconductor Device Having An Interconnect Layer With A Plurality Of Layout Regions Having Substantially Uniform Densities Of Active Interconnects And Dummy Fills |

Schedule B(1)(b) – Semic Processing B

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------|----------|------------|------------|-----------|--------------------------|---|
| 09484310 | 6436807 | 2000-01-18 | 2002-08-20 | Granted | United States of America | Method For Making An Interconnect Layer And A Semiconductor Device Including The Same |
| 10414601 | 7276441 | 2003-04-15 | 2007-10-02 | Granted | United States of America | Dielectric barrier layer for increasing electromigration lifetimes in copper interconnect structures |
| 12764004 | 8043968 | 2010-04-20 | 2011-10-25 | Granted | United States of America | Dielectric Barrier Layer For Increasing Electromigration Lifetimes In Copper Interconnect Structures |
| 11736402 | 7728433 | 2007-04-17 | 2010-06-01 | Lapsed | United States of America | Dielectric Barrier Layer For Increasing Electromigration Lifetimes In Copper Interconnect Structures |
| 09861839 | 6475931 | 2001-05-21 | 2002-11-05 | Granted | United States of America | Method For Producing Devices Having Piezoelectric Films |
| 09502868 | 6329305 | 2000-02-11 | 2001-12-11 | Granted | United States of America | Method For Producing Devices Having Piezoelectric Films |
| 10418375 | 6982229 | 2003-04-18 | 2006-01-03 | Lapsed | United States of America | Ion recoil implantation and enhanced carrier mobility in CMOS device |
| 11098290 | 7129516 | 2005-04-04 | 2006-10-31 | Lapsed | United States of America | Ion recoil implantation and enhanced carrier mobility in CMOS device |
| 10360903 | 6874510 | 2003-02-07 | 2005-04-05 | Lapsed | United States of America | Method to use a laser to perform the edge clean operation on a semiconductor wafer |
| 11014476 | | 2004-12-16 | | Abandoned | United States of America | Method to Use a Laser to Perform the Edge Clean Operation on a Semiconductor Wafer |
| 08791244 | 6117736 | 1997-01-30 | 2000-09-12 | Expired | United States of America | Method of fabricating insulated-gate field-effect transistors having different gate capacitances |
| 09594478 | 6300663 | 2000-06-15 | 2001-10-09 | Expired | United States of America | Insulated-gate field-effect transistors having different gate capacitances |
| 09665988 | 6553166 | 2000-09-20 | 2003-04-22 | Lapsed | United States of America | Concentric optical cable with full duplex connectors |
| 09956409 | | 2001-09-19 | | Abandoned | United States of America | Parallel Active Optical SCSI Cable |
| 10697506 | 7323228 | 2003-10-29 | 2008-01-29 | Granted | United States of America | Method of vaporizing and ionizing metals for use in semiconductor processing |
| 11939482 | 7670645 | 2007-11-13 | 2010-03-02 | Lapsed | United States of America | Method of Treating Metal and Metal Salts to Enable Thin Layer Deposition in Semiconductor Processing |
| 10253158 | 6713394 | 2002-09-24 | 2004-03-30 | Granted | United States of America | Process for planarization of integrated circuit structure which inhibits cracking of low dielectric constant dielectric material adjacent underlying raised structures |
| 09661465 | 6489242 | 2000-09-13 | 2002-12-03 | Granted | United States of America | Process for planarization of integrated circuit structure which inhibits cracking of low dielectric constant dielectric material adjacent underlying raised structures |
| 09724225 | 6521549 | 2000-11-28 | 2003-02-18 | Granted | United States of America | Method of reducing silicon oxynitride gate insulator thickness in some transistors of a hybrid integrated circuit to obtain increased differential in gate insulator thickness with other transistors of the hybrid circuit |

Schedule B(1)(b) – Semic Processing B

| App.No | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------|----------|------------|------------|-----------|--------------------------|---|
| 10304631 | 6656805 | 2002-11-26 | 2003-12-02 | Lapsed | United States of America | Method of reducing silicon oxynitride gate insulator thickness in some transistors of a hybrid integrated circuit to obtain increased differential in gate insulator thickness with other transistors of the hybrid circuit |
| 10205229 | 6566268 | 2002-07-25 | 2003-05-20 | Granted | United States of America | Method and apparatus for planarizing a wafer surface of a semiconductor wafer having an elevated portion extending therefrom |
| 09364140 | 6451699 | 1999-07-30 | 2002-09-17 | Granted | United States of America | Method and apparatus for planarizing a wafer surface of a semiconductor wafer having an elevated portion extending therefrom |
| 09517150 | 6479857 | 2000-03-02 | 2002-11-12 | Lapsed | United States of America | Capacitor having a tantalum lower electrode and method of forming the same |
| 10228859 | 6861310 | 2002-08-27 | 2005-03-01 | Lapsed | United States of America | Capacitor having a tantalum lower electrode and method of forming the same |
| 12191171 | 7646077 | 2008-08-13 | 2010-01-12 | Granted | United States of America | Dielectric Barrier Films For Use As Copper Barrier Layers in Semiconductor Trench And Via Structures |
| 10321938 | 6939800 | 2002-12-16 | 2005-09-06 | Lapsed | United States of America | Dielectric barrier films for use as copper barrier layers in semiconductor trench and via structures |
| 11131003 | 7427563 | 2005-05-16 | 2008-09-23 | Granted | United States of America | Dielectric barrier films for use as copper barrier layers in semiconductor trench and via structures |
| 09723516 | 6436845 | 2000-11-28 | 2002-08-20 | Granted | United States of America | Silicon nitride and silicon dioxide gate insulator transistors and method of forming same in a hybrid integrated circuit |
| 10171700 | 6562729 | 2002-06-14 | 2003-05-13 | Granted | United States of America | Silicon nitride and silicon dioxide gate insulator transistors and method of forming same in a hybrid integrated circuit |
| 10195044 | 6858531 | 2002-07-12 | 2005-02-22 | Granted | United States of America | Electro chemical mechanical polishing method |
| 11007694 | 7285145 | 2004-12-07 | 2007-10-23 | Granted | United States of America | Electro chemical mechanical polishing method and device for planarizing semiconductor surfaces |
| 10131431 | 6627556 | 2002-04-24 | 2003-09-30 | Granted | United States of America | Method of chemically altering a silicon surface and associated electrical devices |
| 10600665 | 6822308 | 2003-06-20 | 2004-11-23 | Lapsed | United States of America | Method of chemically altering a silicon surface and associated electrical devices |
| 10195775 | 6673200 | 2002-07-12 | 2004-01-06 | Granted | United States of America | Method of reducing process plasma damage using optical spectroscopy |
| 60384499 | | 1900-01-01 | | Abandoned | United States of America | Impact of F Species on Plasma Charge Damage in a RF Aher |
| 10680503 | 6972840 | 2003-10-06 | 2005-12-06 | Lapsed | United States of America | Method of reducing process plasma damage using optical spectroscopy |
| 10210365 | 6641698 | 2002-08-01 | 2003-11-04 | Granted | United States of America | Integrated circuit fabrication dual plasma process with separate introduction of different gases into gas flow |

Schedule B(1)(b) - Semic Processing B

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------|----------|------------|------------|-----------|--------------------------|--|
| 09747638 | 6461972 | 2000-12-22 | 2002-10-08 | Granted | United States of America | Integrated circuit fabrication dual plasma process with separate introduction of different gases into gas flow |
| 12034750 | | 2008-02-21 | | Abandoned | United States of America | Laser-Marking Hole Shape Of Semiconductor Wafer |
| 10020764 | 7371659 | 2001-12-12 | 2008-05-13 | Granted | United States of America | Substrate laser marking |
| 09617550 | 6569751 | 2000-07-17 | 2003-05-27 | Granted | United States of America | Low Via resistance system |
| 10400252 | 6893962 | 2003-03-27 | 2005-05-17 | Granted | United States of America | Low Via resistance system |
| 09395507 | 6328802 | 1999-09-14 | 2001-12-11 | Granted | United States of America | Method and apparatus for determining temperature of a semiconductor wafer during fabrication thereof |
| 09952540 | 6794310 | 2001-09-14 | 2004-09-21 | Granted | United States of America | Method and apparatus for determining temperature of a semiconductor wafer during fabrication thereof |
| 11381409 | | 2006-05-03 | | Abandoned | United States of America | Adjustable Transmission Phase Shift Mask |
| 10972898 | 7067223 | 2004-10-25 | 2006-06-27 | Lapsed | United States of America | Adjustable transmission phase shift mask |
| 10039508 | 6841308 | 2001-11-09 | 2005-01-11 | Lapsed | United States of America | Adjustable transmission phase shift mask |
| 09670448 | 6486064 | 2000-09-26 | 2002-11-26 | Granted | United States of America | Shallow junction formation |
| 10268736 | 6605846 | 2002-10-10 | 2003-08-12 | Granted | United States of America | Shallow junction formation |
| 09212315 | 6358819 | 1998-12-15 | 2002-03-19 | Granted | United States of America | Dual gate oxide process for deep submicron ICS |
| 10026282 | | 2001-12-21 | | Abandoned | United States of America | Dual Gate Oxide Process for Deep Submicron ICS |
| 60314148 | | 1900-01-01 | | Abandoned | United States of America | Process Enhancement to Prevent LI or Borderless Contact To Well Leakage |
| 10360746 | 6893937 | 2003-02-05 | 2005-05-17 | Granted | United States of America | Method for preventing borderless contact to well leakage |
| 11104050 | 7098515 | 2005-04-11 | 2006-08-29 | Lapsed | United States of America | Semiconductor chip with borderless contact that avoids well leakage |
| 10006540 | 6551901 | 2001-11-30 | 2003-04-22 | Granted | United States of America | Method for preventing borderless contact to well leakage |
| 12574426 | 8021955 | 2009-10-06 | 2011-09-20 | Granted | United States of America | Method Characterizing Materials For A Trench Isolation Structure Having Low Trench Parasitic Capacitance |
| 11262173 | 7619294 | 2005-10-28 | 2009-11-17 | Lapsed | United States of America | Shallow Trench Isolation Structure With Low Trench Parasitic Capacitance |
| 09991202 | 7001823 | 2001-11-14 | 2006-02-21 | Lapsed | United States of America | Method of manufacturing a shallow trench isolation structure with low trench parasitic capacitance |
| 10196787 | 6787180 | 2002-07-17 | 2004-09-07 | Granted | United States of America | Exhaust flow control system |
| 09666507 | 6579371 | 2000-09-20 | 2003-06-17 | Granted | United States of America | Exhaust flow control system |
| 09952790 | 6964924 | 2001-09-11 | 2005-11-15 | Lapsed | United States of America | Integrated circuit process monitoring and metrology system |
| 11072127 | 7115425 | 2005-03-04 | 2006-10-03 | Lapsed | United States of America | Integrated circuit process monitoring and metrology system |
| 10044864 | 7115991 | 2001-10-22 | 2006-10-03 | Lapsed | United States of America | Method for creating barriers for copper diffusion |
| 11104763 | 7829455 | 2005-04-12 | 2010-11-09 | Granted | United States of America | Method For Creating Barriers For Copper Diffusion |
| 09879642 | 6495312 | 2001-06-12 | 2002-12-17 | Granted | United States of America | Method and apparatus for removing photoresist edge beads from thin film substrates |

Schedule B(1)(b) -- Semic Processing B

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------|----------|------------|------------|-----------|--------------------------|---|
| 10263593 | 6614507 | 2002-10-03 | 2003-09-02 | Granted | United States of America | Apparatus for removing photoresist edge beads from thin film substrates |
| 09775223 | | 2001-02-01 | | Abandoned | United States of America | Method and Apparatus for Removing Photoresist Edge Beads From Thin Film Substrates |
| 11927950 | 7579245 | 2007-10-30 | 2009-08-25 | Lapsed | United States of America | Dual-Gate Metal-Oxide Semiconductor Device |
| 10999705 | 7329922 | 2004-11-30 | 2008-02-12 | Granted | United States of America | Dual\imgate Metal\imgate Semiconductor Device |
| 10688231 | 7005703 | 2003-10-17 | 2006-02-28 | Lapsed | United States of America | Metal-Oxide Semiconductor Device Having Improved Performance And Reliability. |
| 11348597 | 7335565 | 2006-02-07 | 2008-02-26 | Granted | United States of America | Metal\imgate Semiconductor Device Having Improved Performance And Reliability. |
| 09083072 | 6024829 | 1998-05-21 | 2000-02-15 | Granted | United States of America | Method Of Eliminating Agglomerate Particles In A Polishing Slurry |
| 09427306 | 6355184 | 1999-10-26 | 2002-03-12 | Granted | United States of America | A Method Of Eliminating Agglomerate Particles In A Polishing Slurry |
| 09992135 | 6750145 | 2001-11-14 | 2004-06-15 | Granted | United States of America | A Method Of Eliminating Agglomerate Particles In A Polishing Slurry |
| 09878657 | 6482694 | 2001-06-11 | 2002-11-19 | Granted | United States of America | Semiconductor Device Structure Including A Tantalum Pentoxide Layer Sandwiched Between Silicon Nitride Layers |
| 09259001 | 6294807 | 1999-02-26 | 2001-09-25 | Granted | United States of America | Semiconductor Device Structure Including A Tantalum Pentoxide Layer Sandwiched Between Silicon Nitride Layers |
| 09894117 | 6439972 | 2001-06-28 | 2002-08-27 | Granted | United States of America | Polishing Fluid, Polishing Method, Semiconductor Device And Semiconductor Device Fabrication Method |
| 09483785 | 6328633 | 2000-01-14 | 2001-12-11 | Granted | United States of America | Polishing Fluid, Polishing Method, Semiconductor Device And Semiconductor Device Fabrication Method |
| 09461609 | 6409829 | 1999-12-15 | 2002-06-25 | Granted | United States of America | Manufacture Of Dielectrically Isolated Integrated Circuits |
| 10091291 | 6727567 | 2002-03-05 | 2004-04-27 | Granted | United States of America | Integrated Circuit Device Substrates With Selective Epitaxial Growth Thickness Compensation |
| 10762962 | 7276767 | 2004-01-22 | 2007-10-02 | Granted | United States of America | A Thin Film Resistor Device And A Method Of Manufacture Therefor |
| 09614992 | 6703666 | 2000-07-12 | 2004-03-09 | Granted | United States of America | A Thin Film Resistor Device And A Method Of Manufacture Therefor |
| 08347527 | 6445043 | 1994-11-30 | 2002-09-03 | Granted | United States of America | Process For Forming Isolation Regions In An Integrated Circuit and Structure Formed Thereby |
| 08620964 | 5763314 | 1996-03-22 | 1998-06-09 | Expired | United States of America | Process For Forming Isolation Regions In An Integrated Circuit |
| 08668310 | 5641994 | 1996-06-26 | 1997-06-24 | Expired | United States of America | Multilayered Al-alloy Structure For Metal Conductors |
| 08365652 | 5561083 | 1994-12-29 | 1996-10-01 | Expired | United States of America | Method of Making Multilayered Al-alloy Structure For Metal Conductors |
| 10750348 | 6969683 | 2003-12-31 | 2005-11-29 | Granted | United States of America | Method of preventing resist poisoning in dual damascene structures |
| 10025304 | 6713386 | 2001-12-19 | 2004-03-30 | Granted | United States of America | Method of preventing resist poisoning in dual damascene structures |
| 09962641 | 6495875 | 2001-09-25 | 2002-12-17 | Granted | United States of America | Method Of Forming Metal Oxide Metal Capacitors Using Multi-Step Rapid Thermal Process And A Device Formed Thereby |

Schedule B(1)(b) – Semic Processing B

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------|----------|------------|------------|---------|--------------------------|---|
| 09418106 | 6323078 | 1999-10-14 | 2001-11-27 | Granted | United States of America | A Method Of Forming Metal Oxide Metal Capacitors Using Multi-Step Rapid Thermal Process And A Device Formed Thereby |
| 12243137 | 7713811 | 2008-10-01 | 2010-05-11 | Lapsed | United States of America | Multiple Doping Level Bipolar Junctions Transistors And Method For Forming |
| 12727304 | 7910425 | 2010-03-19 | 2011-03-22 | Granted | United States of America | Multiple Doping Level Bipolar Junctions Transistors And Method For Forming |
| 10953894 | 7095094 | 2004-09-29 | 2006-08-22 | Lapsed | United States of America | Multiple Doping Level Bipolar Junctions Transistors And Method For Forming |
| 13026528 | 8143120 | 2011-02-14 | 2012-03-27 | Granted | United States of America | Multiple Doping Level Bipolar Junctions Transistors And Method For Forming |
| 11458270 | 7449388 | 2006-07-18 | 2008-11-11 | Lapsed | United States of America | Method For Forming Multiple Doping Level Bipolar Junctions Transistors |
| 10953292 | 7061264 | 2004-09-29 | 2006-06-13 | Lapsed | United States of America | Test Semiconductor Device And Method For Determining Joule Heating Effects In Such A Device |
| 11403750 | 7388395 | 2006-04-13 | 2008-06-17 | Granted | United States of America | Test Semiconductor Device And Method For Determining Joule Heating Effects In Such A Device |
| 09940126 | 6573149 | 2001-08-27 | 2003-06-03 | Granted | United States of America | A Semiconductor Device Having A Metal Gate With A Work Function Compatible With A Semiconductor Device |
| 10003871 | 6579775 | 2001-10-24 | 2003-06-17 | Granted | United States of America | A Semiconductor Device Having A Metal Gate With A Work Function Compatible With A Semiconductor Device |
| 09572060 | 6383879 | 2000-05-17 | 2002-05-07 | Granted | United States of America | A Semiconductor Device Having A Metal Gate With A Work Function Compatible With A Semiconductor Device |
| 09886780 | 6649422 | 2001-06-21 | 2003-11-18 | Granted | United States of America | Integrated Circuit Having A Micromagnetic Device And Method Of Manufacture Therefor |
| 09338143 | 6255714 | 1999-06-22 | 2001-07-03 | Granted | United States of America | An Integrated Circuit Having A Micromagnetic Device And Method Of Manufacture Therefor |
| 09578082 | 6465884 | 2000-05-24 | 2002-10-15 | Granted | United States of America | Semiconductor Device With Variable Pin Locations |
| 10218783 | 6833286 | 2002-08-14 | 2004-12-21 | Granted | United States of America | Semiconductor Device With Variable Pin Locations |
| 10038734 | 6762459 | 2001-12-31 | 2004-07-13 | Granted | United States of America | Method For Fabricating MOS Device With Halo Implanted Region |
| 09523782 | 6362054 | 2000-03-13 | 2002-03-26 | Granted | United States of America | Method For Fabricating MOS Device With Halo Implanted Region |
| 09015981 | 6153920 | 1998-01-30 | 2000-11-28 | Expired | United States of America | A Semiconductor Device Configured to Control Dopant Diffusion In the Semiconductor Device Substrate |
| 08862226 | 5731626 | 1997-05-23 | 1998-03-24 | Expired | United States of America | Process For Controlling Dopant Diffusion In A Semiconductor Layer And Semiconductor Layer Formed Thereby |
| 08848113 | 5982020 | 1997-04-28 | 1999-11-09 | Expired | United States of America | Deuterated Bipolar Transistors And Method Of Manufacture Thereof |
| 09386592 | 6309938 | 1999-08-31 | 2001-10-30 | Expired | United States of America | Deuterated Bipolar Transistors And Method Of Manufacture Thereof |

Schedule B(1)(b) - Semic Processing B

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------|----------|------------|------------|-----------|--------------------------|--|
| 09261346 | 6153020 | 1999-03-03 | 2000-11-28 | Granted | United States of America | Process For Fabricating Improved Iron-Cobalt Magnetostrictive Alloy And Article Comprising Alloy |
| 09500855 | 6299703 | 2000-02-09 | 2001-10-09 | Granted | United States of America | Process For Fabricating Improved Iron-Cobalt Magnetostrictive Alloy And Article Comprising Alloy |
| 11649197 | 7670203 | 2007-01-03 | 2010-03-02 | Lapsed | United States of America | Process For Making An On-Chip Vacuum Tube Device |
| 09651696 | 7259510 | 2000-08-30 | 2007-08-21 | Granted | United States of America | On-Chip Vacuum Tube Device And Process For Making Device |
| 08881293 | 5811796 | 1997-06-24 | 1998-09-22 | Expired | United States of America | Optical Probe Microscope Having A Fiber Optic Tip That Receives Both A Dither Motion And A Scanning Motion, For Nondestructive Metrology Of Large Sample Surfaces |
| 08657390 | 5693938 | 1996-06-03 | 1997-12-02 | Expired | United States of America | Optical Probe Microscope Having A Fiber Optic Tip That Receives Both A Dither Motion And A Scanning Motion, For Nondestructive Metrology Of Large Sample Surfaces |
| 11748569 | 7407824 | 2007-05-15 | 2008-08-05 | Granted | United States of America | Guard Ring For Improved Matching |
| 10941665 | 7253012 | 2004-09-14 | 2007-08-07 | Granted | United States of America | Guard Ring For Improved Matching |
| 09456224 | 6576529 | 1999-12-07 | 2003-06-10 | Granted | United States of America | A Method Of Forming An Alignment Feature In Or On A Multi-Layered Semiconductor Structure |
| 10704449 | 6977128 | 2003-11-07 | 2005-12-20 | Lapsed | United States of America | Multi-Layered Semiconductor Structure |
| 09867202 | 6706609 | 2001-05-29 | 2004-03-16 | Granted | United States of America | Method Of Forming An Alignment Feature In Or On A Multi-Layered Semiconductor Structure |
| 10360276 | | 2003-02-07 | | Abandoned | United States of America | Two-Step Oxidation Process For Oxidizing A Silicon Substrate Wherein The First Step Is Carried Out At A Temperature Below The Viscoelastic Temperature Of Silicon Dioxide And The Second Step Is Carried Out At A Temperature Above The Viscoelastic Temperature |
| 09597076 | 6551946 | 2000-06-20 | 2003-04-22 | Granted | United States of America | Two-Step Oxidation Process For Oxidizing A Silicon Substrate Wherein The First Step Is Carried Out At A Temperature Below The Viscoelastic Temperature Of Silicon Dioxide And The Second Step Is Carried Out At A Temperature Above The Viscoelastic Temperature |
| 10316386 | 7148153 | 2002-12-11 | 2006-12-12 | Granted | United States of America | Process For Oxide Fabrication Using Oxidation Steps Below And Above A Threshold Temperature |
| 11385156 | 7282461 | 2006-03-21 | 2007-10-16 | Granted | United States of America | Phase-Shifting Mask And Semiconductor Device |
| 10655050 | 7053405 | 2003-09-04 | 2006-05-30 | Lapsed | United States of America | Phase-Shifting Mask And Semiconductor Device |
| 09488662 | 6638663 | 2000-01-20 | 2003-10-28 | Granted | United States of America | Phase-Shifting Mask And Semiconductor Device |
| 09533428 | 6312565 | 2000-03-23 | 2001-11-06 | Granted | United States of America | Thin Film Deposition Of Mixed Metal Oxides |
| 09917365 | 6540974 | 2001-07-27 | 2003-04-01 | Granted | United States of America | Process For Making Mixed Metal Oxides |
| 10819253 | 7242056 | 2004-04-05 | 2007-07-10 | Granted | United States of America | Structure And Fabrication Method For Capacitors Integratable With Vertical Replacement Gate Transistors |

Schedule B(1)(b) – Semic Processing B

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------|----------|------------|------------|-----------|--------------------------|--|
| 11809686 | 7633118 | 2007-05-31 | 2009-12-15 | Lapsed | United States of America | Structure And Fabrication Method For Capacitors Integratable With Vertical Replacement Gate Transistors |
| 12319603 | 7700432 | 2009-01-09 | 2010-04-20 | Lapsed | United States of America | Method of Fabricating a Vertical Transistor and Capacitor |
| 11809873 | 7491610 | 2007-06-01 | 2009-02-17 | Granted | United States of America | Fabrication Method |
| 09956381 | | 2001-09-18 | | Abandoned | United States of America | An Integratable Vertical Replacement Gate (VRG)-type Poly-Nitride-Poly (PNP) Or Metal-Nitride-poly (MNP) Capacitor |
| 12610733 | 7911006 | 2009-11-02 | 2011-03-22 | Granted | United States of America | Structure And Fabrication Method For Capacitors Integratable With Vertical Replacement Gate Transistors |
| 09137920 | 6215130 | 1998-08-20 | 2001-04-10 | Granted | United States of America | Thin Film Transistors |
| 09450522 | 6232157 | 1999-11-29 | 2001-05-15 | Granted | United States of America | Thin Film Transistors |
| 09280103 | 6252245 | 1999-03-29 | 2001-06-26 | Granted | United States of America | Device Comprising N-Channel Semiconductor Material |
| 09476511 | 6387727 | 2000-01-03 | 2002-05-14 | Granted | United States of America | Device Comprising N-Channel Semiconductor Material |
| 09276912 | 6187427 | 1999-03-27 | 2001-02-13 | Expired | United States of America | Hybrid Inorganic\miOrganic Composite For Use As An Interlayer Dielectric |
| 08911489 | 5965202 | 1997-08-14 | 1999-10-12 | Expired | United States of America | Hybrid Inorganic\miOrganic Composite For Use As An Interlayer Dielectric |
| 09339895 | 6320238 | 1999-06-25 | 2001-11-20 | Granted | United States of America | A Gate Stack Structure For Integrated Circuit Fabrication |
| 08995435 | 6548854 | 1997-12-22 | 2003-04-15 | Granted | United States of America | Compound, High-k, Gate And Capacitor Insulator Layer |
| 08872250 | 6118351 | 1997-06-10 | 2000-09-12 | Expired | United States of America | A Micromagnetic Device For Power Processing Applications And Method Of Manufacture Therefor |
| 09292860 | 6191495 | 1999-04-16 | 2001-02-20 | Expired | United States of America | Micromagnetic Device Having An Anisotropic Ferromagnetic Core and Method of Manufacture Therefor |
| 09511343 | 6440750 | 2000-02-23 | 2002-08-27 | Expired | United States of America | Method Of Making Integrated Circuit Having A Micromagnetic Device |
| 10387846 | 7021518 | 2003-03-13 | 2006-04-04 | Lapsed | United States of America | Micromagnetic Device For Power Processing Applications And Method Of Manufacture Therefor |
| 09978871 | 6696744 | 2001-10-15 | 2004-02-24 | Expired | United States of America | Integrated Circuit Having A Micromagnetic Device And Method Of Manufacture Therefor |
| 09109963 | 6163234 | 1998-07-02 | 2000-12-19 | Expired | United States of America | A Micromagnetic Device For Data Transmission Applications And Method Of Manufacture Therefor |
| 09490655 | 6160721 | 2000-01-24 | 2000-12-12 | Expired | United States of America | A Micromagnetic Device For Power Processing Applications And Method Of Manufacture Therefor |
| 08718113 | 5804975 | 1996-09-18 | 1998-09-08 | Expired | United States of America | Detecting Breakdown In Dielectric Layers |
| 09002497 | 6043662 | 1998-01-02 | 2000-03-28 | Expired | United States of America | Detecting Defects In Integrated Circuits |
| 12502057 | 8097179 | 2009-07-13 | 2012-01-17 | Granted | United States of America | Arrangement And Method For Abating Effluent From A Process |
| 09942330 | 7578883 | 2001-08-29 | 2009-08-25 | Lapsed | United States of America | Arrangement And Method For Abating Effluent From A Process |
| 08353015 | 5576240 | 1994-12-09 | 1996-11-19 | Expired | United States of America | Method for Making A Metal to metal Capacitor |
| 08644086 | 5851870 | 1996-05-09 | 1998-12-22 | Expired | United States of America | Method For Making A Capacitor |

Schedule B(1)(b) -- Semic Processing B

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------|----------|------------|------------|-----------|--------------------------|--|
| 08472033 | 5654581 | 1995-06-06 | 1997-08-05 | Expired | United States of America | Integrated Circuit Capacitor |
| 08909563 | 6040616 | 1997-08-12 | 2000-03-21 | Expired | United States of America | A Device and Method of Forming A Metal To Metal Capacitor Within an Integrated Circuit |
| 08863713 | 5825073 | 1997-05-27 | 1998-10-20 | Expired | United States of America | An Electronic Component For An Integrated Circuit |
| 09081403 | 6239491 | 1998-05-18 | 2001-05-29 | Granted | United States of America | Integrated circuit structure with thin dielectric between at least local interconnect level and first metal interconnect level and process for making same |
| 09790821 | 6486056 | 2001-02-22 | 2002-11-26 | Granted | United States of America | Process for making integrated circuit structure with thin dielectric between at least local interconnect level and first metal interconnect level |
| 09741568 | 6576404 | 2000-12-19 | 2003-06-10 | Granted | United States of America | Carbon-doped hard mask and method of passivating structures during semiconductor device fabrication |
| 10405666 | 6846569 | 2003-04-02 | 2005-01-25 | Granted | United States of America | Carbon-doped hard mask and method of passivating structures during semiconductor device fabrication |
| 09607169 | 6541383 | 2000-06-29 | 2003-04-01 | Granted | United States of America | Apparatus and method for planarizing the surface of a semiconductor wafer |
| 10336444 | | 2003-01-03 | | Abandoned | United States of America | Apparatus and Method for Planarizing the Surface of a Semiconductor Wafer |
| 09098635 | 6060370 | 1998-06-16 | 2000-05-09 | Granted | United States of America | Method for shallow trench isolations with chemical-mechanical polishing |
| 09507042 | 6424019 | 2000-02-18 | 2002-07-23 | Granted | United States of America | Shallow trench isolation chemical-mechanical polishing process |
| 09442078 | 6179956 | 1999-11-16 | 2001-01-30 | Granted | United States of America | Method and apparatus for using across wafer back pressure differentials to influence the performance of chemical mechanical polishing |
| 09005364 | 6531397 | 1998-01-09 | 2003-03-11 | Granted | United States of America | Method and apparatus for using across wafer back pressure differentials to influence the performance of chemical mechanical polishing |
| 08976033 | 5994211 | 1997-11-21 | 1999-11-30 | Granted | United States of America | Method and composition for reducing gate oxide damage during RF sputter clean |
| 09251702 | 6204550 | 1999-02-17 | 2001-03-20 | Granted | United States of America | Method and composition for reducing gate oxide damage during RF sputter clean |
| 10640778 | 6943042 | 2003-08-13 | 2005-09-13 | Lapsed | United States of America | Method of detecting spatially correlated variations in a parameter of an integrated circuit die |
| 10020407 | 6787379 | 2001-12-12 | 2004-09-07 | Granted | United States of America | Method of detecting spatially correlated variations in a parameter of an integrated circuit die |
| 08924903 | 5981352 | 1997-09-08 | 1999-11-09 | Expired | United States of America | Consistent alignment mark profiles on semiconductor wafers using fine grain tungsten protective layer |

Schedule B(1)(b) - Semic Processing B

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------|----------|------------|------------|-----------|--------------------------|--|
| 09361684 | 6060787 | 1999-07-27 | 2000-05-09 | Expired | United States of America | Consistent alignment mark profiles on semiconductor wafers using fine grain tungsten protective layer |
| 08925200 | 5966613 | 1997-09-08 | 1999-10-12 | Expired | United States of America | Consistent alignment mark profiles on semiconductor wafers using metal organic chemical vapor deposition titanium nitride protective |
| 09289828 | 6157087 | 1999-04-12 | 2000-12-05 | Expired | United States of America | Consistent alignment mark profiles on semiconductor wafers using metal organic chemical vapor deposition titanium nitride protective layer |
| 10306011 | 6891219 | 2002-11-26 | 2005-05-10 | Granted | United States of America | Metal-insulator-metal capacitor formed by damascene processes between metal interconnect layers and method of forming same |
| 09723434 | 6524926 | 2000-11-27 | 2003-02-25 | Granted | United States of America | Metal-insulator-metal capacitor formed by damascene processes between metal interconnect layers and method of forming same |
| 08861899 | | 1997-05-22 | | Abandoned | United States of America | Integrated Circuit With Isolation Of Field Oxidation By Noble Gas Implantation And Method Of Making Such An Integrated Circuit |
| 08479104 | | 1995-06-07 | | Abandoned | United States of America | Integrated Circuit With Isolation Of Field Oxidation By Noble Gas Implantation And Method Of Making Such An Integrated Circuit |
| 08641027 | | 1996-04-29 | | Abandoned | United States of America | Integrated circuit with isolation of field oxidation by noble gas implantation |
| 08918577 | 6093936 | 1997-08-19 | 2000-07-25 | Expired | United States of America | Functional OBIC analysis |
| 08701476 | 5905381 | 1996-08-22 | 1999-05-18 | Expired | United States of America | Functional OBIC analysis |
| 09244327 | 6154039 | 1999-02-03 | 2000-11-28 | Expired | United States of America | Functional OBIC analysis |
| 09526101 | 6383414 | 2000-03-15 | 2002-05-07 | Expired | United States of America | Use of corrosion inhibiting compounds to inhibit corrosion of metal plugs in chemical-mechanical polishing |
| 08918360 | 6068879 | 1997-08-26 | 2000-05-30 | Expired | United States of America | Use of corrosion inhibiting compounds to inhibit corrosion of metal plugs in chemical-mechanical polishing |
| 08889839 | 5895267 | 1997-07-09 | 1999-04-20 | Expired | United States of America | Method to obtain a low resistivity and conformity chemical vapor deposition titanium film |
| 09218780 | 6297555 | 1998-12-22 | 2001-10-02 | Expired | United States of America | Method to obtain a low resistivity and conformity chemical vapor deposition titanium film |
| 09388727 | 6359314 | 1999-09-02 | 2002-03-19 | Granted | United States of America | Swapped drain structures for electrostatic discharge protection |
| 10026186 | 6587322 | 2001-12-20 | 2003-07-01 | Granted | United States of America | Swapped drain structures for electrostatic discharge protection |
| 09177335 | 6201253 | 1998-10-22 | 2001-03-13 | Granted | United States of America | Method and apparatus for detecting a planarized outer layer of a semiconductor wafer with a confocal optical system |
| 09754429 | 6354908 | 2001-01-04 | 2002-03-12 | Granted | United States of America | Method and apparatus for detecting a planarized outer layer of a semiconductor wafer with a confocal optical system |
| 09863979 | | 2001-05-23 | | Abandoned | United States of America | Method and Apparatus for Deposition of Porous Silica Dielectrics |
| 09302832 | 6287987 | 1999-04-30 | 2001-09-11 | Granted | United States of America | Method and apparatus for deposition of porous silica dielectrics |

Schedule B(1)(b) – Semic Processing B

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|------------|----------|------------|------------|-----------|--------------------------|---|
| 10459072 | 6806162 | 2003-06-11 | 2004-10-19 | Lapsed | United States of America | Method for composing a dielectric layer within an interconnect structure of a multilayer semiconductor device |
| 09164069 | 6614097 | 1998-09-30 | 2003-09-02 | Lapsed | United States of America | Method for composing a dielectric layer within an interconnect structure of a multilayer semiconductor device |
| 09162407 | 6211555 | 1998-09-29 | 2001-04-03 | Granted | United States of America | Semiconductor device with a pair of transistors having dual work function gate electrodes |
| 09591108 | 6514824 | 2000-06-09 | 2003-02-04 | Granted | United States of America | Semiconductor device with a pair of transistors having dual work function gate electrodes |
| 08954006 | 6096625 | 1997-10-20 | 2000-08-01 | Expired | United States of America | Method for improved gate oxide integrity on bulk silicon |
| 08720514 | | 1996-09-30 | | Abandoned | United States of America | Method for improved Gate Oxide Integrity on Bulk Silicon |
| 61350494 | | 2010-06-02 | | Expired | United States of America | CUB eDRAM cell with local interconnects to reduce stacked contact parasitics impact |
| 13046973 | 8283713 | 2011-03-14 | 2012-10-09 | Granted | United States of America | Logic-Based eDRAM Using Local Interconnects to Reduce Impact of Extension Contact Parasitics |
| 11230188 | | 2005-09-19 | | Abandoned | United States of America | Shallow Trench Isolation Structures And A Method For Forming Shallow Trench Isolation Structures |
| 11926469 | 7906407 | 2007-10-29 | 2011-03-15 | Granted | United States of America | Shallow Trench Isolation Structures And A Method For Forming Shallow Trench Isolation Structures |
| 08430084 | 5891784 | 1995-04-27 | 1999-04-06 | Expired | United States of America | Transistor Fabrication Method |
| 08587061 | 6498080 | 1996-01-16 | 2002-12-24 | Expired | United States of America | Transistor Fabrication Method |
| 12114589 | | 2008-05-02 | | Abandoned | United States of America | Transistor Fabrication Method |
| 10224220 | | 2002-08-20 | | Abandoned | United States of America | Transistor Fabrication Method |
| 12689749 | 8030199 | 2010-01-19 | 2011-10-04 | Granted | United States of America | Transistor Fabrication Method |
| 2000079900 | 3432783 | 2000-03-22 | 2003-05-23 | Lapsed | Japan | Low Dielectric Constant Multiple Carbon-Containing Silicon Oxide Dielectric Material For Use In Integrated Circuit Structures, And Method Of Making Same |
| 09281602 | 6204192 | 1999-03-29 | 2001-03-20 | Granted | United States of America | Plasma cleaning process for openings formed in at least one low dielectric constant insulation layer over copper metallization in integrated circuit structures |
| 2001554123 | 4831802 | 2002-07-19 | 2011-09-30 | Lapsed | Japan | Mask Having An Arbitrary Complex Transmission Function |
| 09274457 | 6303047 | 1999-03-22 | 2001-10-16 | Granted | United States of America | Low dielectric constant multiple carbon-containing silicon oxide dielectric material for use in integrated circuit structures, and method of making same |
| 09362645 | 6114259 | 1999-07-27 | 2000-09-05 | Granted | United States of America | Process for treating exposed surfaces of a low dielectric constant carbon doped silicon oxide dielectric material to protect the material from damage |
| 09233828 | 6197456 | 1999-01-19 | 2001-03-06 | Granted | United States of America | Mask having an arbitrary complex transmission function |
| 09207395 | 6144076 | 1998-12-08 | 2000-11-07 | Granted | United States of America | Well formation for CMOS devices integrated circuit structures |

Schedule B(1)(b) – Semic Processing B

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|---------------|----------|------------|------------|---------|--------------------------|---|
| 1019980025571 | 537034 | 1998-06-30 | 2005-12-09 | Lapsed | Korea, Republic of (KR) | Process For Forming MOS Device In Integrated Circuit Structure Using Cobalt Silicide Contacts As Implantation Media |
| 1998068296 | 4932980 | 1998-03-18 | 2012-02-24 | Lapsed | Japan | Semiconductor Die Having On-Die Decoupling Capacitance |
| 09121283 | 6156620 | 1998-07-22 | 2000-12-05 | Granted | United States of America | Isolation trench in semiconductor substrate with nitrogen-containing barrier region, and process for forming same |
| 09097081 | 6185706 | 1998-06-12 | 2001-02-06 | Granted | United States of America | Performance monitoring circuitry for integrated circuits |
| 09321659 | 6299723 | 1999-05-28 | 2001-10-09 | Granted | United States of America | Anti-airlock apparatus for filters |
| 09321658 | 6276379 | 1999-05-28 | 2001-08-21 | Granted | United States of America | Anti-microbubble deposition apparatus |
| 09266174 | 6258514 | 1999-03-10 | 2001-07-10 | Granted | United States of America | Top surface imaging technique using a topcoat delivery system |
| 09340704 | 4054424 | 1997-11-26 | 2007-12-14 | Lapsed | Japan | Method And Apparatus Of Fourier Manipulation In An Optic Lens Or Mirror Train |
| 09045738 | 6130173 | 1998-03-19 | 2000-10-10 | Granted | United States of America | Reticle based skew lots |
| 1997355616 | 4620189 | 1997-12-24 | 2010-11-05 | Granted | Japan | A Novel Method To Improve Uniformity/Planarity On The Edge Die And Also Remove The Tungsten Stringers From Wafer Chemi-Mechanical Polishing |
| 08978979 | 6043539 | 1997-11-26 | 2000-03-28 | Granted | United States of America | Electro-static discharge protection of CMOS integrated circuits |
| 09038684 | 6033998 | 1998-03-09 | 2000-03-07 | Granted | United States of America | Method of forming variable thickness gate dielectrics |
| 08995875 | 6218276 | 1997-12-22 | 2001-04-17 | Granted | United States of America | Silicide encapsulation of polysilicon gate and interconnect |
| 08947742 | 5953614 | 1997-10-09 | 1999-09-14 | Expired | United States of America | Process for forming self-aligned metal silicide contacts for MOS structure using single silicide-forming step |
| 08944247 | 6054062 | 1997-10-06 | 2000-04-25 | Expired | United States of America | Method and apparatus for agitating an etchant |
| 08899464 | 6692338 | 1997-07-23 | 2004-02-17 | Expired | United States of America | Through-pad drainage of slurry during chemical mechanical polishing |
| 08935584 | 5888121 | 1997-09-23 | 1999-03-30 | Expired | United States of America | Controlling groove dimensions for enhanced slurry flow |
| 08912597 | 6093280 | 1997-08-18 | 2000-07-25 | Expired | United States of America | Chemical-mechanical polishing pad conditioning systems |
| 08924493 | 5913715 | 1997-08-27 | 1999-06-22 | Expired | United States of America | Use of hydrofluoric acid for effective pad conditioning |
| 08942006 | 6234883 | 1997-10-01 | 2001-05-22 | Expired | United States of America | Method and apparatus for concurrent pad conditioning and wafer buff in chemical mechanical polishing |
| 08921758 | 5941761 | 1997-08-25 | 1999-08-24 | Expired | United States of America | Shaping polishing pad to control material removal rate selectively |
| 08837618 | 5923047 | 1997-04-21 | 1999-07-13 | Expired | United States of America | Semiconductor die having sacrificial bond pads for die test |
| 08902343 | 6064220 | 1997-07-29 | 2000-05-16 | Expired | United States of America | Semiconductor integrated circuit failure analysis using magnetic imaging |
| 08899629 | 5990789 | 1997-07-24 | 1999-11-23 | Expired | United States of America | System and method for preventing smoke and fire damage to people and equipment in a clean room area from a fire |
| 08771472 | 5960305 | 1996-12-23 | 1999-09-28 | Expired | United States of America | Method to improve uniformity/planarity on the edge die and also remove the tungsten stringers from wafer chemi-mechanical polishing |
| 08940156 | 5863825 | 1997-09-29 | 1999-01-26 | Expired | United States of America | Alignment mark contrast enhancement |

Schedule B(1)(b) - Semic Processing B

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|------------|----------|------------|------------|-----------|--------------------------|--|
| 08890222 | 5874342 | 1997-07-09 | 1999-02-23 | Expired | United States of America | Process for forming MOS device in integrated circuit structure using cobalt silicide contacts as implantation media |
| 08768428 | 5963566 | 1996-12-18 | 1999-10-05 | Expired | United States of America | Application specific integrated circuit chip and method of testing same |
| 08727257 | 5771267 | 1996-10-08 | 1998-06-23 | Expired | United States of America | Burn-in activity monitor |
| 08840948 | 6198153 | 1997-04-21 | 2001-03-06 | Expired | United States of America | Capacitors with silicized polysilicon shielding in digital CMOS process |
| 08710783 | 5702957 | 1996-09-20 | 1997-12-30 | Expired | United States of America | Method of making buried metallization structure |
| 08770109 | 5963801 | 1996-12-19 | 1999-10-05 | Expired | United States of America | Method of forming retrograde well structures and punch-through barriers using low energy implants |
| 08652999 | 5646406 | 1996-05-24 | 1997-07-08 | Expired | United States of America | Stroboscopic photometer |
| 08932614 | 5994775 | 1997-09-17 | 1999-11-30 | Expired | United States of America | Metal-filled via/contact opening with thin barrier layers in integrated circuit structure for fast response, and process for making same |
| 08531727 | 5759921 | 1995-09-21 | 1998-06-02 | Expired | United States of America | Integrated circuit device fabrication by plasma etching |
| 09873043 | 6562700 | 2001-05-31 | 2003-05-13 | Granted | United States of America | Process for removal of resist mask over low k carbon-doped silicon oxide dielectric material of an integrated circuit structure, and removal of residues from via etch and resist mask removal |
| 08655249 | 5703376 | 1996-06-05 | 1997-12-30 | Expired | United States of America | Multi-level resolution lithography |
| 08517479 | 5834821 | 1995-08-21 | 1998-11-10 | Expired | United States of America | Triangular semiconductor "AND" gate device |
| 08756662 | 5959776 | 1996-11-26 | 1999-09-28 | Expired | United States of America | Method and apparatus of Fourier manipulation in an optic lens or mirror train |
| 08630267 | 5877045 | 1996-04-10 | 1999-03-02 | Expired | United States of America | Method of forming a planar surface during multi-layer interconnect formation by a laser-assisted dielectric deposition |
| 08501289 | 5670393 | 1995-07-12 | 1997-09-23 | Expired | United States of America | Method of making combined metal oxide semiconductor and junction field effect transistor device |
| 09865900 | 6506670 | 2001-05-25 | 2003-01-14 | Granted | United States of America | Self aligned gate |
| 08557721 | 5744399 | 1995-11-13 | 1998-04-28 | Expired | United States of America | Process for forming low dielectric constant layers using fullerenes |
| 08192228 | 5681779 | 1994-02-04 | 1997-10-28 | Expired | United States of America | Method of doping metal layers for electromigration resistance |
| 2012269037 | 5650185 | 1999-03-12 | 2014-11-21 | Granted | Japan | Electronic Components With Doped Metal Oxide Dielectric Materials And A Process For Making Electronic Components With Doped Metal Oxide Dielectric Materials |
| 201398165 | | 2013-05-08 | | Abandoned | Japan | Method To Improve Metal Defects In Semiconductor Device Fabrication |
| 2000245497 | | 2000-08-14 | | Abandoned | Japan | A Process For Manufacturing An Integrated Circuit Including A Dual-Damascene Structure And An Integrated Circuit |
| 09792685 | 6858195 | 2001-02-23 | 2005-02-22 | Lapsed | United States of America | Process for forming a low dielectric constant fluorine and carbon-containing silicon oxide dielectric material |

Schedule B(1)(b) - Semic Processing B

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------|----------|------------|------------|---------|--------------------------|---|
| 09703745 | 6417093 | 2000-10-31 | 2002-07-09 | Granted | United States of America | Process for planarization of metal-filled trenches of integrated circuit structures by forming a layer of planarizable material over the metal layer prior to planarizing |
| 11323398 | 7436040 | 2005-12-29 | 2008-10-14 | Granted | United States of America | Method and apparatus for diverting void diffusion in integrated circuit conductors |
| 11265040 | 7571397 | 2005-11-02 | 2009-08-04 | Lapsed | United States of America | Method of Design Based Process Control Optimization |
| 11078179 | 7641776 | 2005-03-10 | 2010-01-05 | Granted | United States of America | System and Method for Increasing Yield from Semiconductor Wafer Electroplating |
| 10327283 | 6867127 | 2002-12-19 | 2005-03-15 | Granted | United States of America | Diamond meta-filled patterns achieving low parasitic coupling capacitance |
| 10925497 | 7312880 | 2004-08-24 | 2007-12-25 | Granted | United States of America | Wafer edge structure measurement method |
| 10226884 | 7148131 | 2002-08-23 | 2006-12-12 | Granted | United States of America | Method for implanting ions in a semiconductor |
| 10879629 | 7198546 | 2004-06-29 | 2007-04-03 | Granted | United States of America | Method to monitor pad wear in CMP processing |
| 10867003 | 7039556 | 2004-06-14 | 2006-05-02 | Lapsed | United States of America | Substrate profile analysis |
| 60140909 | | 1999-06-24 | | Expired | United States of America | High Quality Oxide For Use In Integrated Circuits |
| 60115762 | | 1999-01-13 | | Expired | United States of America | Method Of Making A Capacitor |
| 60115842 | | 1999-01-13 | | Expired | United States of America | Aluminum Barrier Layer For High-IC Dielectric In Capacitors/Gate Application |
| 60052440 | | 1997-07-14 | | Expired | United States of America | Process For Device Fabrication |
| 60115520 | | 1999-01-12 | | Expired | United States of America | Damascene Capacitors For Integrated Circuits |
| 60083547 | | 1998-04-29 | | Expired | United States of America | Process For Fabricating A Lithographic Mask |
| 60077720 | | 1998-03-12 | | Expired | United States of America | Article Comprising Fluorinated Diamond-Like Carbon And Method For Fabricating Article |
| 60115604 | | 1999-01-12 | | Expired | United States of America | Integration Of Low Dielectric Material In Semiconductor Circuit Structures |
| 60163230 | | 1999-11-03 | | Expired | United States of America | Phase Shift Gate Lithography For High-Speed Low Voltage DSPs |
| 09712732 | 6588437 | 2000-11-14 | 2003-07-08 | Lapsed | United States of America | System And Method For Removal Of Material |
| 09597077 | 6492712 | 2000-06-20 | 2002-12-10 | Granted | United States of America | High Quality Oxide For Use In Integrated Circuits |
| 09298792 | 6280644 | 1999-04-23 | 2001-08-28 | Granted | United States of America | Method Of Planarizing A Surface Of An Integrated Circuit |
| 10930544 | 7230812 | 2004-08-30 | 2007-06-12 | Granted | United States of America | Predictive Applications For Devices With Thin Dielectric Regions |
| 10219951 | 6893806 | 2002-08-15 | 2005-05-17 | Lapsed | United States of America | Multiple Purpose Reticle Layout For Selectively Printing Of Test Circuits |
| 09364767 | 6291848 | 1999-07-30 | 2001-09-18 | Granted | United States of America | Integrated Circuit Capacitor Including Anchored Plugs |
| 09250501 | 6358790 | 1999-02-16 | 2002-03-19 | Granted | United States of America | Method Of Making A Capacitor |
| 09464811 | 6657302 | 1999-12-17 | 2003-12-02 | Granted | United States of America | Integration Of Low K Dielectric Material In Semiconductor Circuit Structures |
| 09385258 | 6146913 | 1999-08-30 | 2000-11-14 | Granted | United States of America | Method For Making Enhanced Performance Field Effect Devices |

PATENT
REEL: 060885 FRAME: 0132

Schedule B(1)(b) - Semic Processing B

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------|----------|------------|------------|-----------|--------------------------|---|
| 09432725 | 6395611 | 1999-11-01 | 2002-05-28 | Granted | United States of America | An Inductor Or Low Loss Interconnect And A Method Of Manufacturing An Inductor Or Low Loss Interconnect In An Integrated Circuit |
| 09863979 | | 2001-05-23 | | Abandoned | United States of America | Method and Apparatus for Deposition of Porous Silica Dielectrics |
| 10680047 | 6797585 | 2003-10-07 | 2004-09-28 | Granted | United States of America | Nonintrusive wafer marking |
| 09596382 | 6762087 | 2000-06-16 | 2004-07-13 | Granted | United States of America | Process For Manufacturing An Integrated Circuit Including A Dual-Damascene Structure And A Capacitor |
| 09603717 | 6621280 | 2000-06-27 | 2003-09-16 | Granted | United States of America | A Method Of Testing an Integrated Circuit |
| 09754611 | 6731386 | 2001-01-04 | 2004-05-04 | Lapsed | United States of America | Measurement Technique For Ultra-Thin Oxides |
| 09405641 | 6286226 | 1999-09-24 | 2001-09-11 | Granted | United States of America | Tactile Sensor Comprising Nanowires And Method For Making The Same |
| 09473876 | 6287952 | 1999-12-28 | 2001-09-11 | Granted | United States of America | Method Of Etching Self-Aligned Vias To Metal Using A Silicon Nitride Spacer |
| 09364025 | 6103586 | 1999-07-30 | 2000-08-15 | Granted | United States of America | Method For Making Integrated Circuit Capacitor Including Anchored Plugs |
| 09259028 | 6566181 | 1999-02-26 | 2003-05-20 | Granted | United States of America | Process For The Fabrication Of Dual Gate Structures For CMOS Devices |
| 10634416 | 7181353 | 2003-08-04 | 2007-02-20 | Granted | United States of America | Method and apparatus for integrating Six Sigma methodology into inspection receiving process of outsourced subassemblies, parts, and materials: acceptance, rejection, trending, tracking and closed loop corrective action |
| 09323607 | 6346222 | 1999-06-01 | 2002-02-12 | Granted | United States of America | Process For Synthesizing A Palladium Replenisher For Electroplating Baths |
| 09293103 | 6218057 | 1999-04-16 | 2001-04-17 | Granted | United States of America | A Lithographic Process Having Sub-Wavelength Resolution |
| 08918394 | 5846871 | 1997-08-26 | 1998-12-08 | Expired | United States of America | Integrated Circuit Fabrication |
| 09057420 | 5985493 | 1998-04-08 | 1999-11-16 | Granted | United States of America | Membrane Mask For Projection Lithography |
| 08977319 | 5981403 | 1997-11-24 | 1999-11-09 | Granted | United States of America | Layered Silicon Nitride Deposition Process |
| 09140276 | 6365469 | 1998-08-26 | 2002-04-02 | Granted | United States of America | A Method For Forming Dual-Polysilicon Structures Using A Built-In Stop Layer |
| 09092158 | 6982226 | 1998-06-05 | 2006-01-03 | Lapsed | United States of America | Method For The Fabrication Of Contacts In An Integrated Circuit Device |
| 09127373 | 6087683 | 1998-07-31 | 2000-07-11 | Granted | United States of America | Silicon Germanium Heterostructure Bipolar Transistor With Indium Doped Base |
| 08770535 | 6107117 | 1996-12-20 | 2000-08-22 | Expired | United States of America | Method Of Making An Organic Thin Film Transistor |
| 09023220 | 6136673 | 1998-02-12 | 2000-10-24 | Granted | United States of America | A Process For Fabricating A Device With Shallow Junctions |
| 08972904 | 5969421 | 1997-11-18 | 1999-10-19 | Granted | United States of America | Integrated Circuit Conductors That Avoid Current Crowding |
| 08554501 | 5885900 | 1995-11-07 | 1999-03-23 | Expired | United States of America | Method Of Global Planarization In Fabricating Integrated Circuit Devices |

Schedule B(1)(b) – Semic Processing B

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------------|------------|------------|------------|---------|--------------------------|---|
| 08280429 | 5529051 | 1994-07-26 | 1996-06-25 | Expired | United States of America | Method of Preparing Silicon Wafers |
| 08321362 | 5500312 | 1994-10-11 | 1996-03-19 | Expired | United States of America | Masks With Low Stress Multilayer Films And A Process For Controlling The Stress Of Multilayer Films |
| 08546078 | 5663568 | 1995-10-20 | 1997-09-02 | Expired | United States of America | Apparatus For Controlling A Charged Particle Beam And A Lithographic Process In Which The Apparatus Is Used |
| 08923316 | 6110831 | 1997-09-04 | 2000-08-29 | Expired | United States of America | Method Of Mechanical Polishing |
| 08660632 | 5736281 | 1996-06-07 | 1998-04-07 | Expired | United States of America | Dose Modification Proximity Effect Compensation (PEC) Technique For Electron Beam Lithography |
| 08388934 | 5607800 | 1995-02-15 | 1997-03-04 | Expired | United States of America | Method and Arrangement for Characterizing Micro-Size Patterns |
| 09491644 | 6472307 | 2000-01-27 | 2002-10-29 | Granted | United States of America | Method For Improved Encapsulation Of Thick Metal Features In Integrated Circuit Fabrication |
| 10602357 | 6954705 | 2003-06-23 | 2005-10-11 | Lapsed | United States of America | Method of screening defects using low voltage IDDQ measurement |
| 90121234 | NI-166024 | 2001-08-28 | 2003-03-14 | Granted | Taiwan | Methods of fabricating A Metal-Oxide-Metal Capacitor And Associated Apparatus |
| 90114970 | NI-182552 | 2001-06-20 | 2003-08-01 | Lapsed | Taiwan | A Method of Testing an Integrated Circuit |
| 90106474 | NI-161626 | 2001-03-20 | 2002-12-11 | Lapsed | Taiwan | Vertical Replacement Gate (VRG) MOSFET With A Conductive Layer |
| 88105178 | NI-181704 | 1999-04-01 | 2003-07-21 | Granted | Taiwan | Adjacent A Source/Drain Region And Method Of Manufacture Therefor |
| 89101735 | NI-162628 | 2000-02-01 | 2002-09-11 | Lapsed | Taiwan | Device And Method For Polishing A Semiconductor Substrate |
| 86118596 | NI-116286 | 1997-12-10 | 2000-06-21 | Lapsed | Taiwan | A Method For Fabricating A Merged Integrated Circuit Device |
| 093110399 | I332677 | 2004-04-14 | 2010-11-01 | Granted | Taiwan | Method Of Making An Organic Thin Film Transistor |
| 097118239 | I376768 | 2008-05-16 | 2012-11-11 | Granted | Taiwan | Method And Apparatus For Manufacturing Multiple Circuit Patterns Using A Multiple Project Mask |
| 093108543 | I344685 | 2004-03-29 | 2011-07-01 | Granted | Taiwan | Method For Separating A Semiconductor Wafer Into Individual Semiconductor Dies Using An Implanted Impurity |
| 1020000071927 | 704132 | 2000-11-30 | 2007-03-30 | Lapsed | Korea, Republic of (KR) | An integrated circuit device and a process for forming the same |
| 1020010042929 | 829404 | 2001-07-16 | 2008-05-07 | Lapsed | Korea, Republic of (KR) | Semiconductor Device Having Self-Aligned Contact And Landing PAD Structure And Method Of Forming Same |
| 10200100053297 | 773256 | 2001-08-31 | 2007-10-30 | Lapsed | Korea, Republic of (KR) | Electrostatic Discharge Protection Device With Monolithically Formed Resistor-Capacitor Portion |
| 1020010006759 | 859674 | 2001-02-12 | 2008-09-17 | Lapsed | Korea, Republic of (KR) | Stacked Structure For Parallel Capacitors And Method Of Fabrication |
| 20010006412 | 10-0860182 | 2001-02-09 | 2008-09-18 | Lapsed | Korea, Republic of (KR) | Method For Producing Devices Having Piezoelectric Films |
| 1019990035816 | 572647 | 1999-08-27 | 2006-04-13 | Lapsed | Korea, Republic of (KR) | Method For Producing Piezoelectric Films With Rotating Magnetron Sputtering System |
| 20000017524 | 708585 | 2000-04-04 | 2007-04-11 | Lapsed | Korea, Republic of (KR) | Process For Fabricating Vertical Transistors |
| | | | | | | Method For Processing Silicon Workpieces Using Hybrid Optical Thermometer System |

Schedule B(1)(b) - Semic Processing B

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|---------------|------------|------------|------------|---------|-------------------------------|--|
| 1020000050713 | 614782 | 2000-08-30 | 2006-08-16 | Lapsed | Korea, Republic of (KR) | A Process For Manufacturing An Integrated Circuit Including A Dual-Damascene Structure And An Integrated Circuit |
| 9847146 | 320163 | 1998-11-04 | 2001-12-26 | Lapsed | Korea, Republic of (KR) | Method For Using A Hardmask To Form An Opening In A Semiconductor Substrate |
| 9853846 | 294359 | 1998-12-09 | 2001-04-16 | Lapsed | Korea, Republic of (KR) | Lithographic Process For Device Fabrication Using A Multilayer Mask Which Has Been Previously Inspected |
| 1019990020699 | 373193 | 1999-06-04 | 2003-02-10 | Lapsed | Korea, Republic of (KR) | Method For The Fabrication Of Contacts In An Integrated Circuit Device |
| 9843136 | 329139 | 1998-10-15 | 2002-03-06 | Lapsed | Korea, Republic of (KR) | Thin Film Transistor And Organic Semiconductor Material Therefor |
| 9712486 | 469221 | 1997-04-04 | 2005-01-21 | Lapsed | Korea, Republic of (KR) | Process For Device Fabrication In Which A Thin Layer Of Cobalt Sulfide Is Formed |
| 1020010043828 | 803643 | 2001-07-20 | 2008-02-05 | Lapsed | Korea, Republic of (KR) | A Method Of Manufacturing An Integrated Circuit Package |
| 1020000058829 | 757215 | 2000-10-06 | 2007-09-04 | Lapsed | Korea, Republic of (KR) | Lens Array For Electron Beam Lithography Tool |
| 1020020084019 | 10-905210 | 2002-12-26 | 2009-06-23 | Lapsed | Korea, Republic of (KR) | CMOS Vertical Replacement Gate (VRG) Transistors |
| 963093182 | 69624326.1 | 1996-12-19 | 2002-10-16 | Expired | Germany (Federal Republic of) | Polishing Composition for CMP Operations |
| 1020010036899 | 10-983457 | 2001-06-27 | 2010-09-15 | Lapsed | Korea, Republic of (KR) | A Method of Testing an Integrated Circuit |
| 11065740 | 3328600 | 1999-03-12 | 2002-07-12 | Lapsed | Japan | Process For Fabricating Bipolar And BICMOS Devices |
| 11065741 | 3378210 | 1999-03-12 | 2002-12-06 | Granted | Japan | Article Comprising Fluorinated Diamond-Like Carbon And Method For Fabricating Article |
| 11083888 | 3538335 | 1999-03-26 | 2004-03-26 | Lapsed | Japan | Mold For Non-Photolithographic Fabrication Of Microstructures |
| 10043609 | 3768671 | 1998-02-25 | 2006-02-10 | Lapsed | Japan | Thin Film Tantalum Oxide Capacitors And Resulting Product |
| 09020253 | 3677137 | 1997-02-03 | 2005-05-13 | Expired | Japan | Articles Comprising Magnetically Soft Thin Films And Methods For Making Such Articles |
| 2000056110 | 3753915 | 2000-03-01 | 2005-12-22 | Granted | Japan | Fabricating High-Q RF Component |
| 2001262994 | 5090598 | 2001-08-31 | 2012-09-21 | Granted | Japan | Methods of Fabricating A Metal-Oxide-Metal Capacitor And Associated Apparatus |
| 2001009397 | 4718021 | 2001-01-17 | 2011-04-08 | Lapsed | Japan | Method For Making A Semiconductor Device |
| 10315480 | 6969621 | 2002-12-09 | 2005-11-29 | Lapsed | United States of America | Contamination distribution apparatus and method |
| 09577912 | 6506684 | 2000-05-24 | 2003-01-14 | Granted | United States of America | Anti-corrosion system |
| 10236226 | 7016041 | 2002-09-06 | 2006-03-21 | Lapsed | United States of America | Reticle overlay correction |
| 003055712 | 60042804.4 | 2000-07-03 | 2009-08-26 | Granted | Germany (Federal Republic of) | Article Comprising A Variable Inductor |
| 003098035 | 60043148.7 | 2000-11-06 | 2009-10-14 | Granted | Germany (Federal Republic of) | Process for Forming Device Comprising Micromagnetic Components for Power Applications |
| 993024413 | 69944291.5 | 1999-03-29 | 2012-07-04 | Lapsed | Germany (Federal Republic of) | Membrane Mask for Projection Lithography |

Schedule B(1)(b) - Semic Processing B

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|---------------|------------------|------------|------------|-----------|-------------------------------|--|
| 003103058 | 60039956.7 | 2000-11-20 | 2008-08-20 | Granted | Germany (Federal Republic of) | Thin Film Transistors |
| 993064468 | 69909205.1 | 1999-08-17 | 2003-07-02 | Lapsed | Germany (Federal Republic of) | Process For Fabricating Vertical Transistors |
| 983011545 | 69800026.9 | 1998-02-17 | 1999-10-13 | Lapsed | Germany (Federal Republic of) | GAs-Based MOSFET, And Method Of Making Same |
| 983018037 | 69832226.6 | 1998-03-11 | 2005-11-09 | Lapsed | Germany (Federal Republic of) | Semiconductor Device Having Aluminum Contacts Of Vias And Method Of Manufacture Therefor |
| 983005505 | 69802659.4 | 1998-01-27 | 2001-11-28 | Granted | Germany (Federal Republic of) | Electronic Apparatus |
| 09669979 | 6319836 | 2000-09-26 | 2001-11-20 | Granted | United States of America | Planarization system |
| 973081268 | 69734047.3 | 1997-10-14 | 2005-08-24 | Expired | Germany (Federal Republic of) | Article Comprising A Relatively Temperature-Insensitive Ta-Oxide Based Capacitive Element |
| 013007489 | 60144587.2 | 2001-01-29 | 2011-05-11 | Granted | Germany (Federal Republic of) | Method For Producing Piezoelectric Films With Rotating Magnetron Sputtering System |
| 09981154 | 6586332 | 2001-10-16 | 2003-07-01 | Lapsed | United States of America | Deep submicron silicide blocking |
| 09966651 | 6736953 | 2001-09-28 | 2004-05-18 | Granted | United States of America | High frequency electrochemical deposition |
| 09960441 | 6770505 | 2001-09-21 | 2004-08-03 | Granted | United States of America | Arrangement for measuring pressure on a semiconductor wafer and an associated method for fabricating a semiconductor wafer |
| 09997071 | 6767692 | 2001-11-28 | 2004-07-27 | Granted | United States of America | Process for inhibiting edge peeling of coating on semiconductor substrate during formation of integrated circuit structure thereon |
| 09953706 | 6524957 | 2001-09-17 | 2003-02-25 | Lapsed | United States of America | An In\YmSitu Electroplated Oxide Passivating Film For Corrosion Inhibition |
| 10144511 | 6930006 | 2002-05-13 | 2005-08-16 | Lapsed | United States of America | Electronic Circuit Structure With Improved Dielectric Properties |
| 2007237928 | | 2007-09-13 | | Abandoned | Japan | Method For Making A Semiconductor Device |
| 200810210288X | ZL200810210288.X | 2004-08-04 | 2010-07-21 | Lapsed | China | A Spiral Inductor Formed In A Semiconductor Substrate And A Method For Forming The Inductor |
| 0885548 | 5851922 | 1997-05-29 | 1998-12-22 | Expired | United States of America | Process For Fabricating A Device Using Nitrogen Implantation Into Silicide Layer |
| 11519614 | 7547560 | 2006-09-12 | 2009-06-16 | Lapsed | United States of America | Defect Identification System And Method For Repairing Killer Defects In Semiconductor Devices |
| 11673714 | 7804291 | 2007-02-12 | 2010-09-28 | Lapsed | United States of America | Semiconductor Test Device With Heating Circuit |
| 09590310 | 6365528 | 2000-06-07 | 2002-04-02 | Granted | United States of America | Low temperature process for forming a low dielectric constant fluorine and carbon-containing silicon oxide dielectric-material characterized by improved resistance to oxidation and good gap-filling capabilities |
| 10005097 | 6624048 | 2001-12-05 | 2003-09-23 | Lapsed | United States of America | Die attach back grinding |

Schedule B(1)(b) - Semic Processing B

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------|----------|------------|------------|---------|--------------------------|--|
| 08869278 | 6108093 | 1997-06-04 | 2000-08-22 | Expired | United States of America | Automated inspection system for residual metal after chemical-mechanical polishing |
| 08918293 | 6168508 | 1997-08-25 | 2001-01-02 | Expired | United States of America | Polishing pad surface for improved process control |
| 09580106 | 6355577 | 2000-05-30 | 2002-03-12 | Granted | United States of America | System to reduce particulate contamination |
| 09471842 | 6274395 | 1999-12-23 | 2001-08-14 | Granted | United States of America | Method and apparatus for maintaining test data during fabrication of a semiconductor wafer |
| 09434340 | 6090651 | 1999-11-05 | 2000-07-18 | Granted | United States of America | Depletion free polysilicon gate electrodes |
| 09204815 | 6115232 | 1998-12-03 | 2000-09-05 | Granted | United States of America | Method for forming an ion implanted electrostatic chuck |
| 09213803 | 6316276 | 1998-12-17 | 2001-11-13 | Granted | United States of America | Apparatus and method of planarizing a semiconductor wafer that includes a first reflective substance and a second reflective substance |
| 87102155 | 109370 | 1998-02-17 | 1999-11-11 | Granted | Taiwan | Use of MEV implantation to Form a Vertically Modulated n+ Buried Layer in an NPN Bipolar Transistor |
| 09163623 | 6069048 | 1998-09-30 | 2000-05-30 | Granted | United States of America | Reduction of silicon defect induced failures as a result of implants in CMOS and other integrated circuits |
| 08496861 | 5654537 | 1995-06-30 | 1997-08-05 | Expired | United States of America | Image sensor array with picture element sensor testability |
| 09281514 | 6028015 | 1999-03-29 | 2000-02-22 | Granted | United States of America | Process for treating damaged surfaces of low dielectric constant organo silicon oxide insulation material to inhibit moisture absorption |
| 09322191 | 6032529 | 1999-05-28 | 2000-03-07 | Granted | United States of America | Liquid level sensor for buffered hydrofluoric acid |
| 09013510 | 6124143 | 1998-01-26 | 2000-09-26 | Granted | United States of America | Process monitor circuitry for integrated circuits |
| 08986537 | 6097884 | 1997-12-08 | 2000-08-01 | Granted | United States of America | Probe points and markers for critical paths and integrated circuits |
| 08972231 | 5978197 | 1997-11-18 | 1999-11-02 | Granted | United States of America | Testing ESD protection schemes in semiconductor integrated circuits |
| 08960969 | 5957757 | 1997-10-30 | 1999-09-28 | Expired | United States of America | Conditioning CMP polishing pad using a high pressure fluid |
| 08900845 | 5998853 | 1997-07-25 | 1999-12-07 | Expired | United States of America | Methods and apparatus for electrical marking of integrated circuits to record manufacturing test results |
| 08895659 | 5816900 | 1997-07-17 | 1998-10-06 | Expired | United States of America | Apparatus for polishing a substrate at radially varying polish rates |
| 08961382 | 6074288 | 1997-10-30 | 2000-06-13 | Expired | United States of America | Modified carrier films to produce more uniformly polished substrate surfaces |
| 08615437 | 5660682 | 1996-03-14 | 1997-08-26 | Expired | United States of America | Plasma clean with hydrogen gas |
| 08659860 | 5736418 | 1996-06-07 | 1998-04-07 | Expired | United States of America | Method for fabricating a field effect transistor using microtrenches to control hot electron effects |
| 09186793 | 4041187 | 1997-07-11 | 2007-11-16 | Expired | Japan | Rapid Thermal Processing Using A Narrowband Infrared Source And Feedback |
| 08690577 | 6060375 | 1996-07-31 | 2000-05-09 | Expired | United States of America | Process for forming re-entrant geometry for gate electrode of integrated circuit structure |

Schedule B(1)(b) - Semic Processing B

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|---------------|------------|------------|------------|---------|-------------------------------|---|
| 08545880 | 5670892 | 1995-10-20 | 1997-09-23 | Expired | United States of America | Apparatus and method for measuring quiescent current utilizing timeset switching |
| 08631360 | 5904551 | 1996-04-12 | 1999-05-18 | Expired | United States of America | Process for low energy implantation of semiconductor substrate using channeling to form retrograde wells |
| 08396542 | 5656850 | 1995-03-01 | 1997-08-12 | Expired | United States of America | Microelectronic integrated circuit including hexagonal semiconductor "AND" gate |
| 08484003 | 5682047 | 1995-06-07 | 1997-10-28 | Expired | United States of America | Input-output (I/O) structure with capacitively triggered thyristor for electrostatic discharge (ESD) protection |
| 09844352 | 6767832 | 2001-04-27 | 2004-07-27 | Granted | United States of America | In situ liner barrier |
| 003025905 | 60012807.5 | 2000-03-29 | 2004-08-11 | Lapsed | Germany (Federal Republic of) | Plasma Cleaning Process for Openings Formed in One or More Low Dielectric Constant Insulation Layers Over Copper Metallization In Integrated Circuit Structures |
| 08613161 | 5795682 | 1996-03-08 | 1998-08-18 | Expired | United States of America | Guard rings to compensate for side lobe ringing in attenuated phase shift reticles |
| 08531659 | 5662768 | 1995-09-21 | 1997-09-02 | Expired | United States of America | High surface area trenches for an integrated circuit device |
| 08481799 | 5667433 | 1995-06-07 | 1997-09-16 | Expired | United States of America | Keyed end effector for CMP pad conditioner |
| 09872058 | 6583026 | 2001-05-31 | 2003-06-24 | Granted | United States of America | Process for forming a low k carbon-doped silicon oxide dielectric material on an integrated circuit structure |
| 201313971 | 5580439 | 2007-05-17 | 2014-07-18 | Lapsed | Japan | Method For Separating A Semiconductor Wafer Into Individual Semiconductor Dies Using An Implanted Impurity |
| 09870851 | 6559048 | 2001-05-30 | 2003-05-06 | Granted | United States of America | Method of making a sloped sidewall via for integrated circuit structure to suppress via poisoning |
| 1020130112914 | 10-1351293 | 2013-09-23 | 2014-01-08 | Granted | Korea, Republic of (KR) | Method To Improve Metal Defects In Semiconductor Device Fabrication |
| 08626776 | 5789783 | 1996-04-02 | 1998-08-04 | Expired | United States of America | Multilevel metallization structure for integrated circuit I/O lines for increased current capacity and ESD protection |
| 08579383 | 5956613 | 1995-12-27 | 1999-09-21 | Expired | United States of America | Method for improvement of TiN CVD film quality |
| 20133034 | 5579280 | 2013-01-11 | 2014-07-18 | Lapsed | Japan | CMOS Vertical Replacement Gate (VRG) Transistors |
| 08632550 | 5890951 | 1996-04-15 | 1999-04-06 | Expired | United States of America | Utility wafer for chemical-mechanical planarization |
| 09888302 | 6747464 | 2001-06-21 | 2004-06-08 | Granted | United States of America | Water holder for backside viewing, frontside probing on automated wafer probe stations |
| 08578118 | 5776831 | 1995-12-27 | 1998-07-07 | Expired | United States of America | Method of forming a high electromigration resistant metallization system |
| 09605382 | 6346488 | 2000-06-27 | 2002-02-12 | Granted | United States of America | Process to provide enhanced resistance to cracking and to further reduce the dielectric constant of a low dielectric constant dielectric film of an integrated circuit structure by implantation with hydrogen ions |

Schedule B(1)(b) - Semic Processing B

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|---------------|--------------------|------------|------------|-------------|--------------------------|---|
| 001226844 | | 2000-10-18 | | Lapsed | European Patent | Low K Dielectric Composite Layer for Integrated Circuit Structure Which Provides Void-Free Low K Dielectric Material Between Metal Lines While Mitigating Via Poisoning |
| 94124738 | 1364081 | 2005-07-21 | 2012-05-11 | Granted | Taiwan | Failure Analysis Vehicle for Yield Enhancement with Self Test at Speed Burnin Capability for Reliability Testing |
| 09725631 | 6556021 | 2000-11-29 | 2003-04-29 | Granted | United States of America | Device Frequency measurement system |
| 003000437 | | 2000-01-06 | | Application | European Patent | Damascene Capacitors For Integrated Circuits |
| 09212450 | 6329720 | 1998-12-16 | 2001-12-11 | Granted | United States of America | Tungsten local interconnect for silicon integrated circuit structures, and method of making same |
| 2005100882101 | ZL200510088210.1 | 2005-07-25 | 2010-06-23 | Granted | China | Self-Timed Reliability and Yield Vehicle with Gated Data and Clock |
| 094119790 | 1369504 | 2005-06-15 | 2012-08-01 | Granted | Taiwan | Self-Timed Reliability and Yield Vehicle with Gated Data and Clock |
| 102102447 | 1418017 | 2004-06-29 | 2013-12-01 | Granted | Taiwan | A Spiral Inductor Formed In A Semiconductor Substrate And A Method For Forming The Inductor |
| 11184621 | 7216279 | 2005-07-19 | 2007-05-08 | Granted | United States of America | Testing with high speed pulse generator |
| 2000319053 | 4731670 | 2000-10-19 | 2011-04-28 | Lapsed | Japan | Aluminum Pad Power Bus And Signal Routing For Integrated Circuit Devices Utilizing Copper Technology Interconnect Structures |
| 2011236296 | | 2011-10-27 | | Abandoned | Japan | Reduced dry etching lag |
| 11071903 | 7094687 | 2005-03-02 | 2006-08-22 | Granted | United States of America | Process And Apparatus For Simultaneous Light And Radical Surface Treatment Of Integrated Circuit Structure |
| 11046949 | 7553772 | 2005-01-31 | 2009-06-30 | Lapsed | United States of America | Method of predicting quiescent current variation of an integrated circuit die from a process monitor derating factor |
| 10955168 | 7069178 | 2004-09-29 | 2006-06-27 | Lapsed | United States of America | Superconductor wires for back end interconnects |
| 11072158 | 7341978 | 2005-03-04 | 2008-03-11 | Granted | United States of America | Multi-surfaced plate-to-plate capacitor and method of forming same |
| 11266133 | 7327011 | 2005-11-02 | 2008-02-05 | Granted | United States of America | A Spiral Inductor Formed In A Semiconductor Substrate And A Method For Forming The Inductor |
| 201010115825X | ZL 201010115825. X | 2004-08-04 | 2011-12-28 | Lapsed | China | Wafer level dynamic burn-in |
| 09918183 | 6710616 | 2001-07-30 | 2004-03-23 | Granted | United States of America | Low Temperature Tungsten Deposition |
| 60135564 | | 1999-05-24 | | Expired | United States of America | Aluminum Pad Power Bus In A Copper Technology |
| 60462504 | | 2003-04-10 | | Expired | United States of America | Stacked High-K Dielectric Capacitor For Dual Damascene Structure |
| 60115526 | | 1999-01-12 | | Expired | United States of America | Bipolar Transistors having Controllable Temperature Coefficient of Current Gain |
| 11078830 | 7482642 | 2005-03-11 | 2009-01-27 | Lapsed | United States of America | Failure Analysis Vehicle for Yield Enhancement with Self Test at Speed Burning Capability for Reliability Testing |
| 2005100927070 | ZL200510092707.0 | 2005-08-18 | 2009-10-07 | Granted | China | Novel Method Of Making EDRAM Capacitor |
| 60115781 | | 1999-01-13 | | Expired | United States of America | |

Schedule B(1)(b) – Semic Processing B

| AppNo | ParentNo | FiledDate | GrantDate | Status | Country | Title |
|---------------|-----------|------------|------------|-----------|--------------------------|---|
| 60075293 | | 1998-02-20 | | Expired | United States of America | A Process For Device Fabrication Using A Variable Transmission Aperture |
| 10927985 | 7015569 | 2004-08-26 | 2006-03-21 | Lapsed | United States of America | Method and apparatus for implementing a co-axial wire in a semiconductor chip |
| 10944996 | 7799166 | 2004-09-20 | 2010-09-21 | Lapsed | United States of America | Wafer Edge Expose Alignment Method |
| 60165542 | | 1999-11-15 | | Expired | United States of America | System And Method For Removal Of Material |
| 60168911 | | 1999-12-03 | | Expired | United States of America | CMOS With Metal Gates By Work Function Engineering |
| 60158268 | | 1999-10-07 | | Expired | United States of America | Electron Beam Imaging Apparatus |
| 60301295 | | 2001-06-28 | | Expired | United States of America | Full Via First Integration Method Of Manufacture |
| 10945177 | 7154734 | 2004-09-20 | 2006-12-26 | Granted | United States of America | Fully shielded capacitor cell structure |
| 60520265 | | 2003-11-14 | | Expired | United States of America | Control Of Hot Carrier Degradation In LDMOS Devices By A Dummy Gate Field Plate |
| 60197283 | | 2000-04-14 | | Expired | United States of America | Novel Method Of Coil Preparation For Ionized Metal Plasma Processes |
| 09560935 | 6365426 | 2000-04-30 | 2002-04-02 | Granted | United States of America | Method Of Determining The Impact Of Plasma-Charging Damage On Yield And Reliability In Submicron Integrated Circuits |
| 09972482 | 6639298 | 2001-10-05 | 2003-10-28 | Granted | United States of America | A Multi-Layer Inductor Formed In A Semiconductor Substrate |
| 09243047 | 6259149 | 1999-02-03 | 2001-07-10 | Granted | United States of America | Fully Isolated Thin Film Trench Capacitor |
| 60141348 | | 1999-06-28 | | Expired | United States of America | Impact Of Plasma-Charging Damage On Yield And Reliability In Deep Submicron CMOS VLSI Circuits |
| 2009234206 | 5479839 | 2009-10-08 | 2014-02-21 | Lapsed | Japan | Architecture for Circuit Connection of a Vertical Transistor |
| 09334491 | 6309932 | 1999-06-16 | 2001-10-30 | Granted | United States of America | Process For Forming A Plasma Nitride Film Suitable For Gate Dielectric Application In Submicron Technologies |
| 09121266 | 6051346 | 1998-07-23 | 2000-04-18 | Granted | United States of America | Process For Fabricating A Lithographic Mask |
| 1020090066235 | 10-929335 | 2009-07-21 | 2009-11-24 | Granted | Korea, Republic of (KR) | Vertical Replacement-Gate Junction Field-Effect Transistor |
| 60115785 | | 1999-01-13 | | Expired | United States of America | Tapered Plug For EDRAM/Capacitor Application |
| 09190351 | 6015644 | 1998-11-12 | 2000-01-18 | Granted | United States of America | Process For Device Fabrication Using A Variable Transmission Aperture |
| 2009038940 | | 2009-02-23 | | Abandoned | Japan | A Process For Manufacturing An Integrated Circuit Including A Dual-Damascene Structure And An Integrated Circuit |
| 2009032389 | 5334616 | 2009-02-16 | | Granted | Japan | A Process For Manufacturing An Integrated Circuit Including A Dual-Damascene Structure And An Integrated Circuit |
| 11189217 | 7763908 | 2005-07-25 | 2010-07-27 | Lapsed | United States of America | Design Of Silicon-Controlled Rectifier By Considering Electrostatic Discharge Robustness In Human-Body Model And Charged-Device Model Devices |
| 60088157 | | 1998-06-05 | | Expired | United States of America | Method Of Planarizing A Surface Of An Integrated Circuit |
| 60096407 | | 1998-08-13 | | Expired | United States of America | Yield Improvement Via Automatic Analysis Of Wafer Processing Order |

Schedule B(1)(b) - Semic Processing B

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|---------------|----------|------------|------------|-------------|--------------------------|---|
| 60043235 | | 1997-04-11 | | Expired | United States of America | A Process For Forming Patterned Dielectric Oxide Films |
| 10696320 | 7190185 | 2003-10-29 | 2007-03-13 | Granted | United States of America | Methodology to measure many more transistors on the same test area |
| 09056133 | 5976625 | 1998-04-07 | 1999-11-02 | Granted | United States of America | Process For Forming Patterned Dielectric Oxide Films |
| 60033839 | | 1996-12-23 | | Expired | United States of America | Compound, High K, Gate And Capacitor Insulator Layer |
| 60115718 | | 1999-01-12 | | Expired | United States of America | Mask And Implant Savings For Dual Voltage CMOS Technologies |
| 60592153 | | 2004-07-29 | | Expired | United States of America | Method Of Electrical Probing |
| 09481463 | 6403415 | 2000-01-11 | 2002-06-11 | Granted | United States of America | A Semiconductor Device Having A Metal Barrier Layer For A Dielectric Material Having A High Dielectric Constant And A Method Of Manufacture Thereof |
| 60756056 | | 2006-01-04 | | Expired | United States of America | Formation Of An Integrated Circuit Structure With Reduced Dishing In Metallization Levels |
| 09704635 | 6420277 | 2000-11-01 | 2002-07-16 | Granted | United States of America | Process for inhibiting crack formation in low dielectric constant dielectric films of integrated circuit structure |
| 60091896 | | 1998-07-07 | | Expired | United States of America | Fully\mfilmsolated Thin\mfilmm Trench Capacitor |
| 60312389 | | 2001-08-15 | | Expired | United States of America | Multiple Purpose Reticle Layout For Selectively Printing |
| 12618936 | 8119501 | 2009-11-16 | 2012-02-21 | Granted | United States of America | Method For Separating A Semiconductor Wafer Into Individual Semiconductor Dies Using An Implanted Impurity |
| 10610002 | 7581203 | 2003-06-30 | 2009-08-25 | Lapsed | United States of America | Method And Apparatus For Manufacturing Multiple Circuit Patterns Using A Multiple Project Mask |
| 09836365 | 6699372 | 2001-04-16 | 2004-03-02 | Granted | United States of America | Method Of Coil Preparation For Ionized Metal Plasma Process And Method Of Manufacturing Integrated Circuits |
| 09586586 | 6720261 | 2000-06-02 | 2004-04-13 | Granted | United States of America | Method And System For Eliminating Extrusions In Semiconductor Vias |
| 2007800530078 | | 2007-05-17 | | Abandoned | China | Method For Separating A Semiconductor Wafer Into Individual Semiconductor Dies Using An Implanted Impurity |
| 2015105007177 | | 2007-05-17 | | Application | China | Method For Separating A Semiconductor Wafer Into Individual Semiconductor Dies Using An Implanted Impurity |
| 09630463 | 6537867 | 2000-08-02 | 2003-03-25 | Granted | United States of America | High Speed Low Voltage Semiconductor Devices And Method Of Fabrication |
| 09363769 | 6207510 | 1999-07-29 | 2001-03-27 | Granted | United States of America | Method For Making An Integrated Circuit Including High And Low Voltage Transistors |
| 09292422 | 6271596 | 1999-04-15 | 2001-08-07 | Granted | United States of America | Damascene Capacitors For Integrated Circuits |
| 10950839 | 7183181 | 2004-09-27 | 2007-02-27 | Granted | United States of America | Dynamic edge bead removal |
| 09897517 | 6680243 | 2001-06-29 | 2004-01-20 | Granted | United States of America | Shallow junction formation |
| 09967094 | 7071563 | 2001-09-28 | 2006-07-04 | Lapsed | United States of America | A Barrier Layer For Interconnect Structures Of A Semiconductor Wafer And Method For Depositing The Barrier Layer |
| 09466285 | 6303397 | 1999-12-17 | 2001-10-16 | Granted | United States of America | Method For Benchmarking Thin Film Measurement Tools |

PATENT
REEL: 060885 FRAME: 0142

Schedule B(1)(b) - Semic Processing B

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------|----------|------------|------------|---------|--------------------------|--|
| 09388682 | 6320244 | 1999-09-02 | 2001-11-20 | Granted | United States of America | Integrated Circuit Device Having Dual Damascene Capacitor |
| 09517965 | 6294468 | 2000-03-03 | 2001-09-25 | Granted | United States of America | Method Of Chemical Vapor Depositing Tungsten Films |
| 09339894 | 6303940 | 1999-06-25 | 2001-10-16 | Granted | United States of America | Charge Injection Transistor Using High-K Dielectrics Barrier Layer |
| 09416491 | 6313021 | 1999-10-12 | 2001-11-06 | Granted | United States of America | PMOS Device Having A Layered Silicon Gate For Improved Silicide Integrity And Enhanced Boron Penetration Resistance |
| 09340224 | 6235594 | 1999-06-25 | 2001-05-22 | Granted | United States of America | Methods Of Fabricating An Integrated Circuit Device With Composite Oxide Dielectric |
| 09364858 | 6440852 | 1999-07-30 | 2002-08-27 | Granted | United States of America | Integrated Circuit Including Passivated Copper Interconnection Lines And Associated Manufacturing Methods |
| 10260727 | 7005375 | 2002-09-30 | 2006-02-28 | Granted | United States of America | Method To Avoid Copper Contamination Of A Via Or Dual Damascene Structure |
| 10675258 | 7566964 | 2003-09-30 | 2009-07-28 | Granted | United States of America | Aluminum Pad Power Bus And Signal Routing For Integrated Circuit Devices Utilizing Copper Technology Interconnect Structures |
| 10614776 | 6881664 | 2003-07-07 | 2005-04-19 | Granted | United States of America | Process for planarizing upper surface of damascene wiring structure for integrated circuit structures |
| 09364208 | 6169010 | 1999-07-30 | 2001-01-02 | Granted | United States of America | Method For Making Integrated Circuit Capacitor Including Anchored Plug |
| 10696203 | 7114143 | 2003-10-29 | 2006-09-26 | Lapsed | United States of America | Process yield learning |
| 10661013 | 7013222 | 2003-09-12 | 2006-03-14 | Lapsed | United States of America | Wafer edge inspection data gathering |
| 09354711 | 6184755 | 1999-07-16 | 2001-02-06 | Granted | United States of America | Article Comprising A Variable Inductor |
| 09412089 | 6430047 | 1999-10-04 | 2002-08-06 | Granted | United States of America | Standardized Test Board For Testing Custom Chips |
| 09648164 | 6903411 | 2000-08-25 | 2005-06-07 | Granted | United States of America | Architecture For Circuit Connection Of A Vertical Transistor |
| 09042388 | 6121101 | 1998-03-12 | 2000-09-19 | Granted | United States of America | Process For Fabricating Bipolar And BiCMOS Devices |
| 10697507 | 7084408 | 2003-10-29 | 2006-08-01 | Lapsed | United States of America | Vaporization and ionization of metals for use in semiconductor processing |
| 08963687 | 6008123 | 1997-11-04 | 1999-12-28 | Granted | United States of America | Method For Using A Hardmask To Form An Opening In A Semiconductor Substrate |
| 10036020 | 6773994 | 2001-12-26 | 2004-08-10 | Granted | United States of America | CMOS Vertical Replacement Gate (VRG) Transistors |
| 08936132 | 5912797 | 1997-09-24 | 1999-06-15 | Expired | United States of America | Dielectric Materials Of Amorphous Compositions And Devices Employing Same |
| 10121370 | 6899596 | 2002-04-12 | 2005-05-31 | Lapsed | United States of America | Chemical Mechanical Polishing Of Dual Orientation Polycrystalline Materials |
| 10627289 | 6958541 | 2003-07-25 | 2005-10-25 | Lapsed | United States of America | Low gate resistance layout procedure for RF transistor devices |
| 09515730 | 6599837 | 2000-02-29 | 2003-07-29 | Granted | United States of America | Chemical Mechanical Polishing Composition And Method Of Polishing Metal Layers Using Same |
| 09384395 | 6368753 | 1999-08-27 | 2002-04-09 | Granted | United States of America | Mask Repair |
| 09220417 | 6110012 | 1998-12-24 | 2000-08-29 | Granted | United States of America | Chemical-Mechanical Polishing Apparatus And Method |

Schedule B(1)(b) - Semic Processing B

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------|----------|------------|------------|---------|--------------------------|--|
| 10920656 | 7087959 | 2004-08-18 | 2006-08-08 | Lapsed | United States of America | Metal-Oxide-Semiconductor Device Having An Enhanced Shielding Structure |
| 08804782 | 5903037 | 1997-02-24 | 1999-05-11 | Expired | United States of America | Gas-Based MOSFET, And Method Of Making Same |
| 09386065 | 6365327 | 1999-08-30 | 2002-04-02 | Granted | United States of America | A Process For Manufacturing An Integrated Circuit Including A Dual-Damascene Structure And An Integrated Circuit |
| 09384459 | 6225639 | 1999-08-27 | 2001-05-01 | Granted | United States of America | Method Of Monitoring A Patterned Transfer Process Using Line Width Metrology |
| 09034079 | 5955381 | 1998-03-03 | 1999-09-21 | Granted | United States of America | Integrated Circuit Fabrication |
| 10628614 | 7968859 | 2003-07-28 | 2011-06-28 | Granted | United States of America | Wafer edge defect inspection using captured image analysis |
| 09339085 | 6071808 | 1999-06-23 | 2000-06-06 | Granted | United States of America | Method Of Passivating Copper Interconnects In A Semiconductor |
| 10953478 | 7176781 | 2004-09-29 | 2007-02-13 | Granted | United States of America | Structure And Method For Adjusting Integrated Circuit Resistor Value |
| 10679004 | 6982206 | 2003-10-02 | 2006-01-03 | Granted | United States of America | Mechanism for improving the structural integrity of low-k films |
| 09451078 | 6206054 | 1999-11-30 | 2001-03-27 | Granted | United States of America | Automatic Compound Shaking Machine |
| 09174503 | 6363606 | 1998-10-16 | 2002-04-02 | Granted | United States of America | Process For Forming Integrated Structures Using Three Dimensional Printing Techniques |
| 10628986 | 6986112 | 2003-07-28 | 2006-01-10 | Lapsed | United States of America | Method of mapping logic failures in an integrated circuit die |
| 08946413 | 5989984 | 1997-10-07 | 1999-11-23 | Expired | United States of America | Method of Using A Getter Layer To Improve Metal To Metal Contact Resistance At Low Radio Frequency Power |
| 09650606 | 6458669 | 2000-08-30 | 2002-10-01 | Granted | United States of America | Method of Manufacturing An Integrated Circuit |
| 08346706 | 5534721 | 1994-11-30 | 1996-07-09 | Expired | United States of America | Area-Efficient Layout For High Voltage Lateral Devices |
| 08323945 | 5541402 | 1994-10-17 | 1996-07-30 | Expired | United States of America | Imaging Active Pixel Device Having A Non-Destructive Read-Out Gate |
| 09653295 | 6838717 | 2000-08-31 | 2005-01-04 | Granted | United States of America | Stacked Structure For Parallel Capacitors And Method Of Fabrication |
| 08299470 | 5504385 | 1994-08-31 | 1996-04-02 | Expired | United States of America | Spaced-Gate Emission Device And Method For Making Same |
| 08560671 | 5744840 | 1995-11-20 | 1998-04-28 | Expired | United States of America | Electrostatic Protection Devices For Protecting Semiconductor Integrated Circuitry |
| 08987491 | 6042995 | 1997-12-09 | 2000-03-28 | Granted | United States of America | Lithographic Process For Device Fabrication Using A Multilayer Mask Which Has Been Previously Inspected |
| 08951779 | 5936259 | 1997-10-16 | 1999-08-10 | Expired | United States of America | Thin Film Transistor And Organic Semiconductor Material Therefor |
| 09604519 | 6833557 | 2000-06-27 | 2004-12-21 | Lapsed | United States of America | Integrated Circuit And A Method Of Manufacturing An Integrated Circuit |
| 08586412 | 5891605 | 1996-01-16 | 1999-04-06 | Expired | United States of America | Reduction In Damage To Optical Elements Used In Optical Lithography For Device Fabrication |
| 09617687 | 6384452 | 2000-07-17 | 2002-05-07 | Granted | United States of America | Electrostatic Discharge Protection Device With Monolithically Formed Resistor-Capacitor Portion |
| 09250500 | 6720604 | 1999-02-16 | 2004-04-13 | Granted | United States of America | Capacitor For An Integrated Circuit |

PATENT
REEL: 060885 FRAME: 0144

Schedule B(1)(b) - Semic Processing B

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------|----------|------------|------------|---------|--------------------------|--|
| 10675263 | 7078337 | 2003-09-30 | 2006-07-18 | Lapsed | United States of America | Selective Isotropic Etch For Titanium Based Materials |
| 08692836 | 5863843 | 1996-07-31 | 1999-01-26 | Expired | United States of America | Wafer Holder For Thermal Processing Apparatus |
| 09448349 | 6245692 | 1999-11-23 | 2001-06-12 | Granted | United States of America | Method To Selectively Heat Semiconductor Wafers |
| 09337741 | 6448569 | 1999-06-22 | 2002-09-10 | Granted | United States of America | Bonded Article Having Improved Crystalline Structure And Work Function Uniformity And Method For Making The Same |
| 08724128 | 5843827 | 1996-09-30 | 1998-12-01 | Expired | United States of America | Method Of Reducing Dielectric Damage From Plasma Etch Charging |
| 09009399 | 6197699 | 1998-01-20 | 2001-03-06 | Granted | United States of America | In Situ Dry Cleaning Process For Poly Gate Etch |
| 08627560 | 5728625 | 1996-04-04 | 1998-03-17 | Expired | United States of America | Process For Device Fabrication In Which A Thin Layer Of Cobalt Silicide Is Formed |
| 09385165 | 6313025 | 1999-08-30 | 2001-11-06 | Granted | United States of America | A Process For Manufacturing An Integrated Circuit Including A Dual-Damascene Structure And An Integrated Circuit |
| 09286929 | 6830942 | 1999-04-06 | 2004-12-14 | Granted | United States of America | Method For Processing Silicon Workpieces Using Hybrid Optical Thermometer System |
| 09379055 | 6674151 | 1999-08-23 | 2004-01-06 | Granted | United States of America | Deuterium Passivated Semiconductor Device Having Enhanced Immunity To Hot Carrier Effects |
| 09413742 | 6458289 | 1999-10-06 | 2002-10-01 | Granted | United States of America | CMP Slurry For Polishing Semiconductor Wafers And Related Methods |
| 09430226 | 6180518 | 1999-10-29 | 2001-01-30 | Granted | United States of America | Method For Forming Vias In A Low Dielectric Constant Material |
| 09540618 | 6573818 | 2000-03-31 | 2003-06-03 | Granted | United States of America | Planar Magnetic Frame Inductors Having Open Cores |
| 09451054 | 6483144 | 1999-11-30 | 2002-11-19 | Granted | United States of America | Semiconductor Device Having Self-Aligned Contact And Landing PAD Structure And Method Of Forming Same |
| 08735170 | 5754392 | 1996-10-22 | 1998-05-19 | Expired | United States of America | Article Comprising A Relatively Temperature-Insensitive Ta-Oxide Based Capacitive Element |
| 08366192 | 5559052 | 1994-12-29 | 1996-09-24 | Expired | United States of America | Integrated Circuit with Interlevel Dielectric |
| 08566766 | 5620909 | 1995-12-04 | 1997-04-15 | Expired | United States of America | Method of Depositing Thin Passivating Film on Microminiature Semiconductor Devices |
| 09354928 | 6322713 | 1999-07-15 | 2001-11-27 | Granted | United States of America | Nanoscale Conductive Connectors And Method For Making Same |
| 08295303 | 5461245 | 1994-08-24 | 1995-10-24 | Expired | United States of America | Article Comprising A Bipolar Transistor With Floating Base |
| 09152185 | 6242989 | 1998-09-12 | 2001-06-05 | Granted | United States of America | Article Comprising A Multipport Variable Capacitor |
| 08531115 | 5711891 | 1995-09-20 | 1998-01-27 | Expired | United States of America | Water Processing Using Thermal Nitride Etch Mask |
| 08176600 | 5438006 | 1994-01-03 | 1995-08-01 | Expired | United States of America | Method of Fabricating Gate Stack Having a Reduced Height |
| 07815316 | 5880022 | 1991-12-30 | 1999-03-09 | Expired | United States of America | Self-Aligned Contact Window |
| 08977318 | 6147388 | 1997-11-24 | 2000-11-14 | Granted | United States of America | Polyicide Gate Structure With Intermediate Barrier |
| 08595543 | 5780175 | 1996-02-02 | 1998-07-14 | Expired | United States of America | Articles Comprising Magnetically Soft Thin Films And Methods For Making Such Articles |
| 08326449 | 5521031 | 1994-10-20 | 1996-05-28 | Expired | United States of America | Pattern Delineating Apparatus For Use In The EUV Spectrum |
| 08856561 | 6316950 | 1997-05-15 | 2001-11-13 | Expired | United States of America | Method And Apparatus For Imaging Semiconductor Devices |
| 08299701 | 5510007 | 1994-08-31 | 1996-04-23 | Expired | United States of America | Electrochemical Generation Of Silane |

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REEL: 060885 FRAME: 0145

Schedule B(1)(b) – Semic Processing B

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------|-----------|------------|------------|---------|--------------------------|---|
| 09080992 | 6051500 | 1998-05-19 | 2000-04-18 | Granted | United States of America | Device And Method For Polishing A Semiconductor Substrate |
| 08754607 | 5728607 | 1996-11-20 | 1998-03-17 | Expired | United States of America | Method Of Making A P-Channel Bipolar Transistor |
| 08565286 | 5688704 | 1995-11-30 | 1997-11-18 | Expired | United States of America | Integrated Circuit Fabrication |
| 08538318 | 5658485 | 1995-10-03 | 1997-08-19 | Expired | United States of America | Pyrochlore Based Oxides With High Dielectric Constant and Low Temperature Coefficient |
| 08391905 | 5656182 | 1995-02-21 | 1997-08-12 | Expired | United States of America | A Process For Fabricating A Device In Which The Process Is Controlled By Near-Field Imaging Latent Features Introduced Into Energy Sensitive Resist Materials |
| 08451283 | 5948570 | 1995-05-26 | 1999-09-07 | Expired | United States of America | Process For Dry Lithographic Etching |
| 08505047 | 5527425 | 1995-07-21 | 1996-06-18 | Expired | United States of America | Method Of Making In-Containing III/V Semiconductor Devices |
| 08769605 | 6020256 | 1996-12-18 | 2000-02-01 | Expired | United States of America | Method of Integrated Circuit Fabrication |
| 08570906 | 5625140 | 1995-12-12 | 1997-04-29 | Expired | United States of America | Acoustic Analysis Of Gas Mixtures |
| 08359309 | 5559360 | 1994-12-19 | 1996-09-24 | Expired | United States of America | Inductor for High Frequency Circuits |
| 08118109 | 5838033 | 1993-09-08 | 1998-11-17 | Expired | United States of America | Integrated Circuit with Gate Conductor Defined Resistor |
| 09503225 | 6342134 | 2000-02-11 | 2002-01-29 | Granted | United States of America | Method For Producing Piezoelectric Films With Rotating Magnetron Sputtering System |
| 09450525 | 6136702 | 1999-11-29 | 2000-10-24 | Granted | United States of America | Thin Film Transistors |
| 09513390 | 6406609 | 2000-02-25 | 2002-06-18 | Granted | United States of America | A Method Of Fabricating An Integrated Circuit |
| 09567675 | 6603119 | 2000-05-09 | 2003-08-05 | Granted | United States of America | Calibration Method For Quantitative Elemental Analysis |
| 09551050 | 6399413 | 2000-04-18 | 2002-06-04 | Granted | United States of America | Self Aligned Gated Schottky Diode Guard Ring Structures |
| 09432926 | 6358359 | 1999-11-03 | 2002-03-19 | Granted | United States of America | Apparatus for Detecting Plasma Etch Endpoint In Semiconductor Fabrication And Associated Method |
| 09543808 | 6429040 | 2000-04-06 | 2002-08-06 | Granted | United States of America | Device Comprising Bipolar Semi-Conducting Film |
| 09484759 | 6274409 | 2000-01-18 | 2001-08-14 | Granted | United States of America | Method For Making A Semiconductor Device |
| 09553931 | 6726537 | 2000-04-21 | 2004-04-27 | Granted | United States of America | Polishing Carrier Head |
| 09488355 | 6436608 | 2000-01-20 | 2002-08-20 | Granted | United States of America | Lithographic Method Utilizing A Phase-Shifting Mask |
| 09996118 | 6815342 | 2001-11-27 | 2004-11-09 | Granted | United States of America | Low resistance metal interconnect lines and a process for fabricating them |
| 89112402 | NI-198319 | 2000-09-20 | 2004-03-21 | Lapsed | Taiwan | High Quality Oxide For Use In Integrated Circuits |
| 89108620 | NI-203326 | 2000-07-15 | 2004-06-11 | Lapsed | Taiwan | Electron Emitters for Lithography Tools |
| 91119023 | NI-185928 | 2002-08-22 | 2004-01-14 | Lapsed | Taiwan | CMOS Vertical Replacement Gate (VRG) Transistors |
| 88119230 | NI-186701 | 2000-02-18 | 2003-09-01 | Granted | Taiwan | An Inductor Or Low Loss Interconnect And A Method Of Manufacturing An Inductor Or Low Loss Interconnect In An Integrated Circuit |
| 89109253 | NI-172855 | 2000-05-15 | 2003-03-01 | Lapsed | Taiwan | Charge Injection Transistor Using High-K Dielectrics Barrier Layer |
| 89109252 | NI-145230 | 2000-05-15 | 2001-12-01 | Granted | Taiwan | A Gate Stack Structure For Integrated Circuit Fabrication |
| 89100250 | NI-155124 | 2000-01-10 | 2002-05-11 | Lapsed | Taiwan | Damascene Capacitors For Integrated Circuits |
| 88102935 | NI-138362 | 1999-02-26 | 2001-08-11 | Lapsed | Taiwan | Integrated Circuit Fabrication |

Schedule B(1)(b) - Semic Processing B

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|-----------|-----------|------------|------------|---------|--------------------------|--|
| 11427494 | 7982286 | 2006-06-29 | 2011-07-19 | Granted | United States of America | Method To Improve Metal Defects In Semiconductor Device Fabrication |
| 10691938 | 6870386 | 2003-10-23 | 2005-03-22 | Lapsed | United States of America | Method and apparatus for measuring sheet resistance |
| 88119226 | NI-132577 | 1999-11-30 | 2001-05-28 | Granted | Taiwan | Simplified High Q Inductor Substrate |
| | | | | | | A Chemical Mechanical Polisher Including A Pad Conditioner And A Method Of |
| | | | | | | Manufacturing An Integrated Circuit Using The Chemical Mechanical Polisher |
| 09477833 | 6517416 | 2000-01-05 | 2003-02-11 | Granted | United States of America | Architecture For Circuit Connection Of A Vertical Transistor |
| 90121536 | I260734 | 2001-08-29 | 2006-08-21 | Lapsed | Taiwan | A Barrier Layer For Interconnect Structures Of A Semiconductor Wafer And Method For Depositing The Barrier Layer |
| 91101551 | NI-178411 | 2002-01-30 | 2003-09-18 | Granted | Taiwan | Bonded Article Having Improved Crystalline Structure And Work Function Uniformity And Method For Making The Same |
| 89112268 | NI-131524 | 2000-06-22 | 2001-05-01 | Lapsed | Taiwan | Process For Manufacturing An Integrated Circuit Including A Dual-Damascene Structure And A Capacitor |
| 90114096 | I256683 | 2001-06-12 | 2006-06-11 | Lapsed | Taiwan | A Multi-Layer Inductor Formed In A Semiconductor Substrate |
| 91121020 | NI-189019 | 2002-09-13 | 2004-02-16 | Lapsed | Taiwan | A Process For Manufacturing An Integrated Circuit Including A Dual-Damascene Structure And An Integrated Circuit |
| 89111610 | NI-160919 | 2000-06-14 | 2002-08-11 | Lapsed | Taiwan | A Process For Manufacturing An Integrated Circuit Including A Dual-Damascene Structure And An Integrated Circuit |
| 89111675 | NI-162650 | 2000-06-15 | 2002-09-11 | Lapsed | Taiwan | Chemical-Mechanical Polishing Apparatus And Method |
| 88119654 | NI-147721 | 1999-11-10 | 2002-01-01 | Granted | Taiwan | Interdigitated Capacitor Structure For Use In An Integrated Circuit |
| 09505762 | 6383858 | 2000-02-16 | 2002-05-07 | Granted | United States of America | A Spiral Inductor Formed In A Semiconductor Substrate And A Method For Forming The Inductor |
| 093119217 | I412119 | 2004-06-29 | 2013-10-11 | Lapsed | Taiwan | Process For Device Fabrication |
| 87111331 | NI-111955 | 1998-07-13 | 2000-02-21 | Lapsed | Taiwan | Thin Film Transistors |
| 88110493 | NI-124018 | 1999-06-22 | 2001-04-20 | Granted | Taiwan | In Situ Dry Cleaning Process For Poly Gate Etch |
| 87121335 | NI-131816 | 1998-12-21 | 2001-09-03 | Lapsed | Taiwan | Method Of Mechanical Polishing |
| 87114709 | NI-118398 | 1998-09-29 | 2000-08-01 | Lapsed | Taiwan | Method And Apparatus For Imaging Semiconductor Devices |
| 87105344 | NI-106777 | 1998-04-09 | 1999-09-11 | Lapsed | Taiwan | Bipolar Transistor Having A Low K Material In The Emitter Region |
| 09631755 | 6657281 | 2000-08-03 | 2003-12-02 | Lapsed | United States of America | Articles Comprising Magnetically Soft Thin Films And Methods For Making Such Articles |
| 86100615 | NI-104341 | 1997-01-21 | 1999-11-02 | Expired | Taiwan | Vertical Replacement Gate (VRG) MOSFET With A Conductive Layer Adjacent A Source/Drain Region And Method Of Manufacture Therefor |
| 09528753 | 6518622 | 2000-03-20 | 2003-02-11 | Granted | United States of America | A Capacitor For Integration With Copper Damascene Processes |
| 90100857 | NI-151372 | 2001-01-15 | 2002-06-21 | Lapsed | Taiwan | Fabricating High-Q RF Component |
| 89103722 | NI-146566 | 2000-05-24 | 2002-04-08 | Granted | Taiwan | |

Schedule B(1)(b) – Semic Processing B

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|----------------|------------|------------|------------|---------|--------------------------|--|
| 09413741 | 6436830 | 1999-10-06 | 2002-08-20 | Granted | United States of America | CMP System For Polishing Semiconductor Wafers And Related Method |
| 90118908 | Nl-169919 | 2001-08-02 | 2002-11-21 | Granted | Taiwan | Bipolar Transistor Having A Low K Material In The Emitter Region |
| 09384631 | 6586310 | 1999-08-27 | 2003-07-01 | Granted | United States of America | High Resistivity Film For 4T SRAM |
| 102000035106 | 734757 | 2000-06-24 | 2007-06-27 | Granted | Korea, Republic of (KR) | High Quality Oxide For Use In Integrated Circuits |
| 20010002872 | 676643 | 2001-01-18 | 2007-01-25 | Lapsed | Korea, Republic of (KR) | Method For Making A Semiconductor Device |
| 1020000019775 | 614781 | 2000-04-15 | 2006-08-16 | Granted | Korea, Republic of (KR) | A Lithographic Process Having Sub-Wavelength Resolution |
| 1019990008029 | 549974 | 1999-03-11 | 2006-02-01 | Lapsed | Korea, Republic of (KR) | Process For Fabricating Bipolar And BiCMOS Devices |
| 1020000063481 | 756200 | 2000-10-27 | 2007-08-31 | Lapsed | Korea, Republic of (KR) | Method For Forming Vias in a Low Dielectric Constant Material |
| 10199900034561 | 667603 | 1999-08-20 | 2007-01-05 | Lapsed | Korea, Republic of (KR) | Thin Film Transistors |
| 987041 | 292707 | 1998-03-04 | 2001-03-26 | Lapsed | Korea, Republic of (KR) | Thin Film Tantalum Oxide Capacitors And Resulting Product |
| 9850861 | 347648 | 1998-11-26 | 2002-07-24 | Lapsed | Korea, Republic of (KR) | Method For Removing Etching Residues And Contaminants |
| 9849182 | 380514 | 1998-11-17 | 2003-04-03 | Lapsed | Korea, Republic of (KR) | Integrated Circuit Conductors That Avoid Current Crowding |
| 19970024048 | 279034 | 1997-06-07 | 2000-10-26 | Expired | Korea, Republic of (KR) | Dose Modification Proximity Effect Compensation (PEC) Technique For Electron Beam Lithography |
| 9817633 | 271843 | 1998-05-15 | 2000-08-21 | Lapsed | Korea, Republic of (KR) | Method And Apparatus For Imaging Semiconductor Devices |
| 1019980015165 | 329580 | 1998-04-28 | 2002-03-09 | Lapsed | Korea, Republic of (KR) | Deuterated Bipolar Transistors And Method Of Manufacture Thereof |
| 10397451 | 6746925 | 2003-03-25 | 2004-06-08 | Granted | United States of America | High-k dielectric bird's beak optimizations using in-situ O2 plasma oxidation |
| 10423184 | 7262119 | 2003-04-25 | 2007-08-28 | Granted | United States of America | Method for incorporating germanium into a semiconductor wafer |
| 1020010052995 | 847233 | 2001-08-30 | 2008-07-14 | Lapsed | Korea, Republic of (KR) | Method of Manufacturing An Integrated Circuit |
| 1020010025174 | 445020 | 2001-05-09 | 2004-08-10 | Lapsed | Korea, Republic of (KR) | Calibration Method For Quantitative Elemental Analysis |
| 1020000001148 | 695026 | 2000-01-11 | 2007-03-08 | Lapsed | Korea, Republic of (KR) | Integrated Circuit Device Having Dual Damascene Capacitor |
| 1020000000859 | 10-0658954 | 2000-01-10 | 2006-12-12 | Granted | Korea, Republic of (KR) | Damascene Capacitors For Integrated Circuits |
| 10199900031535 | 570910 | 1999-07-31 | 2006-04-07 | Lapsed | Korea, Republic of (KR) | Silicon Germanium Heterostructure Bipolar Transistor With Indium Doped Base |
| 19990011551 | 0313423 | 1999-04-02 | 2001-10-19 | Lapsed | Korea, Republic of (KR) | Membrane Mask for Projection Lithography |
| 1019990008028 | 319571 | 1999-03-11 | 2001-12-20 | Granted | Korea, Republic of (KR) | Electronic Components With Doped Metal Oxide Dielectric Materials And A Process For Making Electronic Components With Doped Metal Oxide Dielectric Materials |
| 1019990001574 | 371623 | 1999-01-20 | 2003-01-27 | Granted | Korea, Republic of (KR) | Electronic Apparatus |
| 20010003082 | 429726 | 2001-01-19 | 2004-04-20 | Lapsed | Korea, Republic of (KR) | A Capacitor For Integration With Copper Damascene Processes |
| 20000010425 | 605779 | 2000-03-02 | 2006-07-20 | Granted | Korea, Republic of (KR) | Fabricating High-Q RF Component |
| 10200000035368 | 767610 | 2000-06-26 | 2007-10-10 | Granted | Korea, Republic of (KR) | A Gate Stack Structure For Integrated Circuit Fabrication |
| 1020070065264 | 10-1359555 | 2007-06-29 | 2014-01-29 | Lapsed | Korea, Republic of (KR) | Method To Improve Metal Defects In Semiconductor Device Fabrication |

Schedule B(1)(b) - Semic Processing B

| AppNo | PatentNo | FiledDate | GrantDate | Status | Country | Title |
|---------------|------------|------------|------------|---------|--------------------------|--|
| 1020040065903 | 10-1084959 | 2004-08-20 | 2011-11-14 | Granted | Korea, Republic of (KR) | A Spiral Inductor Formed In A Semiconductor Substrate And A Method For Forming The Inductor |
| 10435442 | 7001695 | 2003-05-09 | 2006-02-21 | Lapsed | United States of America | Multiple alternating phase shift technology for amplifying resolution |
| 2001138037 | 5544677 | 2001-05-09 | 2014-07-09 | Granted | Japan | Calibration Method For Quantitative Elemental Analysis |
| 2000135070 | 3492977 | 2000-05-08 | 2003-11-14 | Granted | Japan | Electron Emitters for Lithography Tools |
| 2000048754 | 3524461 | 2000-02-25 | 2004-02-20 | Lapsed | Japan | Process For The Fabrication Of Dual Gate Structures For CMOS Devices |
| 2000381501 | 4138232 | 2000-12-15 | 2008-06-13 | Granted | Japan | Dual Damascene Bond Pad Structure for Lowering Stress and Allowing Circuitry Under Pads |
| 1020040023990 | 10-1084957 | 2004-04-08 | 2011-11-14 | Granted | Korea, Republic of (KR) | Aluminum Pad Power Bus And Signal Routing For Integrated Circuit Devices Utilizing Copper Technology Interconnect Structures |
| 10268775 | 3649917 | 1998-09-22 | 2005-02-25 | Lapsed | Japan | Dielectric Materials Of Amorphous Compositions And Devices Employing Same |
| 90121470 | NL-170349 | 2001-08-30 | 2002-12-21 | Granted | Taiwan | Stacked Structure For Parallel Capacitors And Method Of Fabrication |
| 91119882 | NL-188794 | 2002-08-30 | 2004-02-12 | Lapsed | Taiwan | Vertical Replacement-Gate Junction Field-Effect Transistor |
| 20040082410 | 10-1044528 | 2004-10-15 | 2011-06-20 | Lapsed | Korea, Republic of (KR) | Metal-Oxide-Semiconductor Device Having Improved Performance And Reliability. |
| 20050075648 | 10-1184123 | 2005-08-18 | 2012-09-12 | Lapsed | Korea, Republic of (KR) | Metal-Oxide-Semiconductor Device Having An Enhanced Shielding Structure |
| 1020020060412 | 10-939648 | 2002-10-04 | 2010-01-25 | Lapsed | Korea, Republic of (KR) | A Multi-Layer-Inductor Formed In A Semiconductor Substrate |
| 1020040077975 | 10-1045194 | 2004-09-30 | 2011-06-23 | Lapsed | Korea, Republic of (KR) | Real-Time Gate Etch Critical Dimension Control By Oxygen Monitoring |
| 10041685 | 3187764 | 1998-02-24 | 2001-05-11 | Lapsed | Japan | Gas-Based MOSFET, And Method Of Making Same |
| 88122552 | NL-144804 | 2000-02-11 | 2001-11-21 | Granted | Taiwan | Barrier For Copper Metallization |
| 89100359 | NL-144338 | 2000-01-11 | 2002-03-06 | Lapsed | Taiwan | Integrated Circuit Device Having Dual Damascene Capacitor |
| 10349957 | 3242079 | 1998-12-09 | 2001-10-19 | Lapsed | Japan | Lithographic Process For Device Fabrication Using A Multilayer Mask Which Has Been Previously Inspected |
| 10453821 | 6911093 | 2003-06-02 | 2005-06-28 | Lapsed | United States of America | Lid liner for chemical vapor deposition chamber |
| 08314671 | 3226808 | 1996-11-26 | 2001-08-31 | Expired | Japan | Method of Depositing Thin Passivating Film on Microminiature Semiconductor Devices |
| 09085442 | 3600399 | 1997-04-04 | 2004-09-24 | Expired | Japan | Process For Device Fabrication In Which A Thin Layer Of Cobalt Silicide Is Formed |
| 09256542 | 3315064 | 1997-09-22 | 2002-06-07 | Lapsed | Japan | Method Of Reducing Dielectric Damage From Plasma Etch Charging |
| 2001260998 | 4058710 | 2001-08-30 | 2007-12-28 | Lapsed | Japan | Method of Manufacturing An Integrated Circuit |
| 2000190017 | 3737341 | 2000-06-23 | 2005-11-04 | Granted | Japan | High Quality Oxide For Use In Integrated Circuits |
| 90110939 | NL-203745 | 2001-05-08 | 2004-06-21 | Lapsed | Taiwan | Calibration Method For Quantitative Elemental Analysis |

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